

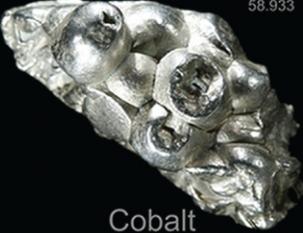
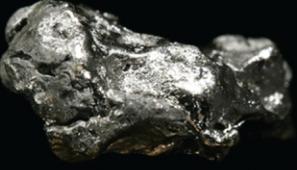
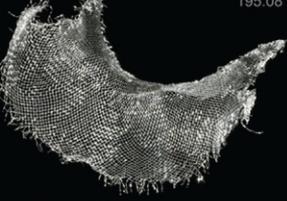
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Condensed Matter and Interphases

Kondensirovannyye Sredy i Mezhfaznye Granitsy
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<p>Rh 45 102.91</p>  <p>Rhodium</p>	<p>Pd 46 106.42</p>  <p>Palladium</p>	<p>Ag 47 107.87</p>  <p>Silver</p>
<p>Ir 77 192.22</p>  <p>Iridium</p>	<p>Pt 78 195.08</p>  <p>Platinum</p>	<p>Au 79 196.97</p>  <p>Gold</p>

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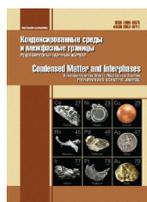
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Original articles

Research article

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Synthesis and study of the properties of synthetic analogues of the mineral naffildite with the participation of rare earth elements

R. M. Agaeva², Sh. H. Mammadov¹✉, D. S. Azhdarova¹, V. M. Ragimova¹, O. M. Aliyev¹¹Nagiev Institute of Catalysis and Inorganic Chemistry of Azerbaijan National Academy of Sciences, 113 G. Javid ave., Baku, Az1143, Azerbaijan²Azerbaijan State Pedagogical University, 68 G. Hajibekli ave., Baku, AZ1000, Azerbaijan**Abstract**

In recent years, there has been a significant increase in interest in ternary and quaternary compounds with the participation of rare earth elements (REE), as well as copper, antimony, and bismuth, which have a wider range of physical properties. Due to their valuable physical properties, they have become promising targets of research for modern materials science. Therefore, the purpose of this work is to study the properties of synthetic analogues of naffildite with the participation of rare earth elements.

The samples were synthesised from ternary sulphides (in the case of obtaining $\text{Cu}_2\text{LaSb}_3\text{S}_7$, $\text{Cu}_2\text{CeSb}_3\text{S}_7$, $\text{Cu}_2\text{PrSb}_3\text{S}_7$ and $\text{Cu}_2\text{NdSb}_3\text{S}_7$) by fusion in sealed quartz ampoules, preliminarily evacuated to a residual pressure of 10^{-3} mmHg at 950–1100 K for 8 hours. The remaining antimony and bismuth-containing analogues, due to the peritectic nature of formation, were synthesised through batches $(2\text{Cu} + \text{Ln} + 3\text{Sb}(\text{Bi}) + 7\text{S})$ from especially pure elements. After completion of the reaction, homogenizing annealing was carried out for a month at 600–700 K, depending on the composition. The obtained samples were investigated by differential thermal (DTA), X-ray phase (XRD) and microstructural (MSA) analyzes, as well as by measuring the microhardness and determining the density.

Compounds of the $\text{Cu}_2\text{LnSb}_3\text{S}_7$ or $\text{Cu}_2\text{LnBi}_3\text{S}_7$ (Ln – REE) type have been synthesised by direct synthesis from elements or from the ligature $\text{CuSbS}_2(\text{CuBiS}_2)$ and $\text{LnSbS}_3(\text{LnBiS}_3)$. It was found that they are isostructural and crystallize in the orthorhombic system ($\text{Cu}_2\text{LnSb}_3\text{S}_7$ – $a = 14.490 \div 14.264$, $b = 21.422 \div 21.206$, $c = 3.902 - 3.804$ Å; $\text{Cu}_2\text{LnBi}_3\text{S}_7$ – $a = 14.722 \div 14.506$, $b = 21.864 \div 21.564$, $c = 4.142 \div 3.464$ Å; $Z = 4$, simple group Pbnm or Pbn2₁) and belong to the structure type of naffildite $\text{Pb}_2\text{Cu}(\text{Pb}, \text{Bi})\text{Bi}_2\text{S}_7$. $\text{Cu}_2\text{LaSb}_3\text{S}_7$, $\text{Cu}_2\text{PrSb}_3\text{S}_7$ and $\text{Cu}_2\text{NdSb}_3\text{S}_7$ melt congruently at 975, 985, and 1015 K, respectively, and other compounds are formed by a peritectic reaction.

Keywords: Compound, Crystal structure, Naffildite, Lattice parameters, Electrical conductivity, Thermal electromotive force

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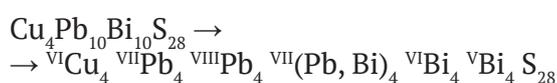
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(trigonal prisms plus two hemi-octahedrons), four Pb atoms and four Bi atoms are arranged in seven-dimensional (hemi-octahedron plus trigonal prism) coordinations. Four Bi atoms are located in the plane at the centre of the hemi-octahedron and have a five-fold coordination. Two Pb atoms and two Bi atoms randomly fill polyhedra consisting of a hemi-octahedron and a trigonal prism which are parallel in a plane. Four Cu atoms are arranged in tetrahedra. They form a quadruple coordination and play the role of a cementing cation. Taking in consideration the aforementioned, the crystal chemical formula of naffildite can be represented as follows:



Thus, the crystal structure of naffildite consists of several polyhedra with complex configurations. It should be noted that this complexity of the configuration of polyhedra allows us to obtain a synthetic homologous series of naffildite by the substitution of cations with the corresponding atoms.

It is known that the CN of lanthanides in complex sulphides varies from 6 to 9 [14], the coordination polyhedra in them are mainly octahedron, trigonal prism, one-, two- and tricapped trigonal prisms. Therefore, the possibility of obtaining new classes of compounds with substitution of Pb in a naffildite structure, which has sevenfold coordination with Eu^{2+} or Yb^{2+} cations (statistically arranged Pb, Bi atoms) with compensating Bi^{3+} cations, located in hemi-octahedra, substituting Sb^{3+} and Ln^{3+} with the naffildite structure, was proposed.

Earlier, we synthesised and studied the properties of synthetic lanthanum and neodymium-containing analogues of the mineral naffildite [15], berthierite [16, 17], aikinite, $\text{CuPbBi}_3\text{S}_6$ [18], and bournonite CuPbSbS_3 [19,20]. Based on this, this study presents the results of the synthesis, X-ray study, and physiochemical properties of analogues of naffildite with other rare earth elements.

2. Experimental

The starting ternary compounds (CuSbS_2 , CuBiS_2 , LnSbS_3 and LnBiS_3) were studied in detail in [1, 21, 22]. For the determination of

the optimal mode of synthesis and growth of single crystals of $\text{Cu}_2\text{LnSb}_3\text{S}_7$ and $\text{Cu}_2\text{LnBi}_3\text{S}_7$ compounds, derived from the structure of naffildite, differential thermal (DTA), X-ray phase (XRD) and microstructural (MSA) analyses, as well as by determination of the microhardness and density were performed. DTA was performed using an NTR-70 Kurnakov thermograph in the temperature range of 298–1200 K. The heating rate was 10 deg/min. Aluminium oxide was used as a standard [23].

X-ray diffraction patterns were recorded using a Bruker D2 PHASER diffractometer (CuK_α -radiation, Ni - filter); MSA was performed using an MIM-8 microscope. The microhardness was measured using a PMT-3 microhardness tester with the loads selected as a result of measuring the microhardness of each phase, and the density was determined by the pycnometric method.

Samples were synthesised from ternary sulphides (in the case of obtaining $\text{Cu}_2\text{LaSb}_3\text{S}_7$, $\text{Cu}_2\text{CeSb}_3\text{S}_7$, $\text{Cu}_2\text{PrSb}_3\text{S}_7$ and $\text{Cu}_2\text{NdSb}_3\text{S}_7$) in sealed quartz ampoules, preliminarily evacuated to a residual pressure of 10^{-3} mmHg at 950–1100 K for 8 hours. The rest of the antimony and bismuth-containing analogues, due to the peritectic nature of the formation, were synthesised through batches ($2\text{Cu} + \text{Ln} + 3\text{Sb}(\text{Bi}) + 7\text{S}$) from extra pure elements. After completion of the reaction, homogenizing annealing was carried out for a month at 600–700 K, depending on the composition.

3. Results and discussion

Phase diagram of CuSbS_2 - PrSbS_3 system, plotted based on the results of physico-chemical analysis, is shown in Fig. 2. As can be seen, with a ratio of components of 2:1, a quaternary sulphosalt of composition $\text{Cu}_2\text{PrSb}_3\text{S}_7$ was formed in the CuSbS_2 - PrSbS_3 system. This compound melts congruently at 985 K and divides the system into two subsystems: CuSbS_2 - $\text{Cu}_2\text{PrSb}_3\text{S}_7$ and $\text{Cu}_2\text{PrSb}_3\text{S}_7$ - PrSbS_3 . Both subsystems are of the eutectic type. Coordinates of eutectic points: 15 mol. % PrSbS_3 and $T = 700$ K, 55 mol. % PrSbS_3 and $T = 825$ K. The solubility based on the original sulphides was limited and was 5 mol. % PrSbS_3 based on CuSbS_2 and 5 mol. % CuSbS_2 based on PrSbS_3 .

The quaternary compound $\text{Cu}_2\text{PrSb}_3\text{S}_7$ is a phase of variable composition and exists in the range of compositions 32÷37 mol. % PrSbS_3 .

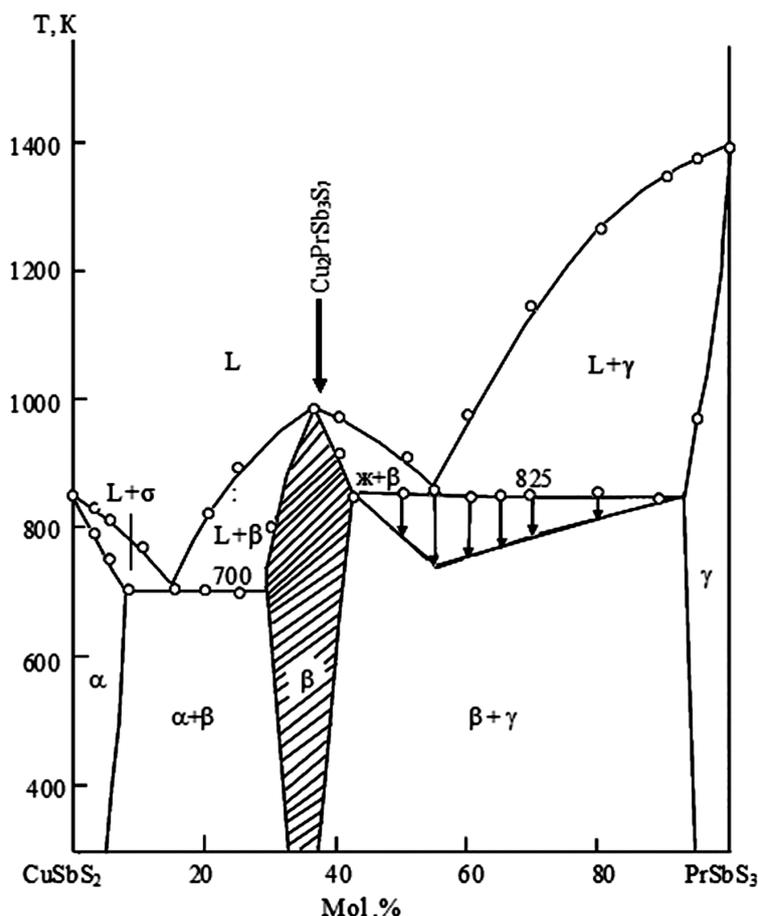


Fig 2. T - x diagram of the $\text{CuSbS}_2 - \text{PrSbS}_3$ system

The formation of a new phase in the system was also confirmed by microhardness measurement data. Depending on the composition in $\text{CuSbS}_2 - \text{PrSbS}_3$ system there are three sets of microhardness values $2300 \div 2450$, $2100 \div 2200$ and $2900 \div 3100$ MPa related to microhardness α , β and γ -phases, respectively.

As we noted above, all systems in the La-Nd series have the same character, i.e., the quaternary compounds melt congruently. Other similar systems involving antimony and bismuth are also quasi-binary, in all cases with a component ratio of 2:1, naffildite-like compounds are formed. However, they melt incongruently.

The XRD data were in complete agreement with the DTA and MSA data and confirm the formation of a compound of $\text{Cu}_2\text{LnSb}_3(\text{Bi})_3\text{S}_7$ type.

Crystallographic data and some physico-chemical properties of compounds of $\text{Cu}_2\text{LnSb}_3(\text{Bi})_3\text{S}_7$ type are shown in Table 1 and the calculations of X-ray diffraction patterns for some compounds of this type are presented in Table 2.

The resulting quaternary compounds are isostructural with each other, crystallize in the orthorhombic syngony, and belong to the naffildite structural type. In the unit cell $\text{Cu}_2\text{LnSb}_3(\text{Bi})_3\text{S}_7$, $Z = 4$, a Pbnm or $\text{Pbnm}2_1$ space group is located. As can be seen from Table 1, the parameters and volume of the elementary cell naturally decrease in the series of lanthanides with an increase in the charge of Ln^{3+} .

The temperature dependences of the electrical conductivity coefficients and thermal electromotive force of some compounds of the $\text{Cu}_2\text{LnBi}_3\text{S}_7$ ($\text{Ln} = \text{La}, \text{Nd}, \text{Sm}, \text{Gd}, \text{Er}$) type were investigated and shown in Fig. 3 and 4.

The measurement results showed that these crystals are characterised by a dependence inherent in impurity semiconductors. In the impurity region (315–343 K), the electrical conductivity gradually increases and, upon transition to the intrinsic region (450–525 K), increases abruptly. The band gap calculated from this region increases in the series $\text{Cu}_2\text{LaSb}_3\text{S}_7 -$

Table 1. Crystallographic and some physicochemical properties of compounds of the $\text{Cu}_2\text{LnSb}_3\text{S}_7$ and $\text{Cu}_2\text{LnBi}_3\text{S}_7$ types

Compound	Lattice parameters, Å			V, Å ³	Density, g/cm ³	Microhardness, MPa	ΔE , eV
	a	b	c				
$\text{Cu}_2\text{LaSb}_3\text{S}_7$	1.4490	21.422	3.902	1232.92	4.38	1950	0.53
$\text{Cu}_2\text{CeSb}_3\text{S}_7$	14.462	21.414	3.972	1230.08	4.46	2000	–
$\text{Cu}_2\text{PrSb}_3\text{S}_7$	14.441	21.460	3.931	1218.23	4.512	2010	–
$\text{Cu}_2\text{NdSb}_3\text{S}_7$	14.460	21.406	3.964	1226.98	4.64	2100	0.60
$\text{Cu}_2\text{SmSb}_3\text{S}_7$	14.392	21.362	3.940	1211.32	4.82	2200	0.73
$\text{Cu}_2\text{GdSb}_3\text{S}_7$	14.362	21.454	3.922	1208.45	4.78	2370	0.80
$\text{Cu}_2\text{ErSb}_3\text{S}_7$	14.303	21.284	3.884	1182.39	4.90	2350	–
$\text{Cu}_2\text{YbSb}_3\text{S}_7$	14.271	21.252	3.842	1152.86	4.96	2400	–
$\text{Cu}_2\text{LuSb}_3\text{S}_7$	14.264	21.206	3.804	1150.64	5.36	2450	–
$\text{Cu}_2\text{LaBi}_3\text{S}_7$	14.722	21.864	4.142	1333.23	5.70	1850	0.38
$\text{Cu}_2\text{CeBi}_3\text{S}_7$	14.704	21.806	4.104	1315.89	5.92	1900	–
$\text{Cu}_2\text{NdBi}_3\text{S}_7$	14.661	21.784	4.046	1292.19	6.16	1940	0.40
$\text{Cu}_2\text{SmBi}_3\text{S}_7$	14.606	21.706	4.022	1275.3	6.32	2080	0.45
$\text{Cu}_2\text{GdBi}_3\text{S}_7$	14.584	21.664	4.00	1263.79	6.54	2150	0.69
$\text{Cu}_2\text{ErBi}_3\text{S}_7$	14.522	21.606	3.486	1093.77	6.70	2200	0.86
$\text{Cu}_2\text{LuBi}_3\text{S}_7$	14.506	21.564	3.464	1083.56	6.83	2360	0.90

Table 2. Calculation of X-ray diffraction patterns of compounds $\text{Cu}_2\text{GdSb}_3\text{S}_7$, $\text{Cu}_2\text{LuSb}_3\text{S}_7$, and $\text{Cu}_2\text{NdBi}_3\text{S}_7$

$\text{Cu}_2\text{GdSb}_3\text{S}_7$				$\text{Cu}_2\text{LuSb}_3\text{S}_7$				$\text{Cu}_2\text{NdBi}_3\text{S}_7$			
d_{exp}	I/I_0	hkl	d_{calc}	d_{exp}	I/I_0	hkl	d_{calc}	d_{exp}	I/I_0	hkl	d_{calc}
7.184	20	200	7.182	7.134	10	200	7.132	7.336	18	200	7.331
4.373	10	320	4.372	5.918	10	230	5.918	5.110	18	230	5.109
3.980	8	330	4.979	4.340	8	320	4.338	4.174	10	150	4.176
3.684	30	250	3.684	4.066	8	150	4.065	4.054	10	330	4.054
3.577	15	060	3.575	3.638	15	250	3.645	3.662	15	400	3.664
3.440	10	031	3.434	3.537	15	060	3.535	3.631	15	060	3.633
3.280	5	221	3.278	3.356	10	201	3.358	3.432	10	131	3.434
3.193	5	260	3.192	3.208	7	221	3.201	3.269	34	430	3.272
3.062	100	141	3.062	3.166	20	280	3.167	3.172	100	141	3.172
2.984	30	440	2.984	3.130	100	147	3.139	3.041	75	440	3.042
2.898	5	241	2.896	2.954	30	440	2.958	2.798	30	450	2.805
2.794	60	331	2.793	2.941	10	241	2.939	2.369	20	470	2.373
2.649	28	401	2.648	2.861	45	331	2.861	2.334	40	271	2.338
2.310	8	511	2.304	2.601	30	401	2.602	2.280	25	560	2.281
2.240	30	560	2.239	2.550	8	161	2.547	2.120	5	650	2.120
2.122	12	1.10.0	2.122	2.271	10	511	2.269	2.093	8	601	2.092
2.034	12	611	2.034	2.226	40	560	2.220	2.050	15	720	2.057
1.958	80	002	1.961	2.120	25	371	2.118	2.023	10	002	2.023
1.875	35	132	1.875	2.100	6	0.10.0	2.098	1.860	30	312	1.862
1.827	8	142	1.827	2.009	8	611	2.007	1.848	35	711	1.853
1.689	12	690	1.689	1.900	10	002	1.902	1.774	25	830	1.778
1.619	8	362	1.618	1.838	6	202	1.837	1.716	8	352	1.718
1.574	5	452	1.597	1.819	30	222	1.811	1.581	8	691	1.583
1.530	10	940	1.530	1.776	8	142	1.776	1.335	26	113	1.333
1.479	5	901	1.478	1.748	20	491	1.747	1.310	10	692	1.310
				1.703	10	741	1.701				
				1.693	10	840	1.690				
				1.670	8	690	1.673				
				1.580	8	362	1.580				
				1.560	10	452	1.560				
				1.520	5	940	1.519				

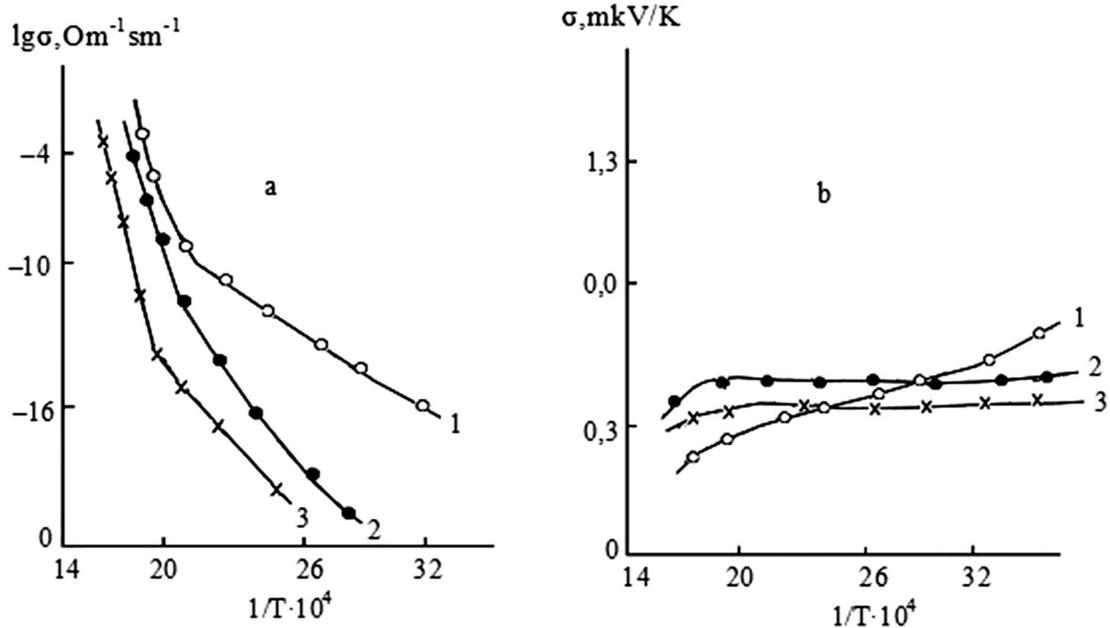


Fig. 3. Temperature dependences of electrical conductivity (a) and thermal electromotive force (b) of compounds of $\text{Cu}_2\text{LaBi}_3\text{S}_7$ (1), $\text{Cu}_2\text{NdBi}_3\text{S}_7$ (2), and $\text{Cu}_2\text{GdBi}_3\text{S}_7$ (3)

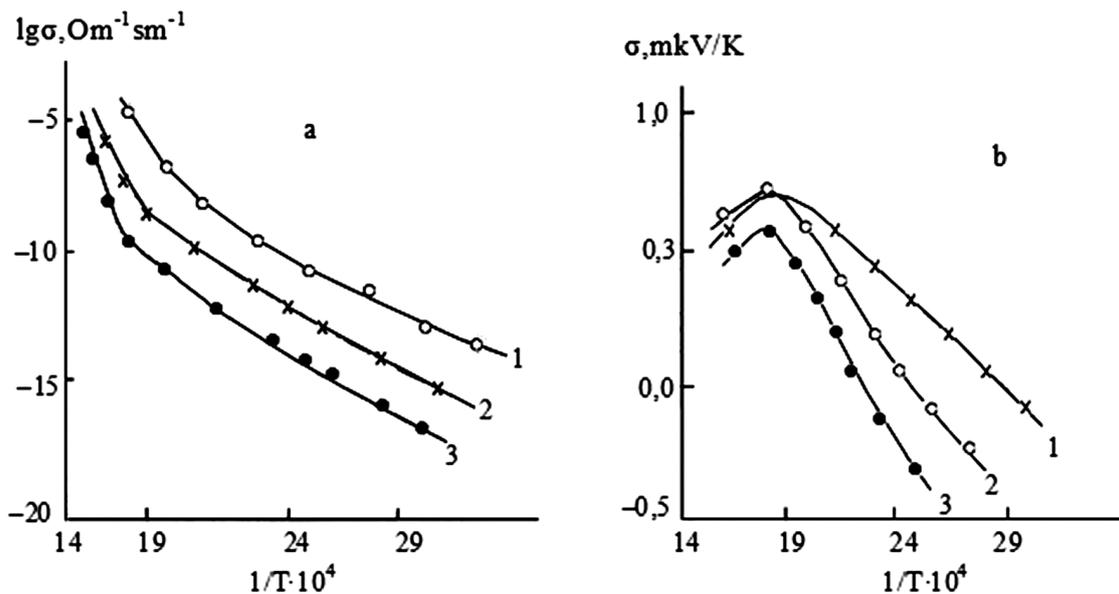


Fig. 4. Temperature dependences of electrical conductivity (a) and thermal electromotive force (b) of compounds of $\text{Cu}_2\text{SmBi}_3\text{S}_7$ (1), $\text{Cu}_2\text{ErBi}_3\text{S}_7$ (2), and $\text{Cu}_2\text{LuBi}_3\text{S}_7$ (3)

$\text{Cu}_2\text{GdSb}_3\text{S}_7$ from $\Delta E = 0.53$ (for $\text{Cu}_2\text{LaSb}_3\text{S}_7$) to $\Delta E = 0.80$ eV (for $\text{Cu}_2\text{GdSb}_3\text{S}_7$) and $\Delta E = 0.38$ eV (for $\text{Cu}_2\text{LaBi}_3\text{S}_7$) to $\Delta E = 0.90$ eV (for $\text{Cu}_2\text{LuBi}_3\text{S}_7$).

The nature of the change of thermal electromotive force (α) for $\text{Cu}_2\text{LaBi}_3\text{S}_7$, $\text{Cu}_2\text{NdBi}_3\text{S}_7$, and $\text{Cu}_2\text{GdBi}_3\text{S}_7$ compounds is similar to a change in electrical conductivity, i.e. in its own region α decreases sharply. In the case of $\text{Cu}_2\text{SmBi}_3\text{S}_7$, $\text{Cu}_2\text{ErBi}_3\text{S}_7$, and $\text{Cu}_2\text{LuBi}_3\text{S}_7$ compounds with an

increase in electrical conductivity, the thermal electromotive force also increases, and in the intrinsic conduction region it decreases, which was probably due to their complex band structure.

4. Conclusions

Technological conditions have been developed and compounds of the $\text{Cu}_2\text{LnSb}_3\text{S}_7$ and $\text{Cu}_2\text{LnBi}_3\text{S}_7$ types have been synthesised. It was

established that they are isostructural, crystallize in the orthorhombic syngony ($\text{Cu}_2\text{LnSb}_3\text{S}_7$ – $a = 14.490 \div 14.264$, $b = 21.422 \div 21.206$, $c = 3.902 - 3.804$ Å; $\text{Cu}_2\text{LnBi}_3\text{S}_7$ – $a = 14.722 \div 14.506$, $b = 21.864 \div 21.564$, $c = 4.142 \div 3.464$ Å; $Z = 4$, space group Pbnm or Pbn₂) and belong to the naffildite structural type.

The crystal lattice parameters of the obtained compounds were calculated and some physicochemical and electrophysical properties were studied. It was established that these compounds are *p*-type semiconductors.

Author contributions

Mammadov Sh. H. – writing of the article and head of scientific research. Aliyev O. M. – idea for the scientific work and writing of the article. Azhdarova D. S. – scientific editing of the text, final conclusions. Agaeva R. M. – conducting research. Ragimova V. M. – conducting research.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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A refined phase diagram of the GeTe-Bi₂Te₃ system

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Abstract

Updated phase diagram of the GeTe–Bi₂Te₃ system was constructed using differential thermal, X-ray diffraction analysis and scanning electron microscopy (SEM) results of alloys synthesized with specially developed technology. The refined version significantly differs from those reported so far. The presented phase diagram reflects six ternary compounds: Ge₄Bi₂Te₇, Ge₃Bi₂Te₆, Ge₂Bi₂Te₅, GeBi₂Te₄, GeBi₄Te₇, and GeBi₆Te₁₀.

The study determined that the first two compounds are formed as a result of solid-state reactions at temperatures of 750–800 K, and the latter four are formed as a result of peritectic reactions at 863, 854, 848, and 843 K, respectively. Wide homogeneity regions based on the initial binary compounds were also found. These regions reach 10 mol% at room temperature. The coordinates of eutectic point are 83 mol% Bi₂Te₃ and 838 K. It crystallises at 838 K. It was found that all the identified ternary compounds crystallise in a tetradymite-like layered structure. Ge₄Bi₂Te₇, Ge₃Bi₂Te₆, Ge₂Bi₂Te₅, and GeBi₂Te₄ compounds belong to the *n*GeTe–Bi₂Te₃ homologous series. Their crystal lattices are formed by the insertion of GeTe bilayers into the quintuple Bi₂Te₃ layers. GeBi₄Te₇ and GeBi₆Te₁₀ compounds are representatives of the GeTe–*m*Bi₂Te₃ homologous series and have a mixed-layer structure. The parameters of the crystal lattices of the compounds were determined by the Rietveld method based on their powder diffraction data.

Keywords: Germanium-bismuth tellurides, Phase diagram, Layered tetradymite-like structures, Solid solutions

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1. Introduction

In recent years, there has been a growth of interest in layered chalcogenides which serve as functional materials for various purposes [1–3]. Such valuable materials include ternary compounds of the A^{IV}Te-B^V₂Te₃ (A^{IV}-Ge, Sn, Pb; B^V-Sb, Bi) systems with a layered tetradymite-like structure. These compounds have long been the focus of research since they are thermoelectric materials with low thermal conductivity [2–8]. After the discovery of a new state of quantum matter - a topological insulator (TI) [9, 10], it was determined that compounds of the types A^{IV}B^V₂Te₄, A^{IV}B^V₄Te₇, A^{IV}B^V₆Te₁₀, etc. are three-dimensional TIs, which can have a variety of applications, including in spintronics, quantum computing, medicine, security systems, etc. [11–19]. In addition, it should be noted that Ge-B^V-Te alloys are widely used in optical storage devices and are currently considered to be the main class of materials with a reversible phase transition between amorphous and crystalline states [20–23].

The development of new methods for the directed synthesis of complex inorganic phases, in particular chalcogenide phases, is based on the data on the phase equilibrium and thermodynamic properties of the corresponding systems [15, 24]. The analysis of the existing literature regarding the phase equilibrium of A^{IV}Te-B^V₂Te₃ systems conducted in [15] showed that, despite the increased interest in the above mentioned ternary compounds, the phase diagrams of these systems are far from being perfect and need to be studied more thoroughly.

A specific feature of GeTe-B^V₂Te₃ systems, which makes them particularly interesting, is the fact that, besides the compounds of the GeTe-*m*B^V₂Te₃ homologous series, typical for all A^{IV}Te-B^V₂Te₃ systems, they also form compounds of the *n*GeTe-B^V₂Te₃ series [15, 25–29]. The information regarding the crystal structure and various physical properties of many of these ternary compounds is given in [15, 18, 25–31].

According to the available literature data, the quasi-binary system GeTe-Bi₂Te₃ has been investigated by a number of studies [25–27, 32]. The first phase diagram of the GeTe-Bi₂Te₃ system was constructed in 1965 [32]. According to [32], the system is characterized by the presence of

compounds Ge₅Bi₂Te₆, GeBi₂Te₄, and GeBi₄Te₇ formed as a result of peritectic reactions, as well as by wide regions of solid solutions based on both of the initial binary compounds. [25–27] describe additional detailed XRD studies of the quasi-binary system GeTe-Bi₂Te₃ and present its compiled phase diagram taking into account the data from [32]. Besides the above listed ternary compounds, the phase diagram shows the presence of compositions of some other ternary compounds without specifying the nature and temperature of their formation.

Considering the above, we undertook a new study of the phase equilibrium in the GeTe-Bi₂Te₃ system using a specially developed technique for the synthesis of the samples. The resulting new version of the T-x diagram in the composition range of 0–50 mol% Bi₂Te₃ was presented in [33].

We have now completed our study of the phase equilibria in the GeTe-Bi₂Te₃ system and constructed its complete T-x diagram. The results are presented in this article.

2. Experimental

2.1. Materials and synthesis

The alloys of the studied system were synthesised in two stages. First, binary compounds GeTe and Bi₂Te₃ were synthesised by melting high purity elemental germanium (CAS 7440-56-4), bismuth (CAS 7440-69-9), and tellurium (CAS 13494-80-9) in evacuated (~10⁻² Pa) quartz ampoules at temperatures of ~50 °C higher than their melting points. The binary compounds were identified using the differential thermal analysis (DTA) and the X-ray diffraction analysis (XRD) methods. Then, we obtained the alloys of the GeTe-Bi₂Te₃ system by fusing the initially synthesized and identified binary compounds in evacuated quartz ampoules with various ratios. The synthesized alloys was examined by means of the DTA and XRD techniques.

When designing the second stage of the synthesis, we took into account the previously published data [26, 34, 35], according to which bulk samples of layered tetradymite-like phases, obtained by the well-known fusion method, do not reach the equilibrium state even after being subjected to thermal annealing for a long time (2000–3000 h). Apparently, this is accounted for by the fact that, in contrast to standard bulk

phases, van der Waals phases obtained under nonequilibrium crystallisation conditions (i.e. standard cooling of the melt), practically do not change during further thermal annealing due to very low diffusion level between layers.

Taking this into account, in order to ensure a high degree of dispersion of the alloys containing layered phases, in [36–39] the fused samples were quenched from the liquid state by dropping ampoules into cold water followed by stepwise annealing.

In this study, we applied the same technique. After the fusion, the samples were quenched from a liquid state (950 K) in iced water and then subjected to thermal annealing at 800 K for 1000 h.

2.2. Research methods

In our study, we used DTA, XRD, and SEM methods.

The DTA was performed using a DSC NETZSCH 404 F1 Pegasus differential scanning calorimeter and a multi-channel DTA device

based on an electronic TC-08 Thermocouple Data Logger. Powder diffraction patterns of the initial compounds and intermediate alloys were recorded on a Bruker D8 diffractometer with CuK_α-radiation within an angle range of $2\theta = 10\div 80^\circ$. The diffraction patterns were indexed and the lattice parameters were calculated using Topas 4.2 software by the *Le Bail method*. The EDX (energy dispersive X-ray spectroscopy) analysis was performed on a HITACHI SU8030 scanning electron microscope with a Bruker-EDX detector system.

3. Results and discussion

XRD study of annealed alloys with compositions of $F > 50$ mol. % Bi₂Te₃ showed that samples correspond to GeBi₄Te₇ and GeBi₆Te₁₀ stoichiometric compositions, as well as with sample with 90 mol.% Bi₂Te₃ composition were single phased. Powder diffraction patterns of the mentioned alloys are given in Fig. 1a-c. An analysis of the powder diffraction patterns showed that they were completely indexed in

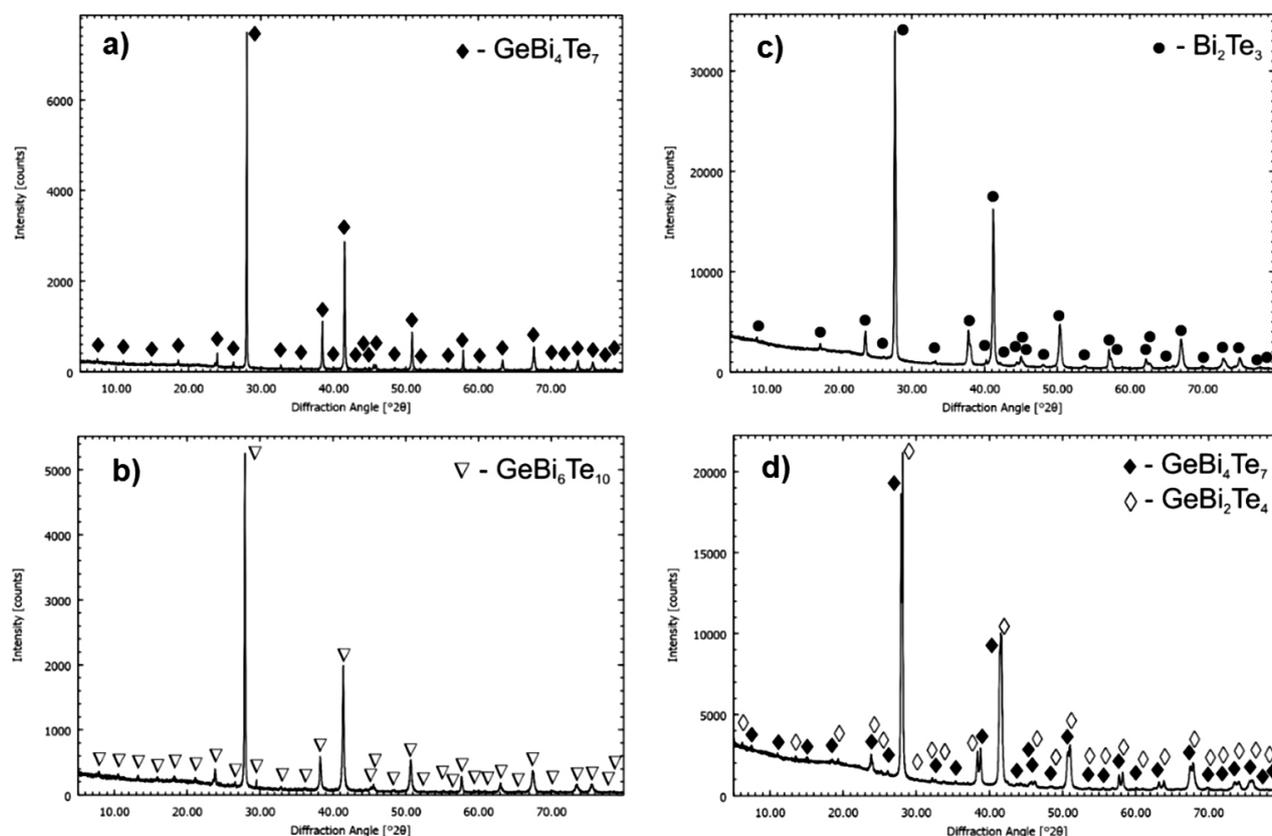


Fig. 1. X-ray powder diffraction patterns of GeBi₄Te₇ (a), GeBi₆Te₁₀ (b), 90 mol% Bi₂Te₃ (c), and 57.5 mol% Bi₂Te₃ (d)

a tetradymite-like hexagonal structure. The lattice parameters calculated by the Rietveld method are given in Table 1. The table also gives the crystallographic parameters of the synthesised GeTe and Bi₂Te₃, as well as of other ternary compounds of the GeTe-Bi₂Te₃ system according to the data obtained in our earlier study [33].

The XRD data also confirmed the phase compositions of the alloys from two-phase regions GeBi₂Te₄-GeBi₄Te₇, GeBi₄Te₇-GeBi₆Te₁₀, and GeBi₆Te₁₀-β. As an example, Fig. 1d shows the diffraction pattern of an alloy with a

57.5 mol% Bi₂Te₃ composition. As we can see, the sample consists of a two-phase mixture GeBi₂Te₄+GeBi₄Te₇.

The results of SEM correlated with the XRD data. Fig. 2 demonstrates the SEM images of compounds GeBi₂Te₄, GeBi₄Te₇, and GeBi₆Te₁₀. These results confirm that all the samples are single-phase and have a layered structure. Fig. 3 and Table 2 show the results of the elemental microanalysis of one of these compounds, namely GeBi₆Te₁₀, which appeared in the phase diagram of the GeTe-Bi₂Te₃ system for the first time. As can be seen from Table 2, the elemental composition

Table 1. Crystallographic parameters of the phases in the GeTe-Bi₂Te₃ system

Composition	Crystal system, space group, and lattice parameters, Å
GeTe	Trigonal, <i>R3m</i> , <i>a</i> = 4.1628(3), <i>c</i> = 10.6675(8)
Ge ₄ Bi ₂ Te ₇	Trigonal, <i>R3m</i> , <i>a</i> = 4.2638(2), <i>c</i> = 73.271(3)
Ge ₃ Bi ₂ Te ₆	Trigonal, <i>R3m</i> , <i>a</i> = 4.2730(3), <i>c</i> = 62.634(4)
Ge ₂ Bi ₂ Te ₅	Trigonal, <i>P-3m1</i> , <i>a</i> = 4.2986(2), <i>c</i> = 17.335(3)
GeBi ₂ Te ₄	Trigonal, <i>R-3m</i> , <i>a</i> = 4.3176(3), <i>c</i> = 41.259(5)
GeBi ₄ Te ₇	Trigonal, <i>P-3m1</i> , <i>a</i> = 4.3556(2), <i>c</i> = 23.928(4)
GeBi ₆ Te ₁₀	Trigonal, <i>R-3m</i> , <i>a</i> = 4.3572(3), <i>c</i> = 101.911(2)
90 mol. % Bi ₂ Te ₃	Trigonal, <i>R-3m</i> , <i>a</i> = 4.3693(2), <i>c</i> = 30.2132(2)

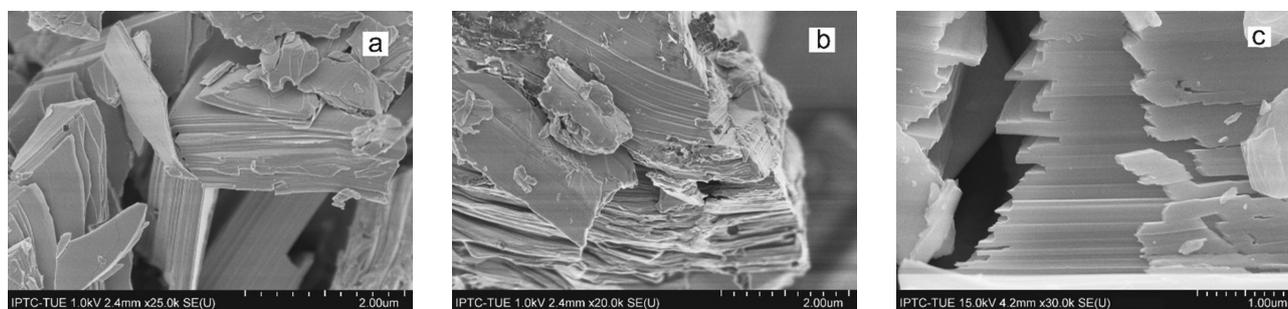


Fig. 2. SEM images of compounds GeBi₂Te₄(a), GeBi₄Te₇, (b) and GeBi₆Te₁₀ (c)

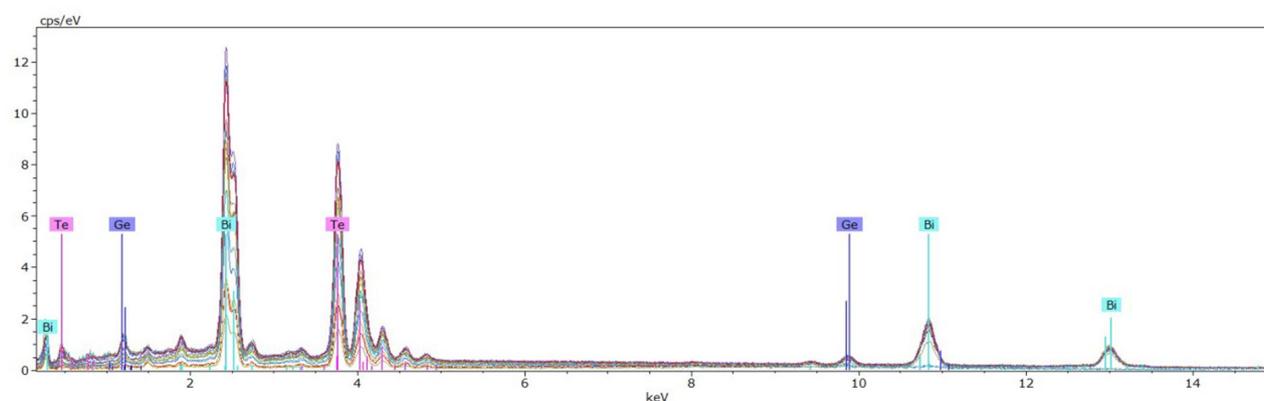
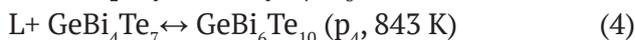
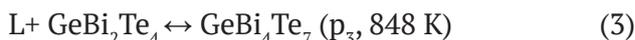


Fig. 3. EDX spectrum of a single crystal GeBi₆Te₁₀

corresponds to the stoichiometry of the said compound.

Based on the DTA data and the results of XRD and SEM, we constructed a T-x diagram of the system GeTe-Bi₂Te₃ (Fig. 4). A part of the phase diagram in the region of 0–50 mol% Bi₂Te₃ composition was adopted from [33]. The diagram presented in Fig. 4 shows the presence of six new ternary compounds, four of which are formed as a result of the following peritectic reactions:



At the peritectic points, the compositions are the following: 52 (p₁), 60 (p₂), 73 (p₃), and 77 mol% Bi₂Te₃ (p₄) respectively.

The system has eutectic equilibrium (E) with the coordinates of the eutectic point being 83 mol% Bi₂Te₃ and 838 K.

The data on the GeTe - GeBi₂Te₄ subsystem is presented and discussed in detail in [33]. A characteristic feature of the phase equilibria in this system is the incongruent nature of melting

Table 2. Elemental composition of GeBi₆Te₁₀ according to EDX

Element	Series [wt %]	Non standard C [wt %]	Standard C [wt %]	Atom C [at %]	Error (3 sigma) [wt %]
Germanium	K-series	2.51	2.69	5.65	0.28
Bismuth	L-series	43.84	47.07	34.33	3.33
Tellurium	L-series	46.79	50.24	60.02	4.10
	Total	93.14	100.00	100.00	

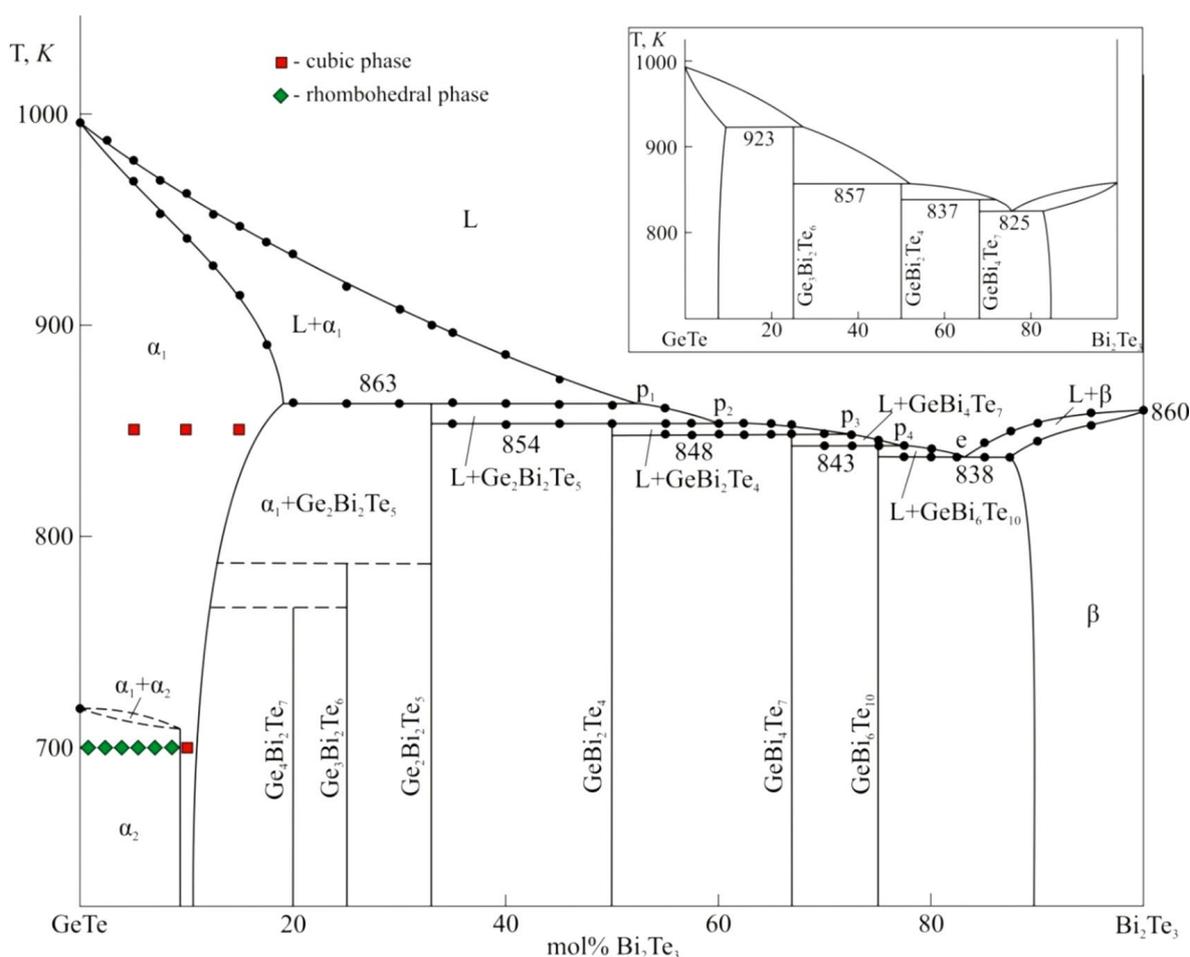


Fig. 4. Phase diagram of the GeTe-Bi₂Te₃ system. A T-x diagram based on the data from [32] is given in the right-hand upper corner.

of the compounds and small difference (5–8°) in the temperatures of peritectic reactions. We registered thermal effects with similar temperatures on the DTA curves of the samples weighing 0.05–0.1 g. For heavier samples these peaks overlap forming one large peak. Fig. 5 demonstrates the DTA heating curves for the samples with a 55 mol% Bi₂Te₃ composition weighing 0.5 and 0.1 g. It is obvious that the sample weighing 0.5 g has 1 endothermic peak covering the temperature range of 848–860 K, while the thermogram of the sample weighing 0.1 g clearly shows three endothermic effects at 848, 854, and 860 K. According to Fig. 4, the first two endothermic effects correspond to peritectic reactions (2) and (1), and the third effect corresponds to the end of melting.

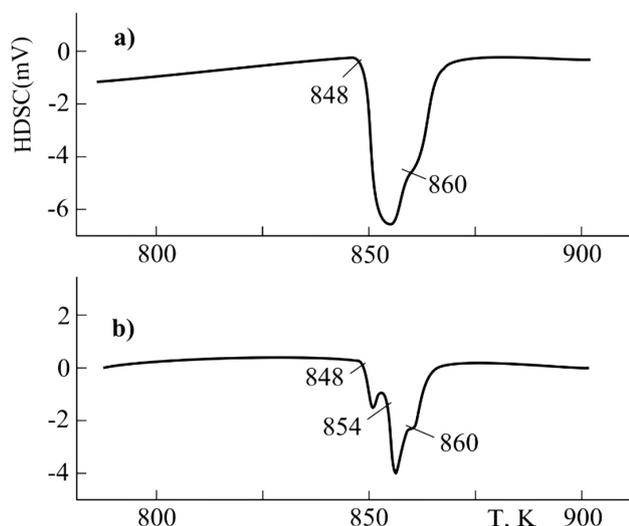


Fig. 5. DTA heating curves of the samples of 55 mol% Bi₂Te₃ weighing 0.5 (a) and 0.1 g (b)

An updated version of the GeTe-Bi₂Te₃ phase diagram differs significantly from that presented in [25, 32] in the number of ternary compounds and the nature and temperature of their formation (Fig. 4). We assume that this may be due to the nonequilibrium of the samples obtained in [25, 32], since the homogenization is hindered due to their layered structure.

3. Conclusions

Based on the results of DTA, XRD, and SEM analyses of carefully homogenized alloys synthesized by means of a specially developed technique, a new version of the phase diagram of the GeTe-Bi₂Te₃ system was constructed. It

shows the presence of six ternary compounds, Ge₄Bi₂Te₇, Ge₃Bi₂Te₆, Ge₂Bi₂Te₅, GeBi₂Te₄, GeBi₄Te₇, and GeBi₆Te₁₀, in the system formed as a result of solid-phase (the first two compounds) and peritectic reactions. The study also revealed wide homogeneity regions based on Bi₂Te₃ and both modifications of GeTe. The constructed phase diagram differs significantly from the ones presented in earlier studies.

It was found that all the identified ternary compounds crystallise in a tetradymite-like layered structure. The first three compounds belong to the *n*GeTe-Bi₂Te₃ homologous series, and the rest of them belong to the GeTe-*m*Bi₂Te₃ series. The parameters of the crystal lattices of the identified ternary compounds were calculated using the Rietveld method based on their powder diffraction patterns. We do not exclude the possibility of existence of other representatives of both homologous series, although we did not observe any in the synthesised samples.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

Research article

<https://doi.org/10.17308/kcmf.2022.24/9051>**Preparation and characterisation of cobalt and cobalt-zinc ferrites for magnetorheological materials**Yu. S. Haiduk¹✉, E. V. Korobko², D. A. Kotsikau¹, I. A. Svito¹, A. E. Usenka¹, V. V. Pankov¹¹Belarusian State University,
4 Nezavisimosty pr., Minsk 220030, Belarus²A. V. Luikov Heat and Mass Transfer Institute of NAS of Belarus,
15 P. Brovki ul., Minsk 220072, Belarus**Abstract**

The aim of this study was to study the structure, morphology, magnetic, and magnetorheological properties of cobalt and cobalt-zinc ferrite powders to be used as a functional component of magnetorheological fluids.

Ferrites of cobalt CoFe_2O_4 and cobalt-zinc $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ were obtained by combined hydrolysis of inorganic metal salt in aqueous solutions followed by thermal treatment of the precipitates. The ferrites were studied by means of X-ray phase analysis, scanning electron microscopy, IR spectroscopy, and magnetometry.

The synthesised ferrites are polydispersed powders with the size of primary particles of 300–400 nm and the size of the coherent scattering regions of 22–33 nm. They demonstrate a high shear stress in magnetorheological suspensions, which is 2.5 times higher than that of the nanosized particles. High-temperature annealing results in a significant increase in the specific magnetisation of the powders, as well as the shear stress in suspensions prepared on their basis. Doping cobalt ferrite with zinc leads to an increase in the specific magnetisation and rheological characteristics.

The studied materials have a high shear stress in suspensions (~ 2.5 kPa at 650 mT) and can be used as functional fillers for magnetorheological materials.

Keywords: Cobalt ferrite, Cobalt-zinc ferrite, Magnetorheological materials

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1. Introduction

Magnetic fluids (MF) and magnetorheological fluids (MRF) belong to the category of magnetically controllable materials. They differ in the degree of the magnetorheological effect, which is much stronger in MRFs than in MFs. MFs usually contain nanosized magnetic particles, whose concentration in the composition does not exceed a few vol%. The concentration of magnetic particles in MRFs can reach up to 50 vol%, and their size usually exceeds 0.1 μm [1]. MRFs are used as an active medium for damping devices designed for the protection of vehicles, industrial equipment, buildings, and structures from vibrations and other mechanical influences, as well as for shaft hermitization, production of prostheses, and production of recoil devices and return systems for artillery, etc. [2].

The most common way to gain the magnetorheological response of a suspension is to increase the magnetisation of micro- and nanosized magnetic particles reducing the coercivity, as well as to obtain anisometric particles (for instance, needle-like particles). In order to do this, it is necessary to enhance the existing methods for synthesising magnetic materials. A promising solution is to combine micro- or nanoparticles rather than to use them separately. It is known that micron particles demonstrate stronger magnetorheological effect, and their combination with nanoparticles stabilises the suspension preventing or slowing down the aggregation and sedimentation processes. A combined effect of several factors (the morphology of the particles, their magnetisation, the coercive force, and the mass fraction in the suspension) can lead to a synergistic effect, which in turn results in an emergent viscosity effect.

Cobalt and cobalt-zinc ferrites synthesised by means of chemical coprecipitation [3–6], the sol-gel method [7], electrostatic spraying [8] and other methods are being actively studied as promising ferrimagnetic materials. Zinc ferrite has a cubic spinel lattice with normal distribution of cations in the spinel sublattices, while cobalt ferrite has a reverse structure. Structural deviations result in a nonequilibrium distribution of cations in the lattice and cause a change in the magnetic properties [9–11]. In addition, changing the distribution of the cations in the ferrite lattice

by forming solid solutions between certain ferrite compositions, we can alter the magnetic properties of the material to a certain degree. Thus, the introduction of a non-magnetic Zn^{2+} ion to the lattice of cobalt ferrite with a strong preference for tetrahedral positions will cause the migration of Fe^{3+} ions into the octahedral positions, leading to an increase in the magnetic moment.

In our earlier study [12], we developed a technique that allows controlling the magnetic properties of cobalt-zinc ferrite by substituting for cobalt ions in the structure of Co-Zn spinel with a non-magnetic double charge cation, namely zinc. We found that an increase in the magnetisation and a decrease in the coercivity occurs until the concentration of zinc reaches $x = 0.35$ ($\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$). The ferrites obtained by spray-drying followed by annealing in the inert component matrix (NaCl) consisted of particles that are uniform in size (~ 50 nm), some of them being in a superparamagnetic state. The powder had specific magnetisation of about ~ 45 $\text{A}\cdot\text{m}^2\text{kg}^{-1}$ and demonstrated a shear stress of ~ 1 kPa in a suspension based on industrial oil, with the magnetic field induction being 600 mT [12].

The aim of this study was to study the structure, morphology, magnetic, and magnetorheological properties of cobalt and cobalt-zinc ferrite powders to be used as a functional components of magnetorheological materials, namely magnetorheological fluids. To increase the average size of the particles, their specific magnetisation, and, as a result, the shear stress in ferrite suspensions, we used the method of chemical precipitation from aqueous solutions followed by high-temperature treatment of the precipitates in air.

2. Experimental

The CoFe_2O_4 ferrite powder was obtained from solutions of the metal salts followed by high-temperature annealing. Samples of $\text{CoSO}_4\cdot 7\text{H}_2\text{O}$ weighing 36.54 g and $\text{Fe}(\text{NO}_3)_3\cdot 9\text{H}_2\text{O}$ weighing 52.54 g were dissolved in 1 l of distilled water. An ammonia solution was poured into the resulting salt solution with vigorous stirring. The pH level of the resulting suspension was monitored (pH = 11.0). The suspension was heated to 90 °C. The precipitate was washed by magnetic

decantation, after which it was heat treated at 740 °C for 8 h in air and ground in an agate mortar.

To obtain $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ samples, powders of $\text{CoSO}_4 \cdot 7\text{H}_2\text{O}$ (16.25 g), ZnCl_2 (4.26 g), and $\text{Fe}(\text{NO}_3)_3$ (49.81 g) were dissolved in 1.5 l of distilled water. The solution was stirred with magnetic stirrer for 5 min to reach complete homogenisation. An ammonia solution was poured into the resulting salt solution under vigorous stirring and the pH level of the formed suspension was monitored using indicator paper (pH = 11.0). The suspension was heated to 90 °C. The precipitate was washed by magnetic decantation [12], after which it was heat treated at 740 °C for 8 h and ground in an agate mortar.

X-ray studies were performed using a DRON-3 diffractometer (CoK_α -radiation, $\lambda = 0.1790$ nm) within an angle range of $2\theta = 6\text{--}90^\circ$. The sizes of coherent scattering regions (CSR) were determined by the broadening of diffraction reflections (Scherrer method).

The radiodensity was calculated using the formula:

$$d_x = \frac{8M}{a^3 N_A}, \quad (1)$$

where M is formal molecular weight; a is the lattice parameter, and Å ; N_A is Avogadro number.

The degree of crystallinity of the samples was determined using the ratio:

$$\left(1 - \frac{I_{\text{background}}}{I_{311}}\right) \times 100\%, \quad (2)$$

where I_{311} is the intensity of the reflex of the spinel, corresponding to the crystallographic direction 311; $I_{\text{background}}$ is the intensity of the background line of the x-ray diffraction pattern.

Dislocation density δ (number of lines per 1 m^2) was calculated using the formula:

$$\delta = \frac{1}{D^2}. \quad (3)$$

IR-spectra were recorded using an AVATAR FTIR-330 spectrometer (Thermo Nicolet) in the wavenumber region (ν) 400–700 cm^{-1} with a resolution of ± 1 cm^{-1} . The spectra were registered in adiffuse scattering mode using the Smart Diffuse Reflectance accessory.

The surface structure of polycrystalline and film samples was studied by means of

scanning electron microscopy using a LEO 1420. Simultaneously, the ratio of the concentration of metal atoms in ferrite powders and the features of their distribution on the surface of the particles were determined by energy dispersive X-ray spectroscopy (EDX-analysis).

The magnetic characteristics were studied using a Cryogen Free Measurement System from Cryogenic Ltd, where hysteresis loops were recorded at temperatures of 10 and 300 K and magnetic field induction $B_{\text{max}} = 8$ T. The weight of the samples, not including the capsule, was 0.04134 g for CoFe_2O_4 and 0.0685 g for $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$.

The dependence of the shear stress (τ) of the suspensions on the magnetic induction of the applied magnetic field was measured using a Physics MCR 301 AntonPaar rotational viscometer in constant shear rate mode (Mobil 22 binder, shear rate $\dot{\gamma} = 200$ s^{-1} , $T = 20^\circ$ C). Powder suspensions in the binder were prepared using a UZDM-2 ultrasonic disperser with a frequency of 44 kHz.

3. Results and discussion

Fig. 1 demonstrates the XRD spectra of the CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ ferrites, obtained by means of coprecipitation followed by thermal treatment in air (740 °C, 8 h), and the XRD spectrum of the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ ferrite, obtained in [12] by spray-drying followed by thermal treatment in air (740 °C, 8 h) for comparison.

By analysing the XRD spectra we can say that in all the three cases the formation of the spinel ferrite structure (space group $Fd\bar{3}m$) is completed under the set thermal treatment conditions. The diffraction peaks demonstrate high intensity and slight broadening, which indicates the formation of a highly ordered crystal lattice. The peaks positions and their relative intensities indicate the presence of a single phase with a spinel structure. The structural parameters of the crystal lattice are given in Table 1.

The size of the coherent scattering regions corresponding to the physical sizes of crystallites was 36 and 31 nm for CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ obtained by coprecipitation, which is significantly greater than that of the sample obtained by spray-drying (20 nm). This is accounted for by the fact that the annealing of ferrite in the

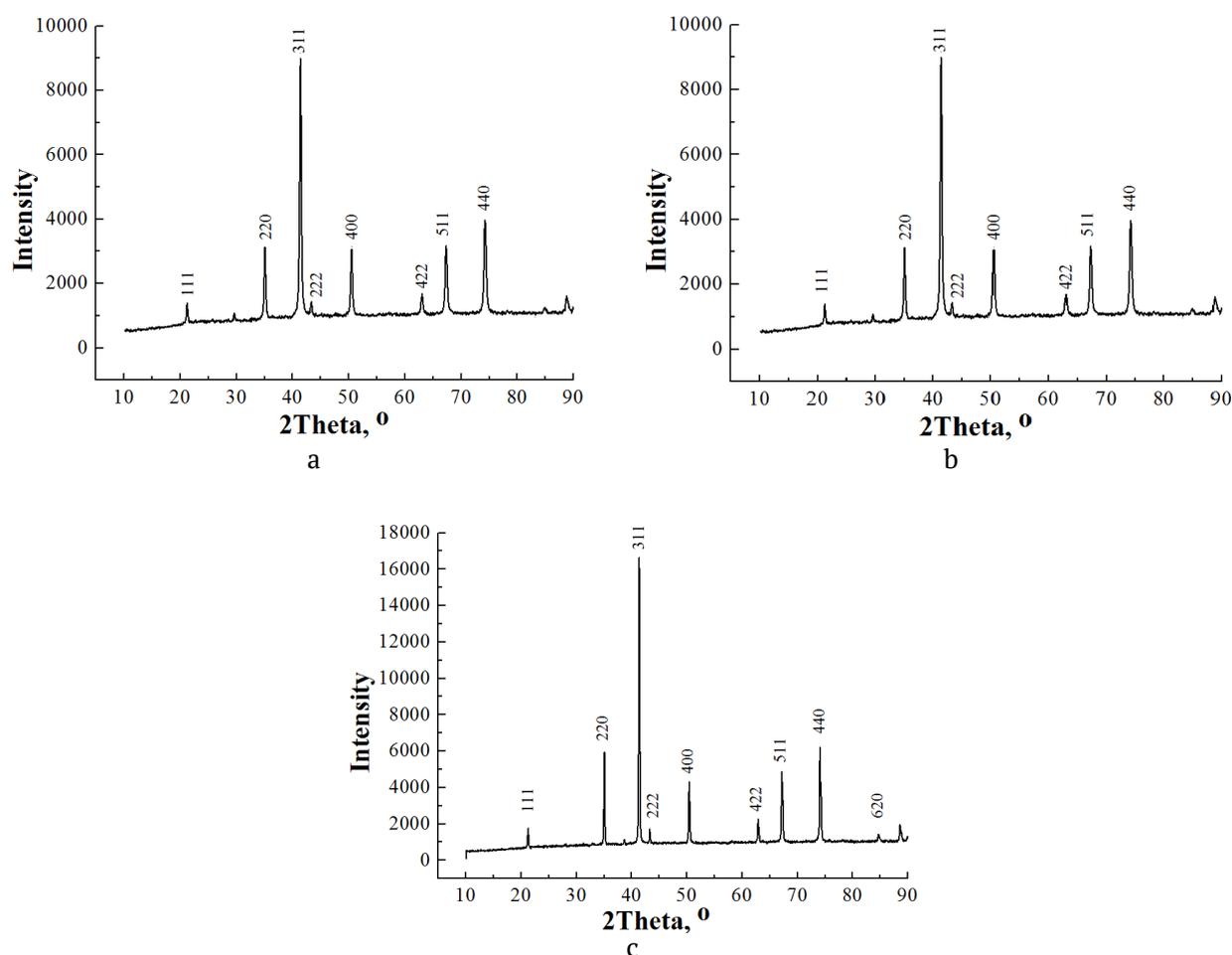


Fig. 1. XRD spectra: a) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ (spray-drying); b) CoFe_2O_4 (coprecipitation), c) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ (coprecipitation)

Table 1. The structural parameters of the crystal lattice: lattice constant a , unit cell volume V , size of the CSR D , dislocation density δ , radiodensity d_x , degree of crystallinity d_c for $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders (spray-drying) (1), CoFe_2O_4 (coprecipitation) (2), $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ (coprecipitation) (3)

Sample	a , Å	V , nm^3	D , nm	$\delta \times 10^2 \text{ nm}^{-2}$	d_x , g/cm^3	d_c , %
1	8,3998	592,626	20	0,2500	5,310	85
2	8,3898	590,554	22	0,2066	5,279	88
3	8,4037	593,488	33	0,0918	5,293	94

inert sodium chloride medium hinders the growth of crystallites. The samples obtained by coprecipitation also demonstrate higher crystallinity and lower dislocation density.

Fig. 2. shows fragments of SEM micrographs of the studied CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders, which demonstrate a high degree of agglomeration of the particles. Agglomerates larger than $1 \mu\text{m}$ appear either due to the surface properties of the particles, or due to the fact that the thermal treatment conditions induced the

first stage of the sintering accompanied by the formation of small bridges between the particles. The primary particles have the size of $300 - 400 \text{ nm}$ and a specific shape with pronounced facets. $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ particles are more crystallized because the temperature of the synthesis and sintering of zinc ferrite is much lower than that of cobalt ferrite.

A comparison of the size of crystallites (coherent scattering regions), calculated by the diffractometry method (Table 1), and the size of

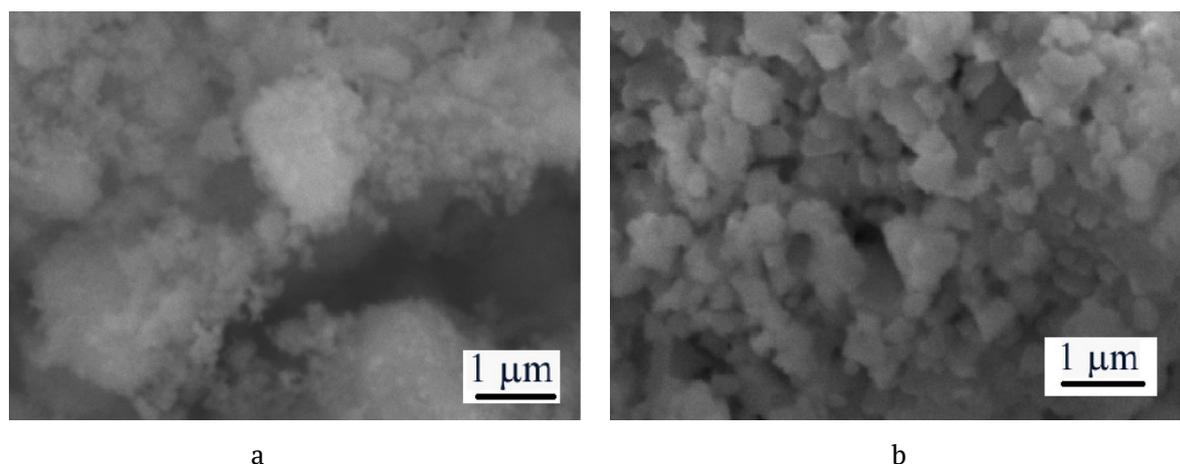


Fig. 2. SEM micrographs: a) CoFe_2O_4 (coprecipitation); b) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ (coprecipitation)

the particles demonstrated that after annealing at $740\ \text{°C}$ some particles include several crystallites and are multidomain. It is known that the critical size for the transition of a single-domain particle to a multidomain at $300\ \text{K}$ is around $40\ \text{nm}$ (for cobalt ferrite, for instance) [13]. In the region of transition to the ferromagnetic state, following the growth of the particles crystallites spontaneously break up into several domains in order to reduce high magnetisation energy of a single-domain particle.

Fig. 3 shows the IR absorption spectra of the CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders.

In the region of characteristic frequencies both CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ spectra demonstrate pronounced combined vibrational bands of $\text{Me}-\text{O}$ (at 414 and $567\ \text{cm}^{-1}$). The band at $414\ \text{cm}^{-1}$ usually refers to the octahedral

vibrations of the metal $\text{Me}_{\text{octa}} \leftrightarrow \text{O}$, and the band at $567\ \text{cm}^{-1}$ corresponds to the internal stretching vibrations of the metal in the site $\text{Me}_{\text{tetra}} \leftrightarrow \text{O}$ [5]. The said absorption bands are also observed in the spectrum of $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ obtained by spray-drying [12]. All the bands have a high degree of resolution, which may reflect a high ordering of the crystal structure.

A wide absorption band at $1600\ \text{cm}^{-1}$ [12], corresponding to vibrations of adsorbed water [11], is much less prominent in the CoFe_2O_4 sample (Fig. 3a) and practically absent in the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ sample (Fig. 3b). The spectrum of $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ obtained by spray-drying also demonstrated absorption at $2100\text{--}2300\ \text{cm}^{-1}$, $1500\text{--}1600\ \text{cm}^{-1}$, and near $1000\ \text{cm}^{-1}$ (presumably explained by the absorption of CO_2 molecules and NO_3^- ions). The corresponding absorption

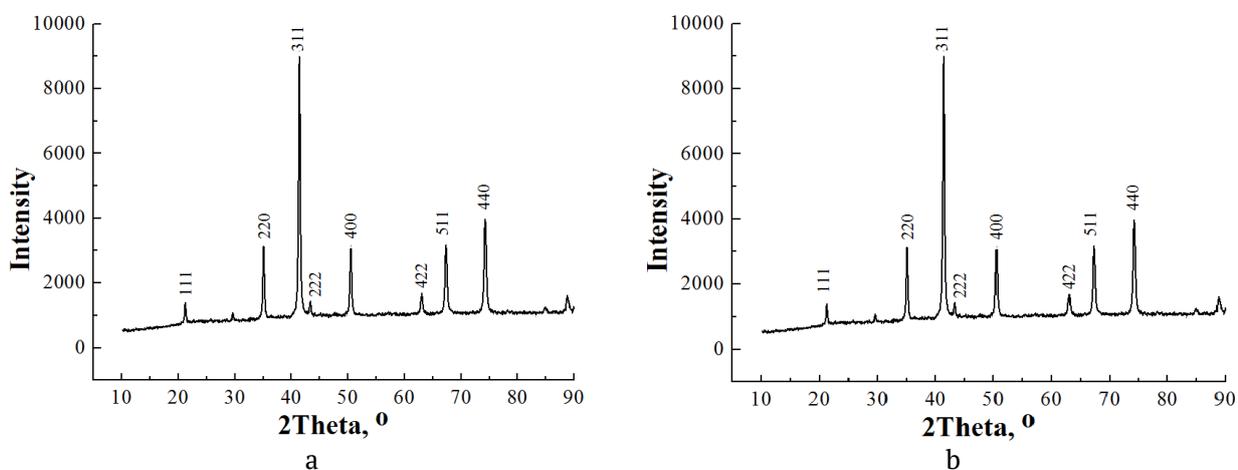


Fig. 3. IR absorption spectrum: a) CoFe_2O_4 ; b) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$

bands are much less prominent in the spectrum of CoFe_2O_4 (Fig. 3a) and absent in the spectrum of the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ sample obtained by coprecipitation (Fig. 3b).

Fig. 5 shows the change in magnetisation for CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ obtained by coprecipitation depending on the magnetic field induction. Both powders exhibited ferrimagnetic behaviour. The specific magnetisation of the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powder obtained in this study exceeds the specific magnetisation of cobalt-zinc ferrites of the same composition obtained using other methods, namely the sol-gel method ($60\div 80 \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$) [14, 15] and coprecipitation from aqueous solutions of inorganic salts ($40\div 70 \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$) [16], ($60 \div 90 \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$) [17].

In our earlier article we demonstrated that with an increase in the zinc content in the cobalt-zinc ferrite, an increase in the saturation magnetisation was noted. Thus, for the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powder the magnetisation was $M_s = 42.6 \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$, and for the CoFe_2O_4 powder it was $M_s = 25.0\text{--}26.0 \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$. When the concentration of Zn^{2+} ions increased from 0 to 0.35, the total magnetisation ($M_{\text{oct.}}M_{\text{tet.}}$) for $\text{Co}_{1-x}\text{Zn}_x\text{Fe}_2\text{O}_4$ also increased due to the displacement of iron ions to the octahedral positions of the spinel by the zinc ions. The increase in the magnetisation of the ferrite is accompanied by an increase in interlattice AB superexchange interactions [12]. When the number of substituting Zn^{2+} ions is large enough ($x > 0.35$), the antiferromagnetic interaction of Fe^{3+} ions located in neighbouring positions in the octahedral sublattice begins. Therefore, the BB interaction leads to a decrease in the total magnetic moment [12].

It was also established earlier, that doping cobalt ferrite with zinc ions results in a decrease in the coercive force for the same particle sizes

[7, 12]. This is explained by the reduction of the magnetic anisotropy of doped powders. Particles of the critical size, i.e. particles on the border of the ferromagnetic state, have the highest coercive force. For cobalt ferrite, the size of such particles is $\sim 40 \text{ nm}$. With the further growth of the particles the coercive force decreases. This dependence can be accounted for by the domain structure, the critical size of the particles, and the degree of the anisotropy of the surface and intercrystalline boundaries. The coercivity of 0.27 kOe obtained at 300 K is much lower than the theoretically calculated coercivity of cobalt (5.3 kOe) [13], which indicates the ferrimagnetic state of the particles.

The magnetic parameters of the powders calculated based on the magnetic hysteresis loops of CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ are given in Table 2.

The shape of the magnetisation curves shown in Fig. 4 is similar to the shape described in the literature and is characterized by their significant rectangularity [18]. Table 2 shows that the value of M_s slightly decreases with the growth of temperature, while the adjusted residual magnetisation M_r/M_s and the coercivity H_c decrease significantly. This happens due to the influence of thermal fluctuations of the magnetisation of individual particles [18–20]. For CoFe_2O_4 $M_r/M_s = 0.83$ at low temperatures, which, according to the Stoner-Wohlfarth model, indicates the presence of cubic anisotropy, while for $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ it is not observed ($M_r/M_s < 0.5$) [12]. The uncharacteristic kinks on the magnetisation curves (Fig. 4a) can result from the interaction between the hard and soft anisotropy regimes, the polydispersity of the powder, the shape of the particles, and their interaction [12].

Table 2 demonstrates that the coercivity of the zinc-containing ferrite is much lower than

Table 2. The parameters of the magnetisation curves of CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders (saturation magnetisation M_s , adjusted remanent magnetisation M_r/M_s , coercivity H_c)

$T, \text{ K}$	CoFe_2O_4			$\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$		
	$M_s, \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$	M_r/M_s	$H_c, \text{ kOe}$	$M_s, \text{ A}\cdot\text{m}^2 \text{ kg}^{-1}$	M_r/M_s	$H_c, \text{ kOe}$
10	83.3	0.77	12.5	123.6	0.44	1.35
100	83.5	0.74	8.0	122.4	0.39	1.1
200	80.7	0.60	3.1	112.5	0.23	0.5
300	73.2	0.37	0.27	97.9	0.12	0.1

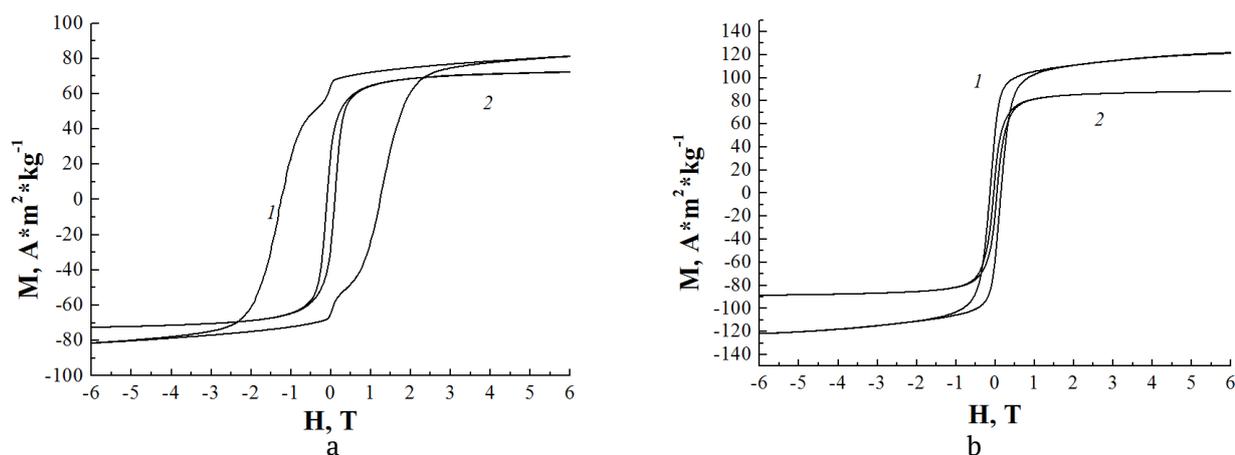


Fig. 4. Curves of the dependence of the magnetisation on the magnetic field strength at different temperatures 1 – 10 K, 2 – 300 K: a) CoFe_2O_4 ; b) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$

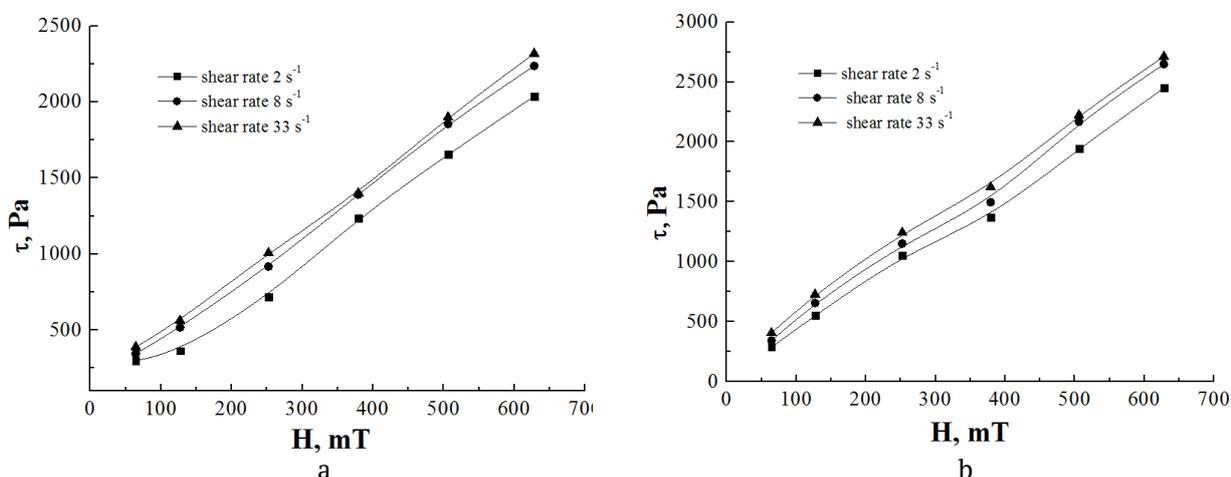


Fig. 5. Dependence of the shear stress of MRF containing 20 wt% of ferrite powder in Mobil 22 on the magnetic field induction at shear rates of 2, 8, and 33 s^{-1} : a) CoFe_2O_4 ; b) $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$

that of CoFe_2O_4 . This is associated primarily with the characteristic constant of the material anisotropy and the introduction of zinc ions into the ferrite structure [12]. The presence of inhomogeneities, impurities, and crystal lattice defects preventing the remagnetisation of the sample, also increase H_c . These factors are associated with the method of synthesising the sample. $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powder obtained in this study has $H_c = 0.1$ kOe at 300 K, while the coercivity of the sample obtained by spray-drying in sodium chloride medium was 0.4 kOe [12]. With regard to MRFs, it is advisable to use ferrites with lower coercivity in order to increase the magneto-control of the composition.

The comparison of M_s for $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ obtained by spray-drying followed by annealing

in the NaCl medium in [12] and for the sample obtained by coprecipitation followed by annealing in air under the same conditions (Table 2) demonstrated a significant increase in the specific magnetisation for the coprecipitation method. The high-temperature annealing of the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powder in air results in the formation of larger particles with a higher degree of crystallinity as compared to the annealing in the NaCl matrix. The surface layer of the particles with random spin orientation has much less effect on the magnetic properties of the particles than in the former case, which is why the specific magnetisation is much higher. Therefore, the suggested annealing conditions proved to be optimal for obtaining high magnetisation of $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$. In this case, we minimised the

negative effect of the non-magnetic surface layer of the particles, while the particles retained their individuality at the nano scale without sintering.

The CoFe_2O_4 and $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders obtained by coprecipitation have high oil absorption and form fairly stable suspensions in the industrial Mobil 22 oil. This makes it possible to use them as functional fillers for magnetorheological materials, including magnetorheological suspensions based on carbonyl iron in synthetic oil. In the latter case, the ferrite additives would perform the modifying and stabilising functions. Fig. 5 shows the dependences of the shear stress of an MRF on the magnetic field induction at different shear rates for the MRF containing 20 wt% of ferrite powder in the industrial Mobil 22 oil.

A high value of shear stress (over 2500 Pa) at 650 mT indicated that the studied powders can be considered promising materials for the above listed applications. It should be noted that the previously studied $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powder obtained by spray-drying at 650 mT demonstrated the shear stress of ~ 1000 Pa [12]. Such a significant increase in the shear stress for the obtained samples is explained by the conditions of the synthesis, namely the high-temperature annealing. Comparing the $\text{Co}_{0.65}\text{Zn}_{0.35}\text{Fe}_2\text{O}_4$ powders obtained by spray-drying [12] and coprecipitation, we can see that besides the increase in the particle size and the degree of crystallinity (from 85 to 97 %) the annealing results in a change in the shape of the particles from spherical to faceted. Such morphological changes influence the rheological behaviour of the powders in the suspension resulting in an increase in the shear stress. At the same time, the density and the oil absorption of the particles can also increase.

4. Conclusions

In this paper we proposed a new technique for synthesising cobalt and cobalt-zinc ferrites based on the method of coprecipitation from aqueous solutions of the corresponding salts. The technique involves high-temperature annealing of the precipitates in air which results in highly crystalline polydispersed powders with high specific saturation magnetisation ($97.9 \text{ A}\cdot\text{m}^2\cdot\text{kg}^{-1}$ at 300 K).

The synthesised ferrites are polydispersed powders with the size of primary particles of 300–400 nm and the size of the coherent scattering regions of 30–35 nm. They demonstrate high shear stress in magnetorheological suspensions, which is 2.5 times higher than that of the nanosized particles.

In our study, we also obtained suspensions of the ferrite powders with the industrial Mobil 22 oil (20 wt%) for the analysis of the dependences of the shear stress on the magnetic field induction. The high shear stress (2.5 kPa) with a relatively low magnetic field induction (from 600 mT and above) allowed us to consider the obtained materials as being promising for use as functional fillers for magnetorheological materials, including magnetorheological suspensions of damping devices.

Author contributions

Haiduk Yu. S. – writing the article, synthesising the materials, conducting research, interpreting the results. Korobko E. B. – conducting research (magnetorheological measurements), interpreting the results, scientific editing. Kotsikau D. A. – conducting research (IR spectroscopy), scientific editing. Svito I. A. – conducting research (magnetic measurements), interpreting the results. Usenko A. E. – scientific leadership, interpreting the results. Pankov V. V. – scientific leadership, research concept, interpreting the results, final conclusions.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

Research article

<https://doi.org/10.17308/kcmf.2022.24/9052>**Formation of a solvate of manganese(III) acetylacetonate with chloroform**

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1 Leninskie Gory, Moscow 119991, Russian Federation***Abstract**

Metal acetylacetonates are coordination compounds consisting of the acetylacetonate anion ($\text{CH}_3\text{COCHCOCH}_3$, indicated as acac) and metal ions. Typically, both oxygen atoms of the anion bind with the metal and form a six-membered chelate ring. The simplest complexes have the formulas $\text{M}(\text{acac})_3$ and $\text{M}(\text{acac})_2$. Many complexes are soluble in organic solvents, and such solutions are used for the synthesis of catalysts. The processes of formation of solvates of acetylacetonates of various metals have not been studied properly. It should be noted that the determination of the composition and properties of solvates is important for understanding the peculiarities of the extraction processes of metal acetylacetonates. Manganese(III) acetylacetonate $\text{Mn}(\text{acac})_3$, for example, is also widely used. The recrystallisation of the complex is most commonly conducted from solutions in chloroform, and in this case, the corresponding solvates may be formed, which can affect the structure and properties of $\text{Mn}(\text{acac})_3$. There are no data on the synthesis conditions and the composition of the solvates of manganese(III) acetylacetonate with chloroform. Therefore, the purpose of this work is to study the possibilities of its formation and to establish the composition of such solvates.

The formation of the solvate in solution was established using Fourier IR spectroscopy by the shift of the absorption band of the C-H chloroform bond. The composition of the $\text{Mn}(\text{acac})_3 \cdot 2\text{CHCl}_3$ solvate was determined using gravimetric analysis.

Keywords: Manganese, Acetylacetonate, Solvate, Gravimetric analysis, IR spectroscopy

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1. Introduction

Manganese(III) acetylacetonate – $[\text{Mn}(\text{C}_5\text{H}_7\text{O}_2)_3]$ – is used as the source material for the synthesis of electrolytes [1] and catalysts [2–8]. Regardless of the synthesis method, $\text{Mn}(\text{acac})_3$ is most frequently recrystallised from solutions in chloroform. In this case, the corresponding solvates may be formed, which can affect the structure and properties of $\text{Mn}(\text{acac})_3$. The processes of formation of solvates of acetylacetonates of various metals have not been studied properly. There are some data on the formation of solvates of acetylacetonates of trivalent chromium, iron, and scandium with chloroform [9, 10]. However, there are no such data for $\text{Mn}(\text{acac})_3$. The purpose of this work was to study the possibilities of formation of solvates of manganese(III) acetylacetonates with chloroform using gravimetry and Fourier IR spectroscopy.

2. Experimental

2.1. Synthesis

To evaluate the possibility of the formation of solvates, we used chloroform as a solvent since it dissolves manganese(III) acetylacetonate well. A saturated solution of $\text{Mn}(\text{acac})_3$ in chloroform was prepared at room temperature. The solution was filtered and left in air until a crystal haze formed. After that, the crystals were separated by decantation. Oversaturation was created through evaporation of chloroform, which allowed regulating the rate of formation and growth of nuclei of new phases, including possible solvates. The crystallisation took from one to several days. Upon cooling, big shiny black crystals of the $\text{Mn}(\text{acac})_3$ solvate with chloroform were isolated at first and then decomposed after drying (for more than 24 hours) in air, which manifested in surface clouding and the transformation of crystals into powder.

2.2. Gravimetric determination of the composition of a $\text{Mn}(\text{acac})_3$ solvate with chloroform

The composition of the $\text{Mn}(\text{acac})_3 \cdot n\text{CHCl}_3$ solvate obtained through the recrystallisation of $\text{Mn}(\text{acac})_3$ from chloroform was determined using gravimetry. To do that, we poured the saturated solution of manganese(III) acetylacetonate in

chloroform into a weighed 50-ml flask and left it in air. Once the free solvent evaporated and signs of decomposition (loss of shine, colour changed from black to dirty green) of the first few crystals appeared, we recorded the weight of the flask and calculated the weight of the solvate. Two weeks later, when the decomposition of the solvate was almost complete (the weight stopped changing), we heated the flask with the substance up to 100 °C for 10 minutes using a heat gun in order to remove the last traces of solvent. After that, the weight was recorded again. The flasks were weighed on scales with an accuracy of 0.01 g. Over the whole period of the experiment the substance in the open flask was kept in a dark and dry place with almost fixed temperature (23 ± 1 °C).

The weight of the flask with the substance at the beginning of decomposition, in other words, the weight of the flask with the solvate, was $M = 34.17 \pm 0.01$ g. At the end of decomposition, after being heated with a heat gun the weight of the flask with crystals (manganese(III) acetylacetonate without chloroform) was $m = 31.45 \pm 0.01$ g. The weight of the empty flask is $m_F = 27.48 \pm 0.01$ g. If we express the composition of the solvate by the formula $\text{Mn}(\text{acac})_3 \cdot n\text{CHCl}_3$, then, using the obtained data, we can calculate the number n of chloroform molecules in the solvate as follows:

$$\begin{aligned} n &= \frac{(M - m) * M(\text{Mn}(\text{acac})_3)}{(m - m_F) * M(\text{CHCl}_3)} = \\ &= \frac{(34.17 - 31.45) * 352.265}{(31.45 - 27.48) * 119.378} = 2.022, \\ \Delta n &= \left(\frac{\Delta M + \Delta m}{M - m} + \frac{\Delta m + \Delta m_F}{m - m_F} \right) * n = \\ &= \left(\frac{0.01 + 0.01}{34.17 - 31.45} + \frac{0.01 + 0.01}{31.45 - 27.48} \right) * 2.022 \pm 0.03, \end{aligned}$$

that is, $n = 2.02 \pm 0.03$, while the composition of the solvate, therefore, can be expressed by the formula $\text{Mn}(\text{acac})_3 \cdot 2\text{CHCl}_3$, in other words, trivalent manganese acetylacetonate forms solvates with chloroform with the ratio of 1:2 as well as the corresponding derivatives of iron(III), chromium(III), and scandium (III).

2.3. Fourier IR spectroscopy

To establish the possibility of the formation of solvates, we analysed the IR spectra of

solutions using Perkin Elmer Frontier FT-IR. The transmission spectrum of the $\text{Mn}(\text{acac})_3$ solution in chloroform was recorded in a potassium bromide cuvette. The device was calibrated using a cuvette with pure chloroform.

A bright band was observed at $\sim 3000\text{ cm}^{-1}$ in the IR transmission spectrum of the $\text{Mn}(\text{acac})_3$ solution in chloroform relative to chloroform (Fig. 1). It corresponds to the vibrations of the C-H bond in CHCl_3 [11]. Its intensity should not be considered significant, since it should be subtracted from the background when recording the spectrum. $\text{Mn}(\text{acac})_3$ does not have such intense absorption bands in this region [12–14]. The considered band is also shifted in relation to the spectrum of pure chloroform. The observed band is associated with the interaction of chloroform molecules with $\text{Mn}(\text{acac})_3$ molecules, in other words, it indicates the formation of $\text{Mn}(\text{acac})_3$ solvates with CHCl_3 .

3. Conclusions

As a result of our work, through the use of Fourier IR spectroscopy, it was found that manganese(III) acetylacetonate forms a solvate with chloroform in solution, and it was also found through the use of gravimetry that the composition of the crystal solvate is expressed by the formula $\text{Mn}(\text{acac})_3 \cdot 2\text{CHCl}_3$. The obtained results are the first steps in the study of the solvation of manganese(III) acetylacetonate. For a more extended picture and a better understanding of the influence of the processes occurring in the solution on the structure of the complex, its solvates should be studied with a number of other solvents, and not only their composition, but also the structure should be established.

The latter task is very difficult, but it is highly interesting as part of the studied issue.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

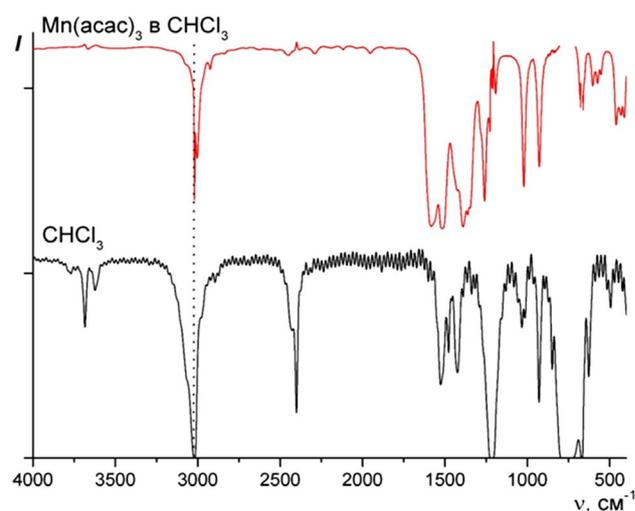


Fig. 1. IR transmission spectra of pure chloroform (relative to air) and a solution of $\text{Mn}(\text{acac})_3$ in chloroform (relative to chloroform). The intensities of the spectra are normalised

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Original articles

Research article

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The influence of the physicochemical nature of the components of the V_2O_5 /GaAs, MnO_2 /GaAs, V_2O_5 /InP, MnO_2 /InP, TiO_2 /InP, and SnO_2 /InP heterostructures and the oxidation conditions on the surface morphology of the synthesised films

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Abstract

The formation of oxide functional films on the surface of semiconductors is a serious technological challenge, which is even more complicated in the nanometre thickness range. It is necessary to form films with specified values of thickness, resistivity, and a certain surface morphology for practical applications. Such films are used in micro- and optoelectronics, environmental monitoring, and alternative energy devices. The goal of this work is to establish the features of the surface morphology of thin films formed as a result of the thermal oxidation of the MnO_2 /GaAs, V_2O_5 /GaAs, V_2O_5 /InP, MnO_2 /InP, TiO_2 /InP, and SnO_2 /InP heterostructures depending on the physicochemical nature of the components and the oxidation conditions.

The synthesis of thin films on the InP and GaAs surfaces was carried out by thermal oxidation under the influence of magnetron-deposited layers of chemostimulator-modifiers. The thickness of the formed films and their composition were determined by laser ellipsometry, X-ray phase analysis, and infra-red spectroscopy. The scanning tunnel and atomic force microscopy were used to determine the morphological characteristics of the films and their dependence on the type of semiconductor substrate, the nature of the chemostimulator-modifier, and the conditions of the thermal oxidation.

The application to the GaAs and InP surfaces of the most effective chemostimulator-modifiers (V_2O_5 and MnO_2) of thermal oxidation and higher temperatures of the oxidation process contributed to the formation of smoother and nanostructured films.

Keywords: Gallium arsenide, Indium phosphide, Heterostructure, Thermal oxidation, Surface morphology, Grain size

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1. Introduction

The synthesis of new materials for electronics has always been important. They have been used to create competitive optoelectronic [1], environmental monitoring [2], and alternative energy [3] devices. The challenges of import substitution and miniaturisation require new highly rapid, environmentally friendly, and cost-effective methods and approaches to create efficient devices based on MIS (metal-insulator-semiconductor) and SIS (semiconductor-insulator-semiconductor) structures [4–7]. Thermal oxidation is one of the most common methods used to create nanosized functional oxide films on the surface of semiconductors [8]. This technological challenge becomes more complicated in the nanometre thickness range since in many processes the regular growth of films begins at a sufficiently developed stage (at a thickness of more than 100 nm) and the dependence of film properties on their surface morphology and structure is the most pronounced in the nanometre thickness range.

The intrinsic thermal oxidation of the A^3B^5 semiconductors leads to the formation of low quality films, which can be improved by changing the process mechanism from intrinsic to chemically stimulated [8, 9]. Nanoscale layers of oxide-chemostimulators, formed by the method of reactive magnetron sputtering contribute to a change in the mechanism of the oxidation of GaAs and InP semiconductors from intrinsic to transit or catalytic, which allows accelerating the process of film growth, purposefully changing their composition, surface morphology, and structure and, consequently, their properties [9].

In [10–13], it was established that nanosized layers of V_2O_5 [10, 11] applied to the InP and GaAs surfaces contribute to catalytic oxidation, whereas the application of nanosized layers of MnO_2 [12, 13] mainly promote transit oxidation. Coated layers of SnO_2 [14, 15] and TiO_2 [16, 17] do not exhibit chemical stimulating properties in the processes of InP thermal oxidation, although they are thermodynamically capable of transferring oxygen to semiconductor components; however, they modify the composition of the film.

The investigation of the surface morphology of films formed as a result of thermal oxidation of heterostructures based on A^3B^5 semiconductors

is necessary in order to track the dynamics of changes in their characteristics compared to reference samples, to understand the dependence of the surface morphology of synthesised objects on the physicochemical nature of the substrate and deposited oxide, the oxidation conditions, and the characteristics of films. Such data are necessary to optimise the formation of low-dimensional composite structures based on A^3B^5 semiconductors, primarily MIS structures. It is assumed that the created oxide films can compete with SiO_2 when manufacturing ohmic contacts, anti-reflective coatings for mirrors of heterolasers on GaAs and InP substrates, and in other aspects of functional electronics [4, 7].

Therefore, the goal of this work is to establish the features of the surface morphology of thin films formed as a result of thermal oxidation of the V_2O_5 /GaAs(100), V_2O_5 /GaAs(111), MnO_2 /GaAs(100), MnO_2 /GaAs(111), V_2O_5 /InP, MnO_2 /InP, TiO_2 /InP, and SnO_2 /InP heterostructures depending on the physicochemical nature of the components and the oxidation conditions.

2. Experimental

As semiconductor substrates, we used pre-prepared (100) and (111) oriented AGChT (tellurium-doped, electronic) gallium arsenide with a concentration of the main charge carriers of at least $8 \cdot 10^{18} \text{ cm}^{-3}$, and (100) oriented FIE-1A (tin-doped, electronic) indium phosphide with a concentration of the main charge carriers of at least $5 \cdot 10^{16} \text{ cm}^{-3}$.

When studying the mechanisms of processes on the surface and in layers of nanometre thickness, it is necessary to pay special attention to the standardisation of the surface morphology of the substrates, which dictates a thorough pretreatment of monocrystals. Before thin-film heterostructures were formed, the used substrates were treated with the following etchers: a) to clean and polish the surface of indium phosphide, we used a peroxide-sulphuric acid polishing solution $H_2SO_4:H_2O_2:H_2O = 2:1:1$, etching time was 10 min; b) to clean and polish the surface of gallium arsenide, we used concentrated hydrofluoric acid ($\omega(HF) = 49\%$), etching time was 10 min. The gallium face of GaAs(111) was determined by the method described in [18]. We needed to determine the gallium face of such a

substrate since it is more preferable for growing films on it: the film's microstructure would be less defective.

A thin nanosized (~35 nm) oxide layer performing a chemically stimulating (modifying) function was deposited by reactive magnetron sputtering of vanadium target (99.99% purity) with a diameter of 50 mm (2 inch) in an oxygen-argon atmosphere (V_2O_5 layers) using an Angstrom engineering CoVap II installation. The initial evacuation of atmospheric air from the vacuum chamber was carried out with a fore vacuum pump, and the subsequent deep evacuation ($p_{res} \sim 10^{-6}$ Torr) was conducted by a Varian Turbo 301 turbomolecular pump. In the process of developing a technique for sputtering a vanadium target in an oxygen-argon atmosphere, the optimal composition of the gas mixture was established for the reactive deposition of vanadium pentoxide layers Ar:O₂ – 3:1. Nanoscale layers of the SnO₂ modifier (Sn target with 99.99 % purity) and TiO₂ (Ti target with a purity of at least 99.8%) were deposited in similar way. The MnO₂ layers (a compressed target of manganese dioxide powder with a purity of at least 99.8 %) were deposited in an Ar atmosphere.

The first step in the study of various characteristics is to determine the composition of layers formed by magnetron sputtering on the surface of semiconductors. For HSs with V_2O_5 , the deposited layer mainly consisted of vanadium pentoxide but in addition to it, the diffraction patterns showed a peak corresponding to V_2O_3 , which can be explained by the specifics of the magnetron sputtering process. However, its relative content was low; therefore, we designated the synthesised HSs as V_2O_5/A^3B^5 [10]. A similar situation was characteristic of HSs with MnO₂: the magnetron-sputtered layer on A^3B^5 mostly consisted of MnO₂ with a relatively small inclusion of Mn₂O₃, therefore, we designated the synthesised HSs as MnO₂/ A^3B^5 [12,13]. Magnetron sputtering of tin dioxide on the InP surface resulted in the formation of a layer of SnO₂, without the formation of undesirable phases [14]. The titanium dioxide layer formed by magnetron sputtering only contained TiO₂ phases in structural modifications of anatase and rutile [19].

The thermal oxidation of synthesised heterostructures $V_2O_5/GaAs(100)$, $V_2O_5/GaAs(111)$, $MnO_2/GaAs(100)$, $MnO_2/GaAs(111)$, V_2O_5/InP , MnO_2/InP , TiO_2/InP , and SnO_2/InP was carried out in a flowing quartz reactor of a horizontal resistive heating furnace MTP-2M-50-500 (TRM-10 sensor unit, adjustment accuracy ± 1 °C) in flowing oxygen (the volume flow rate of 30 l/h) in the temperature range from 500 to 550 °C. The oxidation time varied between 20–180 minutes.

For practical applications, it is necessary to form films with specified values of thickness, resistivity, and a certain stable and reproducible surface morphology. MnO₂/GaAs and $V_2O_5/GaAs$ heterostructures with (100) and (111) oriented substrates were thermally oxidised in various conditions until the target film thickness of up to ~250 nm was reached. The formation of films with a thickness of about 200 nm was necessary to compare them with SiO₂ films of similar thickness, which are widely used to manufacture ohmic contacts, to protect side edges of mesastripes, and to create anti-reflective coatings for mirrors of Fabry-Perot heterolaser resonators on GaAs and InP substrates in a system of GaInAsP isolattice solid solutions covering the wavelength range of 0.8–1.8 μm [3]. A necessary requirement for the formed films is certain values of electrical strength, breakdown voltages, adhesion to the substrate, and surface roughness. The study of films of the nanoscale thickness range is natural due to the further miniaturisation of micro- and optoelectronic objects [6, 7].

The thicknesses of the deposited layers of chemostimulator oxides and films grown as a result of thermal oxidation were controlled by laser (LE, LEF-754, wavelength of 632.8 nm, ± 1 nm accuracy) and spectral ellipsometry (SE, Ellips-1891, wavelength range of 250–1100 nm, the measurement accuracy of the ellipsometric parameters $\Psi\delta = 0.05^\circ$ and $\delta\Delta = 0.1^\circ$). To interpret the measurement results, we used a single-layer model “external medium–film–substrate” with sharp interfaces between the media [20–22].

By increasing the growth rate of the film thickness as compared to the intrinsic oxidation (acceleration of the process), it is possible to judge whether the selected substance is a chemostimulator. A relative increase in the

growth rate of oxide film b during the thermal oxidation of HS was calculated by formula (1):

$$b = \frac{\Delta d_{\text{Me}_x\text{O}_y/\text{A}^3\text{B}^5}}{\Delta d_{\text{A}^3\text{B}^5}}, \quad (1),$$

where $\Delta d_{\text{A}^3\text{B}^5}$ is a change in the thickness of the oxide film during the intrinsic oxidation of the semiconductor (standard) and $\Delta d_{\text{Me}_x\text{O}_y/\text{A}^3\text{B}^5}$ is a change in the thickness of the oxide film during the thermal oxidation of the HS with a deposited chemostimulator layer minus the thickness of the latter [13].

To characterise the heterostructures and thin films formed on the semiconductor surface, a set of instrumental methods was used. The phase composition of the samples was studied by X-ray phase analysis (XPA) using a ARL X'tra diffractometer (Thermo Scientific, $\text{CuK}_{\alpha 1}$ with $\lambda = 1.540562 \text{ \AA}$). Data on the chemical bonds in the synthesised films were obtained by transmission infrared spectroscopy (IRS) using a VERTEX 70 IR-Fourier spectrometer (frequency range of $400\text{--}1400 \text{ cm}^{-1}$). The surface morphology of the samples and reference samples was studied by atomic force microscopy (AFM) using a Solver P47 Pro scanning probe microscope by NT-MDT corporation in the semi-contact mode at various points of the surface with an HA_NC Etalon cantilever and by scanning tunnelling microscopy (STM) using the NTK UMKA in the DC mode. These methods were complementary since the surface of dielectrics could not be studied by the STM method, and one of our tasks was to form dielectric oxide films.

3. Results and Discussion

The results of film thickness measurements (LE, SE) on GaAs monocrystal samples of various

orientations with nanoscale layers of MnO_2 and V_2O_5 chemostimulators at 500 and 530 °C in the time intervals from 20 to 180 minutes are given in Table 1.

Films with a thickness of less than 100 nm were synthesised most quickly on the $\text{V}_2\text{O}_5/\text{GaAs}(111)$ HS, which allows us to conclude that the time of film formation depends on the substrate orientation when the V_2O_5 HS is used as a chemostimulator. For the GaAs(111) orientation of the substrate, there was the largest bond angle between the surface atoms and the plane of the substrate surface (90°), which determined the bond availability for oxygen [18]. This contributed to a higher rate of interaction between the plane and the oxidiser. No such dependence was found for the MnO_2/GaAs heterostructure.

When comparing the thicknesses of the formed films for similar InP-based HSs (Table 2), it was obvious that there was a maximum acceleration when using the magnetron-formed layer of V_2O_5 as a chemostimulator. The layers of tin and titanium dioxides had the opposite effect; they slowed down the process of film formation during the oxidation of the heterostructure but acted as modifiers of the composition of oxide films (Table 3), which was necessary for the formation of films with the desired properties [14].

Films formed by thermal oxidation of the $\text{V}_2\text{O}_5/\text{GaAs}(100)$ HSs consisted of vanadium oxides in various oxidation states (V_2O_5 and VO_2) (Fig. 1a). This was related to the decomposition of V_2O_5 in flowing oxygen during thermal oxidation and the active interaction of vanadium pentoxide with substrate components. The VO_2 phases on the X-ray pattern of the sample with the substrate orientation (111) was not observed (Fig. 1b).

Table 1. Thicknesses of nanoscale films (LE, SE) formed by thermal oxidation of HSs on GaAs with deposited layers of V_2O_5 and MnO_2 in various conditions and the relative change in film thickness calculated by formula (1)

Sample	TO mode	Film thickness, nm		Relative change in film thickness, times
		LE	SE	
$\text{V}_2\text{O}_5/\text{GaAs}(100)$	$T=500 \text{ }^\circ\text{C}, t=50 \text{ min}$	83	81	2.18
$\text{V}_2\text{O}_5/\text{GaAs}(111)$	$T=500 \text{ }^\circ\text{C}, t=25 \text{ min}$	88	86	2.41
$\text{MnO}_2/\text{GaAs}(100)$	$T=500 \text{ }^\circ\text{C}, t=60 \text{ min}$	77	74	1.91
$\text{MnO}_2/\text{GaAs}(111)$	$T=500 \text{ }^\circ\text{C}, t=70 \text{ min}$	72	74	1.68
GaAs	$T=500 \text{ }^\circ\text{C}, t=60 \text{ min}$	27	27	–

Table 2. Thicknesses of films (LE) formed by thermal oxidation of HSs based on InP at 530 °C for 60 min and the relative change in film thickness calculated by formula (1)

Sample	TO mode	Film thickness, nm	Relative change in film thickness, times
SnO ₂ (68 nm)/InP	T=530 °C, t=60 min	82	0.389
TiO ₂ (35 nm)/InP		53	0.48
V ₂ O ₅ (21 nm)/InP		115	2.61
MnO ₂ (21 nm)/InP		76	1.5
InP		41	–

Table 3. Identified phases for GaAs-based HSs after thermal oxidation for 50 and 20 minutes, respectively, at 500 °C

Sample, TO mode	Interplane distance, d_{hkl}	Defined phase
V ₂ O ₅ /GaAs(100) (50 min)	4.3743; 3.1498	V ₂ O ₅
	3.3510	VO ₂
	3.2607; 1.4553	As ₂ O ₅
	2.1903	Ga ₂ O ₃
	2.0628	GaAs
V ₂ O ₅ /GaAs(111) (20 min)	4.3876; 2.7577	V ₂ O ₅
	2.0644	GaAs
	1.4531	As ₂ O ₅
	2.1770	Ga ₂ O ₃

No arsenates were found in the films since the conditions of thermal oxidation were not severe enough, however, gallium and arsenic oxides were present as had been expected (see Table 3). The XPA and IR methods also confirmed the absence of vanadium oxide consumption, i.e., the process of thermal oxidation of the studied HSs in various conditions had a catalyst regeneration cycle, which in our case was vanadium oxide (V) [8–10].

The presence of arsenic in the films in the form of As₂O₅ indicated the binding of the substrate components at the internal interface, which prevented the accumulation of underoxidised arsenic. A change in the orientation of GaAs at a constant temperature of thermal oxidation (500 °C) led to changes in the qualitative phase composition of the films. The X-ray pattern of the film grown by thermal oxidation of the V₂O₅/GaAs(100) HS had 2 reflections corresponding to As₂O₅, while the X-ray pattern of the film formed by the oxidation of V₂O₅/GaAs(111) had no second As₂O₅ peak, which indicated a more efficient binding of oxygen components in case of the (100) oriented substrate.

In case of the transition to other HSs, in which indium phosphide acted as a substrate, the composition of the films became somewhat more complicated. The formed films consisted of vanadium oxides in various oxidation states (V₂O₅; V₂O₃; VO₂), indium oxide (In₂O₃), and indium phosphate (InPO₄) (Table 4) [11]. The qualitative difference from similar gallium arsenide-based HSs was primarily that their X-ray pattern had peaks corresponding to indium phosphate, one of the target oxidation products for this particular semiconductor, formed as a result of the secondary interaction of the corresponding oxides. Using the data about the composition of the film formed on the SnO₂/InP HS, we can draw a conclusion about the modifying properties of SnO₂ [14]. The presence of peaks corresponding to the Sn₃(PO₄)₂ compound indicates an interaction between the SnO₂ layer deposited on the surface with the oxidation products of the substrate components, in particular phosphorus, and, as a consequence, a change in the composition of the film and its surface. Additional studies of the TiO₂/InP sample by IR spectroscopy revealed absorption bands

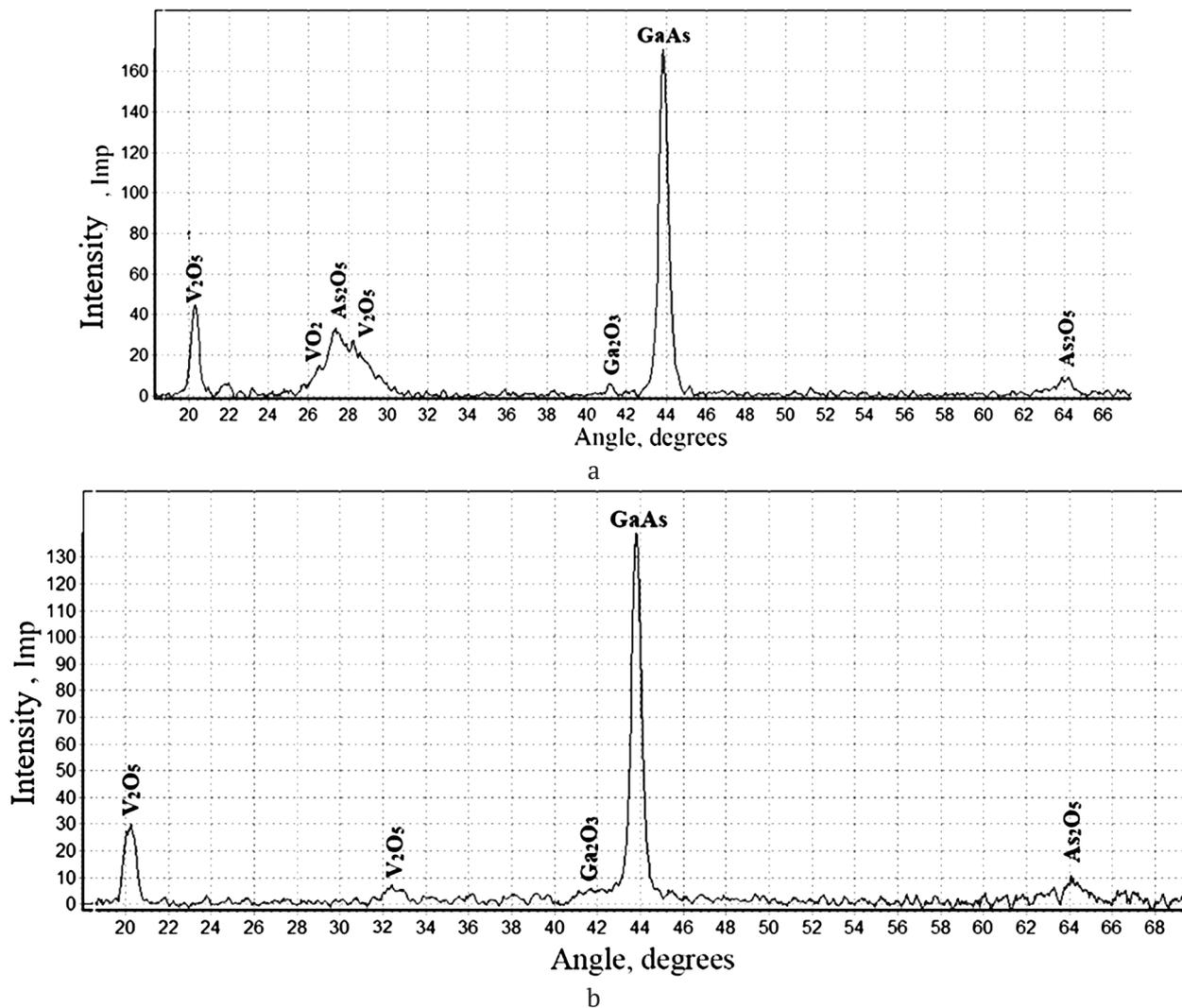


Fig. 1. XRD patterns of $V_2O_5/GaAs(100)$ (a) and $V_2O_5/GaAs(111)$ (b) heterostructures after thermal oxidation at a temperature of 500 °C for 50 minutes and 20 minutes, respectively

of the $Ti(PO_3)_3$, TiP_2O_7 , $Ti_4(P_4O_{12})_3$, $InPO_4$, and $In(PO_3)_3$ compounds [23,24], which also indicates the modifying effect of titanium dioxide layers.

The surface morphology of the synthesised nanosized films reflected the different nature of the effect of the deposited oxides. Thermal oxidation of HSs of $V_2O_5/GaAs$ (relief height within 10 nm) and $MnO_2/GaAs$ (relief height of 70 nm) for 50 and 60 minutes, respectively (Fig. 2), led to the formation of films with a pronounced grain structure with an average lateral grain size of 360 nm for $MnO_2/GaAs(100)$ and 150 nm for $V_2O_5/GaAs(100)$. The ordered arrangement of grains was most pronounced on the surface of the $V_2O_5/GaAs(100)$ sample.

Films formed with a thickness of more than 130 nm had noticeable differences in the data

of laser and spectral ellipsometry, which can be associated with a greater development of the surface of the films with an increase in the oxidation time (according to AFM data, the maximum relief height reached 200 nm for the $MnO_2/GaAs(100)$ sample with an oxide film thickness of 232 nm according to the averaged LE and SE data (Fig. 3)). The films were characterised by a grain structure with an average diameter of the grain of 300 nm. There was a similar tendency to the formation of a more developed surface (relief height of 87 nm at a film thickness of 164 nm, average diameter of the grain of 250 nm) with an increase in the oxidation time for the $V_2O_5/GaAs(100)$ sample.

After 60 minutes of thermal oxidation of the V_2O_5/InP HS at 530 °C (the thickness of the formed

Table 4. Identified phases for the $\text{Me}_x\text{O}_y/\text{InP}$ HSs after TO at 500 and 530 °C, 60 minutes

Sample, TO mode	Interplane distance, d_{hkl}	Defined phase
SnO_2/InP (530 °C)	5.5324	$\text{In}(\text{PO}_3)_3$
	3.6897; 3.5745	$\text{Sn}_3(\text{PO}_4)_2$
	3.0299	InSn_4
	2.932	InP
	1.4814	In_2O_3
	1.5074	InPO_4
	1.4668	P_2O_5
TiO_2/InP (500 °C)	2.9305; 1.4652	InP
	2.9213; 1.5256	In_2O_3
	1.5157; 1.4815; 1.3976	TiO_2
	1.5109; 1.4863	Ti_2O_3
$\text{V}_2\text{O}_5/\text{InP}$ (500 °C)	4.999; 1.729	In_2O_3
	3.414; 4.392	V_2O_5
	1.468; 2.935	InP
	2.480; 2.244	V_2O_3
	2.013	VO_2
	1.451; 3.709	InPO_4
MnO_2/InP (500 °C)	4.999; 1.729	In_2O_3
	3.108; 2.005	MnO_2
	1.468; 2.935	InP
	2.494; 2.110	Mn_2O_3
	1.451; 3.709	InPO_4

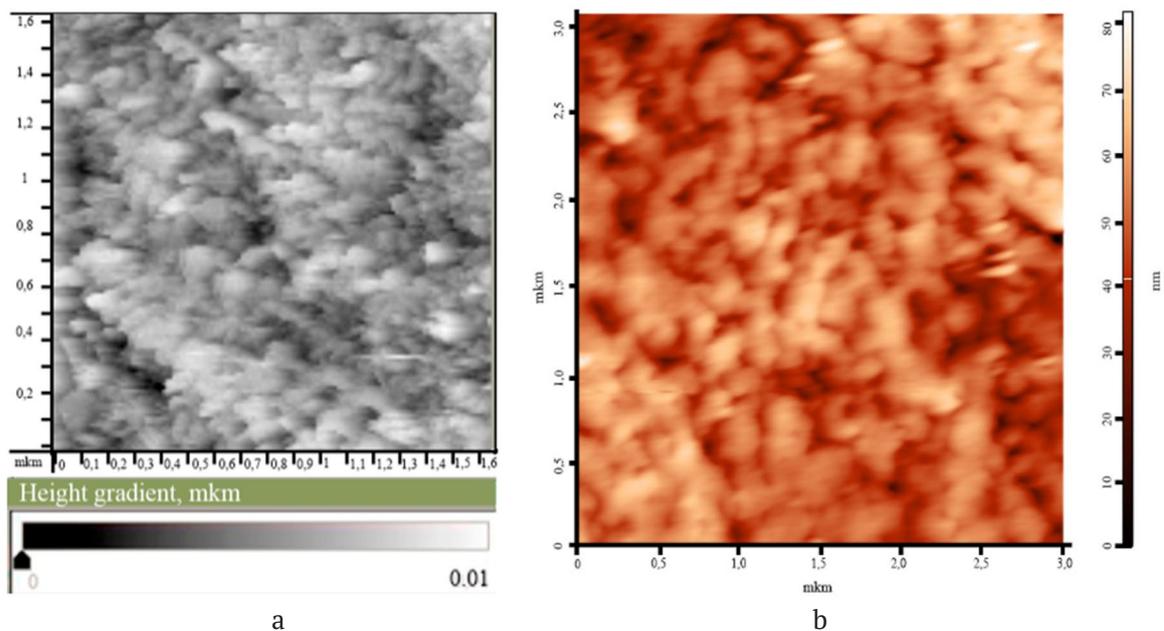


Fig. 2. STM image of the surface of the $\text{V}_2\text{O}_5(35 \text{ nm})/\text{GaAs}(100)$ samples (TO 500 °C, 50 min) (a) and AFM image of the surface of the $\text{MnO}_2(34 \text{ nm})/\text{GaAs}(100)$ sample (TO 500 °C, 60 min) (b). The scanning areas are 1.6×1.6 and $3 \times 3 \mu\text{m}^2$, respectively. The thickness of oxide films (LE) is 83 nm and 77 nm, respectively

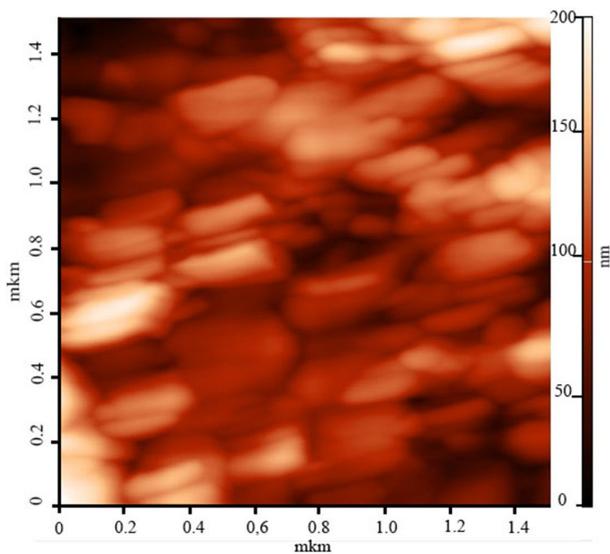


Fig. 3. AFM image of the surface of the $\text{MnO}_2/\text{GaAs}(100)$ sample (TO 500 °C, 180 min). The scanning area is $1.5 \times 1.5 \mu\text{m}^2$. The thickness of the oxide film (LE, SE) is 232 nm

film of 120 nm) (Fig. 4), the surface of the formed film became rough with pronounced structural elements (lines, bends, grains of an average size of 30 nm). After 60 minutes of oxidation of the MnO_2/InP HS at 530 °C (film thickness of 76 nm), the relief height did not exceed 20 nm, and the surface was characterised by a grain structure with an average size of 55 nm [13].

When potential chemostimulators, which are able to modify the composition of the growing films (SnO_2 , TiO_2 [14]), were applied on InP, which resulted in the formation of phosphates of the introduced element (see Table 4), fairly coarse-grained films with a grain diameter of 100–700 nm, depending on the synthesis mode, and a relief height of 20–40 nm were formed at 500–550 °C in 60 minutes (Fig. 5).

The comparison of the morphology of TiO_2/InP samples which were thermally oxidised at temperatures of 500 °C (Fig. 6a) and 530 °C (Fig. 6b) for 60 minutes showed that at higher temperatures the film surface had a more pronounced grain structure but with a smaller height difference.

Table 5 summarises the data that illustrate the effect of the substrate type on the surface morphology of the films grown by thermal oxidation of the corresponding HSs.

It can be seen that films formed on InP generally have a more uniform relief than those

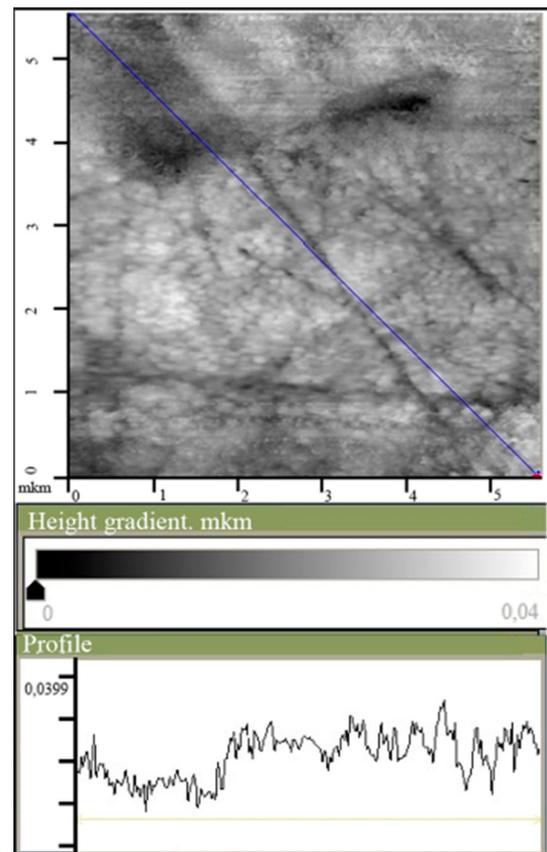


Fig. 4. STM image and surface profile of the $\text{V}_2\text{O}_5/\text{InP}$ sample (TO 530 °C, 60 min). The scanning area is $5.5 \times 5.5 \mu\text{m}^2$. The thickness of the oxide film (LE) is 120 nm

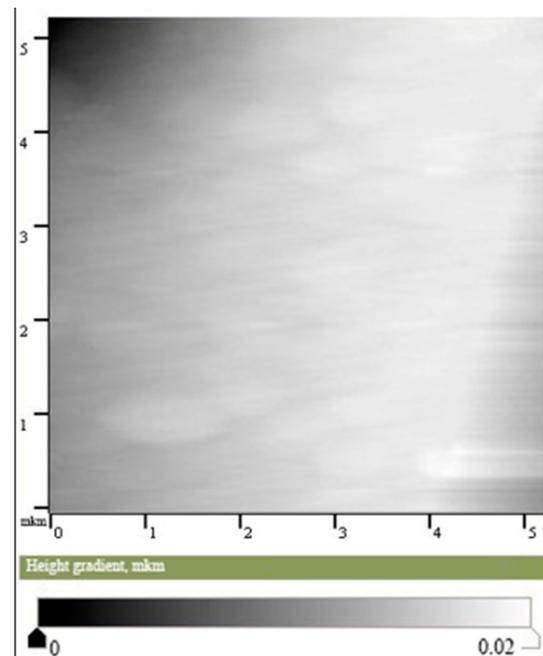


Fig. 5. STM image of the surface of the SnO_2/InP sample (TO 550 °C, 60 min). The scanning area is $5.2 \times 5.2 \mu\text{m}^2$. The thickness of the oxide film (LE) is 90 nm

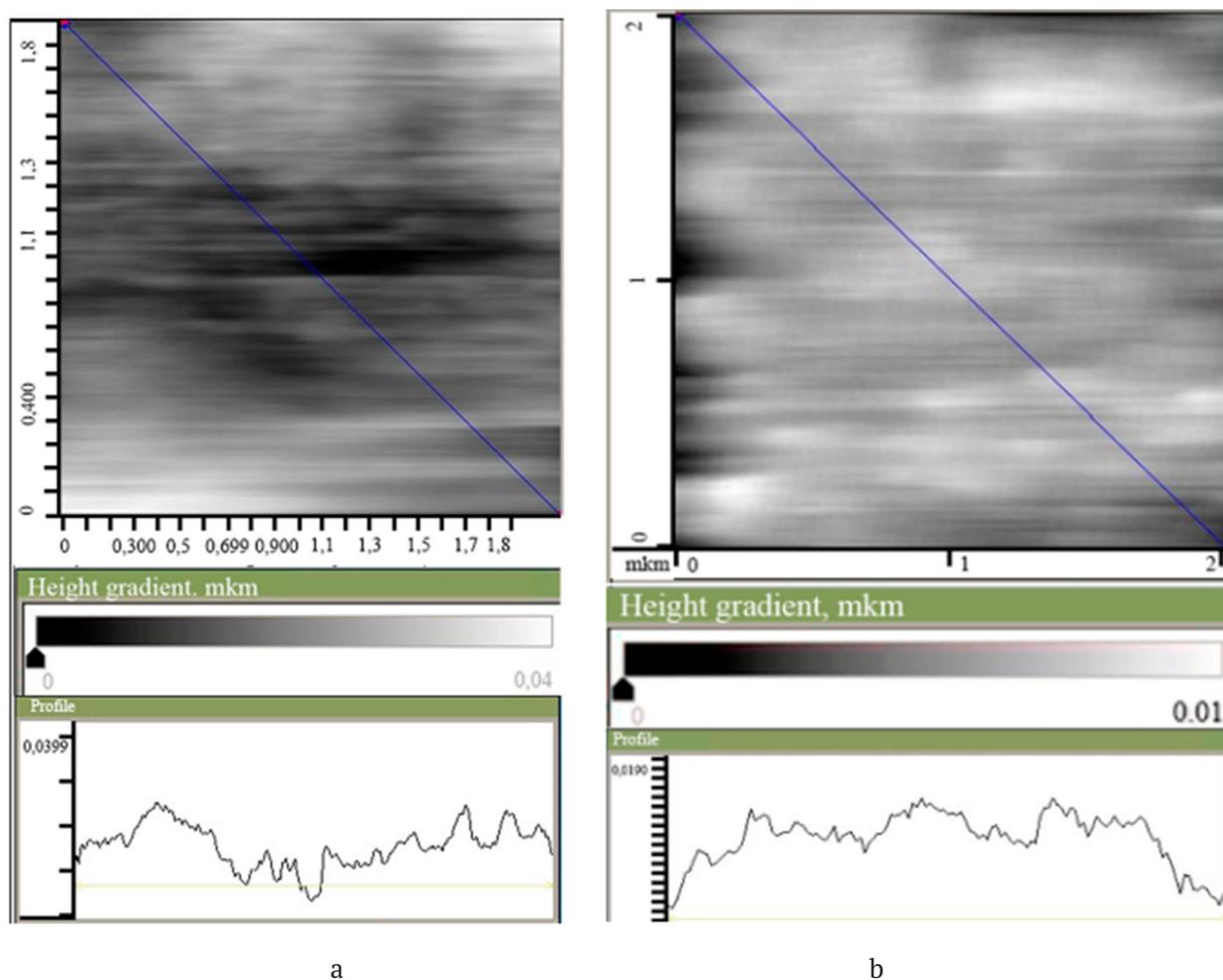


Fig. 6. STM image and the surface profile of the TiO_2/InP samples (TO 500 °C, 60 min) (a) and TiO_2/InP (TO 530 °C, 60 min) (b). The scanning areas are $2 \times 2 \mu\text{m}^2$. The thickness of the formed films (LE) is 50 nm and 55 nm, respectively

Table 5. Surface characteristics (STM, AFM) of $\text{Me}_x\text{O}_y/\text{InP}$ and $\text{Me}_x\text{O}_y/\text{GaAs}$ HSs depending on the type of substrate

Sample	TO mode	Scanning area, μm^2	Relief height, nm	Average grain size, nm
$\text{V}_2\text{O}_5/\text{InP}$	550 °C, 60 min	5.5×5.5	40	30
$\text{V}_2\text{O}_5/\text{GaAs}(100)$	500 °C, 50 min	1.6×1.6	9	150
MnO_2/InP	530 °C, 60 min	5.2×5.2	20	50
$\text{MnO}_2/\text{GaAs}(100)$	500 °C, 60 min	3×3	70	360

formed on GaAs; they also have smaller grains. Such films have a thickness corresponding to the nanoscale range and a nanodispersed structure. The TiO_2/InP HS (Table 6) can be used as an example to trace the effect of temperature at the same duration of the process on the surface morphology of the films. As the table shows, a higher temperature contributes to the smoothing of the surface relief, however, the grain size in

the lateral direction increases more than twice.

The physicochemical nature of the oxides in the deposited layers has the most significant effect on film structuring (Table 7). HSs with oxide layers, which perform the functions of a modifier and have a noticeable chemostimulating effect on the process of thermal oxidation (V_2O_5 , MnO_2) [10–13], for the same semiconductor (InP) produce nanosized and nanostructured films. In

Table 6. Surface characteristics (STM, AFM) of $\text{Me}_x\text{O}_y/\text{InP}$ HSs depending on the thermal oxidation mode

Sample	TO mode	Scanning area, μm^2	Relief height, nm	Average grain size, nm
TiO_2/InP	500 °C, 60 min	2×2	25	90
TiO_2/InP	530 °C, 60 min	2×2	12	250

Table 7. Surface characteristics (STM, AFM) of $\text{Me}_x\text{O}_y/\text{InP}$ HSs depending on the type of chemostimulator

Sample	TO mode	Scanning area, μm^2	Relief height, nm	Average grain size, nm
SnO_2/InP	550 °C, 60 min	5.2×5.2	20	400
TiO_2/InP	530 °C, 60 min	2×2	12	250
$\text{V}_2\text{O}_5/\text{InP}$	550 °C, 60 min	5.5×5.5	40	30
MnO_2/InP	530 °C, 60 min	5×5	20	50

the case of the solely modifying effect on the composition of the formed films (SnO_2/InP , TiO_2/InP), even at a relatively small height of the relief, the films are coarse-grained, with a lateral grain size of up to 400 nm.

4. Conclusion

The targeted selection of compounds, orientations of the A^3B^5 semiconductor substrate, and the oxidation conditions make it possible to vary the thickness and surface morphology of the films. The introduction of the most effective chemostimulator-modifiers (V_2O_5 , MnO_2) of thermal oxidation on the surface of GaAs and InP, as compared to less efficient chemostimulator-modifiers (SnO_2 , TiO_2), causes the formation of smoother films with a nanodispersed surface structure. The smoothing of the surface relief of oxide films is also promoted by a higher temperature of the oxidation process.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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The interconnection of efficiency and the degree of aggregation of nanofiller in polymer nanocomposites

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Abstract

The rule of mixtures was the first theoretical model, used for a description of the elastic modulus of multicomponent systems, including those of polymer nanocomposites. However, the use of nominal magnitudes of the characteristics of system components in such an approach led to overestimated values of their elastic modulus. Therefore, various modified versions of the rule of mixtures are currently used for this purpose, which significantly complicate its application and do not indicate the physical factors leading to overestimated theoretical results.

In this study, a modified rule of mixtures was proposed, taking into account the decrease in the effective (actual) elastic modulus of the nanofiller in a polymer matrix of the nanocomposite compared to the nominal value determined only by the aggregation of the nanofiller. It is known that the aggregation process is the main negative factor reducing the final properties of nanomaterials, while other factors (for example, the interfacial adhesion level, nanofiller orientation, etc.) depend on the degree of aggregation. The physical sense of the aggregation process is a decrease in the relative proportion of nanofiller-polymer matrix interfacial regions, i.e., the effectiveness of a nanofiller as a reinforcing element of a nanocomposite is determined by its ability to generate high-modulus interfacial regions.

The rule of mixtures modified in this way correctly describes the dependence of the elastic modulus of the nanocomposite on the content of the nanofiller, regardless of the type of the latter (carbon nanotubes, graphene, etc.). Therefore, the nanofiller efficiency indicator can serve as a complex parameter that is characteristic of the nanocomposite quality.

Keywords: The rule of mixtures, Nanocomposite, Carbon nanotubes, Graphene, Aggregation, Elastic modulus, Interfacial regions

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1. Introduction

It is known [1], that the rule of mixtures was the first mathematical apparatus used for the description of the properties of polymer composites. Since the simplest initial version of this rule rarely provides a correct description of the properties of composites, in particular, their elastic modulus, a large number of modified versions of the rule of mixtures, taking into account the orientation and anisotropy of the nanofiller, its efficiency, etc., have been developed [2]. The most commonly used modification of the rule of mixtures for anisotropic fillers is as follows [2]:

$$E_c = (\eta_0 E_{ef} - E_m) \varphi_n + E_m, (1)$$

where E_c , E_{ef} , and E_m are the elastic modulus of the composite, the effective modulus of the filler, and the elastic modulus of the matrix polymer, respectively, η_0 is the fibre orientation factor, φ_n is the volume content of the filler.

It should be noted that value of E_{ef} refers to the actual elastic modulus of the filler in the polymer matrix of the composite, which decreases compared to the nominal value of this parameter due to the aggregation of the filler and other factors. Obviously, the complex parameter $\eta_0 E_{ef}$ is the actual elastic modulus of the filler in the polymer matrix. Therefore, the purpose of this study was the determination of the effectiveness of a nanofiller in the reinforcing process of polymer nanocomposites based on the example of two types of these nanomaterials, filled with anisotropic 1D (carbon nanotubes) and 2D (graphene oxide) nanofillers.

2. Experimental

In the case of polyamide-6/carbon nanotube nanocomposites, single-walled carbon nanotubes (CNTs) functionalized with carboxylic acid (CNT-COOH) supplied by Carbon Solutions, Inc. (USA) were used as a nanofiller. Nanotubes of this brand have specific end groups for chemical functionalization - they contain 3-4% carboxylic acid groups and have a relative carbon purity of 80-90%. All other necessary chemical reagents were obtained from Aldrich (USA) and used as supplied [3].

The following procedure was used to obtain nanocomposites based on polyamide-6 (PA-6)

by *in situ* polymerization. Carbon nanotubes and caprolactam were loaded into a flask, and the mixture was sonicated at 353 K for 2 h to obtain a homogeneous CNTs dispersion. Then the flask was placed in an oil bath heated to 373 K, and 6-aminocaproic acid was added to the suspension. The suspension was heated for 6 h at 523 K with mechanical stirring in a nitrogen atmosphere. Then, the resulting mixture was poured into water, where a very rigid polymeric nanomaterial was deposited. The precipitate was cut into small pieces and washed with hot water at 353 K for an hour to remove the unreacted monomer and low molecular weight oligomers [3].

Fibres of PA-6/CNT nanocomposites were obtained by the extrusion of the material heated to 523 K in a nitrogen atmosphere through a hole with a diameter of 0.40 mm and subsequent cooling to room temperature in air. Mechanical tests for uniaxial tension of the fibres obtained by this method using samples with the diameter of ~ 1 mm and length of ~ 40 mm were performed using an Instron Universal Testing Machine (UTM, model 4455, USA) at a temperature of 293 K and a strain rate of ~ 10^{-3} s^{-1} [3].

Poly(ethylene terephthalate) (PET) manufactured by Toray Saehan with a weight-average molecular weight was used as a matrix polymer for polymer/graphene oxide nanocomposites. $M_w = 1.92 \cdot 10^5$. The graphene oxide (GO), prepared according to the modified Hummers method, was used as a nanofiller. The functionalization of GO was performed using S_N2 -type reaction with alkyl bromide, which easily reacts with hydroxyl and carboxyl groups on the surface of GO [4].

PET/GO nanocomposites were obtained by mixing the components (PET and GO) in 0-chlorophenyl and the subsequent sonication of the mixture for 1 h. After that, PET/GO nanocomposite films were obtained by pouring these solutions with different nanofiller contents onto a horizontal substrate. Then the solvent was slowly evaporated at room temperature during the day, and finally the films were dried under vacuum at a temperature of 343 K during the day. The content of graphene oxide in the studied nanocomposites varied within 0.5–3.0 wt%. % [4].

The mechanical properties of PET/GO nanocomposites under uniaxial tension were

measured using an Instron-5543 universal testing machine using a 1 kN load cell at a temperature of 293 K and a slider speed of 3 mm/min [4].

3. Results and discussion

In the case of polymer nanocomposites, the rule of mixtures (equation (1)) can be rewritten as follows:

$$E_n = (\eta_{ef} E_{nan} - E_m) \varphi_n + E_m, \quad (2)$$

where E_n is the elastic modulus of the nanocomposite, E_{nan} is the nominal modulus of the nanofiller, taken for the considered nanomaterials equal to 750 GPa [3], η_{ef} is the efficiency indicator of the nanofiller when increasing the elastic modulus of the nanocomposite.

It should be noted that the most significant difference between equations (1) and (2) is the use of the nominal, rather than the effective value of the elastic modulus of the nanofiller E_{nan} in the last equation. In turn, this means that the efficiency indicator η_{ef} takes into account all factors leading to a decrease in the nominal value of the elastic modulus of the nanofiller (orientation, anisotropy, aggregation, etc.).

The fact that nanofiller aggregation is the strongest factor affecting the properties of nanocomposites is well known [5]. In this study, for the characterization of this process, we used the aggregation parameter χ defined as follows [6]:

$$\chi = \frac{\varphi_n}{\varphi_n + \varphi_{if}}, \quad (3)$$

where φ_{if} is the relative proportion of interfacial regions estimated using the following percolation relation [7]:

$$\frac{E_n}{E_m} = 1 + 11(\varphi_n + \varphi_{if})^{1.7}, \quad (4)$$

where the ratio E_n/E_m is commonly referred to as reinforcement degree of the nanocomposite.

Attention should be paid to the physical meaning of the parameter χ , which is determined according to equation (3). As is known [8], the interfacial regions are the same reinforcing element of the nanocomposite structure as the nanofiller itself [8]. Thus, the parameter χ is determined by the growth of the actual proportion of the reinforcing element of the nanocomposite

structure ($\varphi_n + \varphi_{if}$) relative to the nominal φ_n . In other words, the degree of aggregation of a nanofiller is determined by its ability to generate interfacial regions.

In turn, the value of φ_n is determined according to the well-known formula [7]:

$$\varphi_n = \frac{W_n}{\rho_n}, \quad (5)$$

where W_n is the weight content of the nanofiller, ρ_n is its density, which for carbon nanotubes was estimated as follows [7]:

$$\rho_n = 188(d_{CNT})^{1/3}, \text{ kg/m}^3, \quad (6)$$

where d_{CNT} is the outer diameter of the carbon nanotube, specified in nanometers.

For graphene oxide, the value of ρ_n is taken as being equal to 1600 kg/m³ [9]. The dependence of the nanofiller efficiency indicator η_{ef} on the reciprocal value of aggregation parameter χ is shown in Fig. 1. It was linear and demonstrated an increase in the efficiency of the nanofiller as the degree of its aggregation decreased. This dependence can be analytically expressed by the following equation:

$$\eta_{ef} = 2,8 \cdot 10^{-3} \chi^{-1}. \quad (7)$$

It should be noted that the proposed model is adequate for nanofillers with very different forms of aggregation. For carbon nanotubes, which initially form bundles of collinearly arranged individual nanotubes, the emergence of ring-shaped formations in the polymer matrix is realized, structurally similar to macromolecular coils of branched polymer chains [10]. It should be noted that the emergence of such formations is a common effect for 1D nanofillers [11, 12]. Separate plates of graphene oxide in a polymer matrix form “packages” (tactoids) consisting of several collinearly stacked plates, the number of which varies from 1 to 100 [13]. Nevertheless, the various structural forms of nanofiller aggregation described above are correctly interpreted within the formalism of the proposed model (Fig. 1 and equation (7)).

For the studied PA-6/CNT and PET/GO nanocomposites, the calculation according to equations (3) and (4) showed an increase of χ in the interval 0.0143–0.330 at $\varphi_n \leq 0.02$ (Fig. 1), which, according to equation (7), leads to the

variation of $\eta_{ef} = 0.195-0.009$. Such a variation η_{ef} suggests for a hypothetical nanocomposite with $E_{nan} = 1000$ GPa, $E_m = 2.5$ GPa and $\phi_n = 0.02$ change in magnitude E_n according to equation (2) from 2.68 to 6.40 GPa or a variation in the reinforcement degree E_n/E_m from 1.07 to 2.56, i.e., an increase of about 2.4 times, and this estimate clearly demonstrates the strong effect of nanofiller aggregation on the properties of polymer nanocomposites.

A comparison of the experimentally obtained dependences of the reinforcement degree E_n/E_m on the volume content of the nanofiller ϕ_n for PA-6/CNT and PET/OG nanocomposites, which were calculated according to the rule of mixtures (equations (2) and (7)), is shown in Fig. 2. As can be seen, in both cases, a good agreement between theory and experiment was obtained. Their average discrepancy was 6%. This correspondence was obtained only by using the actual value of the elastic modulus of the nanofiller $\eta_{ef}E_{nan}$, instead of its nominal value E_{nan} . The same figure shows the theoretical curve calculated according to the base case, i.e., equation (1), which does not take into account nanofiller aggregation at $h_0 = 0.38$ [14] for a random orientation of anisotropic nanofillers. This curve provides overestimated values of the reinforcement degree and does not reflect the

actual shape of the dependence $E_n/E_m(\phi_n)$ for PET/GO nanocomposites. It should be noted that the calculation according to the basic equation is in good agreement with the experimental data with low $\phi_n (< 0.002)$, where aggregation is negligible. The obtained correspondence means that the main factor influencing the properties of nanocomposites is the aggregation of the nanofiller, characterized by the parameter χ , and other factors (orientation, anisotropy, etc.) are only derivatives of the main process – aggregation. For example, the authors of [15] showed that the formation of ring-shaped structures of carbon nanotubes in a polymer matrix leads to a change in their anisotropy, namely, a decrease in the radius of these structures determines a decrease in the actual level of anisotropy of this nanofiller. Finally, it should be mentioned, that the change E_n/E_m with ϕ_n for the studied nanocomposites (Fig. 2), the authors of [3, 4] also explained by the increase in the degree of aggregation of the nanofiller as its content increased, without provision of any quantitative estimates to confirm this assumption.

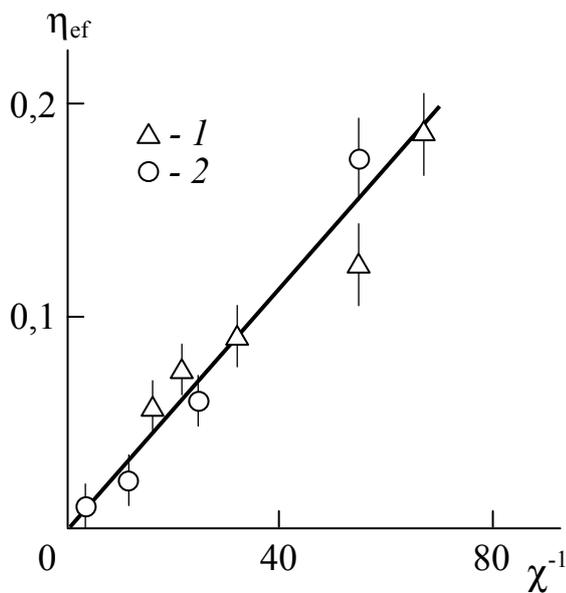


Fig. 1. The dependence of efficiency indicator of nanofiller η_{ef} on the reciprocal value of aggregation parameter c for nanocomposites PA-6/CNT (1) and PET/GO (2)

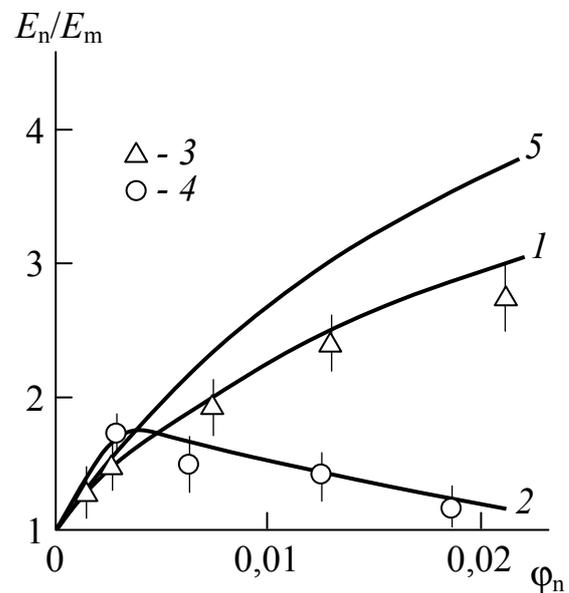


Fig. 2. Comparison of dependences of the reinforcement degree E_n/E_m on the volume content of the nanofiller ϕ_n for nanocomposites PA-6/CNT (1, 3) and PET/GO (2, 4) calculated according to the rule of mixtures (the equations (2) and (7)) (1, 2) and those experimentally obtained (3, 4). 5 – calculation according to the basic equation (1) at $h_0 = 0.38$

4. Conclusions

Thus, the fundamental novelty of the obtained results consists of the following postulates. The effectiveness of a nanofiller in improving the properties of polymer nanocomposites is determined only by the degree of its aggregation. Other factors (orientation, anisotropy, etc.) are derivatives of this main process. The physical meaning of the aggregation parameter is the ratio of the nominal and actual content of the reinforcing component in the structure of the nanocomposite, i.e., the efficiency of the nanofiller is determined by its ability to generate high-modulus interfacial regions. The rule of mixtures provides a correct description of the elastic modulus (or reinforcement degree) only when using the actual (effective) elastic modulus of the nanofiller, and not its nominal value. The nanofiller efficiency indicator can serve as a complex characteristic of the quality of the resulting polymer nanocomposites.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

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Characteristics of the formation and composition of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{Si}(111)$ heterostructures grown using a porous silicon buffer layer

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Abstract

In this work, we studied the efficiency of introducing nanoporous silicon as a buffer layer in the growth of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ on a single-crystal silicon by molecular beam growth technology. We also considered its influence on the morphological characteristics and atomic composition of the surface layers of heterostructures. As determined by X-ray diffraction, microscopic, and X-ray photoelectron methods, the heterostructure grown on Si(111) *n*-type monocrystalline silicon wafer with nanoporous por-Si buffer layer has a more homogeneous epitaxial layer, and the surface morphology of the layer is also more homogeneous.

Keywords: Porous silicon buffer layer, Heterostructures, Epitaxy

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1. Introduction

The integration of III-N technology with existing silicon technology is highly promising for creating new types of microwave and optoelectronic devices. The use of silicon substrates for the growth of III-N heterostructures is advantageous due to their commercial availability and the high level of Si technology. The main problem of integrating the two technologies is the considerable mismatch of crystal lattice parameters and thermal expansion coefficients. This results in a large number of defects, uncontrolled fluctuations of solid solution composition, as well as peeling and cracking of heterostructures. An equally important problem in the production of high-power microwave nitride transistors is the heat removal from devices, which have a power dissipation of dozens of watts [1–5].

The latest way to solve these problems is to introduce various transition buffer layers into the III-N/Si(111) heterostructure. These are multi-period superlattices, layers of alternating 2D–3D morphology, or layers with gradually changing composition [6–7]. The thickness of the buffer layers can reach several tens of micrometres. The main methods for growing heterostructures for various devices are metalorganic vapour-phase epitaxy (MOVPE) and molecular beam epitaxy (MBE).

The aim of this study was to determine how introducing por-Si nanoporous silicon as a buffer layer in the growth of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{Si}(111)$ heterostructure influenced the structural-morphological characteristics and atomic composition of the surface layers. For this purpose, we used X-ray diffraction, microscopic, and X-ray photoelectron methods.

2. Experimental. Obtaining heterostructures by molecular beam epitaxy, structural and morphological research methods

We obtained $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ heterostructures of two types, with a buffer por-Si layer and without it. They were grown simultaneously on a monocrystalline silicon Si(111) wafer by nitrogen-

plasma-assisted molecular beam epitaxy (PA MBE) on a Veeco Gen 200 unit [7]. We used standard Si(111) wafers of monocrystalline silicon of KDB grade (boron-doped p-type silicon) as substrates for the growth of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}$ heterostructure layers. First, we formed nanoporous layers with a thickness of about 20 nm and an average pore diameter of less than 3 nm on half of the wafer surface using the original technique described in [8]. Immediately before growing the heterostructure, the wafers were annealed and nitrided for 30 min [9] in the growth chamber of the unit.

The formation of all the layers composing the heterostructures took place under metal enriched conditions. The growth rate was controlled and limited by the nitrogen flow, it was $F_N \sim 0.05 \mu\text{m}/\text{h}$. An AlN buffer layer was formed on the substrate surface to prevent etching of the silicon substrate with liquid Ga and the formation of Ga-Si eutectic. After that, the growth of the main $\text{Al}_x\text{Ga}_{1-x}\text{N}$ layer took place. Figure 1 shows the expected design set by the technological growth regime and the expected thickness of the layers of an $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}$ heterostructure with a buffer layer of nanoporous silicon.

The morphology of the grown heterostructures was examined with a JEOL JSM 6380 LV scanning electron microscope (SEM) and a SOLVER P47 PRO atomic force microscope (AFM). Statistical analysis of the surface morphology was performed using the NOVA software.

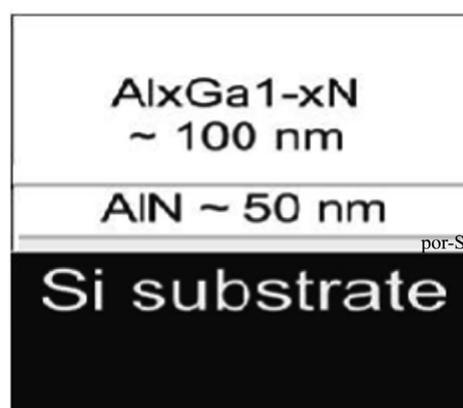


Fig. 1. The design of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}$ heterostructure with nanoporous silicon buffer layer

The samples were studied by X-ray photoelectron spectroscopy (XPS) on a SPECS spectrometer. The depth of the XPS analysis of the sample surface is 1–2 nm.

When processing the measurement results, Shirley algorithms were used to determine the background line and subtract the background values. To determine the binding energy of the heterostructure elements, we used the C1s line of natural hydrocarbon impurities of the sample surface not subjected to special cleaning as a reference line, the binding energy $E_b[\text{C1s}] = 285$ eV. The core levels of the elements and their chemical state were determined using the X-ray photoelectron spectra database of the US National Institute of Standards [10].

The HR XRD data were obtained at 305 K on a Bruker D8 Discover diffractometer with a Ge220 monochromator.

3. Results and discussion

3.1. X-ray diffraction data

Figure 2 shows the results of X-ray diffraction in the ω - 2θ geometry using the characteristic radiation of copper. It can be seen from the experimental data that the (111) diffraction line of the Si(111) silicon substrate is the most intense on the scans of both heterostructures. In

addition, both scans show high-intensity reflexes (0002) from the basic plane of the hexagonal unit cell, which belong to the $\text{Al}_x\text{Ga}_{1-x}\text{N}$ solid solution with a hexagonal structure. The fact that the diffractogram of the heterostructure with por-Si sublayer (dotted curves in Fig. 2) shows only the reflection from the basic plane (0002) suggests the monocrystalline state of the epitaxial film.

The diffractogram of the heterostructure grown on the c-Si(111) substrate without a porous sublayer (solid curves in Fig. 2) shows the reflection from the plane (11-20) of the $\text{Al}_x\text{Ga}_{1-x}\text{N}$ solid solution. This reflection may be due to growth of $\text{Al}_x\text{Ga}_{1-x}\text{N}$ solid solution columns in the $\langle 11-20 \rangle$ direction. Similar reflections were not observed in the ω - 2θ scan of the heterostructure with a porous sublayer, indicating greater homogeneity and perfection of its crystalline structure.

3.2. Sample morphology studied by scanning electron and atomic force microscopy.

Fig. 3. shows SEM images of the surface of heterostructures obtained on monocrystalline silicon substrates (a) and using a buffer sublayer of porous silicon (b).

The surface of the samples exhibits sub-micron inhomogeneities caused by the columnar

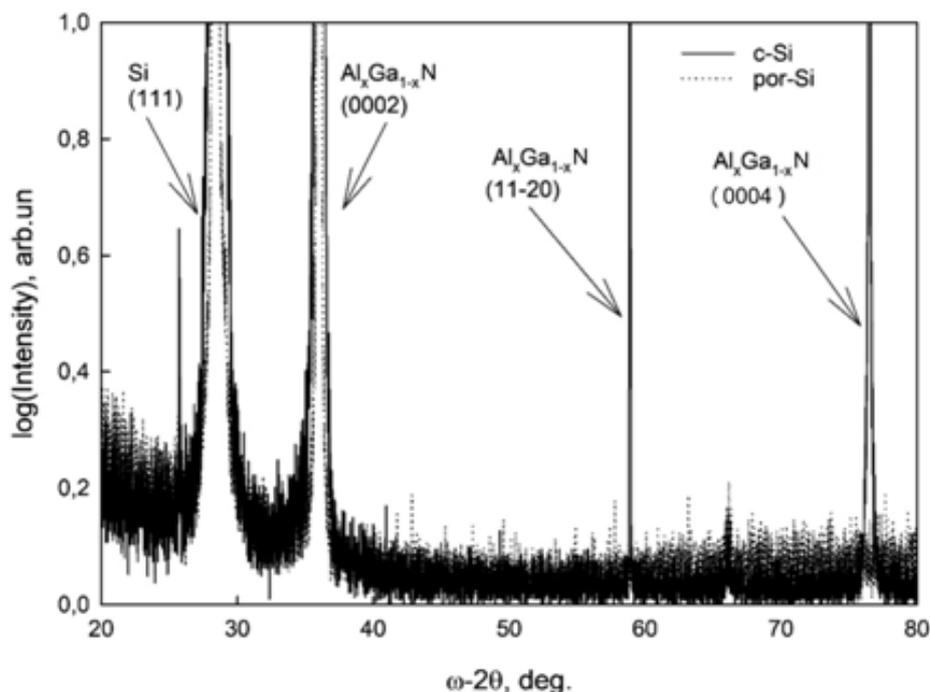


Fig. 2. XRD patterns of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}$ heterostructures grown on c-Si(111) (dotted line) and por-Si/c-Si(111) (solid line) wafers

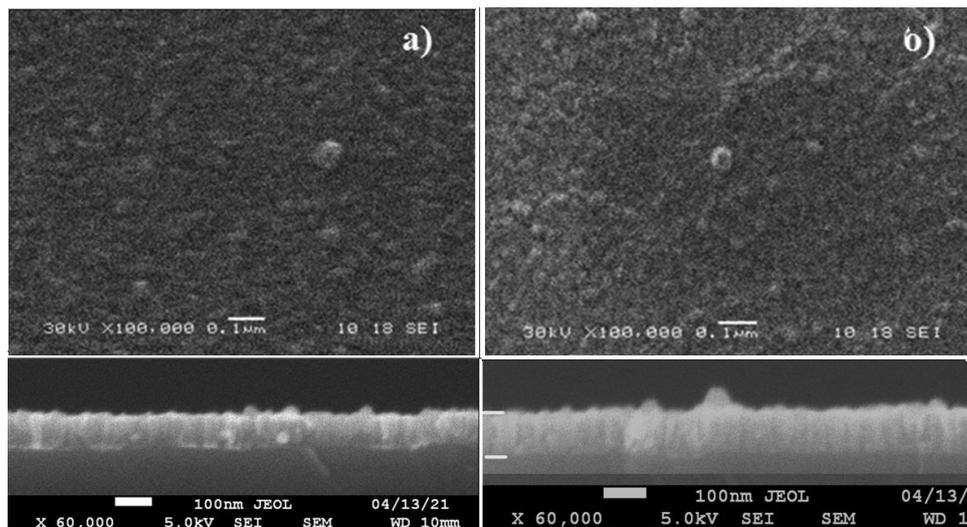


Fig. 3. SEM images of the surface and chipping of heterostructures: a) on the $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ monocrystalline silicon wafer; b) on the $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{Si}(111)$ wafer with por-Si buffer layer

film structure observed in SEM images of the chipped samples. We had observed a similar columnar film structure in $\text{In}_x\text{Ga}_{1-x}\text{N}/\text{Si}(111)$ heterostructures [11–12]. We compared the morphology of the two types of heterostructures, with and without the por-Si sublayer, and saw that the heterostructure grown on a porous layer had a smaller spread in the sizes of the surface inhomogeneities. So, its film structure was more homogeneous compared to the heterostructure grown without the buffer layer. This conclusion confirmed the above XRD data.

The analysis of the profile SEM images showed that the actual thickness of the heterostructure layers coincided with those specified in the technological procedure. The lateral size distribution of surface

inhomogeneities caused by the columnar structure of the film was determined by analysing AFM images (Figure 4).

Fig. 4 shows the AFM surface images and size distribution profiles of two $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ heterostructures grown directly on a c-Si(111) wafer and with a preformed buffer layer of porous silicon. The samples with the por-Si buffer layer have a smaller spread in the size of inhomogeneities compared to the heterostructure grown on crystalline silicon (Fig. 4a). The average inhomogeneity size on the surface of the samples grown with the por-Si buffer layer is ~ 100 nm. $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}$ samples grown on crystalline silicon show two maxima of nanocolumn size distribution of ~ 65 and 130 nm (Fig. 4c).

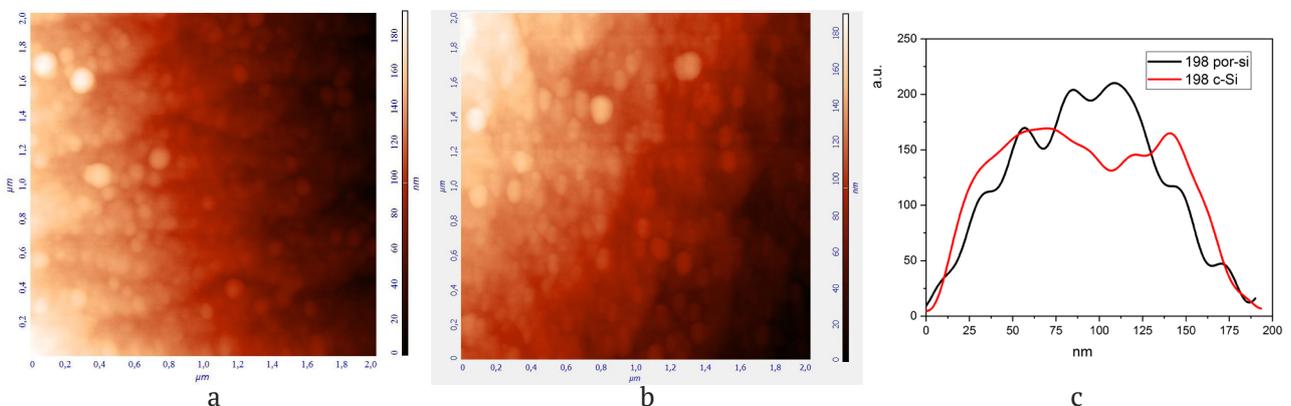


Fig. 4. AFM surface images of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}$ heterostructures grown: on the monocrystalline c-Si(111) wafer (a), on the por-Si/s-Si(111) wafer with a porous sublayer (b), and size distribution profiles of inhomogeneities on their surface (c)

3.3. Atomic composition of the surface of heterostructures as determined by X-ray photoelectron spectroscopy (XPS).

Figures 5 and 6 show XPS images of Al 2p, Ga 2p, and N1s core levels for heterostructures grown directly on monocrystalline silicon c-Si(111) (Fig. 5) and with a porous sublayer (Fig. 6). Table 1 shows the values of the binding energy determined with an accuracy of 0.05 eV and the half width values based on XPS study of the core levels for the two heterostructures.

XPS spectra analysis showed that on the surface of both heterostructures Al and Ga atoms formed chemical bonds with nitrogen. The binding energy (and half-width) of the core level spectra of all three elements in the $\text{Al}_x\text{Ga}_{1-x}\text{N}$ solid solution were practically identical. The values were close to the binding energy of aluminium

and gallium in nitrides [10]. In addition, the Al 2p spectra demonstrated the contribution of the low-intensity component of oxidised aluminium Al_2O_3 ($E_b = 75.5$ eV), formed on the surface of the samples when exposed to air. The Ga 2p3/2 spectrum showed no similar component, but that may be due to the nitrogen N KLL Auger line superimposed on the low-energy part of the gallium spectrum. The binding energy values of the N1s nitrogen spectra correspond to Al and Ga nitrides [10]. In addition, a low-energy hydride component was observed in the nitrogen spectra, apparently it was due to the residual reagents on the surface of heterostructures (NH_3 type bonds, $E_b = 398.7$ eV [10]).

By analogy with studies [13,14], the aluminium content of the film can be calculated using relation (1):

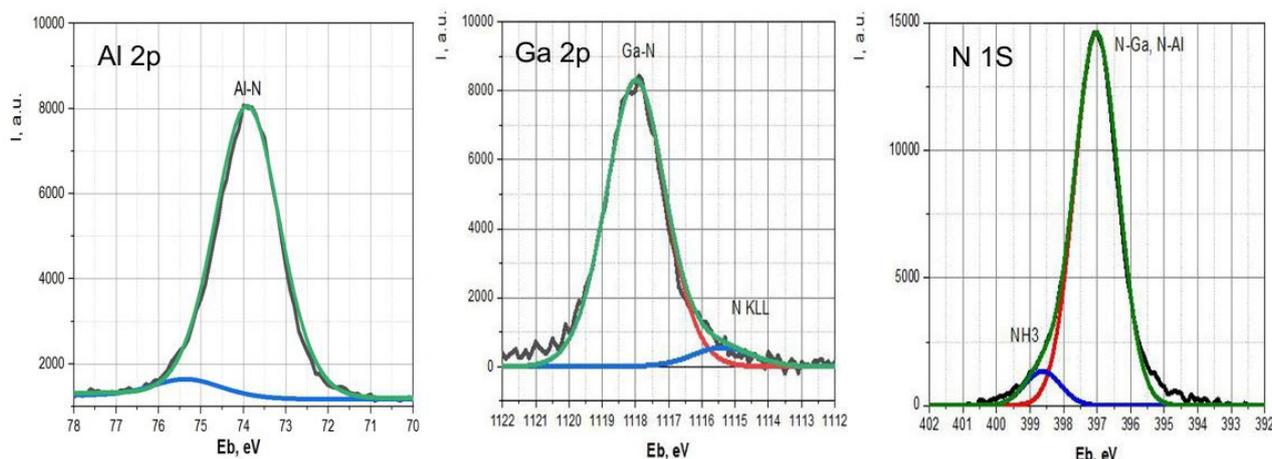


Fig. 5. XPS of Al 2p, Ga 2p3/2, and N1s in $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ heterostructures, grown on the monocrystalline silicon Si(111) wafer

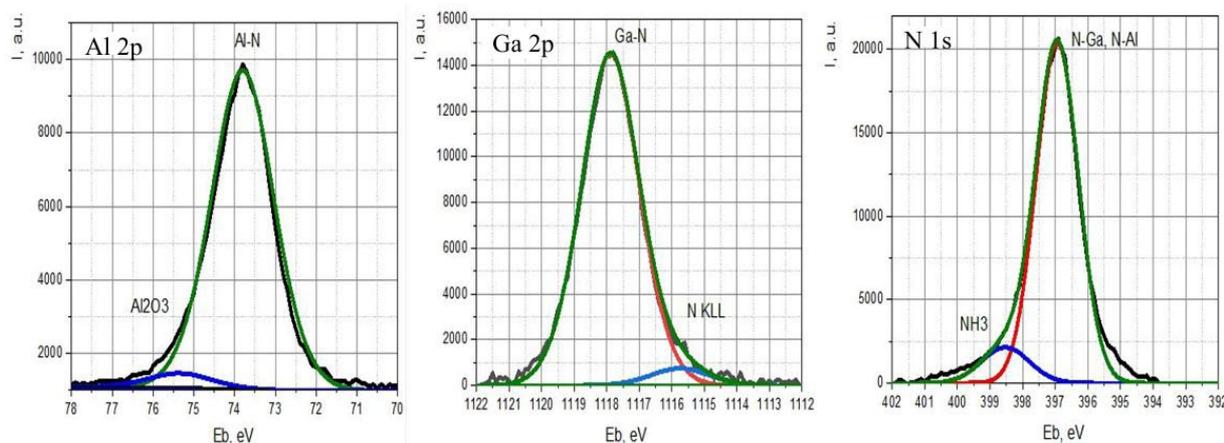


Fig. 6. XPS of Al 2p, Ga 2p3/2, and N1s in $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{Si}(111)$ heterostructures grown on monocrystalline silicon wafer with a buffer layer of porous silicon

Table 1. Binding energy and half-width values by XPS of Al 2p, Ga 2p_{3/2}, and N 1s core levels for heterostructures grown on c-Si(111) and on por-Si/c-Si(111)

	Binding energy, eV/ Half-width, eV					
	Al2p		Ga2p _{3/2}		N1s	
$\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{c-Si}$	73.80	1.64	1117.92	2.10	396.97	1.55
$\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{c-Si}$	73.91	1.72	1117.87	2.15	396.93	1.56
AlN [10]	73.90		1117.80		397.0	
GaN [10]					397.30	
GaN [10]						
AlN [10]						

$$x_{\text{Al}} = \frac{I_{\text{Al}_{2\text{P}_3}} / F_{\text{Al}_{2\text{P}_3}}}{(I_{\text{Al}_{2\text{P}_3}} / F_{\text{Al}_{2\text{P}_3}} + I_{\text{Ga}_{2\text{P}_3}} / F_{\text{Ga}_{2\text{P}_3}})}, \quad (1)$$

where I is the integral intensity of the photoelectron maxima of the corresponding lines in the spectrum and F is the sensitivity factor ($F_{\text{Ga}_{2\text{P}_3}} = 2.75$ and $F_{\text{Al}_{2\text{P}_3}} = 0.54$). Based on relation (1), we determined the Al atom concentration values in solid solution. They were $x_{\text{a,cryst}} = 0.49$ for samples of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}(111)$ grown directly on monocrystalline silicon and $x_{\text{a,por}} = 0.54$ for samples of $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{Si}/\text{por-Si}/\text{Si}(111)$ grown using a porous buffer layer. It coincided quite well with the expected technological values of $x=0.50$ specified during synthesis. The slight difference in the values of x of the two heterostructures may be due to their minor structural and morphological differences.

4. Conclusions

For the first time, $\text{Al}_x\text{Ga}_{1-x}\text{N}/\text{AlN}/\text{por-Si}/\text{Si}(111)$ heterostructures were formed by nitrogen-plasma-assisted molecular beam epitaxy using a buffer layer of por-Si porous silicon.

X-ray diffraction and electron microscopy methods showed that the formation of $\text{Al}_{0.54}\text{Ga}_{0.46}\text{N}$ solid solution on a buffer layer of porous silicon results in a more homogeneous size distribution and orientation in the basic direction of the solid solution nanocolumns compared to the similar solid solution $\text{Al}_{0.49}\text{Ga}_{0.51}\text{N}$, grown simultaneously on the same plate of monocrystalline silicon without porous layer under the same technological conditions.

The slight shift of $\sim 5\%$ towards Al demonstrated by the surface composition of the solid solution on the substrate with a buffered porous layer may be due to the more

homogeneous structural and morphological characteristics of this heterostructure.

Author contributions

Lenshin A. S. – scientific guidance, research concept, sample synthesis, text writing, and final conclusions. Zolotukhin D. S. – text writing, final conclusions. Beltyukov A. N. – measurements, text writing. Seredin P. V. – measurements, text writing. Mizerov A. M. – sample synthesis, text writing. Kasatkin I. A. – measurements, text writing. Radam A. O. – measurements. Domashevskaya E. P. – text editing, final conclusions.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

Research article

<https://doi.org/10.17308/kcmf.2022.24/9056>**Corrosion inhibition of steel by selected homologues of the class 3-alkyl-5-amino-1H-1,2,4-triazoles in acidic media**D. V. Lyapun, A. A. Kruzhilin[✉], D. S. Shevtsov, Yu. V. Aseeva, Kh. S. Shikhaliev¹Voronezh State University,
1 Universitetskaya pl., Voronezh 394018, Russian Federation**Abstract**

The use of hydrochloric acid in the treatment of the bottomhole formation zone leads to the significant corrosion of metals, as well as hydrogen and chloride stress cracking of pump compressor pipes. In order to solve this problem, corrosion inhibitors are added to a hydrochloric acid solution. This article presents the results of a study of the anticorrosive activity of a number of derivatives of the class of 3-alkyl-5-amino-1H-1,2,4-triazole under the conditions of hydrochloric acid corrosion of low-carbon steel.

During the study, selected 3-alkyl-5-amino-1H-1,2,4-triazoles were synthesized. Their structure was confirmed and proved using NMR spectroscopy and HPLC/MS spectrometry. Regularities of the anticorrosive action of the investigated compounds have been established using polarization electrochemical studies and gravimetric direct corrosion tests. Corrosion rates, inhibition coefficients and degrees of protection have been calculated for all inhibitors. The probable mechanism of the inhibitory action of the studied compounds has been substantiated using quantum chemical calculations based on the density functional theory using the Gaussian program.

It was shown that the structure of the alkyl substituents has the greatest effect on the inhibitory activity of the studied compounds. The mechanism was proposed for the adsorption of the inhibitor, which explained the increase in protective properties with an increase in the length of the alkyl substituent. The high hydrophobicity of the aliphatic fragment, not involved in the chemisorption process, additionally prevents the acid solution from contacting the metal surface, while the heterocyclic moiety ensures the sorption of the inhibitor on the metal surface.

As a result, it was shown that derivatives of the homologous series of 3-alkyl-5-aminotriazole are suitable as inhibitors of acid corrosion of ST-3 steel. The minimum length of a hydrocarbon radical at which significant inhibitory activity was observed is 7 carbon atoms. Protection degrees of 65–85% were achieved when 3-heptyl-5-amino-1H-1,2,4-triazole additives at a concentration of at least 2 g/L were added to the hydrochloric acid solution.

Keywords: Metal corrosion, Steel, corrosion inhibitors, Heterocyclic compounds, Aminotriazoles, Physicochemical research methods, Drilling equipment

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1. Introduction

The intensification of production in oil fields is currently one of the priority areas for the development of the oil industry. At the same time, a large share of carbonate reservoirs in oil and gas reserves, relatively low production and low oil recovery in such oil fields make this group of reservoirs especially promising in terms of the use of new technologies for intensifying production. There are a large number of methods for influencing the bottomhole zone of wells in carbonate reservoirs. Hydrochloric acid technologies and their modifications are widespread in oil fields; they play a huge role in intensifying oil production. Their use is so high that, according to the total effect of additional oil produced from the deposit, they are equated with methods of enhanced oil recovery.

The use of hydrochloric acid in the treatment of the bottomhole formation zone leads to significant corrosion of metals, as well as hydrogen and chloride stress cracking of pump compressor pipes. As a result of corrosion, pipelines quickly become unusable, and this affects the economic effect of acid treatments. In order to solve this problem, corrosion inhibitors are added to the hydrochloric acid solution.

Various organic and inorganic compounds are used as such additives. However, many currently known corrosion inhibitors are non-biodegradable, contributing to a significant pollution of waste water and soil, and therefore, recently, research into the search for and synthesis of environmentally friendly and harmless compounds of natural origin, promising as anti-corrosion agents, are being intensified [1–2].

To date, a wide range of heterocyclic compounds exhibiting anticorrosive properties for steel have been studied. These compounds include, for example, aminopyrazoles [3], aminopyridines [4], pyrimidines [5–6], thiazoles [7], benzimidazoles [8–9], etc., however, various triazole derivatives are undoubtedly and undeniable leaders. In particular, the effect of benzotriazole (BTA) on ferrous and non-ferrous metals has been studied in detail [10–12]. This substance is a fairly versatile inhibitor for various environments. However, the BTA has some drawbacks: the indicators of degree of protection and the

coefficients of inhibition of acid corrosion of steel are very low. It is also known that it is moderately hepatotoxic, is a mutagen, and the semi-lethal dose is ~560 mg/kg [13].

Fatty acids, which are mostly environmentally friendly, biodegradable compounds involved in the metabolism of many organisms, can be used for the production of various organic compounds, including corrosion inhibitors for both ferrous and non-ferrous metals. For example, fatty acid hydrazides and thiosemicarbazides [14] and Schiff bases of fatty acids of soybean oil [15] inhibit steel corrosion. Heterocyclic corrosion inhibitors for steel based on carboxylic acids, such as imidazoles [16] and 3-alkyl-5-mercapto-1,2,4-triazoles [17] are known. At the same time, it is known that the simplest representative of the class of aminotriazoles, amitrol, possesses low toxicity ($LD_{50}=1100$ mg/kg) [18].

Therefore, the synthesis of heterocyclic inhibitors of the class of 5-amino-3-alkyl-1,2,4-triazoles based on carboxylic acids for the investigation of their anti-corrosion properties under the conditions of acid corrosion of steel is an important and urgent task. The goal of this study was the investigation of anti-corrosion activity of derivatives of the class of 3-alkyl-5-amino-1H-1,2,4-triazole under the conditions of hydrochloric acid corrosion of low-carbon steel.

2. Experimental

2.1. Synthesis of starting compounds

General procedure for the synthesis of 3-alkyl-5-amino-1H-1,2,4-triazoles.

The corresponding carboxylic acid was added in portions with stirring to a mixture of 100 ml of toluene with aminoguanidine carbonate (0.2 M), 0.21 M. The mixture was carefully heated to 50–70°C and, after the evolution of carbon dioxide had ceased, it was boiled with a Dean-Stark apparatus and a reflux condenser. After the separation of water in the trap ceased, the reaction mass was cooled and the solvent was decanted. The residue was ground and washed on the filter with toluene, dried, and recrystallized from a boiling mixture of isopropyl alcohol and petroleum ether. The precipitate formed after cooling was filtered, washed with petroleum ether, and dried at 60°C.

3-methyl-5-amino-1H-1,2,4-triazole (b). Yield 65–70%, mp 148–150 °C. White powder. ¹H NMR spectrum: 2.02 (s, 3H, CH₃); 5.73 (s, 2H, NH₂); 11.50 (s, H, NH). Determined, m/z: 99.0672 [M+H]⁺. C₃H₆N₄+H⁺. Calculated, m/z: 99.0665.

3-ethyl-5-amino-1H-1,2,4-triazole (c). Yield 57–63%, mp 139–141 °C. White powder. ¹H NMR spectrum: 1.02 (t, 3H, J=7.5, CH₃); 2.40 (q, J=7.5, 2H, CH₂); 5.70 (s, 2H, NH₂); 11.49 (s, H, NH). Determined, m/z: 113.0816 [M+H]⁺. C₄H₈N₄+H⁺. Calculated, m/z: 113.0822.

3-butyl-5-amino-1H-1,2,4-triazole (d). Yield 55–57%, mp 124–126 °C. White powder. ¹H NMR spectrum: 0.87 (t, J=7.5, 3H, CH₃); 1.29–1.37 (m, 2H, CH₂); 1.44–1.51 (m, 2H, CH₂); 2.38 (t, J=7.3, 2H, CH₂); 5.61 (s, 2H, NH₂); 11.49 (s, H, NH). Determined, m/z: 141.1127 [M+H]⁺. C₆H₁₂N₄+H⁺. Calculated, m/z: 141.1135.

3-pentyl-5-amino-1H-1,2,4-triazole (e). Yield 55–64%, mp 124–127 °C. White powder. ¹H NMR spectrum: 0.86 (t, J=7.5, 3H, CH₃); 1.29–1.38 (m, 4H, 2CH₂); 1.52–1.59 (m, 2H, CH₂); 2.38 (t, J=7.3, 2H, CH₂); 5.56 (s, 2H, NH₂); 11.49 (s, H, NH). Determined, m/z: 155.1299 [M+H]⁺. C₇H₁₄N₄+H⁺. Calculated, m/z: 155.1292.

3-heptyl-5-amino-1H-1,2,4-triazole (f). Yield 60–64%, mp 120–124 °C. White powder. ¹H NMR spectrum: 0.85 (t, J=7.5, 3H, CH₃); 1.25–1.36 (m, 8H, 4CH₂); 1.52–1.59 (m, 2H, CH₂); 2.38 (t, J=7.3, 2H, CH₂); 5.55 (s, 2H, NH₂); 11.49 (s, H, NH). Determined, m/z: 183.1301 [M+H]⁺. C₉H₁₈N₄+H⁺. Calculated, m/z: 183.1605.

2.2. Methods for structure proof of compounds

Control of the individuality of the reagents and the obtained compounds and the course of the reaction, was carried out using thin layer chromatography (hereinafter referred to as TLC) on Silufol UV-254 plates. Chloroform was used as the eluent; the development of chromatograms was carried out in UV light and iodine vapour. ¹H NMR spectra were recorded using a Bruker AC-300 (operating frequency 300 MHz) in pulsed Fourier mode in a DMSO-d₆; The assignment of the signals was carried in relation to the residual signals of the proton of the deuterium solvent. Mass spectra were recorded using an MX-1321 spectrometer with direct injection of the sample into the ion source at 100–150 °C and an accelerating voltage of 70

eV. The melting point was determined using a PTP-M device.

2.3. Electrochemical research

Polarization curves were obtained on an electrode made of ST-3 steel (with an area of 1.0 cm²) in an electrochemical cell with undivided electrode spaces using an IPC-PRO potentiostat. The working electrode was preliminarily cleaned with K2000 sandpaper and degreased with ethyl alcohol. Electrode potentials (*E*) was measured relative to the silver chloride electrode, connecting the space of the electrochemical cell and the reference electrode through an electrolytic bridge based on agar-agar and sodium nitrate, and recalculated to the scale of a standard hydrogen electrode (potential was +202 mV relative to SHE). A platinum grid was used as an auxiliary electrode.

The test substances were introduced into the acid until the required concentration was obtained. The electrodes were placed in the prepared solution and kept until the onset of a stationary state for 30 min. After the open-circuit potential (*E*_{cor}) was established, polarization curves with a potential scan rate of 0.2 mV/s in the anode and cathode directions were obtained. Polarization curves were recorded until the current density reached 0.1 A cm⁻².

2.4. Calculation of the corrosion rate using the polarization resistance method

The rate of corrosion in current units was determined by the polarisation resistance technique as summarized by Mansfeld [19].

The studies were carried out using a three-electrode cell with undivided cathode and anode spaces without mixing under natural aeration conditions, the reference electrode was silver chloride (potential +202 mV relative to SHE), and the auxiliary electrode was a platinum grid. The reference electrode was separated from the cell by an electrolytic bridge based on agar-agar and NaNO₃.

The working electrode was preliminarily cleaned with P2000 sandpaper, degreased with ethyl alcohol (96%), and washed with distilled water. The electrodes were placed in the prepared solution and kept until the onset of a stationary state for 30 min. When the steady state was

reached, the electrode was polarized in the range of ± 30 mV from the value E_{cor} in potentiodynamic mode with a scanning rate of 0.2 mV/s.

Polarization resistance R_p was determined as the slope of the polarization curve at the point E_{cor} in the coordinates $\Delta E - i$, where ΔE is the difference between the current electrode potential and the open-circuit potential ($E - E_{\text{cor}}$). Next, the dependence was plotted with the coordinates $2.3 \cdot R_p \cdot i - \Delta E$. Coefficients b_a and b_c (Tafel slopes of the cathode and anode segments of the polarization curve) were determined using the TableCurve 2D program as the approximation parameters of the equation:

$$2.3 \cdot R_p \cdot I = \frac{b_a \cdot b_c}{b_a + b_c} \left[\exp\left(\frac{E - E_{\text{cor}}}{b_{1a}}\right) - \exp\left(-\frac{E - E_{\text{cor}}}{b_{2c}}\right) \right] \quad (1)$$

The corrosion current was calculated taking into account the obtained coefficients according to the equation:

$$I_{\text{cor}} = \frac{B}{R_p} \quad (2)$$

For the comparison of the data obtained in various studies, the values of the corrosion current density (i_{cor}) calculated using the expression will be presented further:

$$i_{\text{cor}} = \frac{I_{\text{cor}}}{S}, \quad (3)$$

where S is the geometric area of the electrode. For the convenience of further comparison of the obtained data, the ratio of the corrosion current density of each test sample to the current density of the background experiment was calculated ($i_{\text{cor}}^0 \approx 6.8$ mA/cm²):

$$i_{\text{cor(relative)}} = \frac{i_{\text{cor}}}{i_{\text{cor}}^0} \times 100\%. \quad (4)$$

Measurements for each concentration of the substance were made at least 5 times until reproducible data were obtained with subsequent statistical processing of the measurement results.

2.5. Gravimetric direct corrosion tests

Corrosion tests were carried out on steel plates (20×40 mm, thickness 1.2 mm). Each sample was preliminarily polished with K 1000 fine-grained sandpaper, after which it was washed

with distilled water, ethanol, and dried with filter paper. The experiments were carried out in a 24% HCl solution (for 7 days) under natural aeration without stirring for three samples in parallel (for each inhibitor concentration). After testing, the plates were washed with distilled water and treated with compositions in accordance with GOST 9.907-83.

The corrosion rate was determined according to the weight loss of the samples and was calculated using the formula:

$$k_{\text{inh}} = \frac{\Delta m}{S \cdot t} \quad (5)$$

where $\Delta m = m_0 - m$ (m_0 is the weight of the sample before the start of the experiment, m is the weight of the sample after test, g), S is the total surface area of the plate, m².

For each solution, the corrosion rate k_0 without inhibitor additive was determined ($k_{0(\text{medium})} \approx 16.9 \pm 0.5$ g/m² day is the average value of the corrosion rate without the addition of an inhibitor, obtained over the course of the studies). The effectiveness of the inhibitory action of aminotriazole derivatives was evaluated according to the value of the inhibition coefficient:

$$\gamma = \frac{k_0}{k_{\text{inh}}} \quad (6)$$

and the degree of protection:

$$Z = \left[\frac{(k_0 - k_{\text{inh}})}{k_0} \right] \cdot 100\%, \quad (7)$$

where k_0 and k_{inh} are the corrosion rates in the background solution and in the solution with the inhibitor, respectively.

2.6. Quantum-chemical calculations

All molecules of the synthesized compounds were fully optimized using the density functional theory (DFT) with the B3LYP functional using the 6-31G (d, p) basis in the Gaussian program [20]. The optimized geometry shows non-negative frequencies, resulting in the molecules being positioned at minimum energy on the potential energy surface. Determination of the energies of HOMO and LUMO molecular orbitals, their difference HLG (HOMO-LUMO-gap), as well as the ionization potential (IP), electron affinity (EA), electronegativity (χ), absolute hardness (η),

and absolute softness (σ) for all molecules were carried out at the same level of theory.

According to the density functional theory, the absolute hardness (η) is defined as [21]

$$\eta = \frac{1}{2} \frac{\partial \mu}{\partial N} = \frac{1}{2} \frac{\partial^2 E}{\partial N^2}, \quad (8)$$

where μ is the chemical potential, N is the number of electrons, and E – energy. R. G. Pearson proposed a working definition of absolute hardness as

$$\eta = \frac{IP - EA}{2}, \quad (9)$$

where IP and EA are ionization potential and electron affinity. Also, according to Koopmans' theorem IP and EA are defined as

$$IP = -E_{\text{HOMO}}; \quad EA = -E_{\text{LUMO}}, \quad (10)$$

E_{HOMO} and E_{LUMO} are the energies of the highest occupied and lowest unoccupied molecular orbitals.

Electronegativity (χ) is also defined in terms of HOMO and LUMO energies as

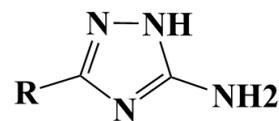
$$\chi = \frac{IP + EA}{2}. \quad (11)$$

According to formulas described above (9, 11), the hardness is a measure of the resistance to changes in the electron cloud of a chemical system and is an important parameter in the reaction chemistry. Absolute softness (σ) is inversely proportional to hardness. It is generally accepted [21] that in the homologous series of organic compounds, the most reactive substances have a higher softness value in comparison with their homologues. This idea makes possible the theoretical evaluation and comparison of the degree of binding of inhibitors of the same class of organic compounds with metal and, as a result, estimate their probable inhibitory ability.

3. Results and discussion

Along with the inhibitors synthesized in the study (Fig. 1), Amitrol, a commercially available 3H-5-amino-1H-1,2,4-triazole **a**, was also studied in corrosion tests. Solutions with inhibitor concentrations of 1 g/l and 2 g/l were studied.

As a result of potentiodynamic studies, it was found that the addition of 3-H-5-amino-



R: H (a), CH₃ (b), C₂H₅ (c), C₄H₉ (d), C₅H₁₁ (e), C₇H₁₅ (f)

Fig. 1. Structure of the studied derivatives of 1,2,4-triazole

1H-1,2,4-triazole **a** to the acid solution up to 2 g/l slightly changed the shape and position of the anodic and cathodic parts of the polarization curves. (Fig. 2). However, for the cathode sections, insignificant decrease in the current density at all studied concentrations of the inhibitor (C_{inh}) was revealed. The addition of 3-methyl-5-amino-1H-1,2,4-triazole up to 2 g/l had a similar effect on the nature of the polarization curves. Thus, for 3-methyl- and 3H-5-amino-1H-1,2,4-triazoles, we can assume an insignificant inhibitory effect due to inhibition of the cathodic reduction half-reaction of the oxidizer.

The addition of 3-ethyl-5-amino-1H-1,2,4-triazole to the acid solution up to 2 g/l slightly changed the shape and position of the anodic and cathodic segments of the polarization curves relative to the control measurement without amino-1H-1,2,4-triazole. The nature of the polarization curves for 3-butyl-5-amino-1H-1,2,4-triazole and 3-pentyl-5-amino-1H-1,2,4-triazole was similar to the results for 3-ethyl derivatives. Thus, the presence of an inhibitory effect according to potentiodynamic measurements for compounds **b-e** is unlikely.

With the addition of 3-heptyl-5-amino-1H-1,2,4-triazole at a concentration of 1 g/L, the polarization curves were hardly distinguishable from the control curves; only a slight decrease in current densities was observed in all parts of the curve. With an increase in concentration to 2 g/l, a significant, up to 1 order of magnitude, decrease in the density of the anode and cathode current was observed at a given value of the electrode potential. At the same time, the open-circuit potential was slightly different from the control value. Such a course of the polarization curve

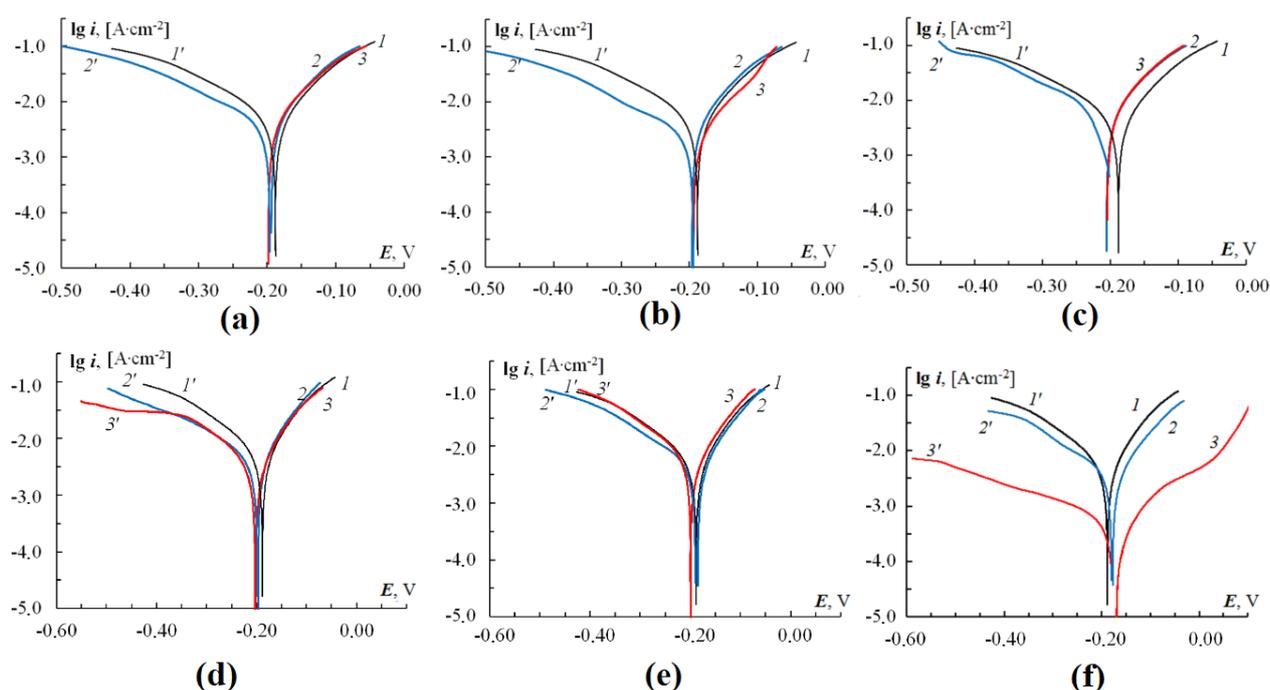


Fig. 2. Anodic (I -3) and cathodic (I' -4') polarization curves of ST-3 steel in HCl (24 %) at C_{inh} (g/L): 1, I' - 0.0; 2, $2'$ - 1.0; 3, $3'$ - 2.0, obtained by the addition of 3-H-5-amino-1H-1,2,4-triazole (a), 3-methyl-5-amino-1H-1,2,4-triazole (b), 3-ethyl-5-amino-1H-1,2,4-triazole (c), 3-butyl-5-amino-1H-1,2,4-triazole (d), 3-pentyl-5-amino-1H-1,2,4-triazole (e), 3-heptyl-5-amino-1H-1,2,4-triazole (f)

indicates the presence of a noticeable inhibitory effect of 3-heptyl-5-amino-1H-1,2,4-triazole in relation to steel in concentrated hydrochloric acid.

The results of direct corrosion tests in general correlated with electrochemical studies. Degrees of protection Z for compounds a-e did not exceed 10-15%, which for the direct tests can

be considered as evidence of the absence of an inhibitory effect. The introduction of 3-heptyl-5-amino-1H-1,2,4-triazole f into a hydrochloric acid solution significantly reduced the corrosion of the studied steel plates (protection degree $Z \sim 65\%$ at an inhibitor concentration of 2 g/l). Calculations carried out using the polarization resistance method also confirmed this trend

Table 1. Corrosion rate and degree of protection data calculated by polarization resistance method and direct corrosion tests

No.	Inhibitor	C_{inh} , g/l	C_{inh} , g/l	γ	Z , %	$I_{cor}^{(abs)}$, mA/cm ²	$i_{cor}^{(rel)}$
a	5-amino-1H-1,2,4-triazole	1.00	14.19	1.19	16.04	6.2±0.9	8.8 %
		2.00	14.19	1.19	16.04	6.8±0.9	0.0 %
b	3-methyl-5-amino-1H-1,2,4-triazole	1.00	15.41	1.10	8.82	6.8±0.7	0.0 %
		2.00	15.20	1.11	10.06	6.6±0.6	2.9 %
c	3-ethyl-5-amino-1H-1,2,4-triazole	1.00	13.93	1.21	17.57	7.6±1.2	-11.7 %
		2.00	13.87	1.22	17.93	9.8±0.8	-44.1 %
d	3-butyl-5-amino-1H-1,2,4-triazole	1.00	12.37	1.37	26.80	7.7±0.9	-13.2 %
		2.00	12.28	1.38	27.34	6.3±1.3	7.3 %
e	3-pentyl-5-amino-1H-1,2,4-triazole	1.00	14.55	1.16	13.91	8.5±0.1	-24.9 %
		2.00	13.24	1.28	21.66	8.6±0.8	-26.5 %
f	3-heptyl-5-amino-1H-1,2,4-triazole	1.00	9.86	1.71	41.66	7.1±0.7	-4.4 %
		2.00	5.74	2.94	66.04	0.8±0.5	89.0 %

(Table 1). With an inhibitor concentration of 2 g/l, the average degree of protection for the heptyl derivative **f** was ~90%. For all other compounds, the degrees of protection calculated as a result of electrochemical studies indicate the absence of an inhibitory effect or the intensification of the course of electrode processes in their presence (at $i_{cor}(\text{rel}) < 0$)

The analysis of the results of quantum chemical calculations for the molecules of studied corrosion inhibitors (Table 2) demonstrated the absence of significant change of the orbital characteristics with an increase in the length of the aliphatic fragment. The main electron density is distributed over the molecular orbitals of the heterocyclic fragment and the exocyclic amino group of the inhibitors. This finding shows that the heterocyclic matrix, as well as the amino group with high probability are the main centre of triazole molecules involved in adsorption and binding to the metal surface (Fig. 3). Thus, correlating the results of corrosion tests and quantum chemical calculations, we can conclude

that the structure of the alkyl substituent, and not the electronic structure of the molecule as a whole, has the greatest effect on the inhibitory activity of the studied compounds, since the distribution of electron densities in the molecules of inhibitors practically does not change with changes in the structure of the side aliphatic substituent.

As can be seen from the test results, effective protection of steel from acid corrosion in

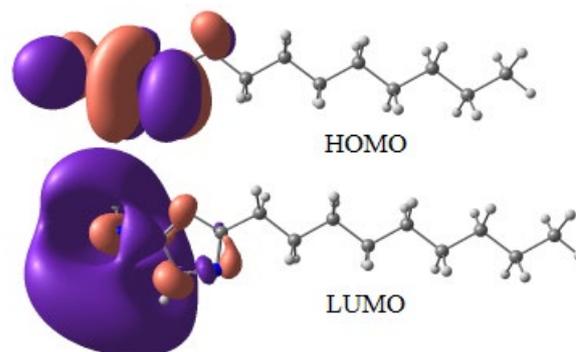
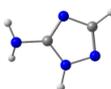
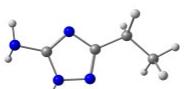
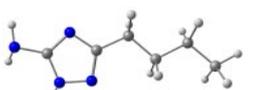
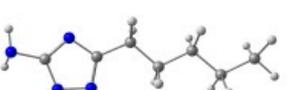
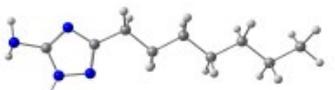


Fig. 3. HOMO and LUMO visualization of the 3-heptyl-5-amino-1H-1,2,4-triazole molecule

Table 2. Optimized structures, calculated HOMO, LUMO energies, HOMO-LUMO gap (HLG), Ionization Potential (*IP*), Electron Affinity (*EA*), Electronegativity (χ), Absolute Hardness (η) and Softness (σ) in eV at B3LYP/6-311+G (d,p) level of theory

No.	Structure	HOMO	LUMO	HLG	<i>IP</i>	<i>EA</i>	χ	η	σ
a		-6.62	-0.54	6.08	6.62	0.54	3.58	3.04	0.33
b		-6.43	-0.50	5.93	6.43	0.50	3.46	2.96	0.34
c		-6.42	-0.49	5.93	6.42	0.49	3.46	2.96	0.34
e		-6.41	-0.50	5.91	6.41	0.50	3.46	2.96	0.34
e		-6.41	-0.50	5.91	6.41	0.50	3.46	2.96	0.34
f		-6.41	-0.50	5.91	6.41	0.50	3.46	2.95	0.34

hydrochloric acid is possible by increasing the length of the aliphatic substituent in the homologous series of 3-alkyl-5-amino-1H-triazoles to 7 carbon atoms.

This feature of steel passivation can be explained by an increase in the lyophilic nature of the inhibitor molecule. Probably, the introduction of hydrophobic substituents into the cycle reduces the interaction of the organic molecule with the solvent and increases its adsorption capacity.

As a result, most probably the formation of protective triazole layers on the metal surface occurs under the considered conditions. (Fig. 4). Probably, a self-organization mechanism occurs, in which the inhibitor molecule is oriented on the metal surface according to the “head-tail” principle, when the heterocyclic moiety provides self-organization and binding of the inhibitor to the metal surface, and the lateral hydrophobic aliphatic substituent of the molecule prevents contact of the acid solution with a metal surface. This mechanism explains the increase in the protective properties of inhibitors with an increase in the length, and, consequently, in the hydrophobic properties of the alkyl substituent.

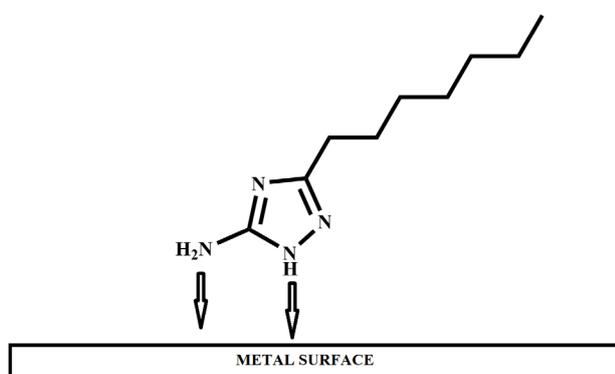


Fig. 4. Schematic diagram of the formation of protective layers by the example of 3-heptyl-5-amino-1H-1,2,4-triazole

Earlier in the study [22], the mechanism of formation of such layers was also studied in detail for copper chloride corrosion. It was shown that when copper was protected with 3-alkyl-5-aminotriazoles, inhibitory activity was observed already when 3-butyl-1H-5-aminotriazole was introduced into the system at concentrations of at least 0.001 M.

The results obtained in this study do not contradict the results of earlier studies, as well as literature data.

Thus, it was found that inhibitory activity under the condition of hydrochloric acid corrosion of steel is probable for compounds of the homologous series of 3-alkyl-5-aminotriazole. The minimum length of the hydrocarbon fragment, at which a significant protective effect is observed, is 7 carbon atoms.

4. Conclusions

The study performed using polarization methods and direct corrosion tests allowed establishing that derivatives of the homologous series of 3-alkyl-5-aminotriazole are suitable as inhibitors of chloride acid corrosion on ST-3 steel.

The minimum length of the hydrocarbon radical, at which significant anti-corrosion properties are observed, is 7 carbon atoms. In this case, the minimum concentration of inhibition is 1 g/L. However, high degrees of protection of 65–85% are achieved when 3-heptyl-5-amino-1H-1,2,4-triazole is added to the hydrochloric acid solution at a concentration of at least 2 g/l.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Specifics of the formation of regular opal structures from spherical silica particles in various colloidal solutions

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Abstract

Photonic crystal opal matrices are bulk spatial periodic structures based on amorphous spherical silica particles whose size is compatible with the wavelengths of the visible light spectrum. These structures are very promising and can be used as matrices for new functional materials.

The article studies the formation of a regular opal structure on dielectric substrates by means of the evaporation of droplets and layers of colloidal solutions based on water and ethanol with various concentrations of spherical SiO₂ particles with a diameter of about 250 nm synthesised using the Stöber method.

Keywords: Opal structures, Evaporation-induced self-assembly method, Tetraethoxysilane, Sedimentation, Lyophilic medium, Iridescence

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1. Introduction

An opal matrix is a face-centred cubic lattice (FCC) formed by densely packed spheres of amorphous silicon dioxide (SiO_2) with similar diameters and the size of 0.1–1.0 μm . The space between the SiO_2 spheres is occupied by a void sublattice, which can be filled with other materials. Such structures serve as a basis for photonic crystals with the electromagnetic band gap blocking the waves with wavelengths compatible with the parameters of the periodic structure. By filling the voids between the structural elements of an opal matrix with various substances, we can create periodic nanocomposites of optically active materials to be used in optoelectronics, semiconductor engineering, opal-semiconductor based photonic media, magnetic recording systems, etc. [1–11].

In order to obtain regular opal structures, first we need to synthesise spherical particles of silica, whose size should not vary by more than a few percent. In this regard, the Stöber method is considered to be the most appropriate [12]. This method is based on the hydrolysis of tetraethoxysilane (TEOS) in an aqueous-alcoholic medium in the presence of ammonium hydroxide serving as a catalyst. This method was first described by *G. Kolbe* in 1956 [13] and then elaborated by *W. Stober* et al. The method allows for the synthesis of SiO_2 particles of almost ideal spherical shape in a wide range of diameters: from tens of nanometres to several micrometres. The size and sphericity of the particles depend on the purity and concentrations of the reagents, the temperature, and the composition of the colloidal solution, which is most commonly based on ethyl alcohol. The next important and equally difficult task is to obtain ordered 2D and 3D microstructures with linear dimensions of up to several millimetres. The most popular method for the creation of such structures is the method of natural sedimentation in alcoholic colloidal solutions. In this case the particles deposit on a flat horizontal substrate at a rate determined according to Stokes' law [1]. It takes several weeks to obtain opal layers of several millimetres.

The evaporation-induced self-assembly method proved to be quite effective for alcoholic media [8, 9]. This method involves the deposition of spherical silica particles on an inclined or vertical

substrate during the evaporation of the alcoholic suspension. Although opal films obtained during the formation of a regular structure in alcoholic media are more perfect than bulk samples, the number of cracks and dislocations in the obtained samples is still very large. In fact, there are hardly any 1 mm^2 regions with no dislocations. The film obtained using this method demonstrated a mesh of horizontal and vertical bands [10], which the authors explained by the fluctuations in the temperature and the concentration of particles in the solutions being evaporated under conditions which are difficult to control.

D. V. Kalinin et al. developed a promising technique for obtaining regular structures from spherical submicron silica particles [1, 5]. The technique involves packing the particles in a droplet or a 0.1–0.5 mm thin layer in a lyophilic medium based on dimethyl sulfoxide. To increase the mobility of the silica spheres, a plasticiser (namely isopropanol) is added to the quite viscous suspension. During its formation in the suspension, the structure demonstrates plasticity, which significantly enhances the regularity of packing and reduces the chance of microcracks resulting from the shrinkage of the film during drying. This method can be used to obtain 3D opal structures with the width of tens of layers of SiO_2 particles over an area of 1–2 cm^2 .

The existing literature does not provide enough comparative data on the formation of regular opal structures by submicron silica particles from various suspensions depending on the concentrations of the solutions. Therefore, the purpose of our study was to compare the suspensions most commonly used by other researchers as the media for obtaining regular opal structures based on ethyl alcohol and water. In our study, we investigated the possibility of using a 50% aqueous solution of ethanol as a solvent, because there is very little information about it in the literature. To maintain the accuracy of our experiments, we used silica particles synthesised by means of the Stöber method in the laboratory.

2. Experimental

The starting materials for the synthesis of spherical silica particles were: 95% ethanol by Alfa-him, 25% ammonia (P.A.), tetraethoxysilane by

various Russian and international manufacturers (P.A. and E.P.), and distilled water.

For the distillation of TEOS, a special unit was assembled consisting of a three-neck flask and a refrigerator made of heat-resistant glass. To enhance the accuracy of the fractionation of the reagents, the flask was placed on a specially designed electrical furnace regulated by means of a RIF-101 based precision temperature controller. To control the temperature, we used a platinum-rhodium thermocouple placed at the inlet of the refrigerator. Each TEOS composition was divided into 4–5 fractions in the range of 165–173 °C. Each fraction was used separately in the experiments. The best results were obtained when the most volatile fraction of TEOS was used.

To prevent the formation of moisture during the distillation process, we passed argon through the system and used a tube with calcined calcium chloride. The silica particles were synthesised in a 50–200 ml glassware by mixing the components at 20 °C. The solution was stirred on a MM-5 magnetic stirrer or a Meos Praha T2 vibrating plate for 1–2 hours, after which the particles were formed within an interval of 8–24 hours without any mechanical influences. The synthesised spherical silica particles were separated from the alcoholic solution in a centrifuge (Elecon R10-01 or TsUM-1) with the rotation speed of 1500–2000 rpm, which was reconfigured for 50 ml test tubes. The obtained precipitates containing the minimum amount of moisture were put into containers with: a) ethyl alcohol (C_2H_5OH), b) 1:1 aqueous-alcoholic solution, and c) distilled water - in order to obtain suspensions with the concentration of silica particles from 15 to 0.5 wt%.

The layers and droplets of the suspensions with various concentrations of silica particles were put on a 24×24×0.17 mm glass plate (microscope slides) using a glass rod, a pipette, or a brush. The relative change in the weight of the substrate before and after the application of the suspension was registered by means of VLA-200 analytical scales with an accuracy of 0.2 mg. We also registered the time of evaporation of the colloidal solution and the area of drop spreading. This helped us to calculate the thickness of the solution layer and the film of the silica spheres after drying out the suspension. Either visually or via an MBS-2 microscope, we observed the

presence of an interference pattern from the film (iridescence), when the SiO_2 spheres were regularly packed at a reflection angle of about $\sim 5^\circ$. We also determined the crack density of the film on a BIOLAM transmission microscope at 50× and 200× magnifications. The surface structure of the films was studied using a Carl Zeiss EVO LS 10 electron microscope.

3. Results and discussion

In our study, we determined, as did the authors of [7, 11], that the reproducibility of the experiments on the synthesis of monodisperse silica particles heavily depends on the quality of TEOS. The use of TEOS of different manufacturers under identical conditions resulted in silica particles of different shape and size, which could hardly be used to obtain ordered regular structures. The diameters of the silica particles differed by 2–4 times (Fig. 1).

Only the use of TEOS purified from high-temperature fractions resulted in reproducible monodisperse silica particles. In our further analysis, we used 250 ± 10 nm particles. Table 1 presents the characteristics of the films of spherical silica particles formed from an alcoholic suspension depending on the concentration of SiO_2 . We determined that the height of the droplets decreases with smaller concentrations of the suspension. The average thickness of the silica films also decreases significantly: it is about 5 μm for the 10% suspension, and about 1 μm for the

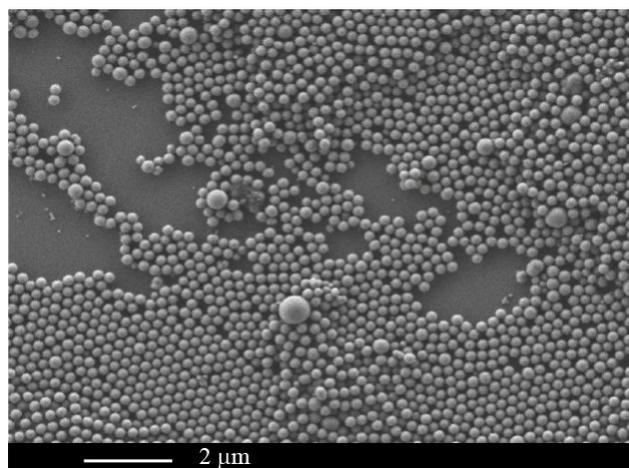


Fig. 1. SiO_2 spheres of various diameters obtained when using the commercial reagent of TEOS (evaporation-induced self-assembly in a 10% alcoholic suspension)

2.5% suspension. Since for all the compositions with the concentration of the suspension of over 1% we clearly observed iridescence (both visually and via a microscope with the reflection angle of about $\sim 5^\circ$), we can conclude that submicron SiO_2 particles are regularly packed in dried droplets of alcoholic suspension. The defects include radial beam-like cracks in the direction from the periphery to the centre. The results of our study are consistent with the results obtained in [11]. The latter study modelled the process of particles packing using various methods and demonstrated the identity of the formation of the SiO_2 film from alcoholic suspensions by means of the evaporation-induced self-assembly method and the droplet evaporation method.

Our study demonstrated the difference between the formation of regular opal structures in a layer or in a droplet of an alcoholic suspension depending on the concentration of silica particles. The structure of the iridescent layer with the silica particles the concentration in the suspension of over 10 % is not uniform, as shown in [6]. The periphery of the film is significantly thinner, which indicates the maximum iridescence, which then decreases towards the centre (Fig. 2).

Droplets of the alcoholic suspension with the concentration of SiO_2 particles below 10 wt% demonstrated larger drop spreading with the thickness being significantly more uniform. The thickening of the outer ring in the droplet's periphery is almost imperceptible,

Table 1. Characteristics of the films of spherical silica particles formed from the alcoholic suspension depending on the concentration of SiO_2

Solvent $\text{C}_2\text{H}_5\text{OH}$	Silica concentration, wt%									
	15	10	5	3	1	0.5				
Droplet weight, mg	6.7	11	5.5	8.8	4.4	8	4	1	2.6	5
Droplet area, cm^2	0.8	2.5	0.8	4.0	2.2	3.8	2.3	1.2	2.1	3
Suspension density, g/cm^3	0.9	0.85	0.85	0.82	0.82	0.8	0.8	0.79	0.79	0.79
Droplet height, μm	93	50	80	26	24	26	22	10	16	12
Height of the SiO_2 nanosphere layer, μm		5.6		1.3		1.2				
Film iridescence	+	+	+	+	+	+	+	слаб.	слаб.	? -

Table 2. Characteristics of the films of spherical silica particles formed from the aqueous suspension depending on the concentration of SiO_2

Solvent H_2O	Silica concentration, wt%					
	15	10	5	2.5	1	0.5
Droplet weight, mg	15.8	16.3	15.8	12.8	15.8	15.0
Droplet area, cm^2	0.5	0.7	0.7	0.8	1.1	0.6
Suspension density, g/cm^3	1.06	1.04	1.02	1.01	1.0	1.0
Droplet height, μm	300	224	220	170	145	135
Film iridescence	+	+	+	слаб.	-	-

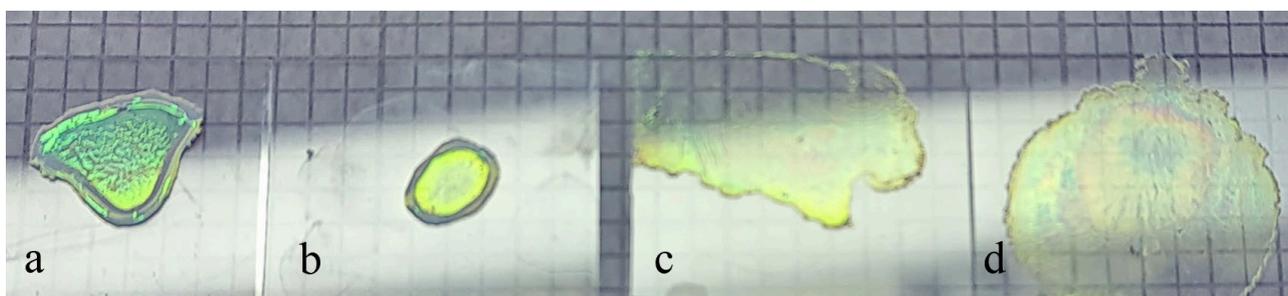
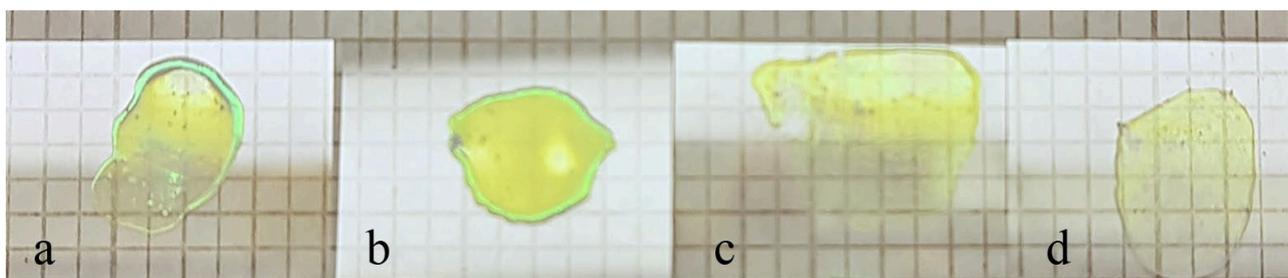


Fig. 2. Films of spherical SiO_2 particles obtained by the evaporation of the droplets of the alcoholic suspension of SiO_2 with various concentrations of submicron silica spheres (see Table 1): a – SiO_2 concentration: 15 %; b – SiO_2 concentration: 10 %; c – SiO_2 concentration: 5 %; d – SiO_2 concentration: 3 %

Таблица 3. Характеристики пленок из сферических частиц кремнезема, сформированных из водно-спиртовой суспензии, в зависимости от концентрации SiO_2

Solvent $\text{C}_2\text{H}_5\text{OH}(50\%)+\text{H}_2\text{O}(50\%)$	Silica concentration, wt%								
	15	10		5		3	2.5	1	0.5
Droplet weight, mg	15.8	16.3	14.1	15.8	16.3	13.8	14.8	15.6	15
Droplet area, cm^2	0.55	0.7	0.7	0.7	0.9	0.8	0.85	1.0	0.9
Suspension density, g/cm^3	0.96	0.94	0.94	0.92	0.92	0.91	0.9	0.9	0.9
Droplet height, μm	300	250	210	240	195	190	190	170	185
Height of the SiO_2 nanosphere layer, μm			1.2		1.1		0.2		
Film iridescence	+	+	+	+	+	+	+	слаб	?

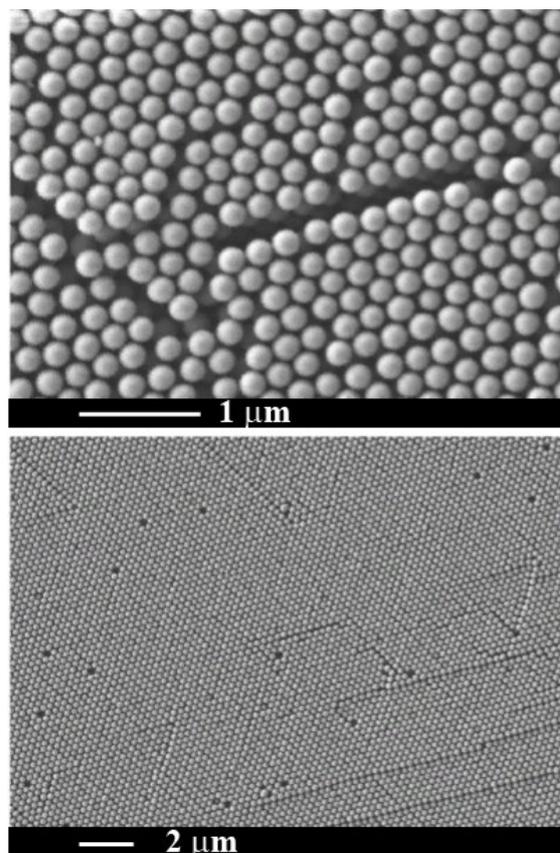
**Fig. 3.** Films of spherical SiO_2 particles obtained by the evaporation of the droplets of the 50 % $\text{C}_2\text{H}_5\text{OH}$ – 50 % H_2O suspension with various concentrations of submicron silica spheres: a – SiO_2 concentration: 10 %; b – SiO_2 concentration: 5 %; c – SiO_2 concentration: 2.5 %; d – SiO_2 concentration: 1 %

and the homogeneity of the films increases over the spreading area. Table 2 presents the characteristics of the films of spherical silica particles formed from an aqueous suspension depending on the concentration of SiO_2 .

The study demonstrated that it takes 4–6 hours for a droplet to evaporate, and the homogeneity of the films is higher than that of the films obtained from alcoholic compositions with larger concentrations (> 10 wt%). The iridescence, which is less bright than the iridescence in alcoholic suspensions, is only observed in thick suspensions with concentrations of SiO_2 of over 5 %.

Using aqueous-alcoholic suspensions (with a 50% concentration of $\text{C}_2\text{H}_5\text{OH}$), we obtained films similar to those formed during the evaporation of the alcoholic suspension (Fig. 3).

Table 3 presents the characteristics of the films of spherical silica particles formed from an aqueous-alcoholic suspension depending on the concentration of SiO_2 . The average evaporation time was 25–30 minutes, which is several times more than the time required for the evaporation of alcoholic suspensions, but is an order of magnitude less than the time required for the evaporation of an aqueous suspension. The thickness of the iridescent films with a minimum concentration of SiO_2 is lower than the thickness

**Fig. 4.** Regular structure of the layer of 250 ± 10 nm silica spheres obtained during the evaporation of a 10% aqueous-alcoholic (50%) suspension on a horizontal substrate

of films obtained from alcoholic suspensions, and the spread of the droplets of the suspension with concentrations of 2.5 and 1 % is more uniform (Fig. 3).

Fig. 4 shows the image of a film consisting of silica spheres obtained during the evaporation of an aqueous-alcoholic suspension layer on a horizontal glass substrate.

4. Conclusions

The films consisting of submicron silica spheres obtained by means of evaporation of colloidal aqueous, alcoholic, and aqueous-alcoholic (50%) solutions of various concentrations are characterised by concentric and radial banding. [10] suggests that this (as well as a series of horizontal and vertical bands appearing when using the evaporation-induced self-assembly method) is caused by a single reason: then change in the concentration of silica particles in the suspension. Comparing the surface of the films obtained under identical conditions by means of the evaporation-induced self-assembly method on an inclined substrate and the droplet evaporation of the suspension on a horizontal substrate, we can see that in the latter case there are much fewer bands or other defects. We suppose that using aqueous-alcoholic suspensions of spherical silica particles in order to obtain opal layers on a horizontal substrate is a promising method that can be used to enhance the regularity and the quality of films.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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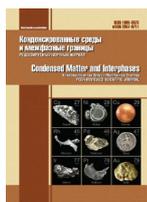
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Original articles

Research article

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Effect of the morphology and composition of trimetallic PtCuAu/C catalysts on the activity and stability of the methanol oxidation reaction

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Abstract

A study on the influence of the method for obtaining trimetallic PtCuAu/C catalysts on their activity in the oxidation of methanol has been carried out.

The structural characteristics of the obtained trimetallic catalysts have been studied by X-ray diffraction and transmission electron microscopy. The nanoparticles of the material obtained by the galvanic synthesis method had a size twice as large (~ 6 nm) than the nanoparticles of the material obtained by the co-deposition of metal precursors. According to the results from the accelerated stress testing of catalysts, it was found that the material obtained by the galvanic method of substitution of copper atoms with gold had a higher residual activity in the oxidation of methanol than the commercial Pt/C analogue.

This study shows the potential of obtaining and using multicomponent platinum-containing nanoparticles deposited on a carbon carrier as effective catalysts for use in methanol fuel cells.

Keywords: methanol fuel cells, catalysis, trimetallic catalysts, galvanic replacement

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1. Introduction

The study of the methanol oxidation reaction (MOR) is of great practical importance for the commercialization of direct methanol fuel cells (DMFC). Despite numerous studies in the field of DMFC, their widespread use is hindered by several factors: the slow methanol oxidation reaction, the poisoning of the catalytic layer by intermediate oxidation products, and the high cost of the catalysts themselves containing noble metals. These problems are relevant for both an anode catalyst of methanol oxidation [1] and a cathode oxygen reduction catalyst. At the same time, another important problem of cathode catalysts is the crossover of methanol into the cathode space [2]. Pt nanoparticles deposited on a finely dispersed carbon carrier are one of the most common catalysts; however, the rather high cost of this metal, combined with its low tolerance to intermediate oxidation products, remains the main problem preventing the widespread use of Pt as an anode and/or cathode in DMFC.

The mechanism of methanol oxidation in an acidic medium can be represented as a sequence of several stages [3].

1. Electro adsorption of methanol molecules on a Pt electrode followed by the formation of intermediate products such as -CHO, -COOH, -CO, etc.

2. The formation of Pt-OH on the catalyst surface because of water decomposition followed by the participation of hydroxyl groups in the oxidation of intermediate products.

3. Removal of formed CO₂.

Among the intermediate products of methanol oxidation, CO is the most harmful. CO molecules are chemisorbed on the surface of the Pt catalyst, which leads to blocking of active surface areas and reduces the activity of the catalyst. One of the possible ways to solve this problem is to change the electronic structure of the metal by doping the Pt catalyst with various noble (Pd, Ru, Au) and some transitional *d*-metals (Cu, Ni, Fe, Co, etc.), which contribute to the removal of CO from the surface, facilitating its oxidation to CO₂ [4–6]. PtRu alloys are well-known catalysts with a lower sensitivity to CO compared to pure Pt [7–8]. However, due to the relatively high cost of the Ru doping component, the most relevant

are catalysts doped with transition *d*-metals, such as PtNi [9], PtCu [10], PtCo [10–11].

Thus, the authors of [10] showed that the obtained PtCo/C and PtCu/C catalysts demonstrated higher activity in the oxidation reaction, compared to PtRu/C. At the same time, the authors of the study noted that in the process of standardization (activation) of the surface, the doping component can be dissolved from the catalyst surface, and copper ions passing into the electrolyte can distort the results of experimental studies.

It was shown in [4] that the doping of platinum with copper atoms increased the catalytic activity in the reactions of methanol oxidation and oxygen reduction by 5 and 2 times, respectively, compared to Pt/C. The positive influence of the doping component on the activity of Pt catalysts can be explained by two effects. The first is a bifunctional mechanism of catalysis, in which the high rate of methanol oxidation is determined by the easier adsorption of OH groups on the surface of the doping component, which in turn led to the faster oxidation of chemisorbed CO molecules on neighbouring areas of the Pt surface [12]. The second is the electronic effect associated with the electronic interaction of the atoms of the doping component with Pt atoms. This effect leads to a decrease in the binding energy of adsorbed particles with the catalyst surface. As we mentioned earlier, the main disadvantage of bimetallic PtCu/C catalysts is the possible selective dissolution of the doping component during their functioning [10]. Over the past two years, the preparation and modification of bimetallic PtCu/C catalysts has been an urgent task for researchers around the world. In addition, more and more groups are focusing on the preparation and study of trimetallic nanoparticles (NP) containing Cu: PtCuNi [13], PtCuAu [14], PtPdCo [15], PtCuCo [16], etc. Earlier, it was shown [18–19] that the substitution of Cu atoms by Au atoms on the surface of a platinum-containing catalyst promotes not only an increase in the activity in MOR and the oxygen reduction reaction (ORR), but also a decrease in the selective dissolution of the doping component in the electrochemical cell. However, the question of the relationship between the structure, activity, and stability of trimetallic catalysts remains unclear.

The purpose of this study was the investigation of the relationship between the structure, activity in MOR and the stability of trimetallic PtCuAu/C catalysts obtained by various methods.

2. Experimental

Synthesis of trimetallic PtCuAu/C catalysts was carried out by two different methods. In the first case, the preparation of the catalyst was performed in two stages. At the first stage, a PtCu/C material with a solid solution structure and theoretical Pt:Cu ratio of 1:1 was obtained [18–19]. For this, the required amount of precursors of $\text{H}_2\text{PtCl}_6 \cdot 6\text{H}_2\text{O}$ (Aurat, Russia, mass fraction of patina – 37.6%) and $\text{CuSO}_4 \cdot 5\text{H}_2\text{O}$ (analytical grade) were added to the water–ethylene glycol suspension of the Vulcan-XC72 carbon carrier in such a way that the mass fractions of metals will be 30 wt% Pt and 10 wt% Cu. Then, with constant stirring, an excess of 0.5 M NaBH_4 solution was added for joint reduction of Pt and Cu. This synthesis method is described in more detail in [20–21]. Further, after filtration and drying, a part of the PtCu/C catalyst obtained in the first stage was used in the second stage of synthesis. For this, a water–ethylene glycol solution was added to a weighed portion of the PtCu/C material, the resulting suspension was dispersed by ultrasound, and the calculated amount of the gold precursor $\text{HAuCl}_4 \cdot 4\text{H}_2\text{O}$ (Aurat, Russia, mass fraction of gold 49.04%) was added with constant stirring. The amount of gold precursor was calculated in such a way that at full reduction, the gold content in the resulting material was 5 at% of the metal phase. In this case, after the addition of the gold precursor, galvanic substitution of Cu atoms by Au atoms from the catalyst surface occurred. After keeping the suspension under constant stirring for 30 min the resulting suspension was filtered, washed several times with water and isopropyl alcohol, and then dried over P_2O_5 . The resulting catalyst was labelled as PtCuAu/C_G.

Another method for the synthesis of the PtCuAu/C catalyst is based on the reduction of three metal with a NaBH_4 solution in water–ethylene glycol suspension [18–19]. In this case, the theoretical calculation of the mass fractions of metals corresponded to the PtCuAu/C_G material. This catalyst was labelled as PtCuAu/C_A.

The mass fraction of metals was determined by thermogravimetry based on the weight of the unburned residue. For this, the test sample was placed in a pre-calcined crucible with a constant weight and heat treated in a muffle furnace in an air atmosphere at 800 °C for 40 min. It should be considered that the unburned residue consists of Pt, Au, and CuO. The metal ratios of Pt:Cu and Pt:Cu:Au in the obtained catalysts was determined by X-ray fluorescence analysis (XRF) using a RFS-001 spectrometer (Research Institute of Physics, Southern Federal University, Russia). The conditions of the analysis were following X-ray tube voltage, 50 kV; current, 150 μA ; anode material, molybdenum; spectrum acquisition time, 300 s. Registration and processing of X-ray fluorescence spectra was carried out using the UniverS software (Southern Federal University, Russia) [22].

The phase composition of the materials and the average crystallite size were determined by powder X-ray diffraction at room temperature using ARL X'TRA diffractometer ($\text{CuK}\alpha$), within an angle range of 2θ from 15 to 55 degrees, with a step of 0.02 degrees and a registration rate of 2 degrees per minute. The average crystallite size was determined using the Scherrer formula [23]:

$$D = \frac{K\lambda}{\text{FWHM} \cdot \cos\theta},$$

where $K = 0.98$ is the Scherrer constant, λ is the wavelength of monochromatic radiation in Å, FWHM is the full width of the peak at half maximum (in radians), D is the average crystallite size, nm; θ is the reflection angle in radians.

The study by transmission electron microscopy (TEM) was performed using a microscope JEM-2100 (JEOL). Samples of materials weighing 0.5 mg were placed in 1 ml of heptane, the resulting suspension was homogenized in ultrasound for 2–3 min and applied to a nickel mesh coated with a thin layer of amorphous carbon. The materials were studied by transmission electron microscopy (TEM), high-resolution transmission electron microscopy (HRTEM), and scanning transmission electron microscopy (STEM) using an energy dispersive X-ray (EDX) microanalysis of the elemental composition. The electrochemical behaviour of the catalysts was studied at room temperature on a rotating disk electrode in a three-electrode cell by cyclic voltammetry using

a VersaSTAT 3 potentiostat. A saturated silver chloride electrode with a potential of 0.208 V was used as a reference electrode. Later in the study, all potentials were recalculated relative to the potential of a reversible hydrogen electrode. For the application of the studied catalyst to the working electrode, catalytic ink was prepared according to the procedure described in [24]. For the preparation, a catalyst sample weighing 0.0060 g was placed in a mixture of 900 μL of isopropanol and 100 μL of 0.5% Nafion alcohol solution (DuPont). The resulting suspension was stirred on a magnetic stirrer for 10 min, and then dispersed by ultrasound for the same time, while monitoring the temperature of the catalytic ink, which did not rise above 25 $^{\circ}\text{C}$ [25–26]. The mixing procedure was repeated, and then a 6 μL aliquot of ink was applied to the end of the disk electrode, dried at 700 rpm at room temperature, while the surface of the disk electrode was preliminarily polished and degreased according to the manufacturer's recommendations.

The surface of the catalytic layer was standardized in 0.1 M HClO_4 saturated with Ar for 30 min in the potential range of 0.04–1.20 V with a potential sweep rate of 200 mV/s. After standardization, the electrolyte was replaced with freshly prepared 0.1 M HClO_4 (Sigma Aldrich) to exclude the influence of dissolved copper ions on the values of the measured characteristics. After that, the cell was again saturated with argon and the electrochemical surface area (ESA) was measured with a potential sweep rate of 20 mV/s. ESA values were calculated based on the electrochemical adsorption and desorption of hydrogen [27] using the formula:

$$\text{ESA} = \frac{Q_{\text{H}}}{R \cdot m},$$

where $Q_{\text{H}} = \frac{(Q_{\text{ad}} + Q_{\text{des}})}{2}$ is the average amount of electricity used for the electrochemical adsorption and desorption of hydrogen; R is the amount of electricity used for the adsorption/desorption of a monolayer of atomic hydrogen, which is 210 $\mu\text{C}/\text{cm}^2$; m is the weight of platinum on the electrode (the weight of platinum was calculated based on the weight of the catalytic layer deposited on the working electrode, taking into account the mass fraction of metals). This approach for

the calculation of the ESA value is successfully used not only for Pt/C, but also for bimetallic catalysts [28]. In addition, for bimetallic catalysts, a good correlation between the ESA values measured independently by the adsorption/desorption of an atomic hydrogen monolayer and by the estimation of the area based on the oxidation of a chemisorbed CO monolayer was shown [18–19].

The activity of catalysts in MOR was evaluated in 0.1 M HClO_4 with the addition of 0.5 M CH_3OH with a potential sweep rate of 20 mV/s. At the same time, for the estimation of the activity in MOR, the generally accepted characteristics of cyclic voltammograms [29], are: $Q_{\text{CH}_3\text{OH}}$ is the amount of electricity used for the oxidation of methanol in the forward potential sweep; I_{Max} is the maximum current density in the forward potential sweep. For the assessment of the tolerance of catalysts to intermediate products of methanol oxidation, chronoamperograms were recorded under similar conditions at a potential of 0.87 for 30 min. The potential of 0.87 V corresponds to the potential of the direct peak of methanol oxidation. An increase in the polarizing potential is impractical due to the formation of passivating oxide compounds on the surface of the electroactive catalyst particles, which, along with the adsorption of the oxidation product, carbon monoxide, can be the cause of the observed current drop in the chronoamperograms. For the assessment of the tolerance, the following

coefficients were calculated: $K = \frac{I_{\text{initial}}}{I_{\text{final}}} \cdot 100\%$ is

the degree of residual current after 30 min, where I_{initial} and I_{final} are the initial and final current densities on the chronoamperogram, respectively,

and $\delta = \frac{100}{I_0} \cdot (dI/dt)_{t>500}$ is the coefficient of

long-term CO poisoning [30], taking into account the slope of the curve, where I_0 is the current density at the beginning of polarization inversely extrapolated from the linear decay of the current, $(dI/dt)_{t>500}$ is the slope of the linear attenuation of the current.

For the assessment of the stability of the obtained catalysts, we chose the mode of multiple cycling (1000 cycles) in the potential range of 0.4–1.6 V with a potential sweep rate of 100 mV/s [31]. Upon completion of stress testing in

the electrochemical cell, 0.5 M CH₃OH was added to the electrolyte and cyclic voltammograms and chronoamperograms were reordered. The stability of the catalysts in MOR was evaluated by comparing the parameters characterizing the activity and tolerance of materials. All potentials in this study are shown relative to a reversible hydrogen electrode (RHE).

3. Results and discussion

2.1. Study of the composition and structure of PtCuAu/C materials

The mass fraction of metals in the obtained catalysts turned out to be close to the calculated value (40 wt%) and amounted to 34–37 wt%. Table 1). The wide reflection maximum within an angle range of 2θ about 41° on the X-ray diffraction pattern of the PtCu/C catalyst (Fig. 1a) was shifted to the region of large values of angles

2θ (Fig. 1), as compared to the platinum phase ($2\theta = 39.8^\circ$), which was due to the formation of a solid PtCu solution. With the subsequent galvanic substitution of part of the copper for gold, a smaller shift of the Pt (111) maximum was observed in the X-ray diffraction pattern, compared to the PtCu/C material, which may be due to the formation of a PtCuAu solid solution, since the lattice parameter of gold (3.83 Å) is larger than that of platinum and copper. The similar position of the maximum was demonstrated for the PtCuAu/C_A material obtained by the co-reduction of precursors. For this material, additional weak peaks of the gold phase were also observed in the region of angles 2θ around 38° and 44° , corresponding to Au (111) and Au (200). These maxima indicate the presence of a separate Au phase in the PtCuAu/C_A material and, accordingly, the incomplete incorporation of gold into the composition of the

Table 1. Composition and structural characteristics of the obtained catalysts and commercial Pt/C material

Materials	Composition (XRF)	M-Loading (M), ω %	Average Size of Crystallites D_{Av} , nm (XRD)	Crystal lattice parameter, Å	Average Size of Nanoparticles D_{Av} (NPs), nm (TEM)
PtCu/C	Pt ₁ Cu ₁	37±1	1.9 ± 0.3	3.79	–
PtCuAu/C_G	Pt ₁ Cu _{0.51} Au _{0.10}	34±1	2.0 ± 0.3	3.82	6.5
PtCuAu/C_A	Pt ₁ Cu _{0.49} Au _{0.10}	36±1	2.6 ± 0.3	3.83	2.9
JM20	Pt	40±1	2.0 ± 0.2	3.94	3.6*

* TEM for Pt/C from literature [37]

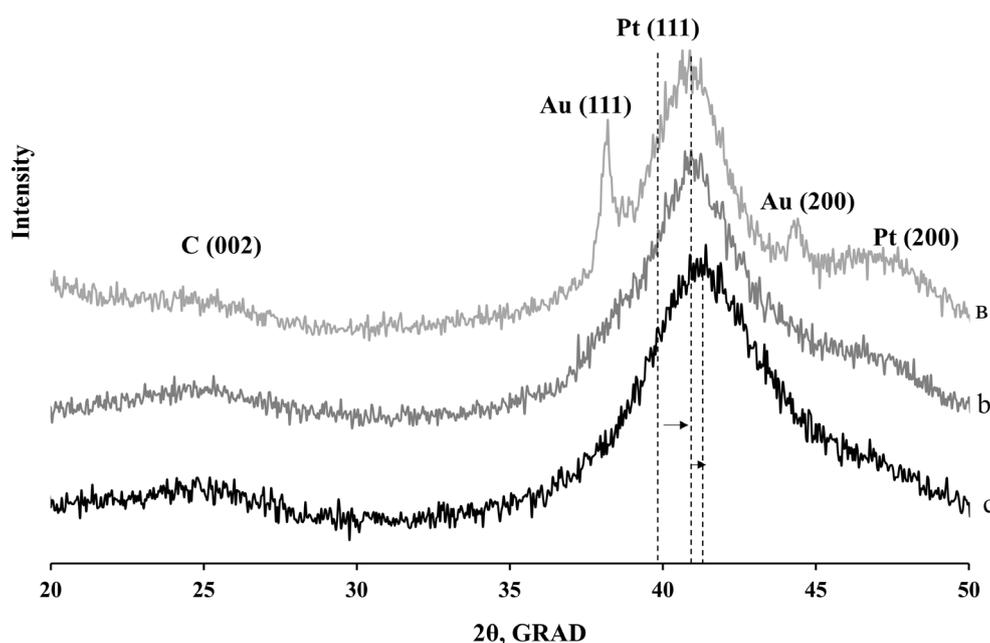


Fig. 1. X-ray diffraction patterns of catalysts: (a) PtCu/C, (b) PtCuAu/C_G, and (c) PtCuAu/C_A

PtCu solid solution. It should be noted that peaks corresponding to the phases of pure copper and its oxides were not revealed in the diffraction patterns of the studied catalysts. Nevertheless, the presence of amorphous structures cannot be ruled out [32]. The average crystallite size for the obtained catalysts, determined using the Scherrer equation, was in the range of 1.9–2.6 nm.

According to the TEM results (Fig. 2), the obtained PtCuAu/C_G and PtCuAu/C_A catalysts were characterized by a uniform distribution of metal NP over the surface of the carbon carrier. For the determination of the average size and size distribution of metal NP, TEM photographs were processed; the size of at least 400 particles was determined for each material. It was found that the average nanoparticle size for the PtCuAu/C_G material was 6.5 nm (Table 1), which is much higher than for the PtCuAu/C_A catalyst, the average particle size of which was 2.7 nm. The PtCuAu/C_A sample was characterized by a narrow size distribution of nanoparticles, while the PtCuAu/C_G sample was characterized by a

wide size distribution of NP, from 2 to 12 nm (see histograms in Fig. 2). It should be noted that the average size of NP according to the TEM data for the studied catalysts turned out to be larger than the average size of crystallites calculated using the Scherrer equation (Table 1) [33], which indicates the polycrystalline nature of the particles. Probably, the larger size of NP for the PtCuAu_G catalyst is associated with the larger size of nanoparticles of the initial PtCu/C catalyst, which is due to the peculiarities of the boron hydride synthesis technique. Thus, it was shown in [34] that the PtCu/C material obtained under similar conditions has an average NP size of about 5.5 nm. Probably, the galvanic substitution of gold leads only to an insignificant enlargement of PtCu NP.

The actual composition of the obtained materials turned out to be close to that calculated based on the loading of precursors (Table 1). For the EDX analysis of the elemental composition of individual areas of the surface of PtCuAu/C materials, elemental mapping was used. According to EDX data, the most metal nanoparticles

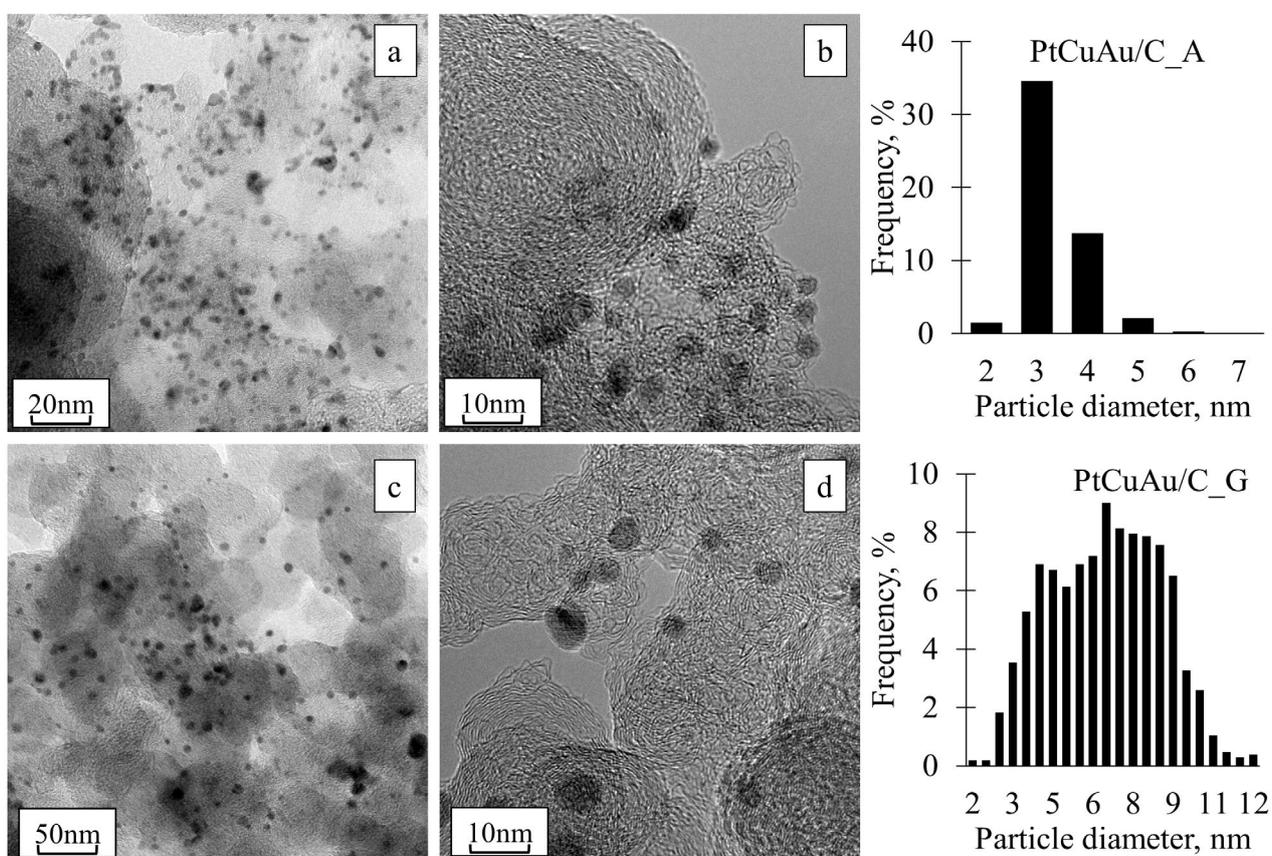


Fig. 2. TEM photographs and histograms of the nanoparticle size distribution obtained on their basis, for samples a,b – PtCuAu/C_A; (c, d) PtCuAu/C_G. 1000 particles of each material were selected for analysis

contained Pt, Cu, and Au atoms. The intensity of the signal from gold atoms was significantly lower, which was due to its lower atomic fraction in the material compared to other metals. For a more detailed analysis, the stencil grid, consisting of ellipses applied to the localizations of Pt (red) and gold (yellow), was transferred to photographs showing the localizations of other metals (Fig. 3). It can be seen from the Figure that all three components were not always included in the composition of the same nanoparticles. For example, in the PtCuAu/C_G material, in addition to trimetallic PtCuAu nanoparticles, bimetallic CuAu nanoparticles were present, since for the yellow ellipses a mismatch in the localization of gold and platinum atoms was revealed. For the PtCuAu/C_A material, the presence of CuAu nanoparticles was not typical (Fig. 3b, Fig. 3c).

2.2. Study of activity and stability of PtCuAu/C catalysts

Electrochemical standardization of the electrodes was carried out before measuring the

activity of catalysts by cyclic voltammetry [18–21]. At the stage of electrochemical standardization of the obtained PtCuAu/C catalysts, no peaks of copper dissolution typical for the dissolution of copper from its own phase or the solid solution phase [35–36] were found in cyclic voltammograms in the potential ranges of 0.25–0.45 V and 0.70–0.80 V relative to RHE. Probably, this was due to the absence of the copper phase on the surface of the nanoparticles or on the carbon carrier and indicated a rather complete incorporation of copper into the solid solution. On the other hand, the absence of copper dissolution peaks in cyclic voltammograms does not disprove the possibility of the presence of X-ray amorphous copper oxide.

After standardization of the surface of the materials, cyclic voltammograms were recorded (Fig. 4), the hydrogen region of which was used to determine the ESA value of the catalyst based on the electrochemical adsorption/desorption of hydrogen atoms. The ESA values for PtCu/C and

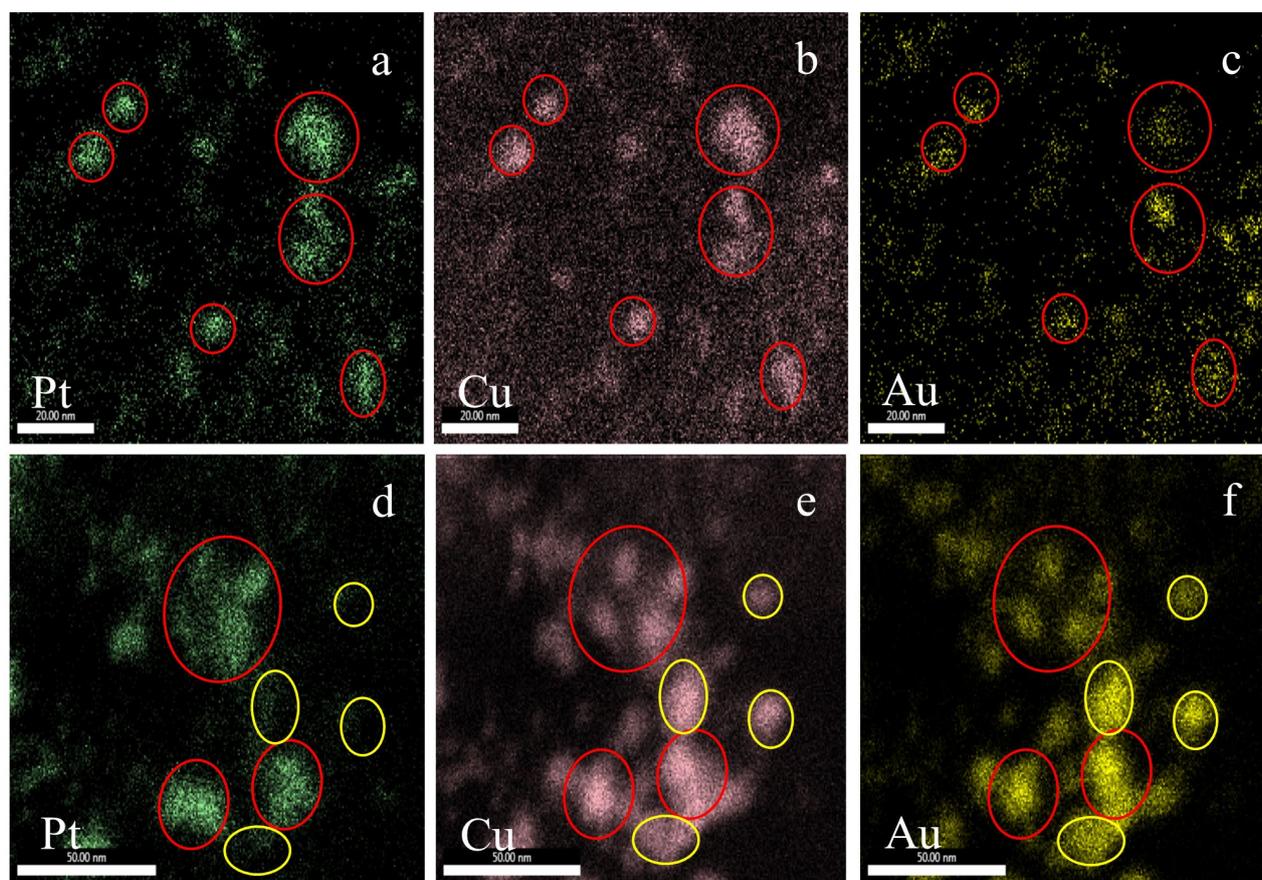


Fig. 3. EDX mapping of a,b,c - PtCuAu/C_A and d,e,f - PtCuAu/C_G catalysts

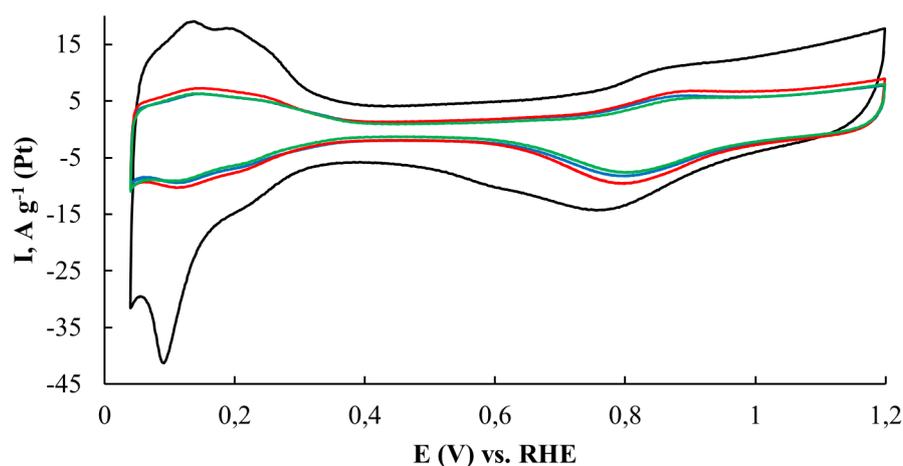


Fig. 4. Cyclic voltammograms of catalysts. Electrolyte is 0.1 M HClO₄, Ar atmosphere. The potential sweep rate is 20 mV s⁻¹

Table 2. Values of electrochemically active surface and catalyst activity in methanol

Materials	$Q_{\text{CH}_3\text{OH}}, \text{C/g(Pt)}$ 10^5	ESA, $\text{m}^2/\text{g(Pt)}$	$I_{\text{max}}, \text{A/g(Pt)}$	I chronoamperograms, A/g(Pt)		Long-term poisoning rate CO δ , %/s
				I_{initial}	I_{final}	
PtCu/C	43	28 ± 3	380	220	48	0.0435
PtCuAu/C_G	59	32 ± 3	572	395	77	0.0481
PtCuAu/C_A	52	31 ± 3	516	331	75	0.0495
JM20	42	77 ± 8	350	320	127	0.0327

PtCuAu/C materials were noticeably inferior to the ESA value calculated for the commercial Pt/C analogue (Table 2). In the case of the PtCuAu/C_G sample, the lower ESA value can be explained by the significantly larger size and wide size distribution of nanoparticles compared to the commercial Pt/C material. At the same time, the particle size of the PtCuAu/C_A material according to TEM slightly differs from that for

the Pt/C catalyst. Possibly, the lower ESA value was due to the substitution of a proportion of the platinum atoms on the surface of the catalyst nanoparticles for gold atoms, which are not characterized by reversible adsorption/desorption of hydrogen, as well as to a higher degree of NP agglomeration due to the used synthesis technique [34]. It should be noted that the ESA value of the PtCuAu/C_G material differs slightly

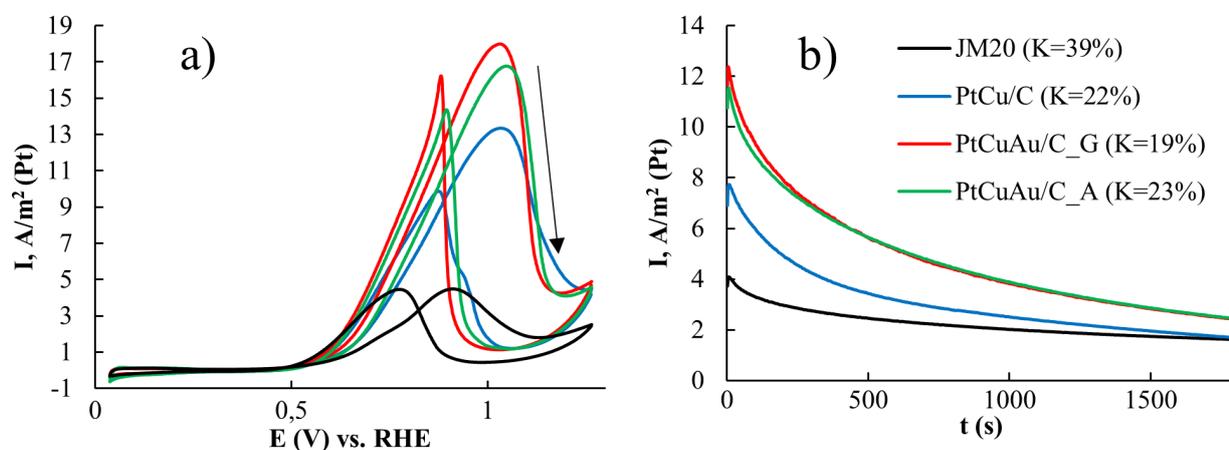


Fig. 5. (a)-cyclic voltammograms and (b) – chronoamperograms at a potential of 0.87 V. Electrolyte is 0.1 M HClO₄ + 0.5 M CH₃OH, Ar atmosphere

from the ESA value of the PtCu/C catalyst from which it was obtained. This fact indicates that in the process of galvanic substitution of copper atoms by gold, surface defects do not occur.

The activity of the catalysts in MOR was studied by the method of cyclic voltammograms after the addition of 0.5 M CH₃OH to the electrolyte (Fig. 5a). The PtCuAu/C_G and PtCuAu/C_A materials demonstrated the highest activity in MOR, both per platinum weight in the catalyst and per ESA value (Table 2). At the same time, for the PtCuAu/C_G catalyst, the maximum specific current and the amount of electricity used for the oxidation of methanol in the forward potential sweep among the studied materials were observed. According to the results of chronoamperometric measurements at the potential $E = 0.87$ V (Fig. 5b, Table 2), the PtCuAu/C_G and PtCuAu/C_A catalysts demonstrate both the highest initial and final specific currents recorded after 30 min at a constant potential compared to PtCu/C and Pt/C materials. At the same time, PtCu/C and both PtCuAu/C catalysts were characterized by a larger relative drop in currents with time (Fig. 5b), reflected in the value of the K coefficient (Figs. 5b, 6b). The long-term CO poisoning coefficient (δ) considers the current decay with time and will have the lowest value for catalysts for which the difference between the initial and final currents is close. Indeed, the CO poisoning coefficient was the lowest for the commercial Pt/C material. Probably, the lowest value of the coefficient for the Pt/C sample was since already after 500 sec of the experiment, the current reached a practically constant value, which indicates a high tolerance of the catalyst to the intermediate products of methanol oxidation. Accelerated stress testing of PtCu/C and PtCuAu/C catalysts in a three-electrode cell revealed that the highest current value per

platinum weight after 30 min of the experiment was observed for the Pt/C catalyst (Table 2). Thus, doping of platinum with copper and gold atoms led to an increase in the catalytic activity in the methanol oxidation reaction, but at the same time caused a decrease in the tolerance of materials to poisoning by intermediate products.

The study of catalyst stability in accelerated stress testing showed that bi- and trimetallic catalysts degrade less than the commercial Pt/C analogue. This was clearly seen by comparison of ESA values after completion of the tests (Table 3). Thus, ESA decreased by 18% for PtCuAu/C_G, by 38% for PtCuAu/C_A, and by 33% for PtCu/C. At the same time, for the commercial Pt/C (JM20) catalyst, the reduction in ESA was 78%. The fact that after the completion of stress testing, both the weight and specific activity in MOR turned out to be the highest for the PtCuAu/C_G catalyst is even more important (Fig. 6a, Table 3). The same catalyst, PtCuAu_G, demonstrated the highest tolerance to methanol conversion products (Fig. 6b, Table 3). The tendency towards a decrease in the poisoning coefficient, observed for bi- and trimetallic materials after stress testing also should be mentioned.

4. Conclusions

Based on the results of evaluation of the catalytic activity, stability, and tolerance to intermediate products of methanol oxidation of the obtained catalysts by cyclic voltammetry and chronoamperometry, it was found that, despite the lower values of ESA compared to commercial Pt/C analogue, bi- and trimetallic catalysts have the highest activity in MOR.

It was established that a small addition of gold can increase the activity of the initial PtCu/C catalyst in MOR. The tolerance to the intermediate products of methanol oxidation for

Table 3. Values of electrochemically active surface and catalyst activity in methanol after stress testing

Materials	$Q_{\text{CH}_3\text{OH}}$, C/g(Pt)·10 ⁵	ESA, m ² /g(Pt)	I_{max} , A/g(Pt)	I chronoamperograms, A/g(Pt)		Long-term poisoning rate CO δ , %/s
				I_{initial}	I_{final}	
PtCu/C	21	19 ± 2	235	216	11	0.0333
PtCuAu/C_G	37	26 ± 3	370	284	71	0.0394
PtCuAu/C_A	19	19 ± 3	216	207	14	0.0353
JM20	4	17 ± 8	50	86	3	0.0499

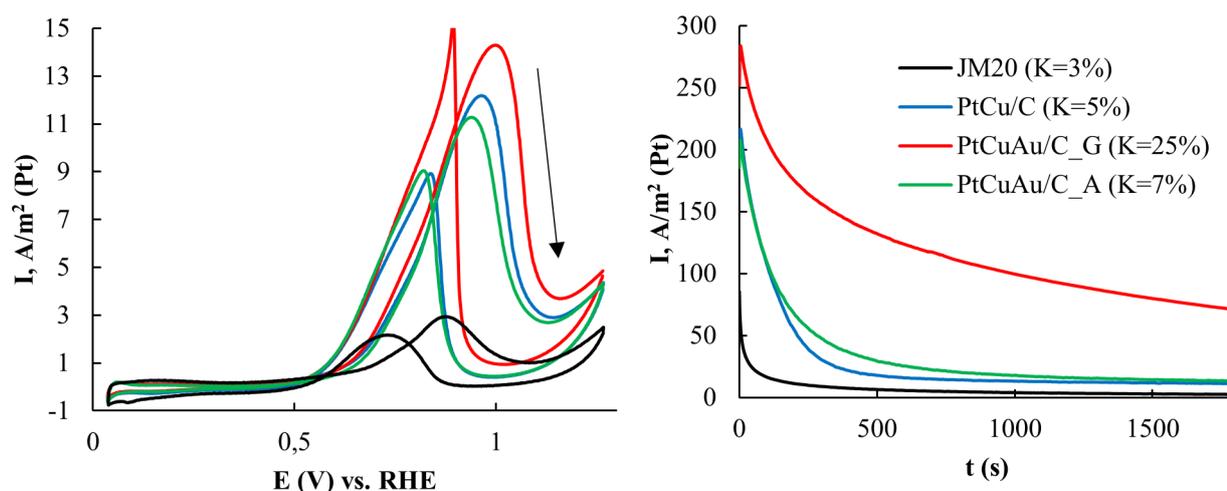


Fig. 6. (a)-cyclic voltammograms and (b)- chronoamperograms at a potential of 0.87 V after stress testing in an electrochemical cell. Electrolyte is 0.1 M HClO₄ + 0.5 MCH₃OH, Ar atmosphere

the obtained catalysts turned out to be lower than that of the Pt/C material, which may be due to the lowest ESA values. With a smaller ESA value of the material, the same amount of methanol was oxidized over a smaller surface area and the amount of oxidized methanol was greater per unit surface area. This results in higher surface poisoning compared to materials with higher ESA values. However, after the completion of stress testing, the activity and tolerance for the obtained trimetallic catalysts turned out to be an order of magnitude higher than for the Pt/C (JM20) material. Among the studied catalysts, the PtCuAu/C_G catalyst demonstrated the highest activity and tolerance in MOR after stress testing, which was 7.5 times higher than the Pt/C (JM20) material. The trimetallic PtCuAu/C_A and PtCuAu/C_G catalysts obtained by different synthesis methods demonstrated comparable activity in MOR; however, after stress testing, the PtCuAu/C_G material significantly outperformed the PtCuAu/C_A catalyst in terms of activity. This fact may be related to the large size of trimetallic nanoparticles for PtCuAu/C_G compared to PtCuAu/C_A, which ensures greater stability of this material according to the results of stress testing. For example, in [14], the PtCuAu/C material exhibits an activity 4.5 times higher than the commercial Pt/C. Thus, trimetallic catalysts are of interest for further study and testing in MEA. An important issue that needs to be addressed for testing is the prevention of copper dissolution during the MEA operation. One of

the ways to solve this problem, along with the substitution of atoms copper by gold, is the pre-treatment of obtained catalysts in acids.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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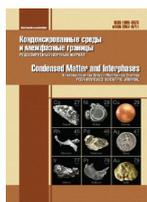
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The kinetics of cathodic hydrogen evolution on titanium disilicide in a sulphuric acid solution

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Abstract

The kinetics and mechanism of hydrogen evolution reaction on the TiSi_2 electrode in $x \text{ M H}_2\text{SO}_4 + (0.5 - x) \text{ M Na}_2\text{SO}_4$ ($x = 0.5; 0.35; 0.20; 0.05$) solutions were studied using the methods of polarisation and impedance measurements.

The cathodic polarisation curves of TiSi_2 were characterised by a Tafel section with a slope of 0.116–0.120 V at E ranging from -0.30 to -0.48 V (SHE). The value of hydrogen evolution overpotential at $i = 1 \text{ A/cm}^2$ for TiSi_2 was 0.90–0.96 V. The kinetic parameters of the hydrogen evolution reaction on silicide were close to the theoretical values for the slow stage of charge transfer.

Based on the measurements of the differential capacitance of the TiSi_2 electrode (at $f = 10 \text{ kHz}$), depending on the cathodic polarisation and acidity of the electrolyte, it was concluded that a thin dielectric film of silicon dioxide ($\text{Si} + 2\text{H}_2\text{O} \rightarrow \text{SiO}_2 + 4\text{H}^+ + 4\text{e}^-$) was present on the surface of the silicide. The film was not reduced with low cathodic polarisations.

The impedance spectra of the TiSi_2 electrode at the potentials of the Tafel region were capacitive semicircles with a misplaced centre. The impedance spectra were described by an equivalent electrical circuit, the Faraday impedance of which consisted of a series-connected charge transfer resistance R_1 and a parallel R_2C_2 chain corresponding to the adsorption of atomic hydrogen on the electrode surface. The impedance of the double layer capacitance was modelled using the constant phase element CPE_1 . The χ^2 criterion for the circuit was $(1.3\text{--}3.7) \cdot 10^{-4}$ (when using data modulus weighting), the sum of square deviations was $(1.5\text{--}4.1) \cdot 10^{-2}$, and the error in the determination of the values of circuit parameters did not exceed 10 %.

The experimental values of the slopes of $\lg R_1, E^-$, $\lg R_2, E^-$, and $\lg C_2, E^-$ dependences were close to the theoretical values of the slopes for the discharge-electrochemical desorption mechanism, in which both stages were irreversible and the transfer coefficients of the stages were not equal, when the Langmuir isotherm for adsorbed atomic hydrogen was fulfilled. The reaction of absorption of hydrogen with the kinetic control proceeded at the same time as the hydrogen evolution reaction.

Keywords: Titanium disilicide TiSi_2 , Hydrogen evolution reaction, Sulphuric acid solution, Impedance

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1. Introduction

The hydrogen evolution reaction (HER) is an electrocatalytic process whose rate considerably depends on the nature and structure of the electrode material as well as the condition of its surface. Therefore, metals, alloys, intermetallic, and metal-like (carbides, silicides, germanides, nitrides, chalcogenides, and composite materials based on them) compounds were studied as HER catalysts [1–16].

The kinetics of HER on transition metal silicides have not been thoroughly studied. The study of HER on transition metal silicides showed [1–4, 7–9, 10, 13–15] that depending on the nature and concentration of metal and silicon in the compound as well as the pH and composition of the medium, silicides can be characterised by lower or higher hydrogen overpotential as compared to the corresponding pure metals, and it was noted [1, 2, 13] that a thin oxide film of silicon dioxide influences the kinetics of hydrogen evolution on silicides in an acidic media with low cathodic polarisations.

The purpose of this work was to establish the kinetics and mechanism of the hydrogen evolution reaction on titanium disilicide (TiSi_2) in sulphuric acid solutions with various concentrations in order to determine the electrochemical activity of TiSi_2 in HER.

2. Experimental

The study was conducted using titanium disilicide (TiSi_2) obtained by the Bridgman method.

Electrochemical measurements were performed at a temperature of 25°C under natural aeration in unstirred solutions of 0.5 M H_2SO_4 ; 0.35 M H_2SO_4 + 0.15 M Na_2SO_4 ; 0.20 M H_2SO_4 + 0.30 M Na_2SO_4 ; 0.05 M H_2SO_4 + 0.45 M Na_2SO_4 . The solutions were prepared using deionised water (with water resistivity of 18.2 M Ω cm and organic carbon content of 4 $\mu\text{g/l}$) which was obtained using a Milli-Q water purification system by Millipore (France) and chemically pure reagents H_2SO_4 and Na_2SO_4 . The measurements were conducted using a potentiostat/galvanostat with a built-in Solartron 1280C frequency analyser by Solartron Analytical (Great Britain) in a YASE-2 electrochemical cell with cathode and anode sections separated by a porous glass diaphragm. A saturated silver chloride

electrode was used as the reference electrode and a platinum electrode was used as the auxiliary electrode. The potentials presented in this work are relative to the standard hydrogen electrode.

Before performing the measurements, the working surface of the electrode was polished with abrasive papers with decreasing grain size, degreased with ethyl alcohol, and rinsed with a working solution. Once the electrode was immersed in the solution, it was subjected to cathodic polarisation with a current density of 0.5 mA/cm² for 10 minutes, then held with an open circuit potential until a stable potential was established, and then the impedance spectra were recorded. Before the measurement of the impedance spectra, potentiostatic polarisation of the electrode was conducted at each potential until an almost constant current value was established. After that, the impedance was measured at this value of E and lower potentials, and the potential was changed with a fixed step. Cathodic potentiostatic curves were plotted based on the obtained values of i for this value of E . The range of frequencies $f(\omega/2\pi)$ used for impedance measurements was from 20 kHz to 0.02 Hz, while the amplitude of the alternating signal was 5–10 mV.

3. Results and discussion

The cathodic potentiostatic curves of the TiSi_2 electrode in sulphuric acid solutions are presented in Fig. 1. There is a linear section with a slope of 0.116–0.120 V on the cathodic silicide curves in the potential region from -0.30 to -0.48 V, and the range of potentials for recording the linear dependence of E on $\lg i$ decreases with a decrease in the acidity of the electrolyte (Table 1). The slope increases in the region of $E < -0.48$ V with an increase in cathodic polarisation. The value of hydrogen evolution overpotential at $i = 1$ A/cm² for TiSi_2 is 0.90–0.96 V, meaning that in the sulphate electrolyte titanium disilicide refers to materials with high hydrogen evolution overpotential and, as a result, it does not have high electrochemical activity in HER.

The kinetic parameters of the hydrogen evolution reaction on the TiSi_2 electrode with the potentials of the linear dependence of E on $\lg i$ on polarisation curves are close to the theoretical values for the slow stage of charge transfer (Table 1) [17].

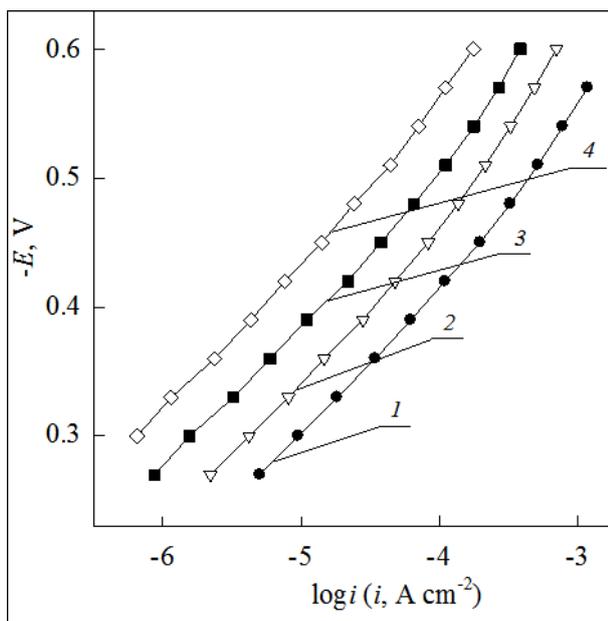


Fig. 1. Cathodic polarisation curves for the TiSi₂ electrode in solutions: 1 – 0.5 M H₂SO₄; 2 – 0.35 M H₂SO₄ + 0.15 M Na₂SO₄; 3 – 0.20 M H₂SO₄ + 0.30 M Na₂SO₄; 4 – 0.05 M H₂SO₄ + 0.45 M Na₂SO₄

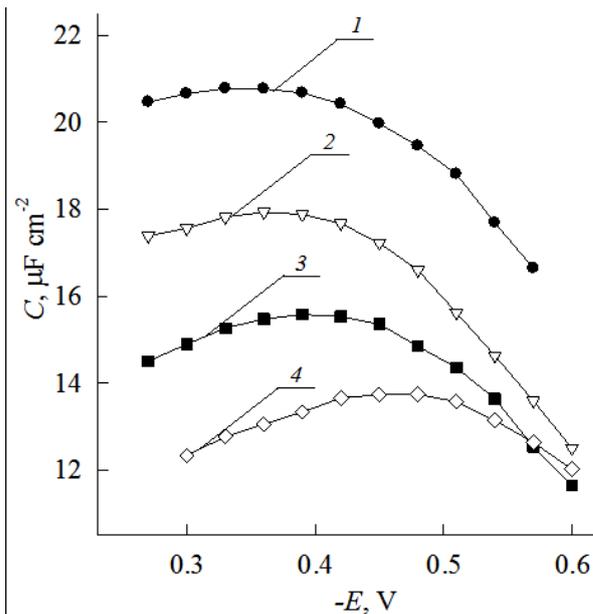


Fig. 2. The dependence of differential capacitance of the TiSi₂ electrode on the potential at a frequency of 10 kHz in solutions: 1 – 0.5 M H₂SO₄; 2 – 0.35 M H₂SO₄ + 0.15 M Na₂SO₄; 3 – 0.20 M H₂SO₄ + 0.30 M Na₂SO₄; 4 – 0.05 M H₂SO₄ + 0.45 M Na₂SO₄

The differential capacitance of the TiSi₂ electrode at an alternating current frequency of $f = 10$ kHz in the studied region was ~ 10 – 22 $\mu\text{F}/\text{cm}^2$ and at the potentials of the linear section on the cathodic curves it passed through a mild maximum and decreased with a decrease in the acidity of the medium (Fig. 2). The differential capacitance was determined using the values of the imaginary component of the impedance Z'' :

$$C = -\frac{1}{\omega Z''},$$

where ω was the circular frequency of the alternating current ($\omega = 2\pi f$).

In accordance with [18], at room temperature titanium disilicide is a metallic conductor and is characterized by resistivity not exceeding

$20 \mu\Omega \text{ cm}$. Therefore, the reduced values of the differential capacitance of the TiSi₂ electrode as compared to the capacitance values typical for solid metal electrodes in aqueous electrolyte solutions (~ 20 – $40 \mu\text{F}/\text{cm}^2$) cannot be associated with the nature of conductivity and low concentration of charge carriers in the silicide.

The low values of the silicide capacitance were apparently due to the presence of a thin dielectric film of silicon dioxide on its surface ($\text{Si} + 2\text{H}_2\text{O} \rightarrow \text{SiO}_2 + 4\text{H}^+ + 4\text{e}^-$, $E^0 = -0.86 \text{ V}$ [19]). An oxide film was formed on the silicide at the corrosion potential and was not subject to reduction during cathodic polarisation. The authors [1, 2] also showed that SiO₂ was stable in acidic media with low cathodic polarisations.

Table. 1. Kinetic parameters of hydrogen evolution reaction for the TiSi₂ electrode in sulphuric acid solutions

Solution	$-E, \text{ V}$	$-\left(\frac{\partial E}{\partial \log i}\right)_{c_{\text{H}^+}}, \text{ V}$	$-\eta, \text{ B}$ at $i = 1 \text{ A}/\text{sm}^{-2}$	$\left(\frac{\partial \log i}{\partial \log c_{\text{H}^+}}\right)_E$	$-\left(\frac{\partial E}{\partial \log c_{\text{H}^+}}\right)_i, \text{ V}$
0.5 M H ₂ SO ₄	0.30–0.48	0.120±0.003	0.90±0.02	1.01±0.04	0.123±0.005
0.35 M H ₂ SO ₄ + 0.15 M Na ₂ SO ₄	0.30–0.48	0.119±0.003	0.92±0.02		
0.20 M H ₂ SO ₄ + 0.30 M Na ₂ SO ₄	0.33–0.48	0.116±0.004	0.94±0.04		
0.05 M H ₂ SO ₄ + 0.45 M Na ₂ SO ₄	0.36–0.48	0.117±0.003	0.96±0.03		

The decrease in the differential capacitance due to a decrease in acidity of the electrolyte (Fig. 2) may be associated with the lower rate of chemical dissolution of SiO_2 in solutions with lower acidity. According to [20], the rate of chemical dissolution of various forms of silicon dioxide (quartz or amorphous oxide) was minimal at pH $\sim(2-3)$ and increased with deviations from this value in both directions. The pH values of the studied electrolytes were 0.4–1.8 and, therefore, correspond to the descending branch of the curve of the dependence of SiO_2 dissolution rate on the pH of the solution.

The introduction of sodium fluoride (0.005 M) into a solution of 0.5 M H_2SO_4 leading to the dissolution of silicon dioxide [20] resulted in an increase in the differential capacity of the silicide by $\sim 1.3-2.1$ times. The higher values of the differential capacitance of silicide in the presence of fluoride confirmed the assumption about the low capacitance of TiSi_2 in an acidic fluoride-free solution associated with the presence of a thin oxide film on its surface.

The impedance spectra of the TiSi_2 electrodes in the studied solutions were capacitive semicircles with a misplaced centre (Fig. 3) which

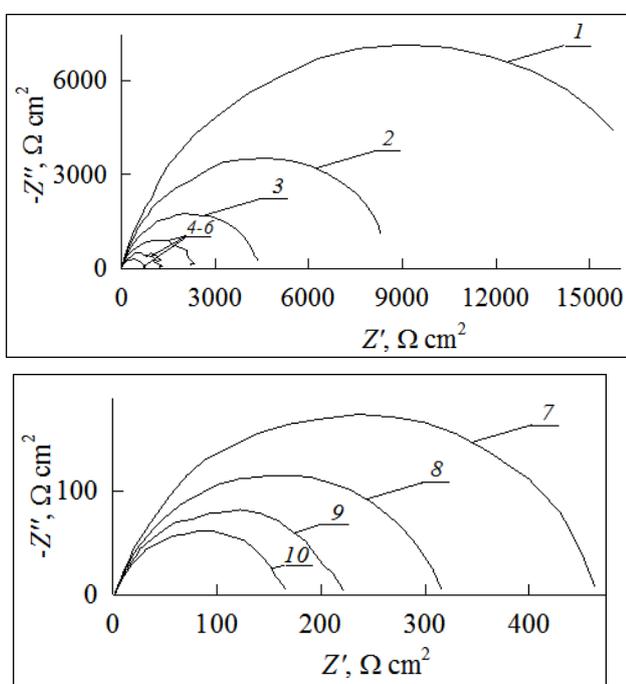


Fig. 3. Impedance spectra of the TiSi_2 electrode in 0.20 M H_2SO_4 + 0.30 M Na_2SO_4 at E , V: 1 – -0.33; 2 – -0.36; 3 – -0.39; 4 – -0.42; 5 – -0.45; 6 – -0.48; 7 – -0.51; 8 – -0.54; 9 – -0.57; 10 – -0.60

corresponded to asymmetric maxima in the graph of the dependence of the phase angle φ on the logarithm of the alternating current frequency f . The electrode quantity $|Z|$ changed in accordance with the shape of the polarisation curves in all solutions (Fig. 1).

An equivalent electrical circuit presented in Fig. 4 was used to simulate HER on the TiSi_2 electrode at potentials of linear dependence of E on $\lg i$ on cathodic polarisation curves in the studied solutions. The circuit includes the following: R_s is the electrolyte resistance, R_1 is the charge transfer resistance, while resistance R_2 and capacitance C_2 describe the adsorption of atomic hydrogen on the electrode surface and the CPE_1 element simulates double layer capacitance on the inhomogeneous surface of the solid electrode.

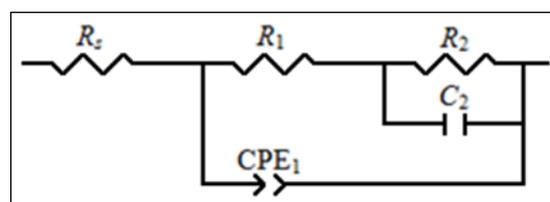


Fig. 4. The equivalent electrical circuit for the TiSi_2 electrode in sulphuric acid solutions over the range of hydrogen evolution potentials

The impedance of the constant phase element was:

$$Z_{\text{CPE}} = Q^{-1}(j\omega)^{-p}.$$

In this ratio with $p = 1 - \gamma$ the constant phase element is non-ideal capacitance and γ is the value significantly less than 1 (typically $\gamma < 0.2$) [21].

The use of the non-linear least squares method (ZView2 program) showed that the equivalent circuit in Fig. 4 presented a satisfactory description of the experimental impedance spectra of the TiSi_2 electrode obtained with E ranging from -0.30 to -0.48 V. The χ^2 criterion calculated for this circuit using ZView2 was $(1.3-3.7) \cdot 10^{-4}$, the sum of square deviations was $(1.5-4.1) \cdot 10^{-2}$, and the error in determining the values of the circuit parameters did not exceed 5% and reached 10% only for the value of R_1 . The latter seemed to be associated with the difficulty of the determination of small values of R_1 as compared to the large values of R_2 . The values of the equivalent circuit parameters for the 0.20 M

$\text{H}_2\text{SO}_4 + 0.30 \text{ M Na}_2\text{SO}_4$ solution are presented in Table 2.

The results of the determination of the numerical values of R_1 , R_2 , and C_2 parameters of the equivalent circuit in Fig. 4 for the TiSi_2 electrode in the studied solutions were analysed depending on the potential in semi-logarithmic coordinates (Fig. 5, Table 3). In the potential region from -0.30 to -0.48 V , the $\lg X, E$ dependences, where $X = R_1, R_2, C_2$, were linear, which confirmed that the Langmuir adsorption isotherm for adsorbed atomic hydrogen was fulfilled [22]. The experimental values of the slopes $(\partial \lg X / \partial E)_{c_{\text{H}^+}}$ were close to the theoretical values of the slopes for the discharge-electrochemical desorption mechanism, in which both stages were irreversible and the transfer coefficients of the stages were not equal [22].

The reduced values of derivatives $(\partial \lg X / \partial E)_{c_{\text{H}^+}}$ according to [23], may be associated with the reaction of absorption of atomic hydrogen by the electrode material proceeding at the same time with the hydrogen evolution reaction. The absence of an additional time constant characterising the hydrogen absorption in the impedance spectra of the TiSi_2 electrode (Fig. 3) with the potentials of linear dependence of E on $\lg i$ on the polarisation curves indicated that the transition of hydrogen from an

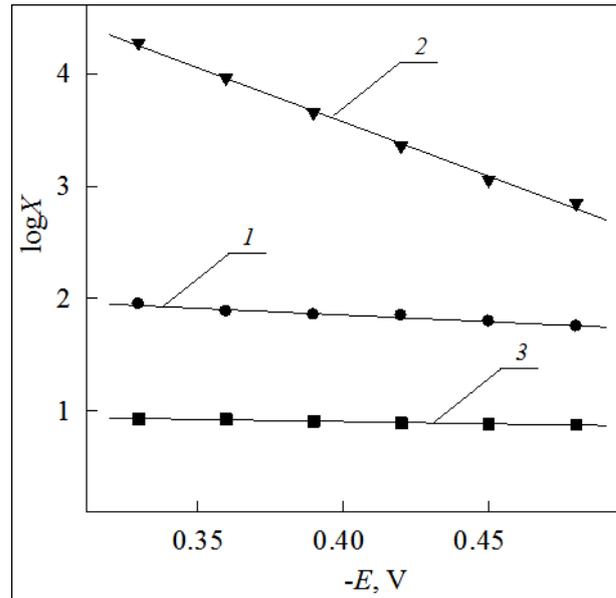


Fig. 5. Dependences of $\lg X$ (X : 1 – R_1 , 2 – R_2 , 3 – C_2) on the potential of the TiSi_2 electrode in a solution of $0.20 \text{ M H}_2\text{SO}_4 + 0.30 \text{ M Na}_2\text{SO}_4$. Units of measurement: R_1 and R_2 in $\text{Ohm} \times \text{cm}^2$, C_2 in $\mu\text{F}/\text{cm}^2$

adsorbed state to an absorbed state was probably the rate-determining process in the absorption of hydrogen. In this case, the resistance R_2 in the equivalent circuit in Fig. 4 was expressed through the adsorption resistance R_{ads} and the absorption resistance R_{abs} : $R_2 = \frac{R_{\text{ads}} R_{\text{abs}}}{R_{\text{ads}} + R_{\text{abs}}}$

Table 2. The values of the equivalent circuit parameters in Fig. 4 for the TiSi_2 electrode in a solution of $0.20 \text{ M H}_2\text{SO}_4 + 0.30 \text{ M Na}_2\text{SO}_4$

$-E, \text{V}$	$R_1, \Omega \text{ cm}^2$	$R_2, \Omega \text{ cm}^2$	$C_2 \cdot 10^6, \text{F} \cdot \text{sm}^{-2}$	$Q_1 \cdot 10^4, \text{F} \cdot \text{sm}^{-2} \cdot \text{s}^{(p_1-1)}$	p_1
0.33	89.2	18818	8.51	1.39	0.817
0.36	76.4	9145	8.43	1.50	0.821
0.39	71.7	4507	8.11	1.59	0.803
0.42	70.4	2263	7.83	1.66	0.798
0.45	62.4	1134	7.65	1.65	0.795
0.48	56.5	704.2	7.53	1.66	0.792

Table 3. Slope values $(\partial \lg X / \partial E)_{c_{\text{H}^+}}$ ($X = R_1, R_2, C_2$) for the TiSi_2 electrode in sulphuric acid solutions

Solution	$-E, \text{V}$	$\left(\frac{\partial \log R_1}{\partial E}\right)_{c_{\text{H}^+}}, \text{V}^{-1}$	$\left(\frac{\partial \log R_2}{\partial E}\right)_{c_{\text{H}^+}}, \text{V}^{-1}$	$\left(\frac{\partial \log C_2}{\partial E}\right)_{c_{\text{H}^+}}, \text{V}^{-1}$
$0.5 \text{ M H}_2\text{SO}_4$	0.30–0.48	0.9 ± 0.5	9.1 ± 0.5	0.35 ± 0.03
$0.35 \text{ M H}_2\text{SO}_4 + 0.15 \text{ M Na}_2\text{SO}_4$	0.33–0.48	1.5 ± 0.2	8.3 ± 0.4	0.23 ± 0.05
$0.20 \text{ M H}_2\text{SO}_4 + 0.30 \text{ M Na}_2\text{SO}_4$	0.33–0.48	1.2 ± 0.3	9.4 ± 0.6	0.37 ± 0.03
$0.05 \text{ M H}_2\text{SO}_4 + 0.45 \text{ M Na}_2\text{SO}_4$	0.36–0.48	1.4 ± 0.2	8.8 ± 0.3	0.25 ± 0.04

4. Conclusions

It was established that the hydrogen evolution reaction on titanium disilicide in a sulphuric acid electrolyte proceeded according to the discharge-electrochemical desorption path, both stages were irreversible, and the transfer coefficients of the stages were not equal. The Langmuir isotherm for adsorbed atomic hydrogen was fulfilled. It was suggested that HER was complicated by the hydrogen absorption reaction with the electrode material proceeding with kinetic control (over the whole range of the studied potentials). It was found that titanium disilicide in a sulphuric acid electrolyte is a material with a high hydrogen evolution overpotential and did not have a high electrochemical activity in HER. The presence of a thin oxide film was noted on the electrode surface at low cathodic polarisations.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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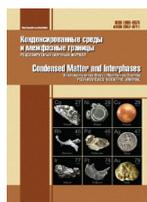
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Original articles

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Effect of ethanol vapour sorption on the semiconductor-metal phase transition in powdered vanadium dioxide

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Abstract

We studied the effect of ethanol vapour on the parameters of the semiconductor-metal transition in a polycrystalline vanadium dioxide powder of the stable monoclinic phase α -VO₂. It was synthesised by reducing vanadium pentoxide with oxalic acid while heated in air. The DC electrical resistance of the samples was studied between room temperature and 100 °C in a tubular heater, in a microcompressor-generated air stream with saturated ethyl alcohol vapour. It was found that in the presence of ethanol vapour, the hysteresis loop shifted to higher temperatures by ten degrees and its cooling branch (corresponding to the transition of vanadium dioxide from the metallic phase to the semiconductor phase) became stepped.

Keywords: Vanadium dioxide, Semiconductor - metal phase transition, Ethanol vapour, Sorption

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1. Introduction

Semiconductor – metal phase transition (SMPT) in vanadium dioxide (VO₂) has been a topical area of research for more than sixty years due to the various practical applications of this effect [1]. Vanadium dioxide as a binary compound with different phase modifications is described in Table 1, their transformation scheme is shown in Figure 1. The structures of vanadium dioxide consist of [VO₆] octahedra. Depending on the synthesis conditions and kinetics, the octahedra can be distorted, connected by edges and vertices in different crystallographic directions, forming

two stable modifications (VO₂ (M₁) and VO₂ (R)) and several metastable modifications.

The stable monoclinic M₁ (P2₁/c) modification (otherwise called α-VO₂) is built from chains of distorted [VO₆] octahedra, which form a three-dimensional structure with a distance of 0.352 nm between vanadium atoms in adjacent chains and 0.265 nm inside the chain. At temperatures above 68 °C (the SMPT temperature), the distortion of the crystal structure is eliminated, when the localised V-V bonds within the chain are broken and the previously paired electrons are released. As a result, the monoclinic structure transforms

Table 1. Lattice parameters of different vanadium dioxide modifications

VO ₂ modifications	Crystal structure (space group)	Lattice parameters			
		a (Å)	a (Å)	a (Å)	β (°)
VO ₂ (M ₁)	Monoclinic (P2 ₁ /c)	5.7513	4.5259	5.3836	122.618
VO ₂ (R)	Tetragonal (P4 ₂ /mnm)	4.55	4.55	2.86	-
VO ₂ (B)	Monoclinic (C2/m)	12.03	3.69	7.68	106.6
VO ₂ (A _T)	Tetragonal (P4/ncc)	8.43	8.43	7.68	-
VO ₂ (A _H)	Tetragonal (I4/m)	8.476	8.476	3.824	-
VO ₂ (M ₂)	Monoclinic (C2/m)	9.07	5.80	4.53	91.9
VO ₂ (C)	Monoclinic (I4/mmm)	5.743	4.517	5.375	121.61

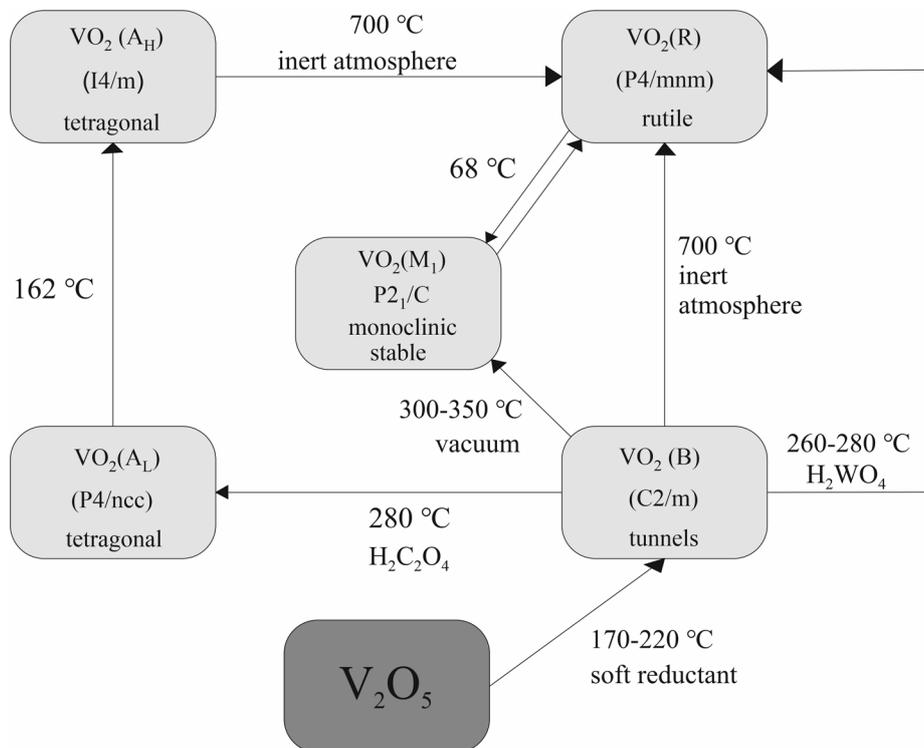


Fig. 1. Technological scheme for the transformations of vanadium dioxide phase modifications (explained in the text)

into a tetragonal (R) ($P4_2/mnm$) rutile structure. In the resulting structure, electrical conductivity, magnetic susceptibility, and light absorption increase dramatically [2]. This allows the M_1 modification to be used as a material for electrical and optical switches, IR-sensitive windows, temperature sensors, and thermochromic indicators.

VO_2 (R) is obtained by heating VO_2 (B) in an inert atmosphere [3]. The rutile (R) modification can also be obtained directly by hydrothermal method. It is similar to the synthesis of VO_2 (B), but it is performed at a higher temperature (260–280 °C) with the addition of tungstic acid (1 %) [4, 5].

Metastable monoclinic modification VO_2 (B) ($C2/m$) has a characteristic structural feature: channels (tunnels) formed by chains of distorted $[VO_6]$ octahedra. This modification is an important and promising material for lithium-ion battery cathodes because lithium cations can be reversibly introduced into the VO_2 (B) tunnel structure [6]. VO_2 (B) is obtained under hydrothermal conditions at a temperature of about 170–220 °C [4, 7] by treating V_2O_5 with a mild reducing agent. When heated in a vacuum to 300–350 °C, VO_2 (B) turns into VO_2 (M_1). At 700 °C in an inert atmosphere it transforms into the thermochromic modification VO_2 (R) [3].

Metastable VO_2 (A) has two modifications. The low-temperature form (A_L , $P4/ncc$) changes to the high-temperature (A_H , $I4/m$) when heated to 162 °C. Both phases have a similar oxygen frame structure in the $[VO_6]$ octahedron, but they have different arrangement of vanadium atoms inside the coordination polyhedron. The abrupt change in the optical properties of VO_2 (A) during the $A_L \leftrightarrow A_H$ phase transition makes it a promising material for optical switches. VO_2 (A_L) can be produced by the reduction of the VO_2 (B) modification with oxalic acid under hydrothermal conditions at 280 °C [5]. The product fraction increases considerably if the starting material is briefly exposed to a pressure of 440 MPa [8]. When VO_2 (A_H) is heated in an inert atmosphere to 700 °C, VO_2 (R) is formed [5].

The monoclinic metastable modification VO_2 (C) ($I4/mmm$) is close to the monoclinic $M1$ phase in structure and lattice energy. It has a layered structure and can be used to produce cathodes

for lithium-ion batteries. VO_2 (C) is obtained by heating $VO_2 \cdot 0.5H_2O$ semihydrate at 200 °C in a vacuum for 4 days [9].

The semiconductor-metal phase transition changes not only the electrical conductivity of vanadium dioxide, but also its optical characteristics, which is beneficial for the production of thermochromic smart glass. Glazing technologies based on the use of chromogenic materials are called “smart”. Chromogenic materials change their optical properties as a result of exposure to electric current, light radiation, changes in temperature, and other factors. Thus, there are electrochromic, photochromic, and thermochromic materials [10]. The heating of vanadium dioxide to 68 °C results in the SMPT, which significantly changes its optical characteristics [11]. The transition temperature depends on the vanadium dioxide crystal state, oxygen nonstoichiometry, and doping. The use of composite coatings based on a transparent film matrix filled with thermochromic material makes smart window technology more flexible and affordable [12, 13].

For smart glasses with chromogenic coatings, the ability to reversibly change light transmission parameters is important. When vanadium dioxide is used as a thermochromic filler, the SMPT temperature and the shape of the hysteresis loop can be regulated by surface doping of the oxide under gas adsorption conditions. A chromogenic layer on the inner surface of the glass in a standard window glass unit makes it possible to chemically sensitise the thermochromic material by introducing electron donor gases (e.g., alcohol vapour) into the air between the panes. Some results obtained in this area of research [14] refer mainly to mixed-valence vanadium oxide films.

This paper is devoted to the study of the effect of ethanol vapor on the parameters of the SMPT in single-phase powdered vanadium dioxide.

2. Experimental

Polycrystalline vanadium dioxide powder (n -type conductivity as determined by the Seebeck effect) was synthesised by reducing vanadium pentoxide with oxalic acid when heated in air to 600–700 °C according to the reaction:



X-ray phase analysis of the powder obtained by the reduction reaction showed the reflexes of vanadium dioxide of the stable α -VO₂ (VO₂ (M₁)) monoclinic phase. At 300 bar, we formed tablets with a diameter of 1 cm and a thickness of 1 mm from the powder. We applied tin foil contacts to the flat surfaces of the tablets. The change of electrical resistance of the samples at direct current was studied in the temperature range from room temperature to 100 °C. The measurements were carried out in a tubular heater in an air stream generated by a microcompressor with saturated ethyl alcohol vapour (about 5% of the volume). The heating and cooling rate was about one degree per minute.

3. Results and discussion

When the samples were heated in air, the sample resistance decreased by two orders of magnitude in the temperature range of 60–80 °C, and the hysteresis loop was slightly asymmetrical (Fig. 2a). In the presence of ethanol vapour, there were significant changes in the parameters of the phase transition. The hysteresis loop shifted to higher temperatures by about ten degrees, and the cooling branch (corresponding to the transition of vanadium dioxide from the metallic phase to the semiconductor phase) became stepped (Fig. 2b).

There is a step on the cooling branch of the hysteresis loop at 80–90 °C (Fig. 2b, branch (2)) under the action of a donor-active gas (ethanol) on the surface of vanadium dioxide. It may result from the asymmetry of the so-called elementary hysteresis loops due to elastic deformation of crystallites during the phase transition [15]. The cooling branch of the thermal hysteresis loop is not multi-step in the absence of donor-active gas on the vanadium dioxide powder surface.

We had previously observed the multi-step shape of both branches of the thermal hysteresis of the semiconductor-metal phase transition in nanocrystalline films of mixed vanadium oxide on silicon in AC conductivity measurements [16]. The steps were formed due to the influence of the size effect on the phase transition in certain groups of crystallites of nearly similar size.

We had also observed “abnormal” electronic semiconductor (VO₂) responses to the chemisorption of electron-donor gas (ethanol) for vanadium dioxide films. Study [17] suggested an energy band model of the structure of vanadium dioxide crystallites that took into account the possible inversion of the conductivity type in the surface layers. An increase up to certain limits (up to inversion) of the electron concentration in the space charge region of the VO₂ surface layer should lead to

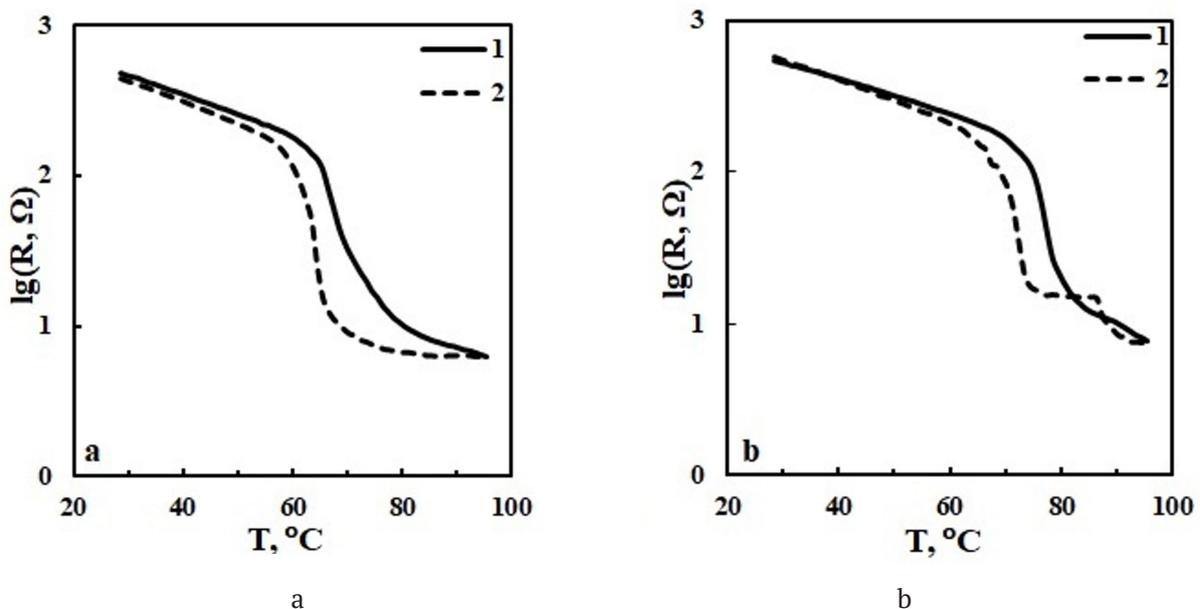


Fig. 2. Dependence of vanadium dioxide resistance on temperature in a clean air stream (a) and in an air stream with saturated ethanol vapour (b): 1 – heating branch, 2 – cooling branch

an increase in the electrical resistance of the material.

4. Conclusions

Thus, using ethanol vapour as an example, this study shows that it is possible to control the semiconductor - metal phase transition parameters in polycrystalline powdered vanadium dioxide by chemisorption of gases.

Authors contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no conflict of interest.

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Original articles

Research article

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Polycondensation in a spray of aqueous-alcoholic solution of lactic acid

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Abstract

The removal of low molecular weight products of the reaction and heat withdrawal is one of the problems of bulk polycondensation. Polycondensation under spray conditions is an effective way to solve these problems.

Based on the example of the reversible reaction of lactic acid polycondensation, it was shown that size effects can significantly affect the conversion rate, the degree of polymerization, and the rate of processes. Chemical thermodynamics suggests that chemical equilibrium in a spray shifts towards the formation of polylactide. In addition, the recondensation of volatile components (water, lactic acid, solvent) stabilizes the concentration of reagents and the temperature in the spray drops throughout the entire process. Model experiments confirming the obtained regularities are presented. Microscopic observation of sessile drops of aqueous and aqueous-alcoholic lactic acid solutions demonstrated the formation of polylactide under normal conditions (without heating, catalyst, evacuation).

The described regularities are of a thermodynamic nature and are relevant for polymerization and polycondensation processes involving volatile monomers and solvents.

Keywords: Polycondensation, Spray, Polylactide, Microencapsulation, Phase transitions

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1. Introduction

The increased interest in spray technologies is due to the possibility of obtaining products and materials with unique properties. The ease of implementation and the efficiency of spray technologies allow using them in the production of polymeric materials [1, 2], pharmaceutical preparations [3], and in organic synthesis [4]. There are good prospects for spray technologies in which polymerization and other chemical processes occur inside or on the surface of aerosol particles [5]. This allows creating functional materials with a special morphology, for example, inorganic particles coated with a polymer shell [6, 7] or organic particles with an oxide shell [8], hollow spheres [9] and polymer microcapsules filled with components for various purposes [10].

Features and benefits of spray technologies are based on size effects, which contribute to the emergence of conditions and states not typical for macroscopic systems. Size effects are understood as the dependence of the properties and dynamics of processes on the size or volume of the system. In the spray, they become significant for submillimeter drops. In particular, size effects during phase transformations of the liquid–liquid type allow reagents to be involved in the processes for which their interactions with each other is complicated by low mutual solubility [11, 12]. Thermodynamic estimates show that a decrease in volume can lead to the complete mutual solubility of low-soluble components [13, 14].

The assessment of the use of the spray technology in organic synthesis was provided in [15], where the synthesis of polylactide (PLA) was one of the examples.

PLA has a wide range of applications as a biocompatible, biodegradable, and thermoplastic polymer. One of the methods for its production is direct synthesis using aqueous organic solutions of lactic acid [16, 17]. The main difficulties of the technology are associated with the removal of a low molecular weight polycondensation product (water), which, like the formation of a high molecular weight product, is accompanied by an increase in viscosity and a slowdown in the heat and mass transfer processes. The consequence is local overheating of the reaction mixture, tarring, and other undesirable chemical transformations.

In the spray, the problems associated with an increase in the viscosity of the reaction mixture

are effectively removed due to interfacial heat and mass transfer, and the removal of a low molecular weight product is facilitated by a large specific surface area and surface curvature.

The vapour pressure above the surface of spray drops is higher than in a macrosystem of the same composition, and the concentration of water in the reaction mixture equilibrium with the gaseous medium, decreases with a decrease in the radius of drops (Kelvin equation). This should shift the equilibrium in the polycondensation reaction towards polymer formation.

Size effects at chemical equilibrium can be associated with the difference in the chemical potentials of the components in the bulk and in the near-surface layer. In this case, the effective constant of chemical equilibrium and the rate of processes become a function of the specific surface area, surface activity, and molar volume of the components [15, 18].

In the spray, chemical and phase equilibrium are interconnected through the chemical potentials of the components in different phases. A large specific surface area and small diffusion paths allow to stabilize the temperature and concentrations of reagents due to mass and heat transfer during the recondensation of volatile components between drops [19, 20]. All low molecular weight components of the reaction (water and lactic acid) are present in the gas phase and participate in the recondensation during the polycondensation of lactic acid.

In the formation of insoluble products (polymer) or separation of the solution, size effects change the mutual solubility of the components and lower the upper critical temperature of separation [21, 22]. An increase in the solubility of lactic acid and its oligomers additionally shifts the equilibrium towards polymerization.

The aim of this study was theoretical substantiation of the statement about the advisability of using spray technology as the best alternative to existing methods for the synthesis of PLA. The task of the above model experiments was to experimentally confirm this statement.

2. Results and discussion

2.1. Thermodynamic model of polycondensation under spray conditions

The scheme of equilibrium transformations involving lactic acid, lactide, PLA, and their

thermodynamic properties are given in [23]. The equilibrium constant of the polycondensation reaction K at low degrees of polymerization and low conversion has the form:

$$K = \frac{x_p x_0^{p-1}}{x_1^p} = \frac{x_p}{x_0} \left(\frac{x_0}{x_1} \right)^p, \quad (1)$$

where p is the degree of polymerization, x_0 , x_1 , x_p are the concentration (mole fraction) of water, monomer, and polymer in the solution, respectively.

At high degrees of polymerization, the polymer passes into the solid phase. If no solid solutions are formed, then $x_p = 1$ and the equilibrium constant takes the form:

$$K_* = \left(\frac{x_0}{x_1} \right)^p x_0^{-1}. \quad (2)$$

The values of K and K_* differ by the correction for the transition energy of the polymer into solution. The reactions of the formation of lactide and PLA from lactic acid are characterized by small positive values of the Gibbs energy [23] and, accordingly, by equilibrium constants close to one.

Phase equilibrium and chemical equilibrium are related through the chemical potentials of the components. This relationship determines the state of drops (radius, composition) and the equilibrium concentrations of components in different phases [19, 20]. For ideal solutions, the condition of equality of chemical potentials in coexisting phases is converted to the equations of Kelvin and Freundlich and Raoult's law. For real solutions, the relationship between the solution concentration x_k , drop radius r , partial pressure in the vicinity of the drop $P_k(r, x_k)$ or external environment $P_{ex,k}$ has a more complex form:

$$P_k(r, x_k) = \gamma_k x_k P_{\infty,k} \exp\left(\frac{2\sigma V_k}{rRT}\right). \quad (3)$$

Here σ is the surface tension, V_k is the molar volume of the component k , R is the universal gas constant, T is temperature, $P_{\infty,k}$ is the vapour pressure above the flat surface of the pure component. Values of γ_k and σ in general depend on the composition of the solution. The equilibrium state of the drop corresponds to the condition $P_k(r, x_k) = P_{ex,k}$, where $P_{ex,k}$ is the partial pressure in the external environment. For low-soluble components, the

expression (3) is given in [19,24]. The temperature dependence of the vapour pressure of lactic acid is given in [23]. Its extrapolation to $T = 298$ K gives $P_{\infty,1} \sim 1.5$ Pa. Saturated vapour pressure of water at the same temperature $P_{\infty,0} = 3.2$ kPa.

According to (3) the equilibrium concentration of the volatile component is determined by the droplet radius, vapour pressure, and activity coefficient:

$$x_k = \frac{P_{ex,k}}{\gamma_k P_{\infty,k}} \exp\left(-\frac{2\sigma V_k}{rRT}\right). \quad (4)$$

If all components of the solution are volatile, the following identity is established:

$$\sum x_k = \sum \frac{P_{ex,k}}{\gamma_k P_{\infty,k}} \exp\left(-\frac{2\sigma V_k}{rRT}\right) = 1. \quad (5)$$

Ratios (3)–(5) determine the equilibrium size and composition of the drops corresponding to the composition of the gaseous medium. For volatile components, this identity limits the conditions for the appearance and existence of a spray by the inequality $\sum P_{ex,k}/P_{\infty,k} \gamma_k > 1$, otherwise the drops evaporate completely. The value $S = \sum P_{ex,k}/P_{\infty,k}$ can be interpreted as the relative supersaturation of vapour.

Identity (5) allows to state that the increase in relative supersaturation S leads to a decrease in the equilibrium drop radius. Positive deviation from the ideal behaviour $\gamma_i > 1$ contributes to an increase in the equilibrium drop radius. Negative deviation from the ideal behaviour $\gamma_i < 1$ lowers the equilibrium drop radius. Drops of solutions with a negative deviation from the ideal behaviour can exist at $S < 1$. These patterns are more complex for solutions containing non-volatile or partially soluble components [19, 20].

Equations (1)–(3) describe the relationship between equilibrium concentrations, degree of polymerization, gas phase composition, and spray drop radius:

$$K = x_p \frac{\gamma_0 P_{\infty,0}}{P_{ex,0}} k^p \exp\left(\frac{2\sigma(V_0 + p(V_1 - V_0))}{rRT}\right), \quad (6)$$

here the multiplier $k = \frac{\gamma_1 P_{ex,0} P_{\infty,1}}{\gamma_0 P_{ex,1} P_{\infty,0}}$ depends on the composition of the gas phase and, taking into

account $\gamma_k = \gamma_k(x_i)$, on the concentration of the solution.

The equation (6) describes the main laws of chemical equilibrium in the spray. For example, a decrease in the drop radius (an increase in the exponential) should be compensated by a corresponding decrease in the values of x_p , x_0 or p . The decrease in the value of k (at $r = \text{const}$) is compensated for by the increase in x_p or p shifting the equilibrium towards polycondensation. In other words, the chemical equilibrium in small drops is shifted towards polymer formation, while a decrease in the average radius of spray drops enhances this effect by increasing $P_{ex,1}$ in a spray cloud (3). The transfer of drops in the environment with lower humidity ($P_{ex,0}$) must be accompanied by both a decrease in the radius and an increase in x_p or p .

The decrease in the γ_1/γ_0 ratio leads to a shift of equilibrium towards the formation of a polymer in real solutions. This explains the effectiveness of methods based on the azeotropic distillation of water in the synthesis of PLA [16, 17]. For spray technology, mixtures with $\gamma_0 > 1$, characterized by the lower equilibrium concentration of water in drops are preferable. This further improves the efficiency of the process.

Let us estimate the effect of the solvent composition on the activity coefficients in water–lactic acid–co-solvent mixtures. Let's consider a solution of lactic acid with a concentration of 80 wt. % ($x_0/x_1 = 1.27$) diluted with two volumes of co-solvent. The values of the activity coefficients of water and monomer are equal in the presence of methyl isobutyl ketone – $\gamma_0 = 0.4$, $\gamma_1 = 1.9$ ($\gamma_1/\gamma_0 = 4.75$), ethanol – $\gamma_0 = 1.1$, $\gamma_1 = 0.8$ ($\gamma_1/\gamma_0 = 0.73$), propanol – $\gamma_0 = 1.2$, $\gamma_1 = 0.8$ ($\gamma_1/\gamma_0 = 0.67$), n-butanol – $\gamma_0 = 1.2$, $\gamma_1 = 1.1$ ($\gamma_1/\gamma_0 = 0.92$), 2-butanol – $\gamma_0 = 1.3$, $\gamma_1 = 1.0$ ($\gamma_1/\gamma_0 = 0.77$). The NRTL parameters for the systems water–lactic acid–methyl isobutyl ketone [25], water–propanol [26], water–ethanol [27], water–butanol-2 [28], water–lactic acid–n-butanol [29] were used in the estimates. The interaction parameters for water–lactic acid provided in the literature for different ternary mixtures can differ significantly [25, 28–30]. Missing parameters of the lactic acid–alcohol interaction were replaced by zeros. In addition to butanol, the authors of [29] describe the use of the NRTL model for aqueous

alcoholic solutions of lactic acid with n-pentanol, n-hexanol, and n-heptanol, which form a two-phase system upon such dilution.

From these estimates and equations (3), (4) it follows that in drops of aqueous-alcoholic solutions of lactic acid, the chemical equilibrium will be shifted towards the formation of a polymer. The greatest effect can be expected from solutions containing propanol and 2-butanol.

The use of co-solvents partly solves the problem of viscosity and overheating of the reaction medium [16]. For the azeotropic distillation of water from lactic acid solutions, organic substances of different classes can be used [17].

2.2. Experimental observations of polycondensation in sessile drops

Direct monitoring of the physical and chemical processes occurring in the spray is practically impossible. However, microscopic observations of the behaviour of sessile drops obtained by the deposition of a spray on a solid surface provide some notions. The conducted experiments qualitatively confirmed the possibility of obtaining PLA in a spray and also allowed to reveal some kinetic regularities.

The result of the evolution of drops of lactic acid solutions on a hydrophobized glass slide is shown in Fig. 1. The method described in [15] was used. The drops were in the air gap between the glass slides, which reduced the evaporation rate and eliminated convective currents.

In the general case, after the creation of the spray, rapid evaporation of the droplets occurred, then they were covered with a shell slowing down the evaporation. On the surface of large drops, the appearance, growth and movement of folds was noted. These changes indicated the formation of polymeric capsules in which the processes of polycondensation continued.

The surface shell can be a PLA layer or a saturated solution of oligomers [31].

To test this assumption, a layer of distilled water was applied on a glass slide with capsules formed from an aqueous solution of lactic acid (80 wt%). Drops that fell into the distilled water, without dissolving, were destroyed and detached from the slide, and moved around inside the water layer. The state of the system after water evaporation is shown in Fig. 1a. It shows particles wetted with a

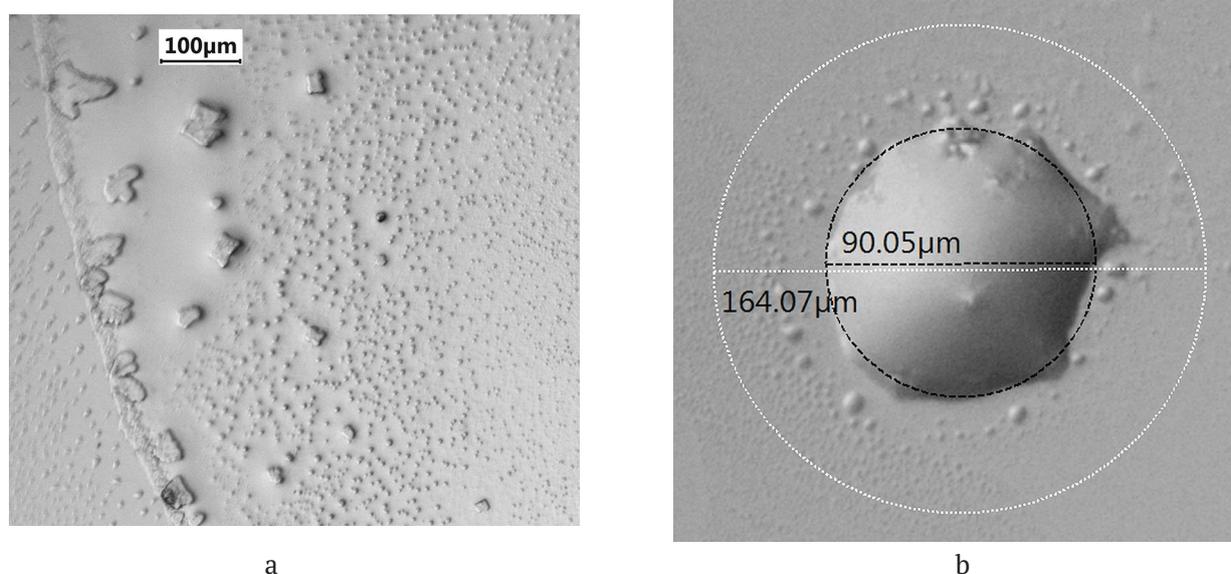


Fig. 1. Structures formed during the destruction of encapsulated drops with distilled water after the evaporation of water (a); the result of the evolution of a large drop of water-alcohol (isopropyl alcohol) lactic acid solution with an indication of the initial and final diameter of the drop (b)

thin layer of non-evaporating solution. The water-insoluble dispersed phase was probably formed by the shells of the destroyed capsules, and the solution surrounding the particles was probably formed by the soluble components (monomer and oligomers) released during the destruction of the capsules. The faceting of individual particles of the dispersed phase (Fig. 1a) shows that the capsule shell was formed either by crystalline PLA or low-soluble oligomers.

The final state of one of the drops of an aqueous-alcoholic solution of lactic acid, prepared by diluting an aqueous solution (80 wt%) with isopropyl alcohol in a ratio of 1 to 2 is shown in Fig. 1b. This state remained unchanged for several days. In the process of evaporation and

polycondensation, in the drop appeared inclusions, and many small non-evaporating drops were detected around it. The formation of a fraction of small drops was observed in experiments with both water-alcohol and aqueous solutions of lactic acid. They originate both in the vicinity of large drops and at a considerable distance from them. The causes and examples of the appearance of such satellite drops are described in [20, 32, 33].

The dynamics of the evaporation of drops of a water-alcohol solution of lactic acid at $t = 23\text{--}25\text{ }^\circ\text{C}$ and humidity $\sim 35\%$ is shown in Fig. 2. The radius of drops was determined based on a sequence of micrographs. The shape of the contact spot of most drops initially differed from round and changed during evaporation;

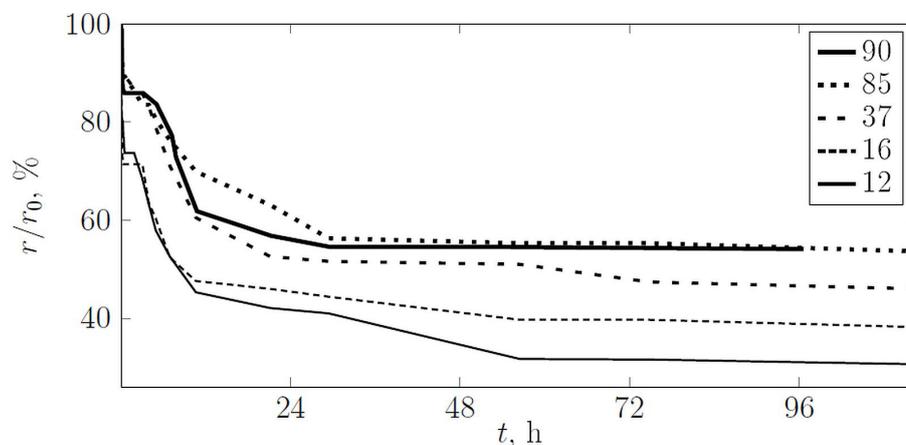


Fig. 2. Dynamics of changes in the relative radius of drops of an aqueous-alcoholic lactic acid solution

therefore, the radius was calculated as half the sum of the maximum and minimum diameters. Normalization of drop sizes by to the initial radius r_0 allows to compare the evaporation rates of drops of different sizes.

The plots shown in Fig. 2 reflect the non-monotonic nature of the process. The evaporation rate was determined based on the change in the drop radius $d(r / r_0) / dt$. The maximal evaporation rate was revealed in the first 5-10 min after the creation of the spray (~ 4%/min). Probably, at this stage, the excess of isopropyl alcohol evaporates, and the solution in drops approaches the azeotrope. After that, the drop sizes stabilized for some time, then decreased again, and the rate increased from zero to ~3%/h. In the last section of the plots, it again asymptotically decreased to 0.

Heterogeneities in the solution, indicating the onset of polycondensation, appeared in large drops 10–15 min after creating the spray. The subsequent decrease in the size of the drops was obviously associated with the processes of polycondensation and azeotropic distillation of the water released in the reaction. The asymptotic slowdown of the processes can be explained by the encapsulation of the drops, which complicated the removal of water, and the increase in conversion.

As can be clearly seen in Fig. 2, the described stages have different durations for large and small drops. In the first minutes, the radius of drops with a radius of 10–20 μm decreased 2 times faster than that of drops with a radius of 40–90 μm . The transition to the asymptotic stage occurred 4–5 h after the creation of the spray for small drops and 5–8 h after the creation of the spray for large drops.

The non-monotonic change of the rate can be explained by the action of at least two reasons:

1. The influence of conversion on the rate of polycondensation. From $x_0 = n_0 / (n_0 + n_{1,\Sigma} - pn_p + n_s)$, where n_0 , n_s , and $n_{1,\Sigma}$ are the number of moles of water, alcohol, and the total number of moles of monomer in a drop, we obtain $n_0 \sim (n_{1,\Sigma} - pn_p + n_s)$. Whence it follows that the increase in conversion (pn_p) and removal of the co-solvent (n_s) during azeotropic distillation leads to a decrease in the amount of water in the drop and, accordingly, to a decrease in its radius.

2. The separation of the solution as a result of the formation and increase in the concentration of low-soluble products (oligomers and polymer). The

core-shell configuration most often occurs in drops as the result of the separation of the solution. In water-organic mixtures, the shell is usually formed by an organic phase with a lower surface tension. A polymer or a concentrated solution of oligomers encapsulate an aqueous solution of low molecular weight components. Encapsulation occurs in experiments with a spray of both aqueous and water-alcohol solutions. The appearance of a new phase should be accompanied by a change in the chemical equilibrium constants (6) from K till K_* , shifting the equilibrium towards PLA formation.

The dependence of water concentration on radius (4) enhances these effects.

The second aspect is also of separate interest. Polymer capsules have many practical applications [34]. For medical applications, it is important that the PLA-coated capsules formed in the spray do not contain catalysts. Their core may contain concentrated aqueous solutions of pharmaceutical dosage forms and biologically active substances added to the spray solution. At the same time, co-solvents partially miscible with water stimulate the formation of capsules even before the polycondensation stage, which allows to control the properties of the shell, taking into account differences in the equilibrium composition of coexisting phases [35].

3. Conclusions

The above theoretical consideration describes the relationship between the equilibrium composition, the volume of condensed phases, the composition of the gaseous medium, and the drop sizes. The performed estimates allowed stating that during the polycondensation of lactic acid solutions in a spray, the chemical equilibrium shifts towards the formation of a polymer and a significant increase in the conversion and the rate of the process are possible.

Size effects increase the conversion and the rate of polycondensation. In particular, the equilibrium concentration of water in drops is lower than in the macrosystem (4), which leads to a shift in the chemical equilibrium towards polymer formation. The recondensation of solvents and reagents stabilizes the temperature of the droplets and the concentrations of the components in them, contributing to the isothermal course of the reaction without overheating of the reaction medium.

The described patterns are reproduced in model experiments with ensembles of sessile drops of aqueous and aqueous-alcoholic solutions of lactic acid. Experiments demonstrate that the polycondensation in a spray of lactic acid solution proceeds without the use of catalysts, heating, and vacuuming. Under the same conditions, the formation of oligomers and PLA do not occur in the macrosystem.

The results of the theoretical consideration and the experiment allowed stating that the spray technology is the basis for the development of an efficient resource-saving production of PLA, including PLA for medical applications.

These regularities are of a thermodynamic nature and should be exhibited in polycondensation processes involving volatile monomers and solvents. They are relevant in the development of new efficient technologies for the production of polymeric materials.

Author contributions

All authors made an equivalent contribution to the preparation of the publication.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

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Structural and magnetic properties of Ho-doped CuFe_2O_4 nanoparticles prepared by a simple co-precipitation method

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Abstract

Nanocrystalline copper (II) ferrite with a spinel structure doped with holmium was synthesized by co-precipitation using an aqueous solution of NaOH as a precipitant and subsequent annealing at 800°C for 60 min. The doping limit was determined by X-ray phase analysis. The similarity of the real and nominal compositions of the doped samples was established by energy-dispersive X-ray spectroscopy using a scanning electron microscope. The obtained particles had an approximately spherical shape, and their size was 40–70 nm (X-ray phase analysis, transmission electron microscopy). The introduction of Ho^{3+} cations to $x = 0.15$ into a CuFe_2O_4 spinel lattice led to a decrease in the average size of crystallites, an increase in the coercive force of nanopowders, and a decrease in excess magnetization and saturation magnetization. Synthesized $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ ($x = 0, 0.1$ and 0.15) nanopowders were magnetically hard materials with high coercive force.

Keywords: CuFe_2O_4 , Ho-doping, Co-precipitation method, Magnetic properties

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1. Introduction

The synthesis and study of the characteristics of nanomaterials now attracts a lot of attention, since nanoparticles possess a set of properties different from those of macrosized analogues [1–5]. Among the magnetic materials, nanocrystalline ferrites with an MFe_2O_4 type spinel structure ($\text{M} = \text{Co}, \text{Ni}, \text{Zn}, \text{Cu}$) are distinguished by high values of magnetic permeability, saturation magnetization, and are used to create new multifunctional materials, such as high-frequency devices, due to a decrease in the energy of Foucault's currents and, accordingly, an increase in the duration of their operation [4, 6–9]. In addition, ferrites with a spinel structure are cheaper and more stable (in time and temperature) compared to metals and alloys.

Ferrites with an MFe_2O_4 spinel structure doped with various metal cations are usually synthesized by methods such as sol–gel technology [6–9], hydrothermal synthesis [10], solid phase reaction [11], or coprecipitation with the addition of organic compounds [12]. The studies [4, 13] describe the features of the formation of nanopowders of ferrites – spinels MFe_2O_4 ($\text{M} = \text{Zn}, \text{Co}, \text{Ni}$) by a simple co-precipitation method via the hydrolysis of cations in boiling water followed by the addition of appropriate precipitants in the absence of surface active substances (SAS). According to literature, CuFe_2O_4 in the form of nanocrystals doped with holmium ($\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$), were not synthesized in a similar way.

Thus, the purpose of this study was the synthesis and investigation of the magnetic properties of nanocrystalline ferrite – copper (II) spinel, doped with holmium, formed by a simple chemical coprecipitation method.

2. Experimental

The starting materials were aqueous solutions of copper (II), iron (III), and holmium (III) nitrates (analytical grade reagents) with molar ratio $\text{Cu}^{2+} : \text{Fe}^{3+} : \text{Ho}^{3+} = 1 : (2-x) : x$ ($x = 0, 0.1, 0.15, \text{ and } 0.2$). An aqueous solution of NaOH was used as a precipitant. An aqueous solution of a mixture of $\text{Cu}(\text{NO}_3)_2 \cdot 3\text{H}_2\text{O}$, $\text{Fe}(\text{NO}_3)_3 \cdot 9\text{H}_2\text{O}$, and $\text{Ho}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ (50 mL) was added dropwise to 450 mL of boiling water with stirring using a magnetic stirrer. After the introduction of salts, boiling was continued for another 10 min, while

the solution acquired a brown-red colour, then the system was cooled to room temperature, and the 5% NaOH solution was added dropwise until the complete precipitation of Cu^{2+} , Fe^{3+} and Ho^{3+} cations similarly to [13–14]. The resulting precipitate was stirred for 60 min and then precipitated within 15 min. After separation on a vacuum filter, the precipitate was washed with distilled water until pH ~ 7.0 was reached and dried at room temperature. Annealing was carried out in a muffle furnace at 800°C for 60 min. Such an annealing regime was chosen based on the results of [13, 15].

The phase compositions of the samples were determined using X-ray phase analysis (XRD, D8-ADVANCE diffractometer, CuK_α -radiation, $\lambda = 1.5406 \text{ \AA}$, $2\theta = 10\text{--}80^\circ$). The average crystal size (D_{av} , nm) of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ samples was calculated using the Scherrer formula.

The shape and size of the particles were determined using transmission electron microscopy (TEM, electron microscope JEM-1400).

The actual qualitative and quantitative elemental composition of the samples was studied by energy dispersive X-ray spectroscopy (EDX) using an FE-SEM S-4800 scanning electron microscope. The quantitative elemental composition was determined as the average of the values obtained at five different points of each sample.

The hysteresis loop and magnetic characteristics of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ ($x = 0, 0.1, 0.15 \text{ and } 0.2$) nanopowders at room temperature, including saturation magnetization (M_s), coercive force (H_c , Oe) and residual magnetization (M_r) were recorded using a Microsene EV11 magnetometer with a vibrating sample under the action of a magnetic field in the range from $-16,000$ to $+16,000$ Oe.

3. Results and discussion

X-ray diffraction patterns of powders of a nominal composition of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ ($x = 0, 0.1, 0.15, \text{ and } 0.2$), obtained by co-deposition after annealing at 800°C for 60 min are shown in Fig. 1. For samples with values $x = 0, 0.1 \text{ and } 0.15$, peaks corresponding to the standard peaks of CuFe_2O_4 spinel phase (JCPDS: 04-001-9258; Copper Iron Oxide) were obtained. On the diffraction pattern of a sample with a nominal degree of doping

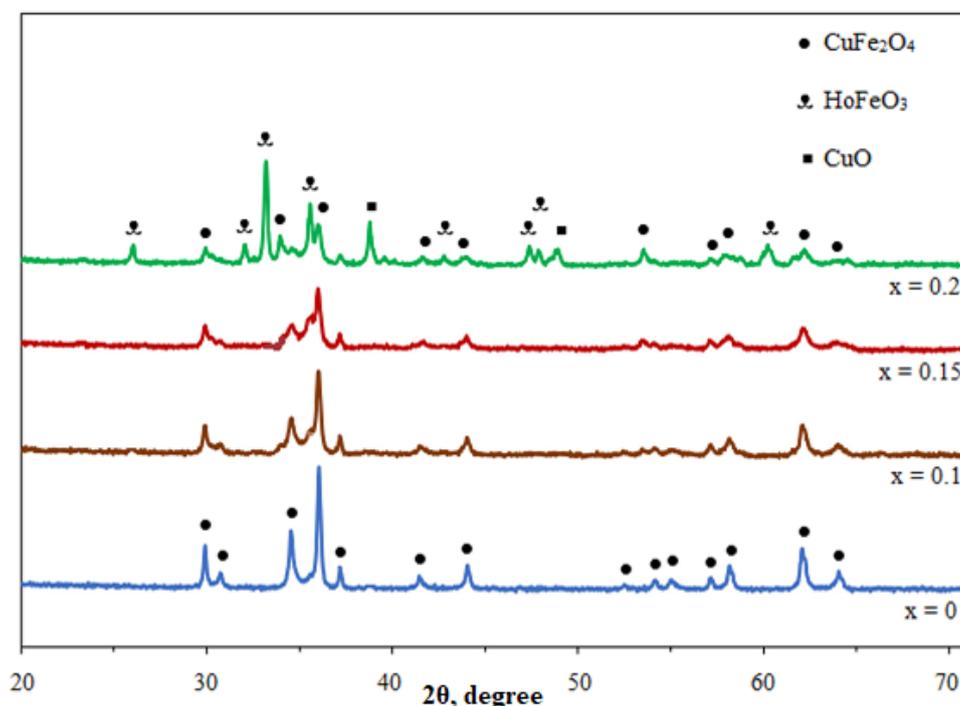


Fig. 1. X-ray diffraction patterns of samples of nominal composition $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ synthesized by co-precipitation after annealing at 800°C for 60 min

$x = 0.2$ in addition to the peaks of the phase with the copper(II) spinel structure CuFe_2O_4 , peaks corresponding to the following phases: CuO (JCPDS: 04-004-5685; Copper Oxide) and HoFeO_3 (JCPDS: 01-084-8725; Holmium Iron Oxide) were revealed.

Thus, according to XRD data, the limit for the doping of ferrite – copper spinel with holmium from $x = 0.15$ to $x = 0.2$ after annealing at 800°C for 60 min was established. The limiting level of doping was due to the difference in the ionic radii of the substituted element and the dopant, the ionic radius Ho^{3+} ($r = 1.04 \text{ \AA}$) was much larger than the ionic radius of Fe^{3+} ($r = 0.65 \text{ \AA}$) [16–17]. An increase in the degree of doping in the CuFe_2O_4 lattice led to a decrease in the value of the angle 2θ for the peak with the highest intensity (Table 1). This once again indicates the

successful doping of copper spinel ferrite with holmium and incorporation of the latter into the CuFe_2O_4 lattice. The analysis of the crystal sizes determined using the Scherrer formula [18] based on X-ray diffractometry data showed a decrease in D_{av} with an increase in the degree of doping of copper ferrite with Ho^{3+} ions from $x = 0$ to $x = 0.15$, followed by an increase at $x = 0.2$ (Table 1). Such an anomaly at $x = 0.2$ could be related to the phase inhomogeneity of the samples when two impurity phases appear (CuO and HoFeO_3) (Fig. 1), which causes an error in the calculation using the Scherrer formula. The reduction of the average crystal size of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ (D_{av}) with an increase in the content of Ho^{3+} cations from $x = 0.0$ to $x = 0.15$ is explained by the fact that the substitution of Fe^{3+} cations ($r = 0.65 \text{ \AA}$) by Ho^{3+} cations with a large ionic radius ($r = 1.04 \text{ \AA}$) causes

Table 1. Characteristics of $\text{CuFe}_{2-x}\text{Ho}_x\text{FeO}_4$ samples synthesized by co-precipitation after annealing at 800°C for 60 min

Samples, nominal composition	$2\theta, ^\circ$	D_{av}, nm	H_c, Oe	$M_r, \text{emu/g}$	$M_s, \text{emu/g}$
CuFe_2O_4	36.0510	54.6	940.72	13.03	23.64
$\text{CuFe}_{1.9}\text{Ho}_{0.1}\text{O}_4$	36.0301	46.2	1320.11	10.81	21.32
$\text{CuFe}_{1.85}\text{Ho}_{0.15}\text{O}_4$	36.0119	37.8	1501.12	9.15	18.29
$\text{CuFe}_{1.8}\text{Ho}_{0.2}\text{O}_4$	35.5868	42.9	1317.82	6.40	13.14

an increase in the defectiveness of the lattice and, accordingly, increased internal stresses, as a result of which the growth of crystals is inhibited. Similar results were observed in the study [19], in which the substitution of Fe^{3+} in the CuFe_2O_4 lattice by doping with Ce^{3+} cations ($r = 1.14 \text{ \AA}$) led to a decrease in the average crystal size from 25.36 to 18.53 nm with a change in x from 0.0 to 0.5.

Determination of the real elemental composition of CuFe_2O_4 and $\text{CuFe}_{1.85}\text{Ho}_{0.15}\text{FeO}_3$ samples showed that peaks were observed only for the elements Cu, Fe, O, and Ho, and their content was very close to the nominal composition. Impurities of other elements were not revealed (Fig. 2).

TEM images of CuFe_2O_4 (A) and $\text{CuFe}_{1.85}\text{Ho}_{0.15}\text{O}_4$ (B), nanopowders annealed at 800°C for 60 min are

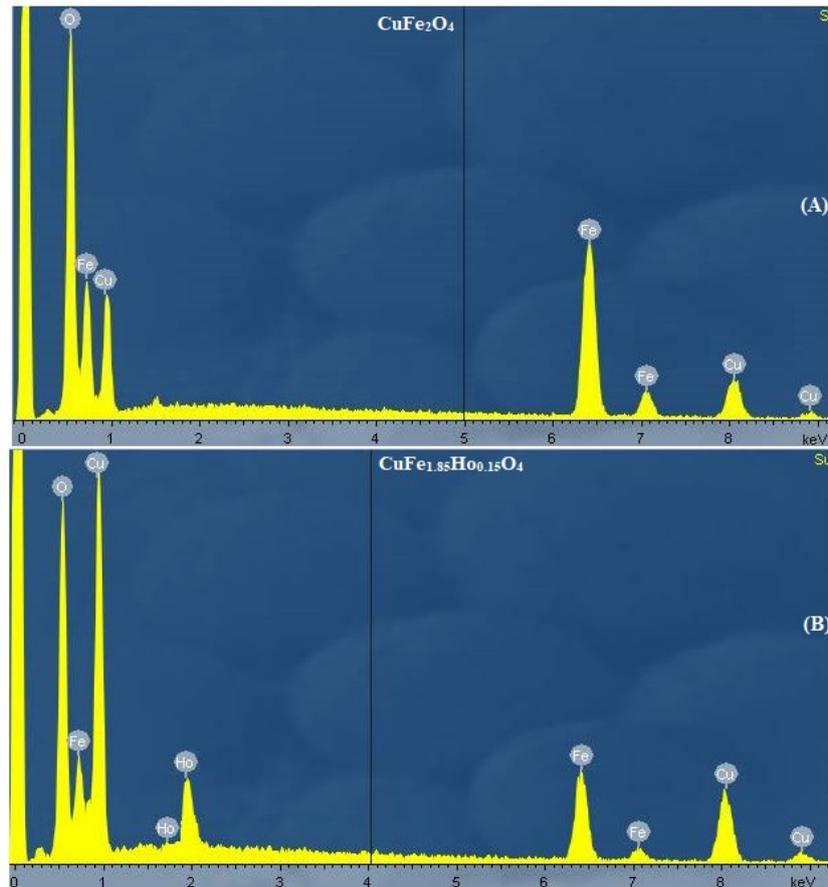


Fig. 2. EDX - X-ray diffraction patterns of CuFe_2O_4 (A) and $\text{CuFe}_{1.85}\text{Ho}_{0.15}\text{O}_4$ (B), samples synthesized by co-precipitation after annealing at 800°C for 60 min

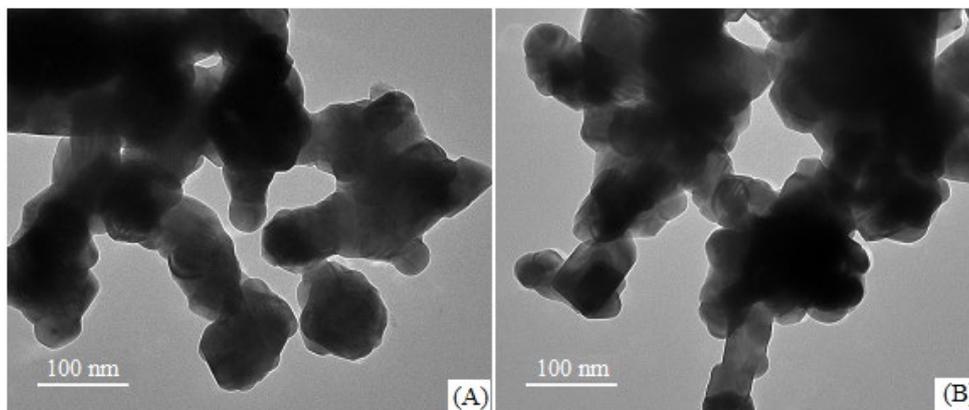


Fig. 3. TEM images of CuFe_2O_4 (A) and $\text{CuFe}_{1.85}\text{Ho}_{0.15}\text{O}_4$ (B), nanoparticles synthesized by co-precipitation after annealing at 800°C for 60 min

shown in Fig. 3. It can be seen that the obtained particles have an approximately spherical shape, and their size was 40–70 nm. The particles were mainly aggregated.

A study of the magnetic characteristics at room temperature showed that the doping of crystal lattice of spinel CuFe_2O_4 with Ho^{3+} affected not only the structural characteristics of crystals, but also the magnetic properties of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ nanopowders (Fig. 4 and Table 1).

Magnetic parameters such as excess magnetization (M_r , emu/g) and saturation magnetization (M_s , emu/g) of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ samples (nominal composition $x = 0, 0.1, 0.15,$ and 0.2) after annealing at 800°C for 60 min decreased with increase in Ho^{3+} content, but the coercive force (H_c , Oe) increased with increase in dopant content. An increase in the coercive force is explained by the fact that an increase in the dopant content in CuFe_2O_4 crystals led to an increase in their magnetic anisotropy [20–21]. Regardless of the dopant content, the synthesized $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ nanopowders had high values of magnetic characteristics: $H_c = 940.72 \div 1501.12$ Oe, $M_r = 13.03 \div 6.40$ emu/g, $M_s = 23.64 \div 13.14$ emu/g, which opens up prospects for their application as

magnetically hard materials for the manufacture of permanent magnets or magnetic recording on hard disks and tapes [20].

4. Conclusions

Ferrite nanopowders $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ ($x = 0, 0.1$ and 0.15) were synthesized by a simple co-precipitation method, using a 5% NaOH aqueous solution as the precipitant. The obtained $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ samples after annealing of the precipitates at 800°C for 60 min had an average particle size of 40–70 nm. Doping limit of spinel ferrite CuFe_2O_4 with Ho^{3+} was detected at a nominal value of $x = 0.15$. The reduction of the average size (D_{av}) of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ crystals with an increase in the content of Ho^{3+} cations from $x = 0.0$ to $x = 0.15$ is explained by the fact that the substitution of Fe^{3+} cations ($r = 0.65 \text{ \AA}$) by Ho^{3+} cations with a large ionic radius ($r = 1.04 \text{ \AA}$) causes an increase in the defectiveness of the lattice and, accordingly, increased internal stresses, as a result of which the growth of crystals is inhibited. Synthesized $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ nanoparticles are characterized by higher values of the coercive force and excess magnetization and, accordingly, are magnetically hard materials.

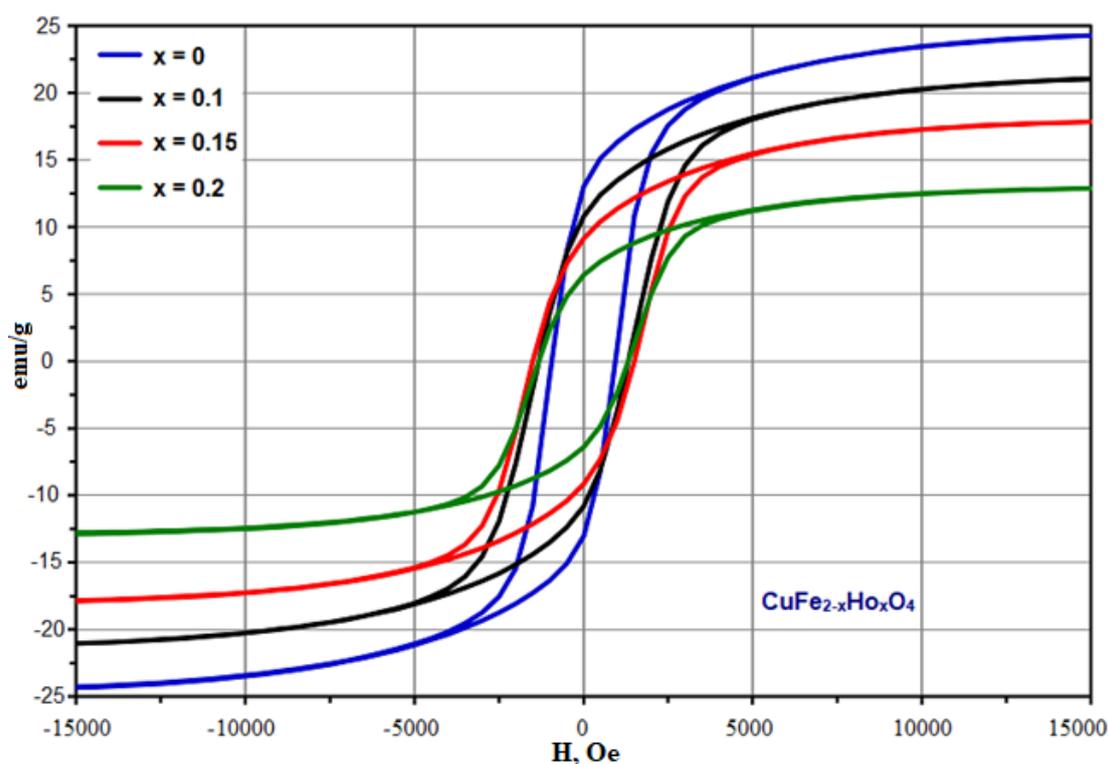


Fig. 4. Field dependences of the magnetization of $\text{CuFe}_{2-x}\text{Ho}_x\text{O}_4$ nanopowders synthesized by co-precipitation after annealing at 800°C for 60 min

Author contributions

The authors contributed equally to this article.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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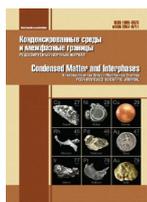
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Original articles

Research article

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Investigation of the effect of a multicomponent additive on the structure formation and hardening of cement composites

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Abstract

The development and application of multicomponent multifunctional additives for cement composites is an important research area since the use of such additives allows controlling both the rheological properties of the freshly prepared mixture and the physical and mechanical characteristics of the finished composite.

This work proposes to use a multicomponent multifunctional additive with the composition of “SiO₂ nanoparticle - superplasticiser - polypropylene fibre” for the modification of cement composite materials based on sand and chalky flour. We studied the peculiarities of the influence of this additive on the technological characteristics of mixtures (plasticity and form stability) and the processes of setting-up, hydration, structure formation, and strength gain of the composite materials.

It was shown that the introduction of this additive allows increasing the plasticity limit and structural strength and reducing relative plastic deformations of the cement mixture at the manufacturing stage. At the same time, this additive accelerates the processes of setting-up, hydration, and strength gain of cement composites. It was proved that the increase in strength is due to the formation of a dense structure of hydrated new growths of the cement substance formed by phases of low and highly basic calcium silicate hydrates of various compositions and morphologies, as well as the absence of a portlandite phase.

The optimal ratio of indicators of plasticity and form stability of cement mixtures and the strength of composites based on them obtained by using the studied additive allows us to recommend to use this additive in the innovative construction 3D printing technology.

Keywords: Cement hardening systems, Modification, Structure formation, Multifunctional additives, Rheological characteristics, Compressive strength

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1. Introduction

The emergence and development of new construction technologies, such as the construction of unique high-rise buildings and structures and construction 3D printing, requires improving existing and creating new cement-based composite materials with a set of specific properties. Therefore, during the initial stage, the freshly prepared mixture should have specified fabricability indicators. In particular, for the innovative 3D printing process, of fundamental importance are such fabricability indicators as plasticity, form stability, and accelerated setting-up times which are required to create a structure using off-form additive manufacturing. What is more, resulting composite material must have high physical and mechanical properties (density, compressive strength, bending strength, frost resistance, etc.) to ensure the standard service life of the constructed building or structure.

To create such composite materials, it is necessary to control the formation of their structure in a targeted manner at each scale (micro, ultramicro, and nano) [1], and, accordingly, at each stage of the evolutionary route of the solid phase formation in the cement hardening system: phase nucleation, growth of particles, their agglomeration and spontaneous structure formation [2]. A variety of existing formulation and technological factors (chemical and mineralogical composition of the initial components, the ratio of the mass of water to the mass of cement, mechanical and chemical activation of the binder, mixing conditions and modes, and the use of chemical additives, in particular, nanoadditives) allows controlling the formation of the structure of the cement hardening system at different scales (from nano to micro) [3].

The simplest and most accessible factor for controlling the structure of a cement composite is the use of chemical additives of various nature (inorganic and organic), morphology, and dispersion. Most often, active mineral additives are used as inorganic additives, for example, microsilica, microalumina, and metakaolin [4], as well as chemically synthesised products, for example, calcium nitrate, nitrite, and chloride, sodium silicate, ammonium chloride [5], etc. Various surface-active substances, in particular super- and hyperplasticisers, are typical

representatives of organic additives [5, 6]. In addition, to improve the physical and mechanical properties of cement composites, disperse reinforcing components such as polypropylene, glass, basalt, or steel fibres are being used more often [7–9].

The above mentioned individual additives are involved in the structural formation of cement hardening systems at various scales and therefore have a selective effect on the properties of the cement composite. In this regard, it is relevant to study the use of multicomponent multifunctional additives which include inorganic, organic, and micro-reinforcing components in their composition, which will determine the multifunctionality and additivity of their action when obtaining the resulting composite.

To ensure the maximum efficiency of a multicomponent additive, it is necessary to select an inorganic component in accordance with the conditions of molecular, morphological, and topological selection [10]. This means that the crystal-chemical structure of the component particles should be close to those of the cement clinker minerals, which will allow them to form the optimal crystal structure of the material (denser, with fewer pores and voids). For cement hardening systems, amorphous silicon dioxide-based additives will meet these conditions. This is confirmed both by the literature data [11–15] and the results of our own studies [16, 17]. At the same time, the dispersion of SiO_2 particles, which are a part of multicomponent additives, can be different (micro-, ultra-, and nano-). It should be noted that nanosized SiO_2 particles influence the formation of the structure of cement hardening systems during the nucleation stage of the solid phase particles (nanoscale). It is advisable to use a superplasticiser as an organic component of the additive, which will prevent the growth and agglomeration of SiO_2 particles and will solve the complex technological problem of their uniform distribution in the volume of the cement system [16]. Thus, the action of the superplasticiser will manifest itself at the ultrascale level of the formation of the composite structure. Various types of fibres can be used as a micro-reinforcing component, which will contribute to the additional strengthening of the cement composite at the microscale level by preventing

the propagation of cracks formed in the process of the spontaneous structure formation.

In this paper, we propose to use a multi-component multifunctional additive of the following composition: “nanosized SiO₂ particles – superplasticiser – polypropylene fibre” for the modification of cement composites. Previously, in our own studies [16], we found that the addition of the composition “nanosized SiO₂ particles – superplasticiser” has a positive effect on the processes of hydration, structure formation, and strength gain of cement systems without fillers and aggregates.

Thus, the purpose of this work was to study the effect of a multicomponent multifunctional additive of the composition “nanosized SiO₂ particles – superplasticiser – polypropylene fibre” on the rheological characteristics and the processes of setting-up, hydration, structure formation, and strength gain of cement composite materials based on quartz sand and chalky flour.

2. Experimental

For experimental studies, modified cement systems were obtained. Their initial components were Portland cement (C), grade CEM I 42.5 (GOST 31108-2016), process water (W) (GOST 23732-2011), superplasticiser (SP) based on polycarboxylate esters, grade Sika® ViscoCreat® T100. Chalky flour (CF) containing at least 95% of CaCO₃ (GOST 32761-2014) was used as a filler. The particle size of chalky flour was between 2 and 55 μm. Quartz sand (S) with a fineness modulus $M_f \leq 1.25$ (GOST 8736-2014) was used as an aggregate.

As a modifier, we used a complex nano-sized additive (CNA) with the composition of SiO₂ particle – SP, Sika® ViscoCreat® T100 ($\omega(\text{SiO}_2) = 0.01\%$, $\omega(\text{SP}) = 0.2\%$ of the mass of cement) with an average particle size of SiO₂ between 5 and 10 nm obtained by sol-gel synthesis using the procedure described in detail in [10]. It should be noted that this modifier was a mixing liquid. A 12 mm long polypropylene fibre (PF), brand SikaFiber® PPM-12 (ISO 9001:2008, EN 14889-2:2008), was used as a reinforcing component. Its content was 0.5% of the mass of cement. To obtain a multicomponent multifunctional additive, the required amount of superplasticiser was added to the mixing liquid

and thoroughly mixed. Next, a polypropylene fibre was added to the resulting solution and mixed again.

Cement systems with the composition C–W–SP–CNA–S, C–W–SP–CNA–S–PF, C–W–SP–CNA–CF, and C–W–SP–CNA–CF–PF were obtained by mixing dry components (cement, sand or cement and chalky flour) and the resulting multi-component multifunctional additive in a mixer for 3 minutes. When obtaining viscoplastic mixtures, the mass ratios of C:CF and C:S were 1:1 and 1:1.25, respectively. The water-cement ratio (the ratio of the mass of water to the mass of cement – formulation and technological parameter, W/C) in systems with sand was 0.26, and in systems with chalky flour was 0.37. These ratios are optimal and were determined experimentally from preliminary studies. The C–W–SP–CNA system (W/C = 0.24) was recognised as a reference system.

The rheological behaviour of the obtained viscoplastic mixtures was evaluated by the methods of compressive rheometry [18–20]. To conduct compression tests, we used cement-water paste to make cylinder samples with the radius R equal to their height $h_0 = 25$ mm. The tests were carried out using the INSTRON 5982 universal floor hydraulic testing system.

To assess the plasticity of mixtures, the compression test was performed at a constant strain rate of 5 mm/s [18]. The curves “load N – displacement Δ ” obtained as a result of testing were interpreted as dependencies of the reduced load F^* on the relative change in sample height h_i/R :

$$F_i^* = \frac{Ph_i}{\pi R^2},$$

where $h_i = (h_0 - \Delta)$, h_0 is the initial height of the sample, Δ is the displacement at the i -th moment of time, the value R was taken as a constant equal to the sample radius at the beginning of the test.

At the first points of inflexion of the obtained experimental curves, the estimate of the plastic yield value $K_i(I)$ was calculated:

$$K_i\left(\frac{h}{R}\right) = \frac{\sqrt{3}}{2} F^*.$$

To assess the form stability, a compression test was performed at a constant load rate of

$v = 0.5$ N/s [19, 20]. As a result of experimental studies, we obtained the following curves “relative displacement Δ – time t ”, “load N – relative displacement Δ ”, which were used to calculate the values of the structural strength of cement systems at the moments corresponding to the beginning of deformation and the beginning of cracking of the samples according to the formula:

$$\sigma = \frac{P}{\pi R^2}.$$

As a result, the plasticity and form stability of mixtures under conditions simulating the action of compressive stresses during extrusion and layering were evaluated by the following criteria:

- Estimation of plastic yield value $K_i(I)$.
- Structural strength σ_0 at the beginning of deformation, which is responsible for the ability of the system to resist deformation under load.
- Plastic strength σ_{pl} and the value of relative plastic deformations Δ_{pl} at the beginning of cracking. They characterise the ability of the system to deform without destruction.

It should be noted that the optimal values of the plasticity and form stability criteria for viscoplastic cement mixtures were determined in [20] and were: $K_i(I) = 1.0$ – 2.5 kPa, $\sigma_0 = 3$ – 5 kPa, $\sigma_{pl} = 30$ – 40 kPa, $\Delta \leq 0.05$ mm/mm.

The kinetics of setting-up of the resulting viscoplastic systems was studied by the penetrometer method [21]. Value P_{pl} was calculated as the reduced value of penetration resistance:

$$P_{pl} = \frac{4N}{\pi d^2},$$

where N is penetration resistance of the mixture when a plunger with a standard diameter is immersed to a depth of 5 mm, kN; d is the plunger diameter, mm. The method error was 10%.

The phase composition of the cement brick was determined by powder diffraction (ARL X'TRA diffractometer, CuK_α is radiation, $\lambda = 1.541788$ Å). The obtained data were processed using the PDWin 4.0 software package [22]. The value of the degree of hydration of the modified cement hardening systems was calculated by the content of the alite phase $3\text{CaO} \cdot \text{SiO}_2$ (C_3S) by comparing their XRD patterns with the XRD pattern of the original cement clinker [23]:

$$D_h(\text{C}_3\text{S}) = \left(1 - \frac{I_{\text{mod}}}{I_0}\right) \times 100\%.$$

where I_{mod} is the intensity of the diffraction maximum at $d = 2.75$ Å of the C_3S phase of the samples of different compositions by types of additives and the timing of cement hydration; I_0 is the intensity of the diffraction maximum at $d = 2.75$ Å of the C_3S phase of the original cement.

The microstructure of the cement brick was assessed using scanning electron microscopy (SEM) (JEOL JSM-7001F scanning electron microscope).

The kinetics of the strength gain of the studied cement hardening systems was determined by the destruction of sample cubes with the size of $5 \times 5 \times 5$ cm using an INSTRON Sates 1500HDS testing machine. To ensure the statistically reliable results of physical and mechanical tests, the number of samples in the series was 6. The measurement uncertainty was 0.5%.

3. Results and Discussion

3.1. Plasticity and form stability of modified systems

Figure 1 shows the curves of the dependence of the reduced load F^* on the relative change in sample height h/R .

The studied cement systems were characterised by two types of curves. The C–W–SP–CNA–P, C–W–SP–CNA–S–PF, and C–W–SP–CNA–CF systems had a horizontal section between two points of inflexion, which is characteristic of viscoplastic fluid before the destruction of the structure. The curves of the C–W–SP–CNA–P and C–W–SP–CNA–CF–PF systems were almost horizontal and did not have a pronounced plasticity region. In this case, the value of the plastic yield value $K_i(I)$ (Table 1) for the system with quartz sand, compared to the reference system, increased by 2.3 times, while in the system with carbonate flour it decreased by 1.6 times. In microreinforced cement systems, the plasticity limit values increased by 2.6 times in the C–W–SP–CNA–S–PF system, and by 1.1 times in the C–W–SP–CNA–CF–PF system.

As a result of the experimental investigation of form stability of the studied systems two types of curves were obtained: “relative displacement Δ – time t ” (Fig. 2a) and “relative displacement –

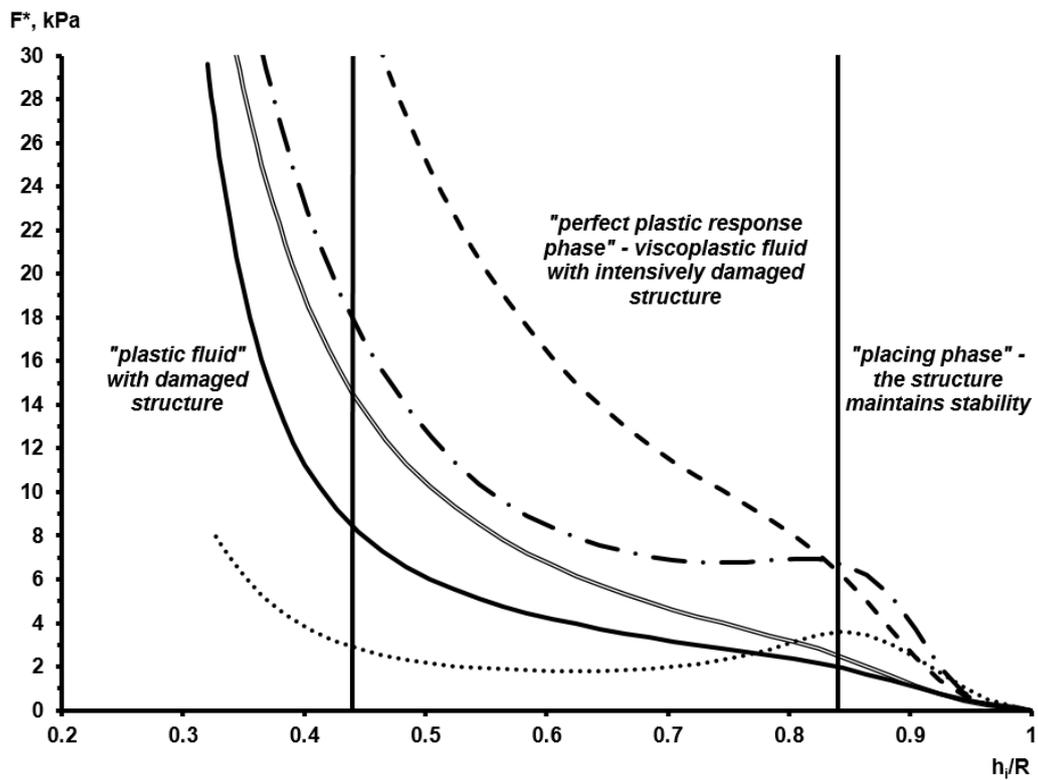


Fig. 1. Curves of the dependence of the reduced load F^* on the relative change in sample height h_i/R . Designated: — C-W-SP-CNA; C-W-SP-CNA-S; --- C-W-SP-CNA-S-PF; -.-.- C-W-SP-CNA-CF; =- C-W-SP-CNA-CF-PF

Table 1. Rheological characteristics of modified cement systems

System	Plastic yield value $K_i(I)$, kPa	Structural strength σ_0 , kPa	Plastic strength σ_{pl} , kPa	Relative plastic deformation Δ_{pl} , mm/mm
C-W-SP-CNA	1.42	1.64	41.20	0.13
C-W-SP-CNA-S	3.28	1.17	57.80	0.07
C-W-SP-CNA-S-PF	3.66	5.44	26.75	0.03
C-W-SP-CNA-CF	0.90	1.43	42.48	0.14
C-W-SP-CNA-CF-PF	1.54	3.04	40.75	0.07

load σ (Fig. 2b). The first type of curves was characterised by three sections: the “phase stability”, which characterised the absence of deformations under loads; “plastic phase”, which characterised the ability of the system to deform without destruction, and “cracking phase”, in which cracking occurred before the complete destruction of the structure. On the “relative displacement – load σ ” curves, the moment when microcracks appeared in the systems corresponded to a sharp drop in the load.

The analysis of the obtained results allowed establishing that the studied systems had form

stability indicators (σ_0 , σ_{pl} , Δ_{pl} Table 1) close to optimal [20].

At the same time, the C-W-SP-CNA-CF-PF and C-W-SP-CNA-S-PF systems had the highest structural strength. In these systems, the values of σ_0 increased by 2.1 and 4.6 times, respectively, compared to the same systems without fibre. It should be noted that the values of maximum structural strength and minimum plastic deformations were achieved in the C-W-SP-CNA-S-PF system and were 5.44 kPa and 0.03 mm/mm, respectively.

The effect of CNA on the rheological behaviour of the studied systems was that nanosized SiO_2

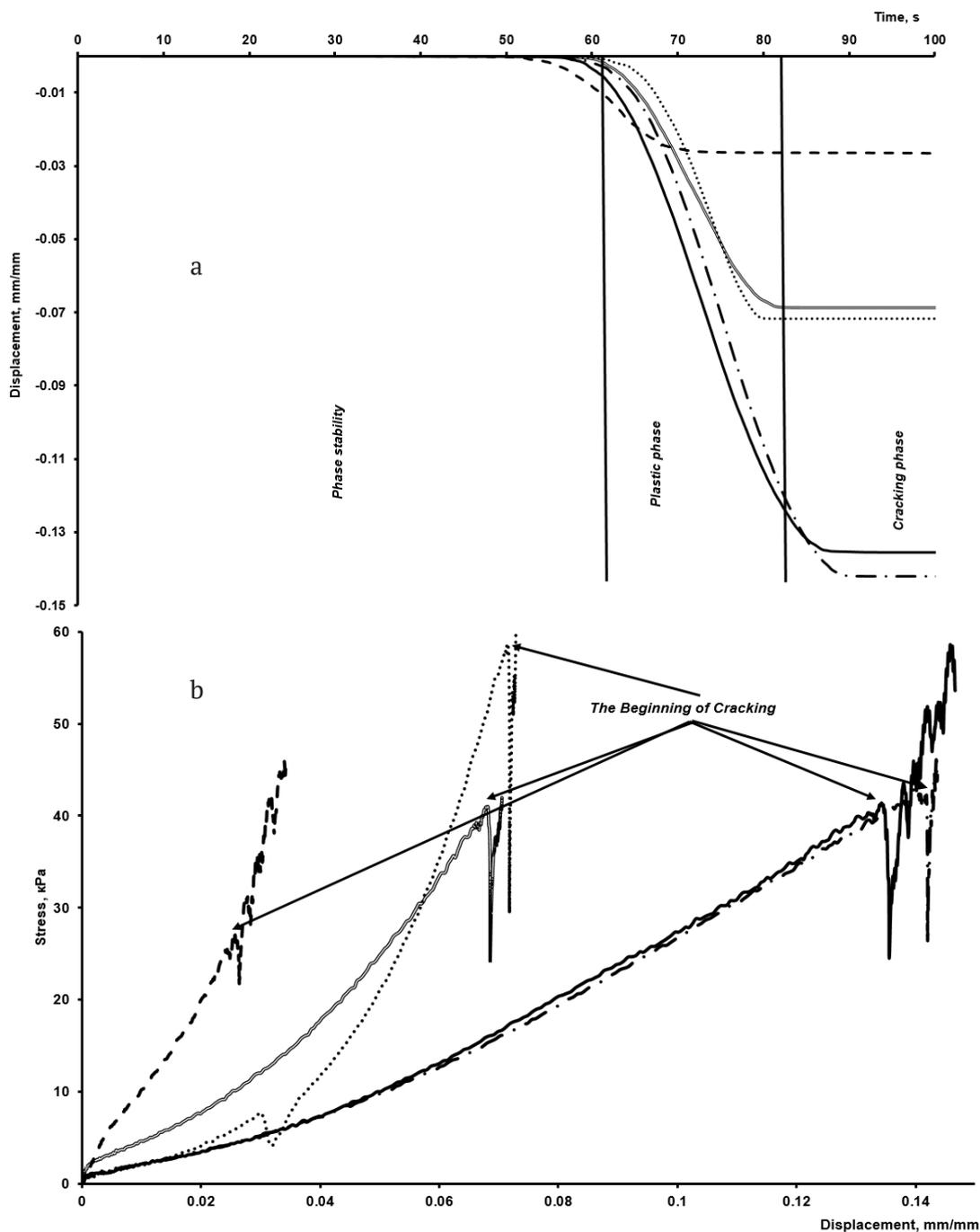


Fig. 2. Dependence curves a) “relative displacement Δ – time t ”; b) “load σ – relative displacement Δ ”. Designated: — C–W–SP–CNA; •••• C–W–SP–CNA–S; - - - C–W–SP–CNA–S–PF; - · - · - C–W–SP–CNA–CF; = = = C–W–SP–CNA–CF–PF

particles contributed to the intensification of the processes of dissolution and hydration of clinker minerals, which could result in the increase of the ionic strength of the disperse medium, which would lead to its destruction and a partial decrease in the structural strength of the cement system. At the same time, the superplasticiser

which was part of the CNA, due to mono- and polymolecular adsorption on the surface of cement clinker particles reduced their interfacial energy, which resulted in their dispersion. In this case, part of the immobilised water was released, which provided for an increase in the plasticity of the mixture and, accordingly, a slight decrease in

structural strength. Obviously, the polypropylene fibre provided cement systems with additional rigidity, which led to a decrease in their plasticity, an increase in structural strength, and a decrease in relative plastic deformations.

It should be noted that the rheological characteristics of the studied cement systems were affected not only by the used CNA but also by the type and dispersion of the components used as aggregates and fillers. Quartz sand and chalky flour used in the work are substances of a polyfraction composition which differ in their crystal-chemical nature and dispersion. Due to the relatively large size of its particles, quartz sand located between the grains of cement clinker created a denser spatial packing of solid phase particles, which led to an increase in the rigidity of the cement system. Chalky flour helped to reduce the plastic yield value and, accordingly, the aggregative stability of cement systems. This was due to the fact that, firstly, its particles have a smaller size compared to sand. Secondly, these particles have a sufficiently active surface and are capable of forming polymolecular layers of adsorbed water, which leads to an increase in the plasticity of the cement system.

Thus, in terms of plasticity and form stability, the nanomodified cement system with chalky flour was quite plastic and prone to flow, whereas the nanomodified cement system with quartz sand was more rigid. It should be noted that the introduction of a polypropylene fibre allowed increasing the plastic yield value ($K_i(I)$) by 1.1 and 2.6 times and structural strength (σ_0) by 2.1 and 4.6 times and reducing relative plastic deformations (Δ_{pl}) by 2 and 2.3 times in the systems with quartz sand and chalky flour, respectively. The acceptable values of the plasticity and form stability criteria ($K_i(I) = 1.54$ kPa, $\sigma_0 = 3.04$ kPa, and $\Delta_{pl} = 0.07$ mm/mm) were achieved in the C-W-SP-CNA-CF-PF system.

3.2. Kinetics of early structure formation of modified cement hardening systems

According to the obtained results (Fig. 3), the beginning of the setting-up process of the studied cement hardening systems varied between 105 and 210 minutes.

The process of setting-up proceeded most rapidly in the C-W-SP-CNA-CF-PF and C-W-SP-CNA-S-PF systems. Values of plastic strength of 582–585 kPa corresponding to the beginning of setting-up were achieved in these systems

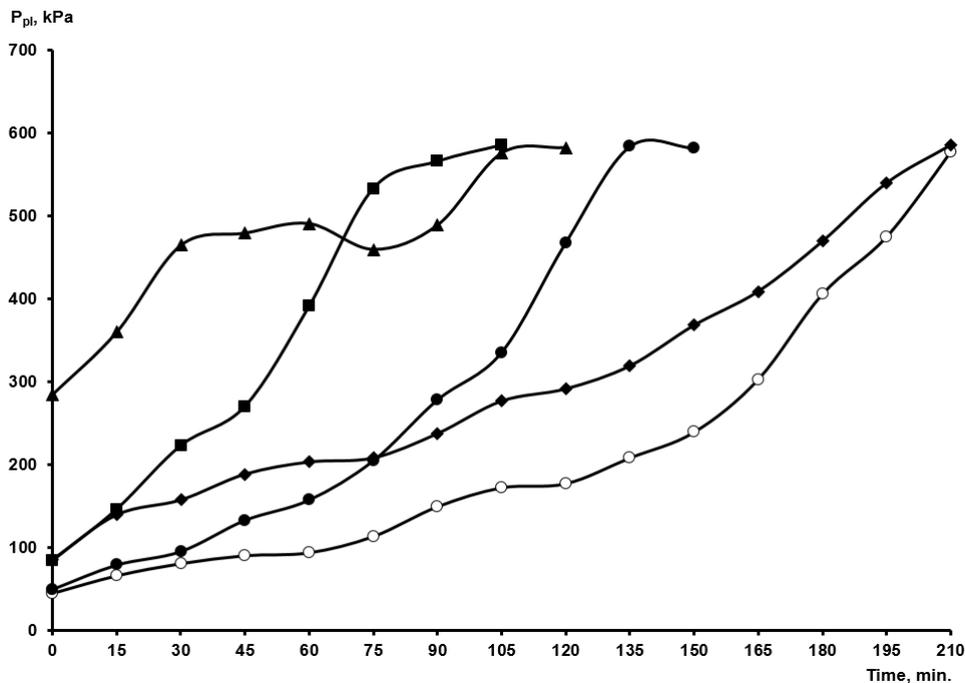


Fig. 3. Curves of the dependence of plastic strength of the studied cement hardening systems on time. Designated: ○ – C-W-SP-CNA; ◆ – C-W-SP-CNA-S; ▲ – C-W-SP-CNA-S-PF; ● – C-W-SP-CNA-CF; ■ – C-W-SP-CNA-CF-PF

within 105 and 120 minutes, respectively. In the C–W–SP–CNA–CF system, similar values of P_{pl} were achieved after 150 minutes, and in the C–W–SP–CNA and C–W–SP–CNA–S systems, they were reached after 210 minutes.

The influence of CNA on the setting-up processes of cement systems was determined by the combined action of its constituent components. For example, the superplasticiser helped to increase the plasticity of cement systems. The mechanism of action was discussed above. At the same time, nanosized SiO_2 particles, due to their high values of surface energy, also acted as ready-made crystallisation centres and chemically could be directly involved in heterogeneous processes of phase formation of hydrated compounds. At the same time, in combination with the effect of the polypropylene fibre, this led to an increase in the values of plastic strength and acceleration of setting-up processes.

It should be noted that the setting-up processes proceeded most rapidly in the nanomodified system with chalky flour, whereas the system based on quartz sand had lower values

of plastic strength regardless of the presence of the polypropylene fibre in the system. This was probably due to the fact that the finer grain size of chalky flour allowed obtaining the maximum possible packing density of the particles of the dispersed phase under the given conditions, which, in combination with the CNA effect, contributed to the acceleration of the setting-up process of the cement hardening system.

3.3. Phase composition and microstructure of the studied systems

According to X-ray diffraction analysis (Table 2), after 28 days of hardening, the studied systems were characterised by rather high values of hydration degrees (D_h), from 88 to 93%. The highest value of D_h (93%) was achieved in the C–W–SP–CNA reference system.

In cement systems with quartz sand, the dominant phase was quartz (SiO_2), and in systems with chalky flour, it was calcium carbonate (CaCO_3) (Fig. 4, Table 2). The main hydrate phases in the reference and quartz sand systems were low and highly basic calcium silicate hydrates

Table 2. Phase composition and degree of hydration of the studied cement systems (duration of hardening 28 days)

System	D_h , %	Phase composition
C–W–SP–CNA	93	$(\text{CaO})_x \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ $x\text{CaO} \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $2\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$
C–W–SP–CNA–S	89	SiO_2 $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $2\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $(\text{CaO})_x \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ $x\text{CaO} \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$
C–W–SP–CNA–S–PF	90	SiO_2 $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $2\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $(\text{CaO})_x \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ $x\text{CaO} \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$
C–W–SP–CNA–CF	88	CaCO_3 $3\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $3\text{CaO} \cdot \text{Al}_2\text{O}_3 \cdot \text{CaCO}_3 \cdot 11\text{H}_2\text{O}$ $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$
C–W–SP–CNA–CF–PF	88	CaCO_3 $3\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ $3\text{CaO} \cdot \text{Al}_2\text{O}_3 \cdot \text{CaCO}_3 \cdot 11\text{H}_2\text{O}$ $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$

$(\text{CaO})_x \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$, $x\text{CaO} \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$, $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$, and $2\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$.

The phase composition of cement systems with chalky flour was represented by low and highly basic calcium silicate hydroxides ($3\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ and $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$, respectively), as well as a small amount of the calcium hydrocarboaluminate phase $3\text{CaO} \cdot \text{Al}_2\text{O}_3 \cdot \text{CaCO}_3 \cdot 11\text{H}_2\text{O}$.

Therefore, the type of aggregate and filler did not affect the degree of hydration of the studied systems, however, they had a significant effect on the phase composition of hydration products. Due to its inertness, quartz sand did not take part in the reactions of hydration and the formation of new growths of the cement brick, whereas chalky flour, due to the relatively active surface of its particles, was able to partially participate in heterogeneous processes of phase formation resulting in the formation of the $3\text{CaO} \cdot \text{Al}_2\text{O}_3 \cdot \text{CaCO}_3 \cdot 11\text{H}_2\text{O}$ compound. It should be noted that calcium carbonate is able to interact with the aluminate component of Portland

cement clinker provided that there is an excess of calcium ions.

It should be noted that the portlandite phase ($\text{Ca}(\text{OH})_2$) was absent in all of the studied systems. This was probably due to the fact that nanosized SiO_2 particles are capable of exhibiting a pozzolanic effect: due to their size and high surface energy, they are able to bind free calcium hydroxide into low and highly basic calcium silicate hydrates. In this case, free $\text{Ca}(\text{OH})_2$ can be formed in the studied systems in two cases: as a result of the alite hydration reaction (both in systems with quartz sand and in systems with chalky flour) and as a result of the formation of calcium hydrocarboaluminate (in systems with chalky flour). Then, the following chemical transformations take place:

1) *dissolution and hydration of alite and tricalcium aluminate:*

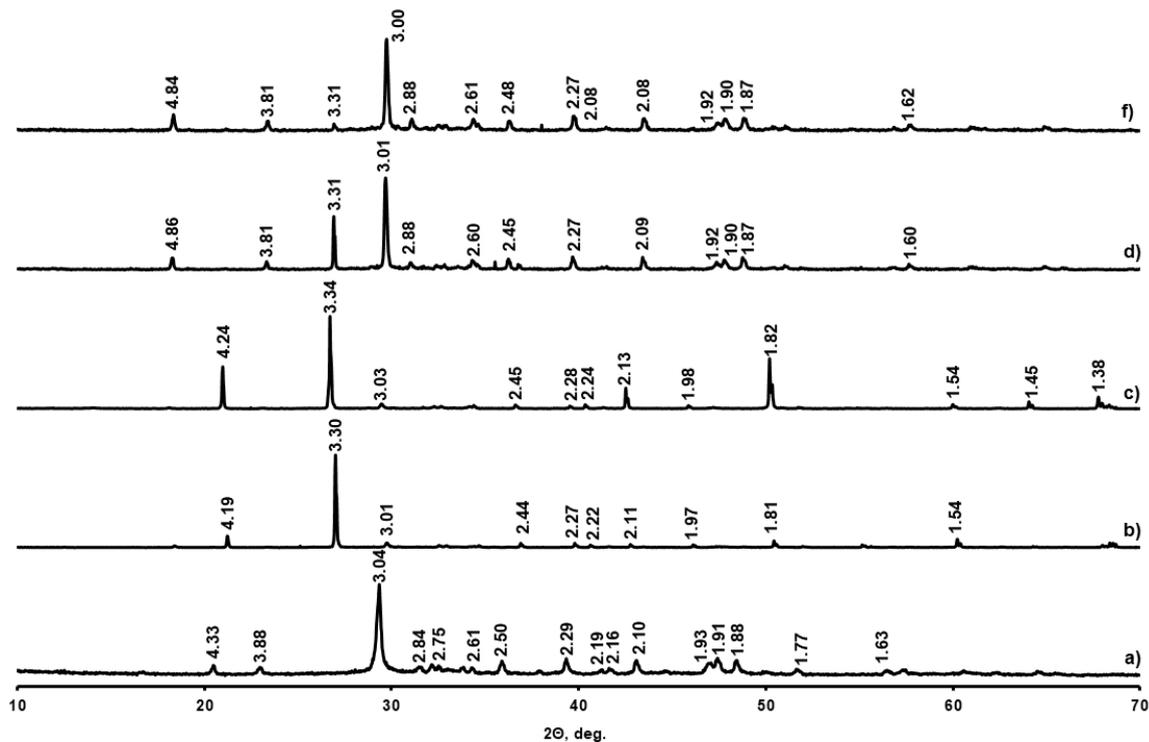
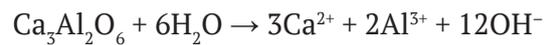
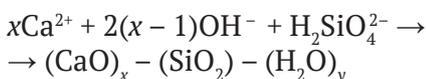
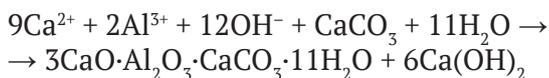


Fig. 4. X-Ray diffraction patterns of the studied cement hardening systems. Designated: a) C–W–SP–CNA; b) C–W–SP–CNA–S; c) C–W–SP–CNA–S–PF; d) C–W–SP–CNA–CF; e) C–W–SP–CNA–CF–PF SiO_2 ($d = 4.25, 3.35, 2.45, 1.82, 1.38 \text{ \AA}$); CaCO_3 ($d = 3.34, 3.03, 2.28, 2.07, 1.59 \text{ \AA}$); $(\text{CaO})_x \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ ($d = 3.05, 2.93, 2.31, 1.67, 1.62 \text{ \AA}$); $x\text{CaO} \cdot \text{SiO}_2 \cdot z\text{H}_2\text{O}$ ($d = 3.06, 2.80, 2.65, 2.14, 2.06 \text{ \AA}$); $\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ ($d = 4.24, 3.01, 2.78, 2.50, 1.89 \text{ \AA}$); $2\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ ($d = 2.92, 2.75, 1.93, 1.86, 1.75 \text{ \AA}$); $3\text{CaO} \cdot \text{SiO}_2 \cdot \text{H}_2\text{O}$ ($d = 3.26, 3.01, 2.88, 2.47, 2.08 \text{ \AA}$); $3\text{CaO} \cdot \text{Al}_2\text{O}_3 \cdot \text{CaCO}_3 \cdot 11\text{H}_2\text{O}$ ($d = 3.78, 2.85, 2.52, 2.34, 2.09 \text{ \AA}$)

2) *formation of calcium hydrocarboaluminate and low and highly basic calcium silicate hydrates:*



The X-ray diffraction data correlated with the SEM data (Fig. 5).

In all studied systems, a sufficiently dense structure was formed with a large number of coalescence and intergrowth contacts between crystallites. What is more, the reference system C–W–SP–NA was characterised by the formation of a predominantly amorphous-crystalline structure from a loose tobermorite-like gel (Fig. 5a). The microstructure of cement systems with sand and chalky flour (Fig. 5b, c) was more crystallised and was represented by crystallites of acicular and fibrous morphology, which probably belonged to low and highly basic calcium silicate hydroxides. In addition, lamellar crystallites adjoining each other were present in the C–W–SP–CNA–CF system (Fig. 5c). Most likely, they were formed by calcium hydrocarboaluminate.

3.4. Kinetics of the strength gain of the studied systems

Physical and mechanical testing of compressive strength showed that after 28 days of hardening, all systems had sufficiently high strength characteristics (Table 3, Fig. 6): $R_{\text{com}} = 82\text{--}93$ MPa. What is more, the C–W–SP–

CNA reference system had the highest indicator of compressive strength both on the 1st and 28th day of hardening.

With the introduction of an aggregate (quartz sand) and a filler (carbonate flour) into the cement hardening system, its strength, as was to be expected, decreased slightly. The polypropylene fibre, which is part of a multicomponent multifunctional additive, as was to be expected, increased their strength. Additionally, at the early stages of hardening (days 1 and 3), regardless of the presence of a polypropylene fibre in the cement system, the system with chalky flour had the lowest values for compressive strength. On day 7 and during the remaining hardening time, regardless of the type of filler, the systems were characterized by close values of R_{com} .

It should be noted that for some systems a drop in strength was observed on the kinetic curves of strength gain (Fig. 6). In the C–W–SP–CNA reference system, it occurred on the 7th day of hardening, and in the C–W–SP–CNA–S and C–W–SP–CNA–CF systems it was observed on the 14th day of hardening. This behaviour of the systems was probably associated with the recrystallisation of primary hydrate formations. However, there was no drop in strength in the C–W–SP–CNA–S–PF and C–W–SP–CNA–CF–PF systems, which was probably due to the presence of the polypropylene fibre in their composition, which contributed to additional strengthening of the systems and compensated the decline in strength that occurred on the 14th day of hardening.

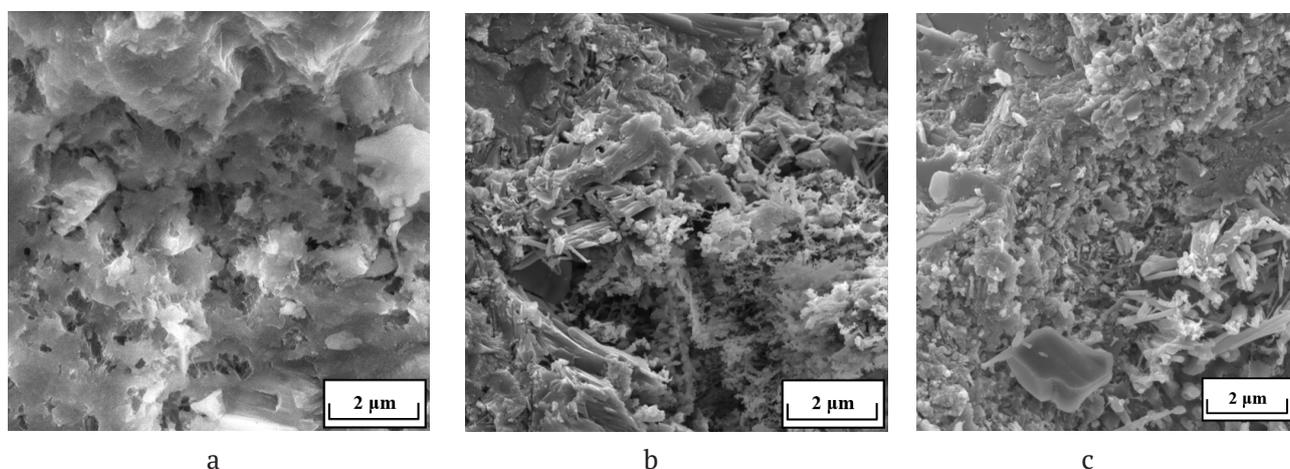


Fig. 5. Micrographs of the studied cement hardening systems (SEM data). Designated: a) C–W–SP–CNA; b) C–W–SP–CNA–S; c) C–W–SP–CNA–CF

Table 3. Results of physical and mechanical tests of cement hardening systems for compressive strength

No	System	Time, days				
		1	3	7	14	28
		Compressive strength, MPa				
1	C-W-SP-CNA	65	75	70	84	93
2	C-W-SP-CNA-S	53	60	73	67	82
3	C-W-SP-CNA-S-PF	44	62	67	73	85
4	C-W-SP-CNA-CF	38	43	67	59	82
5	C-W-SP-CNA-CF-PF	35	60	69	73	82

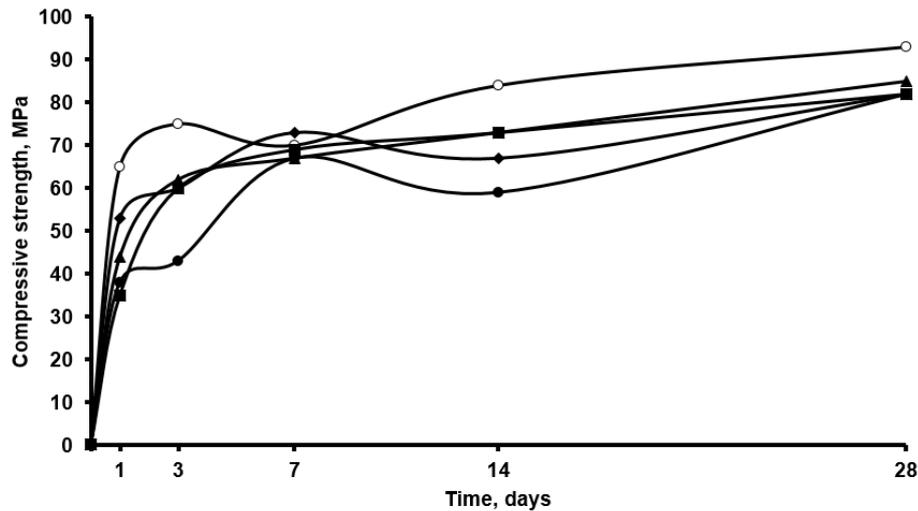


Fig. 6. Kinetic curves of strength gain of the studied cement hardening systems. Designated: ○ – C-W-SP-CNA; ◆ – C-W-SP-CNA-S; ▲ – C-W-SP-CNA-S-PF; ● – C-W-SP-CNA-CF; ■ – C-W-SP-CNA-CF-PF

Therefore, a multicomponent multifunctional additive contributed to the intensification of the process of strength gain in composites based on quartz sand and chalky flour. This effect was probably due to the synergistic effect of all components of the additive but mainly due to nanosized SiO₂ particles which, firstly, performed a catalytic role and acted as ready-made crystallisation centres, they were also directly involved in the formation of hydrated phases of the cement brick. Secondly, they increased the packing density of the system of dispersed particles and changed the porosity structure of the cement composite. This led to a change in the evolutionary route of the structure formation of the cement hardening system at the nanoscale level. What is more, the superplasticiser was able to influence the structure formation of the cement hardening system at the ultramicroscale level, whereas the polypropylene fibre influenced the structure formation at the microscale level due to micro-reinforcement and additional

zoning of the composite structure. As a result, the studied cement composites achieved sufficiently high strength characteristics at the early stages of their hardening.

4. Conclusion

We studied the multicomponent multifunctional additive with the composition “nanosized SiO₂ particles – superplasticiser - polypropylene fibre” for the rheological properties of cement composites with quartz sand and chalky flour, as well as the processes of their setting-up, hydration, structure formation, and strength gain. It was established that when this additive is used in cement composites, acceptable values of fabricability indicators (plasticity and form stability) are achieved and the setting-up processes are accelerated. It was shown that a dense structure is formed in modified cement composites mainly from low and highly basic calcium silicate hydrates of various compositions, which provides them with sufficiently high

strength properties throughout the entire hardening time. The obtained results determine the effectiveness of the used additive for modern cement composites and are of high practical importance: high plasticity and form stability of mixtures obtained by using the multifunctional additive determines the possibility of using them in the innovative technology of off-form additive manufacturing. The developed compositions of mixtures have been submitted for patenting and can be offered for commercial sale.

Author contributions

M. A. Shvedova: text writing and editing, conducting experimental studies, systematisation and description of the results. O. V. Artamonova, G. S. Slavcheva: scientific leadership, research concept, methodology development, text writing and editing, final conclusions.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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Original articles

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A model of interdiffusion occurring during the formation of thin metal films on single-crystal silicon under conditions of limited solubility of the components

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Abstract

Thin metal films are used in semiconductor and microelectronic devices to form ohmic and non-ohmic contacts to single-crystal silicon. A common feature of the used Me–Si systems is the low mutual solubility of elements and the polycrystalline nature of metal films. Solid-phase interactions during the deposition of metals on single-crystal silicon and the subsequent vacuum annealing results in the redistribution of the elements near the Me/Si interface. An important task facing the material science of solid-state electronics is to develop a mechanism of solid-phase interaction of metal thin films and single-crystal silicon. The aim of our study – was to develop a quantitative model of interdiffusion in the Me–Si system under conditions of limited solubility of the components.

The article suggests a mechanism of formation of Me–Si systems based on the diffusion and segregation of silicon near the intergrain boundaries of the metal and the limited formation of complexes during the diffusion-induced penetration of metal into silicon. The article suggests a model of reactive interdiffusion in thin metal film – single-crystal silicon systems under conditions of limited solubility of the components. Mathematical modelling was used to study the interaction of magnetron-sputtered metals Ti, W, and Nb with single-crystal silicon during isothermal vacuum annealing. The numerical analysis of experimental distributions of concentrations of Me and Si obtained by Rutherford backscattering spectroscopy allowed us to determine their individual diffusion coefficients in Me–Si systems.

The model can be used for empirical studies of the redistribution of the elements of two-layer systems with limited solubility, as well as to forecast the technological conditions for the production of electronic devices.

Keywords: Modelling, Reactive interdiffusion, Limited solubility, Metal thin films, Single-crystal silicon.

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1. Introduction

Thin films of metals such as Al, Pt, Nb, Au, Ag, Co, Pd, Ni, Ti, and W [1] are used in semiconductor and microelectronic devices to obtain ohmic and non-ohmic contacts to silicon. The contacts are typically constructed by depositing a metal on silicon followed by annealing in an inert medium. The interaction between the metal and the semiconductor is considered to have the following effect: the presence of the metal in the crystal lattice of silicon results in the weakening and breaking of covalent Si-Si bonds and the formation of mobile silicon atoms [2]. The flow of silicon atoms is directed towards the metal-silicon interface, while the metal atoms flow in the opposite direction. This results in the interdiffusion and redistribution of both metal in silicon and silicon in the metal film. The difference in the diffusion coefficients of the atoms moving towards each other results in the Kirkendall effect [3], which comes in the form of the motion of the interface in the diffusion couple.

Physicochemical interaction between metals and silicon results in the formation of eutectic systems. When the electronegativity of the diffusing metal atoms is significantly different from that of Si, a solid-phase reaction of the formation of silicide can take place [1, 4]. It is assumed that silicide phases with various concentrations of silicon and metal are formed layer-by-layer on the Me/Si interface [5].

A common feature of the used Me-Si systems is that after its deposition on silicon and during the following annealing in an inert medium, the metal remains in a polycrystalline state. The heat treatment facilitates the faster movement of grain boundaries in the metal and faster diffusion of Si in the metal film. However, the existing understanding of the interdiffusion in the Me-Si system does not take into account the role of grain boundaries in the process of diffusion-controlled growth of silicide phases and the formation of solid solutions over a wide range of temperatures.

Another feature of the used Me-Si systems is the limited solubility of silicon in the crystallites of metal and limited solubility of metal in single-crystal silicon. The existing literature does not provide enough details regarding the diffusion mechanism of the used metals in silicon and diffusion of silicon in metal.

To control the redistribution of the components near the metal-silicon interface and obtain the electrical and technological parameters of the formed structures required for the semiconductor and microelectronic devices, it is necessary to develop a mechanism for the solid-phase interaction of thin metal films and single-crystal silicon. Therefore, an important task facing the material science of solid-state electronics is to simulate the processes of interdiffusion, segregation, and solid-phase chemical reactions in the Me-Si system.

The purpose of our study was to develop a model of interdiffusion occurring during the formation of the thin metal film – a single-crystal silicon system under conditions of limited solubility of the components.

2. Description of the model

Let's assume that when a metal interacts with single-crystal silicon, its crystal lattice partially disintegrates. Some of the silicon atoms from the crystal lattice become free and transfer to a free mobile state. In the single-crystal Si, they move as self-interstitial atoms, while in the metal film they move – in the intergrain space.

Silicon has low solubility in metal crystallites. Therefore, regarding the dissolution of silicon in the metal film, we shall assume that silicon does not diffuse and dissolve in the crystallites of metal. However, under conditions of low solubility in crystallites, deep diffusion of silicon may occur along the grain boundaries together with the solubility in the intergrain space containing a large concentration of defects. As a result, the solubility limit of silicon in the intergrain space may be significantly higher than that in the crystallite volume.

Grain boundaries contain unsaturated coordinate bonds appearing on the surface of the metal grains and serve as trap centres for silicon, characterising the presence of vacant positions for silicon trapping. We assume that the mechanism of silicon trapping by metal is accompanied by a release of free metal (silicon replaces metal in the traps). Then, the formation of a solid solution of silicon in metal can be described as a diffusion penetration of mobile silicon from the single-crystal phase to the intergrain space of the metal film followed by a partial segregation trapping by

vacant trap centres. As a result, Me and Si atoms moving in the film become immobilised on the Me grain boundaries, losing their mobility.

This stage of the process is carried out by the mechanism of physical adsorption without chemical interactions resulting in the formation of compounds (silicides). The stage is topochemical and takes place in the Me film volume as a result of diffusion penetration of silicon. It is localised on the grain boundaries where the energy loss induced by bond deformation is minimal and there is some free volume facilitating the reorientation of the reacting particles. The trapping of silicon proceeds until there are no vacant traps. Along with the process of silicon trapping, the solution becomes saturated with dissolved silicon. In terms of numerical value, the concentration of traps corresponds to the solubility limit of silicon in the intergrain space of a polycrystalline metal and constitutes fraction r of the total concentration of the metal.

Regarding the process of dissolution of metal in the single-crystal silicon phase, let's assume that along with the diffusion penetration of metal into silicon, the decomposition of the solid solution of metal in silicon takes place resulting in the formation of stationary multiparticle complexes containing intrinsic point defects in silicon and metal atoms. This process limits the solubility of metal in single-crystal silicon.

A large number of metals can produce silicides with various concentrations of components, when interacting with silicon. With regard to the suggested mechanism, this ability can be interpreted as follows. The intergrain space of the metal film has an increased concentration of defects and therefore enough free volume for the potential formation of silicides whose molar volumes are different from that of the metal. During the later stages of the process and with an increased annealing temperature, a chemical absorption stage with the formation of metal enriched silicides can occur near the Me/Si interface, on the side of the metal film and in its depth. On the silicon side of the Me/Si interface, silicon enriched silicides can be formed based on the obtained complexes. The required free volume will be provided for by the intrinsic point defects in silicon. In this case, silicides do not grow layer-by-layer on the Me/Si interface. Rather, they are

formed inside an extended reaction zone next to it compatible with the initial Me film. The large extent of this zone indicates a relatively slow solid-phase reaction as compared to the rate of diffusion of mobile Si and metal atoms.

[6] suggested a convenient (from the point of view of numerical analysis) mathematical description of the interdiffusion process for a binary system with unlimited solubility. It does not take into account the chemical transformations that may occur during the interdiffusion and is based on the assumption that the molar volume of the system is invariable, regardless of the changes in its composition. In [6], the process is described by means of a boundary value problem for two diffusion equations which contain an effective interdiffusion coefficient which is a linear combination of individual diffusion coefficients of all the components.

The theory suggested in [6] is applied to the formation and growth of interface phases in the diffusion zone [7-10].

[11] for the first time developed the theory suggested in [6] as applied to bulk reactions of the formation of metal silicides during the interaction between the film of the silicide-forming Ni and SiC. However, the model suggested in [11] cannot be used to describe the redistribution of the components inside an extended reaction zone. We believe that this can be down to the fact that the model does not account for the changes in the molar volume of the system during the solid-phase reaction of the formation of silicides.

[12-14] used the mathematical description from [6] in a quantitative model which developed the theory suggested in [6] as applied to the reactive interdiffusion in two-layer metal-metal oxide systems with limited solubility of the components. This model can be used to describe the formation of complex polycrystalline Co-TiO₂ and Fe-TiO₂ thin-film systems which form not by layer-by-layer growth at the metal-oxide interface, but throughout the film thickness of TiO₂.

[15] developed the theory suggested in [6] and introduced a model of reactive interdiffusion in nonstoichiometric polycrystalline oxide film systems with limited solubility under vacuum annealing conditions. The model was used to describe the formation of the phases of complex

oxides distributed along the depth of the system of two nonstoichiometric polycrystalline oxides of titanium and cobalt [16].

The application of the model suggested in [6] to the metal film - single-crystal silicon system with limited solubility of the components has not been studied yet.

In our study, we considered the following components of the system.

- Stationary silicon atoms A which constitute the lattice of single-crystal silicon.
- Mobile silicon atoms B formed as a result of interaction between the metal and silicon.
- Vacant trap centres Ct for mobile silicon in the intergrain space of the metal.
- Silicon atoms Bt trapped in the intergrain space of the metal.
- Mobile (free) metal atoms C.
- Stationary complexes C_p in silicon containing metal and silicon atoms.

The total concentration of silicon was comprised of the following elements:

- concentration of silicon C_A at the points of the silicon crystal lattice A;
- concentration C_B of mobile silicon B;
- concentration C_{Bt} of silicon trapped by Bt traps in the intergrain space of the metal; and
- silicon concentration C_{Cp} in metal-silicon complexes C_p :

$$C_A + C_B + C_{Bt} + C_{Cp}.$$

The total concentration of metal was comprised of the following elements:

- concentration of mobile (free) metal C;
- metal concentration in the vacant trap centres for mobile silicon in the intergrain space of the metal C_{Bt} ;
- metal concentration C_{Cp} in metal-silicon complexes C_p :

$$C_C + C_{Bt} + C_{Cp}.$$

The elements of the system capable of diffusion-induced migration are mobile metal atoms C and mobile silicon atoms B released in the presence of the metal from the crystal lattice of silicon. If the beginning of the reference system is the outer border of the Me film, then, with the ratio of individual diffusion coefficients being ($D_C \gg D_B$), the Me-Si grain boundary will move towards the surface of the film system as a result

of the Kirkendall effect [3]. The elements not capable of diffusion-induced migration will serve as inert markers in the Smigelskas and Kirkendall experiment [3].

In our study, the qualitative nature of the process determines that the molar volume of the system is invariable. Therefore, we assume that the diffusion of Me and Si in the Me-Si system can also be described by means of the mathematical formalism suggested in [6]. Let's determine the effective interdiffusion coefficient for the simulated system as

$$D^* = \frac{D_B \cdot C_C + D_C \cdot C_B}{C_{tot}}, \quad (1)$$

where D_B and D_C – are individual diffusion coefficients of the mobile components - of free silicon and metal respectively, $C_{tot} = C_A + C_B + C_C + C_{Cp} + C_{Bt} + C_{Ct}$ – is the total concentration of all the components of the system.

Let us assume that the rate of destruction of silicon A at the points of the crystal lattice and the rate of generation of mobile silicon B are directly proportional to the concentration of silicon C_A at the points of its crystal lattice A and the concentration of metal C_C in silicon C. The equation describing the concentration of silicon C_A at the points of the crystal lattice A is presented as follows:

$$\frac{\partial C_A}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_A}{\partial x} \right) - k_1 \cdot C_C \cdot C_A. \quad (2)$$

Let's assume that mobile silicon B participates in three processes:

- formation of silicon as a result of the destruction of the crystal lattice at a rate that is directly proportional to the concentration of atoms at the points of the silicon crystal lattice A and the concentration of atoms of the mobile metal C;
- diffusion of the metal film in silicon and the intergrain space by means of segregation trapping at a rate directly proportional to the concentration C_{Ct} of vacant traps Ct of the metal and the concentration C_B of mobile silicon B;
- trapping of the stationary complexes C_p in silicon at a rate directly proportional to the concentration of atoms of the mobile metal C.

Then, the equation for the concentration C_B of mobile silicon B can be presented as follows:

$$\frac{\partial C_B}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_B}{\partial x} \right) + k_1 \cdot C_A \cdot C_C - k_2 \cdot C_{Ct} \cdot C_B - k_3 \cdot C_B \cdot C_C. \quad (3)$$

Silicon is trapped in the intergrain space of the metal at a rate directly proportional to the concentration C_B of mobile silicon B and the concentration C_{Ct} of vacant traps C_t . The equation for the concentration C_{Bt} of silicon Bt trapped in the intergrain space of the metal is

$$\frac{\partial C_{Bt}}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_{Bt}}{\partial x} \right) + k_2 \cdot C_{Ct} \cdot C_B. \quad (4)$$

The rate of trapping C_t in the intergrain space of the metal is directly proportional to the concentration of traps C_{Ct} and the concentration C_B of mobile silicon B. The equation for the concentration C_{Ct} of vacant trap centres C_t is

$$\frac{\partial C_{Ct}}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_{Ct}}{\partial x} \right) - k_2 \cdot C_B \cdot C_{Ct}. \quad (5)$$

The diffusion equation for the concentration C_C of the mobile metal C takes into account the fact that the metal is released from the traps in the intergrain space of the metal according to the exchange mechanism. It also takes into account the trapping of stationary complexes in silicon at a rate directly proportional to the concentration C_B of mobile silicon B:

$$\frac{\partial C_C}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_C}{\partial x} \right) + k_2 \cdot C_{Ct} \cdot C_B - k_3 \cdot C_B \cdot C_C. \quad (6)$$

The equation for the concentration C_{Cp} of metal atoms immobilised in C_p complexes takes into account the fact that the rate of bonding of mobile Me to the metal-silicon complexes is directly proportional to the concentration C_B of mobile silicon B and the concentration C_C of metal C in silicon:

$$\frac{\partial C_{Cp}}{\partial t} = \frac{\partial}{\partial x} \left(D^* \frac{\partial C_{Cp}}{\partial x} \right) + k_3 \cdot C_B \cdot C_C. \quad (7)$$

For equations (2)-(7), t – is the time, x – is the depth from the outer surface of the metal film, and k_1 , k_2 , and k_3 – are rate constants of the formation of mobile silicon, its trapping in the metal film, and formation of metal-silicon complexes respectively.

At the Me-Si interface, the condition for the reflection for all the components of the system is

$$\frac{\partial C_A}{\partial x} = \frac{\partial C_B}{\partial x} = \frac{\partial C_C}{\partial x} = \frac{\partial C_{Cp}}{\partial x} = \frac{\partial C_{Bt}}{\partial x} = \frac{\partial C_{Ct}}{\partial x} = 0 \quad (8)$$

when $x = 0$ and $x = L$,

where L is the thickness of the solution region in silicon.

The initial conditions for equations (2)–(7) when simulating the redistribution are the following:

$$C_A(x, 0) = 0, C_{Ct}(x, 0) = r \times N_{SC}, C_C(x, 0) = (1 - r) \times N_{SC}, \quad \text{when } 0 \leq x \leq h, \quad (9)$$

$$C_A(x, 0) = N_{SA}, C_{Ct}(x, 0) = 0, C_C(x, 0) = 0, \quad \text{when } h < x \leq L, \quad (10)$$

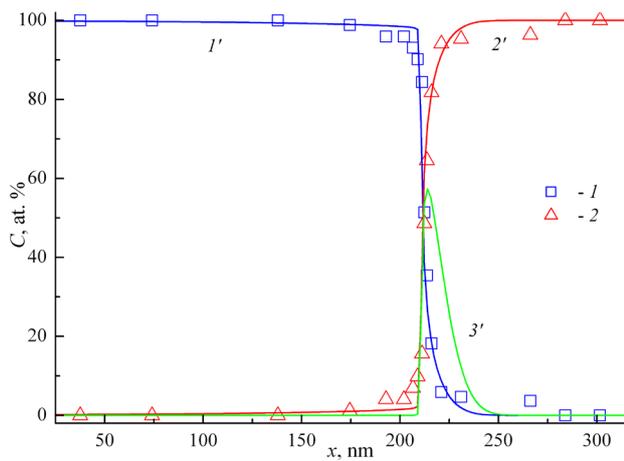
$$C_B(x, 0) = 0, C_{Bt}(x, 0) = 0, C_{Cp}(x, 0) = 0 \quad \text{when all } 0 \leq x \leq L, \quad (11)$$

where h is the thickness of the metal film, N_{SA} is the intrinsic concentration of Si atoms ($N_{SA} = 4.98 \cdot 10^{22} \text{ cm}^{-3}$), N_{SC} is the intrinsic concentration of metal atoms ($N_{SC} = 5.68 \cdot 10^{22} \text{ cm}^{-3}$ for Ti, $6.34 \cdot 10^{22} \text{ cm}^{-3}$ for W, and $5.55 \cdot 10^{22} \text{ cm}^{-3}$ for Nb), and r is the number of traps for Si atoms in the intergrain space of Me.

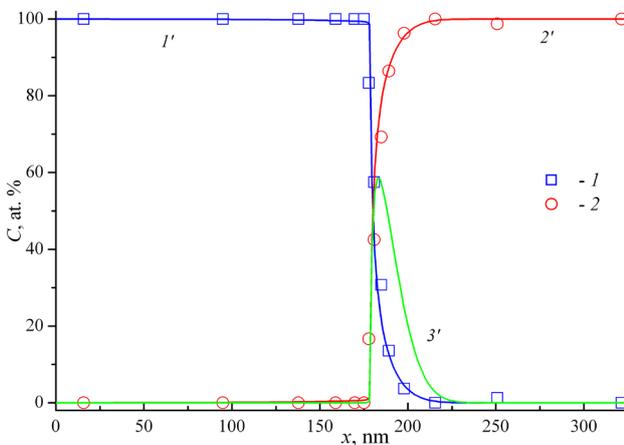
The set of equations (2)–(7) with the concentration dependant interdiffusion coefficient (1) was solved numerically by means of the factorization method using implicit conservative difference schemes [17].

The model had the following parameters: individual diffusion coefficients of Me and Si, rate constants k_1 , k_2 , and k_3 , and r .

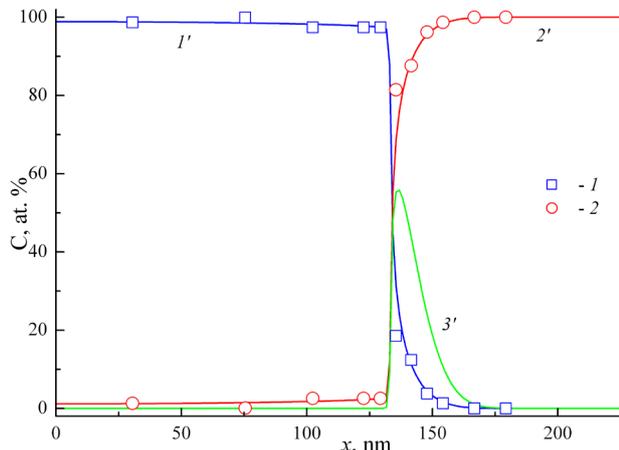
Fig. 1 *a-c* shows experimental (points 1, 2) and calculated (curves 1', 2') concentrations of distributions of Me and Si along the depth of the Me-Si film system obtained by means of Rutherford backscattering spectroscopy (RBS) after magnetron deposition of Me (Ti, W, Nb) on single-crystal silicon and vacuum annealing at $T = 673 \text{ K}$, $t = 30 \text{ min}$. The experimental and calculated distributions were in good agreement when $k_1 = 1 \cdot 10^{-26} \text{ cm}^3/\text{c}$, $k_2 = 1 \cdot 10^{-18} \text{ cm}^3/\text{c}$, and $k_3 = 1 \cdot 10^{-19} \text{ cm}^3/\text{c}$ were identical for all the metals used, and the model parameters were the ones given in Table 1. The obtained curves demonstrate that the dominating diffusant for all the studied systems is mobile silicon (curves 3' in



a



b



c

Fig. 1. Experimental (RBS) (points (symbols) 1, 2) and calculated (curves 1', 2', 3') distributions along the depth of the Me–Si system of the total concentration C of metal (1'), silicon (2'), and its mobile atoms (3'). 1 – Me, 2 – Si; curves: 1' – Me, 2' – Si after magnetron sputtering and vacuum annealing at $T = 673$ K, $t = 30$ min. (a) – Ti, (b) – W, (c) – Nb.

Table 1. Parameters of the model for Ti, W, and Nb in the Me–Si system

Metal	$D_B \times 10^{14}$ cm ² /s	$D_C \times 10^{16}$ cm ² /s	r
Ti	4.0	4.0	0.02
W	1.0	6.0×	0.008
Nb	6.0	4.0	0.028

Fig. 1 a-c). Its distribution maximum is located at the Me/Si interface.

3. Conclusions

In our study, we developed a model of interdiffusion occurring during the formation of the polycrystalline metal film – single-crystal silicon system with limited solubility of the components. The model is based on the knowledge of solubility of silicon in the intergrain space of the metal, its segregation on the intergrain traps, and the solubility of metal in silicon limited by the complex formation process. Using the numerical analysis of the experimental distribution of concentrations of the elements of Me(Ti, W, Nb)–Si systems within the model, we determined the individual diffusion coefficients for metal and silicon, as well as the number of traps for Si atoms in the intergrain space of Me.

The model can be used to describe the redistribution of the elements of the Me–Si systems for the synthesis conditions ensuring the chemical interaction between metal and silicon and the formation of silicides. It also describes the mechanism of the possible formation of silicide phases near the Me/Si interface as the deep interdiffusion of the elements rather than layer-by-layer growth on the Me/Si interface.

The article also demonstrated that mathematical formalism suggested in [6] for the description of the interdiffusion in binary systems with unlimited solubility, can be used to describe the redistribution of the elements of Me–Si systems with limited solubility of the components.

The model can be used for empirical studies of the interdiffusion processes in Me–Si systems with limited solubility as well as to forecast the technological conditions for obtaining ohmic and non-ohmic Me–Si contacts in micro- and nanoelectronic devices.

Author contributions

Afonin N. N. – scientific leadership, research concept, simulation, text writing, final conclusions. Logachova V. A. – conducting research, review and text writing, editing the text.

Conflict of interests

The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

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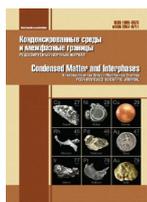
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Condensed Matter and Interphases

Kondensirovannye Sredy i Mezhfaznye Granitsy
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Professor Mahammad B. Babanly's anniversary



In January, Mahammad B. Babanly, an outstanding scientist and our good friend, celebrated his 70th birthday.

Babanly was born in 1952. In 1968–1973 he studied at the Faculty of Chemistry of Baku State University, graduated with honours, and enrolled on a PhD programme. In 1977 he defended his PhD thesis at Belarusian State University, and in 1988 he defended his doctoral thesis in the field of “inorganic chemistry” at Moscow State University. In 1990 Babanly gained the title of full professor.

At Baku State University he has worked as a junior researcher (1977–1979), senior researcher (1979–1983), lecturer (1983–1986), associate professor (1986–1989), and professor (1989–1994). From 1992 to 1994 he was vice-rector at Baku State University. In 1994–2005 he was head of the Department of General and Inorganic Chemistry at Baku State University, and from 2006 to the end of March of 2014 he was a professor at this department and scientific supervisor of the “Inorganic material science” research laboratory. At the Institute of Catalysis and Inorganic Chemistry, Azerbaijan National Academy of

Sciences, he was deputy director for research from 2014 and became executive director in 2021.

Professor Babanly is a renowned scientist who has created a new scientific field and a scientific school in the field of chemistry, thermodynamics, and material science of complex inorganic semiconductors. In the late 1970s, he was the first to introduce the EMF method into the traditional set of methods for the study of phase equilibria (PE) of three-component semiconductor systems and started a new comprehensive approach to the study of their PE and thermodynamic properties (TP). As part of this approach, he developed a thermodynamically strict method for the calculation of integral thermodynamic functions of ternary and more complex condensed phases based on the partial molar quantities of one of the components and the phase diagram of the corresponding system. Continuing to develop this field of study, he was the first to use solid electrolytes with cationic conductivity for the physicochemical study of complex semiconductor chalcogenides in the late 1980s. Thus he significantly expanded the possibilities of the EMF method so it could be applied to many systems that could not be studied using the traditional version of this method. He also found a new type of potential formation reactions in complex concentration cells and developed a technique for their practical application in thermodynamic studies.

Regular comprehensive studies of the PE and TP of complex semiconductor systems have been conducted under the supervision of Mahammad B. Babanly for over 30 years. For the first time, a set of consistent data on PE and TP was obtained for over 100 three-component chalcogen-containing systems based on thallium, copper, and silver, while dozens of quaternary and quinary systems were studied along stable planes (quasi-ternary and mutual systems). Multiple new compounds and phases of variable compositions



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were discovered, and the researchers established the nature of their formation, homogeneity regions, types and parameters of the crystal lattice, standard thermodynamic functions of formation, thermodynamic functions of melting and polymorphic transformations, as well as other properties.

Over the last 10 years, Professor Babanly and his colleagues have also been developing physicochemical bases for obtaining ternary and more complex chalcogenide phases that are topological insulators. Comprehensive studies of single crystals of a series of such phases that were grown by them together with their colleagues from EU countries and Japan showed that it is a promising solution for the new generation quantum computers and spintronics.

The issues raised in the works of Professor Babanly are highly important for the development of fundamental inorganic chemistry and, in particular, physicochemical analysis, chemical thermodynamics, and material science of complex inorganic systems.

Babanly has published more than 1,000 research papers, including 4 monographs, over 550 articles, and 5 patents. Over 200 articles have been published in the international journals included in Science Citation Index

(Nature Communications, Journal of Alloys and Compounds, Physical Review Letters, Physical Review B, *Mettalkunde*, International Journal of Materials Research, and journals of the Russian Academy of Sciences, such as Russian Journal of Inorganic Chemistry, Inorganic materials, Physical Chemistry Journal, Electrochemistry, and others). He has also repeatedly presented his reports at numerous international and regional scientific conferences.

Most scientific results obtained by Professor Babanly and his colleagues have been included into such fundamental reference works as “Phase equilibria diagrams”, “Ternary alloys”, “State diagrams of metal systems”, etc., as well as into the databases of the information agencies Springer, Elsevier, Tomson Reuters, and others.

M. Babanly continues to form and develop his own scientific school. He has supervised 2 doctoral dissertations and 35 PhD theses. Among the scientists with a PhD degree supervised by him are researchers from Syria, Afghanistan, Vietnam, and Korea.

M. Babanly maintains close academic connections with many research organisations of the European Union, Japan, Russian Federation, and Ukraine resulting in numerous joint publications.

Professor Babanly actively participates in the scientific and social life of the Republic of Azerbaijan. In previous years he was a member, the chair, and deputy chair of the Expert Board on Chemistry of the State Commission for Academic Degrees under the President of the Republic of Azerbaijan, a member of the Academic Council of Baku State University as well as several dissertation boards. At present, he is the member of the dissertation board at the Institute of Catalysis and Inorganic Chemistry and the editorial boards of the Turkish Journal of Chemistry, Russian Journal of Inorganic Chemistry, Condensed Matter and Interphases, Physics and Chemistry of Solid State, New Materials, Compounds and Applications and Chemical Problems, and Azerbaijan Chemistry Journal.

In 2000, he was awarded with a Taraggi Medal by the Decree of the President of the Republic of Azerbaijan. In 2011 he received a prize and a diploma of the Praesidium of the Russian





Academy of Sciences for a series of research articles published in the journals of the Russian Academy of Sciences.

In 2016, he was awarded with the Thomson Reuters Special Prize for the most cited “Outstanding Scientific Article”.

In 2016, he won the “Scientist of the Year” competition held by the Science Development Fund under the President of the Republic of Azerbaijan.

He also received diplomas from the Russian Journal of Inorganic Chemistry as the author of the most cited articles in 2019 and 2020.

For his scientific achievements he was repeatedly awarded with honorary certificates by the Ministry of Education of the Republic of Azerbaijan, the Department of Chemistry of Azerbaijan National Academy of Sciences, and the rector of Baku State University.

Mahammad B. Babanly is a long-time friend of the Faculty of Chemistry who has come to

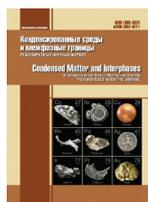
Voronezh many times and acted as the chair of the Physicochemical Analysis section of the All-Russian Conference with International Participation “PHYSICAL AND CHEMICAL PROCESSES IN CONDENSED MATTER AND INTERPHASE BOUNDARIES”. He has repeatedly presented plenary reports that were memorable, attracted great interest, and were discussed by scientists from various cities of Russia for a long time. We are grateful to M. B. Babanly for his active work on the editorial board of the journal “Condensed Matter and Interphases” as an editor, reviewer, and author. Thanks to him, the editorial portfolio includes articles by his colleagues from Azerbaijan that are cited in international scientific databases. We hope that no outside challenges will interfere with our cooperation and future meetings.

We would like to congratulate Professor Mahammad B. Babanly on his 70th birthday and wish him good health, success, and new achievements in his further endeavours!

The team of the Faculty of Chemistry of Voronezh State University,

The Editorial Board of the journal Condensed Matter and Interphases

Translated by Marina Strepetova



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Review/Original article/Short communication
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Modelling of interdiffusion and phase formation in thin-film two-layer systems of polycrystalline oxides of titanium and cobalt

(All proper nouns should be capitalized; titles and subtitles should be left-aligned)

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Article structure

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The introduction (1–2 pages) states the problem under consideration, its relevance, and the most important tasks that need to be resolved. Describe the scientific problems which have not yet been solved and which you sought to solve in your research. The introduction should contain a short critical review of previously published works in this field and their comparative analysis. It is recommended that the analysis is based on 20–30 studies (at least 15 references to scientific papers, no more than 20% of references to the author's own works, at least 30% of references should be to original articles by international authors, at least 50% of the references should be to articles published within the previous 5 years). **The purpose** of the article is indicated by the problem statement.

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Example:

Fig. 1. Dependences of the parameters a and c of the tetragonal lattice of nanocrystalline PdO films on the oxidation temperature T_{ox} : 1 – single-phase PdO films, 2 – heterophase PdO + Pd films; 3 – data of the ASTM standard [22, 23]

Table 1. The values of relative electronegativity (ENE) of some chemical elements [30] and the proportion of the ionic component of the chemical bond in binary compounds of the AB composition formed by these elements

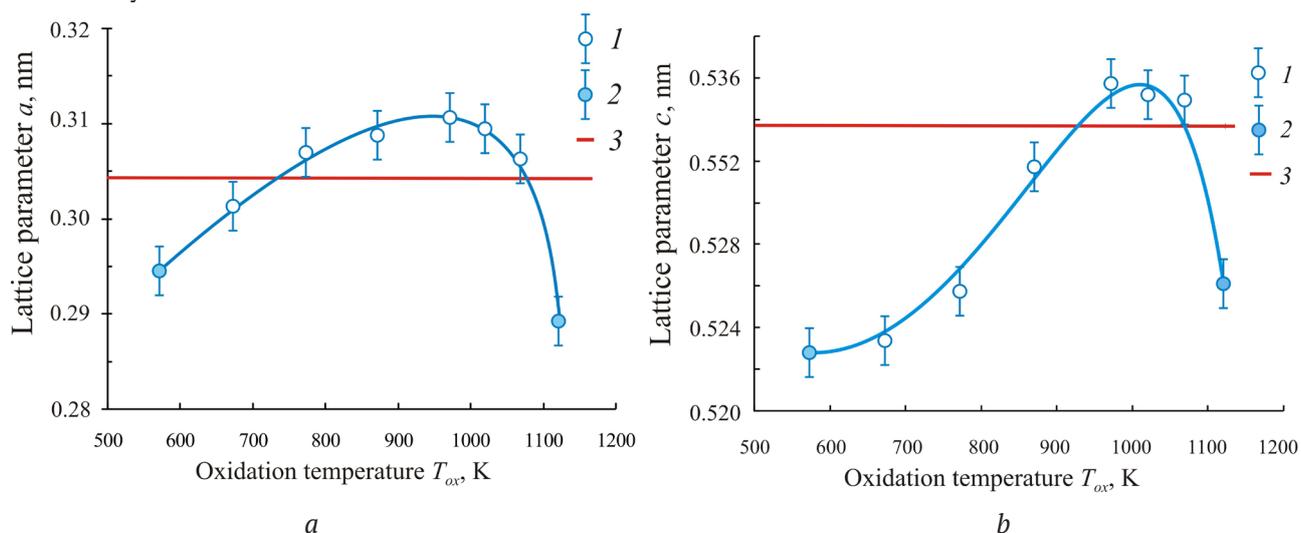


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Table 1. Values of the ionic radii of palladium Pd²⁺ and oxygen O²⁻ [30–32]

Ion	Coordination number CN	Coordination polyhedron	Values of ionic radii R_{ion} , nm
Pd ²⁺	4	Square (rectangular)	0.078 [30]; 0.086 [31]; 0.078 [32]
O ²⁻	4	Tetragonal tetrahedron	0.132 [30]; 0.140 [31]; 0.124* [31]; 0.132 [32]

*The values of ionic radius were obtained on the basis of quantum mechanical calculations.

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